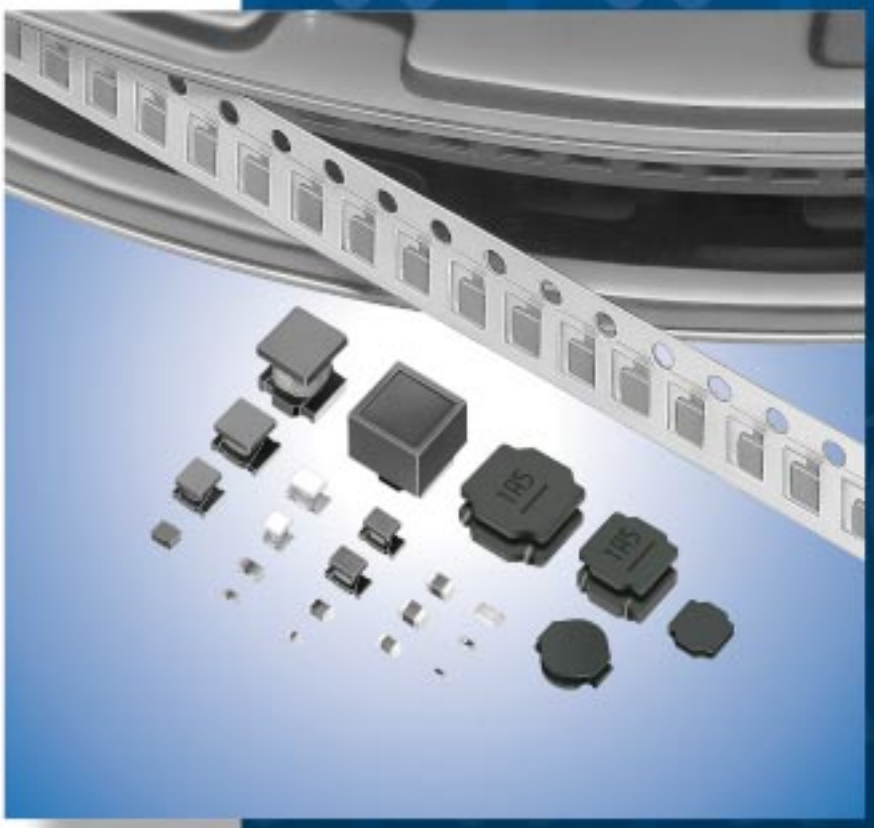
Chip Inductors (Chip Coils)



Innovator in Electronics

Murata
Manufacturing Co., Ltd.

Cat.No.O05E-21

for EU RoHS Compliant

・All the products in this catalog comply with EU RoHS.
・EU RoHS is "the European Directive 2002/95/EC on the Restriction of the Use of Certain Hazardous Substances in Electrical and Electronic Equipment".
・For more details, please refer to our website 'Murata's Approach for EU RoHS' (http://www.murata.com/info/rohs.html).

CONTENTS

● Part Numbering

Chip Inductors (Chip Coils)(SMD)

(Part Number)

LQ	H	32	M	N	331	K	2	3	L
❶	❷	❸	❹	❺	❻	❼	❽	❾	❿

❶Product ID

Product ID	
LQ	Chip Inductors (Chip Coils)

❷Structure

Code	Structure
G	Multilayer Type (Air-core Inductor (Coil))
H	Wire Wound Type (Ferrite Core)
M	Multilayer Type (Ferrite Core)
P	Film Type
W	Wire Wound Type (Air-core Inductor (Coil))

❸Dimensions (L×W)

Code	Dimensions (L×W)	EIA
02	0.4×0.2mm	01005
03	0.6×0.3mm	0201
04	0.8×0.4mm	03015
15	1.0×0.5mm	0402
18	1.6×0.8mm	0603
21	2.0×1.25mm	0805
2B	2.0×1.5mm	0805
2M	2.0×1.6mm	0806
2H	2.5×2.0mm	1008
3N	3.0×3.0mm	1212
31	3.2×1.6mm	1206
32	3.2×2.5mm	1210
43	4.5×3.2mm	1812
44	4.0×4.0mm	1515
55	5.7×5.0mm (5.87×5.2mm)	2220
6P	6.0×6.0mm	2424
66	6.3×6.3mm	2525
88	8.0×8.0mm	3131

❹Applications and Characteristics

Code	Series	Applications and Characteristics
H	**LQG**	Multilayer Air-core Inductor (Coil)
N	**LQM**	for Resonant Circuit
D		for Choke (Low-current DC Power Supplies)
F		for Choke (DC Power Supplies)
M	**LQP**	Film Type
T		Film Type (Low DC Resistance Type)
A	**LQW**	High Q Type (UHF-SHF)
H		High Q Type (VHF-UHF)
N	**LQH**	for Resonant Circuit
M		for Resonant Circuit (Coating Type)
D		for Choke
C		for Choke (Coating Type)
S		for Choke (Magnetically Shielded Type)
H		for High-frequency Resonant Circuit
P	**LQM/LQH**	for Power Line

❺Category

Code	Category
N	Standard Type
S	

❻Inductance

Expressed by three-digit alphanumerics. The unit is micro-henry (μH). The first and second figures are significant digits, and the third figure expresses the number of zeros which follow the two figures. If there is a decimal point, it is expressed by the capital letter "**R**". In this case, all figures are significant digits. If inductance is less than 0.1μH, the inductance code is expressed by a combination of two figures and the capital letter "**N**", and the unit of inductance is nano-henry (nH).
The capital letter "**N**" indicates the unit of "nH", and also expresses a decimal point. In this case, all figures are significant digits.

❼Inductance Tolerance

Code	Inductance Tolerance
B	±0.1nH
C	±0.2nH
D	±0.5nH
G	±2%
H	±3%
J	±5%
K	±10%
M	±20%
N	±30%
S	±0.3nH
W	±0.05nH

❽Features (Except **LQH□□P/LQM□□P**)

Code	Features	Series
0	Standard Type	**LQG/LQP/LQW/LQM***1**/LQH***2
1	High-Q/ Low DC Resistance	**LQW15A/18A/2BH**
	Standard Type	**LQM21N**
2	Standard Type	**LQH32C/32M**
3	Low DC Resistance	**LQH32C**
5	Low Profile Type	**LQH2MC/32C**
7	Large Current Type	**LQM21F**
8	Low DC Resistance /Large Current Type	

*1 Except LQM21N Series
*2 Except LQH32 Series

Continued on the following page.

Continued from the preceding page.

(Part Number) **LQ H 32 M N 331 K 2 3 L**
❶ ❷ ❸ ❹ ❺ ❻ ❼ ❽ ❾ ❿

❽Thickness (**LQH□□P/LQM□□P** Only · Except **LQH6PP/LQH88P**)

Code	Dimensions (T)
C	0.5mm
E	0.7mm
0	0.85mm
G	0.9mm
J	1.1mm
M	1.4mm
N	1.55mm
P	1.65mm
R	1.85mm

❾Electrode (Except **LQH□□P/LQM□□P**)

•Lead (Pb) Free

Code	Electrode	Series
0	Sn	**LQG18H/LQP03T/LQW□□A/LQM**
2		**LQG15H/LQP02T/LQP03T/LQP15T/ LQP□□M/LQH2MC**
3	LF Solder	**LQW□□H/LQH** (Except **LQH2MC**)
4	Au	**LQP03T**

❾Specification (**LQH□□P/LQM□□P** Only · Except **LQH6PP/LQH88P**)

Code	Specification
0	Standard Type

❽❾Thickness (**LQH6PP/LQH88P** Only)

Code	Dimension (T)
38	3.8mm
43	4.3mm

❿Packaging

Code	Packaging	Series
K	Embossed Taping (ø330mm Reel)	**LQH***1 **/LQW□□H***6 **/LQM31F/LQM21***2
L	Embossed Taping (ø180mm Reel)	**LQH/LQW□□H/LQM31F/LQM21***2 **/LQM31P/LQM2HP/LQM2MP**
B	Bulk	**LQH2MC/LQW/LQG/LQM/LQP**
J	Paper Taping (ø330mm Reel)	**LQW18A/LQG/LQM18/LQM21***3 **/LQP***5
D	Paper Taping (ø180mm Reel)	**LQW□□A/LQG/LQM18/LQM21***4 **/LQP**

*1 Except LQH2MC/LQH32P/LQH3NP/LQH43C
*2 LQM21D(22 - 47µH)/LQM21F(4.7 - 47µH)/LQM21N(2.7 - 4.7µH) only.
*3 LQM21D(1.0 - 10µH)/LQM21F(1.0 - 2.2µH)/LQM21N(0.1 - 2.2µH) only.
*4 LQM21D(1.0 - 10µH)/LQM21F(1.0 - 2.2µH)/LQM21N(0.1 - 2.2µH)/LQM21P only.
*5 Except LQP02T/15T
*6 Except LQW21H

Product Guide

Murata's LQ□ series of chip inductors (chip coils) consists of compact, high-performance inductors. Their innovative coil and case structures mean low DC resistance and outstanding high-frequency characteristics. The series is designed for a variety of applications, facilitating component selection for individual circuit requirements.

	Part Number	Structure	Size Code Inch (mm)	Inductance Range (1n 10n 100n 1µ 10µ 100µ 1m 10m)	Rated Current (mA) (10 100 1000 10000)
Power Inductor	**LQM21P**	Magnetically Shielded Multilayer	0805 (2012)	470nH 2.2µH	600 1300
	LQM2MP		0806 (2016)	470nH 4.7µH	1100 1600
	LQM2HP_J0		1008 (2520)	1.0µH 3.3µH	1000 1500
	LQM2HP_G0		1008 (2520)	470nH 4.7µH	1100 1800
	LQM2HP_E0		1008 (2520)	560nH	1500
	LQM31P_00		1206 (3216)	470nH 4.7µH	700 1400
	LQM31P_C0		1206 (3216)	470nH 2.2µH	900 1300
	LQH2MC_02	Wire Wound	0806 (2016)	1.0µH 82µH	90 485
	LQH2MC_52		0806 (2016)	1.0µH 22µH	130 595
	LQH3NP_M0		1212 (3030)	1.0µH 100µH	200 1400
	LQH3NP_J0		1212 (3030)	1.0µH 47µH	200 1620
	LQH3NP_G0		1212 (3030)	1.0µH 250µH	80 1525
	LQH32P		1210 (3225)	470nH 22µH	450 2550
	LQH44P_P0		1515 (4040)	1.0µH 22µH	790 2450
	LQH44P_J0		1515 (4040)	1.0µH 47µH	300 1530
	LQH55P		2220 (5852)	1.2µH 22µH	670 2600
	LQH6PP		2424 (6060)	1.0µH 100µH	800 4300
	LQH88P		3131 (8080)	1.0µH 100µH	1000 8000
Chokes	**LQM18F**	Magnetically Shielded Multilayer	0603 (1608)	1.0µH 10µH	50 150
	LQM21D		0805 (2012)	1.0µH 47µH	7 60
	LQM21F		0805 (2012)	1.0µH 47µH	7 220
	LQM31F		1206 (3216)	10µH	70
	LQH31C	Wire Wound	1206 (3216)	120nH 100µH	80 970
	LQH32C_23/_33		1210 (3225)	150nH 560µH	60 1450
	LQH32C_53		1210 (3225)	1.0µH 100µH	100 1000
	LQH43C		1812 (4532)	1.0µH 470µH	90 1080
	LQH55D		2220 (5750)	120nH 10mH	50 6000
	LQH66S	Magnetically Shielded	2525 (6363)	270nH 10mH	50 6000
General Frequency Range	**LQM18N**	Magnetically Shielded Multilayer	0603 (1608)	47nH 2.2µH	15 50
	LQM21N		0805 (2012)	100nH 4.7µH	30 250
	LQH31M	Wire Wound (ferrite core)	1206 (3216)	150nH 100µH	45 250
	LQH32M		1210 (3225)	1.0µH 560µH	40 445
	LQH43M(N)		1812 (4532)	1.0µH 2.2mH	30 500
High Frequency Range	**LQG15H**	Multilayer	0402 (1005)	1.0nH 270nH	110 300
	LQG18H		0603 (1608)	1.2nH 100nH	300 500
Tight Inductance Tolerance	**LQP02T**	Film	01005 (0402)	0.4nH 18nH	140 320
	LQP03T_02		0201 (0603)	0.6nH 120nH	40 850
	LQP03T_00		0201 (0603)	0.6nH 56nH	100 840
	LQP03T_04		0201 (0603)	0.6nH 56nH	50 420
	LQP15T		0402 (1005)	1.0nH 18nH	80 300
	LQP15M		0402 (1005)	1.0nH 33nH	60 400
	LQP18M		0603 (1608)	1.3nH 100nH	50 300
	LQW04A	Wire Wound (air core)	03015 (0804)	1.1nH 33nH	140 990
	LQW15A		0402 (1005)	1.3nH 120nH	110 1200
	LQW18A		0603 (1608)	2.2nH 470nH	75 1400
	LQW2BH		0805 (2015)	2.7nH 470nH	160 1900
	LQW31H		1206 (3216)	8.8nH 100nH	230 750
	LQW21H	Wire Wound (ferrite core)	0805 (2012)	470nH 2.2µH	75 160
	LQH31H		1206 (3216)	54nH 880nH	180 920

Inductance Lineup
: E-24 or Higher
: E-12
: Other
*There are some items which do not match to E step.

CAUTION: Use rosin-based flux, but not strong acidic flux (with chlorine content exceeding 0.2wt%) when soldering chip inductor (chip coil). Do not use water-soluble flux.

Selection Guide

Construction?

Circuit Type?	Application?		Wire Wound	Multilayer	Film
Power Line	Voltage Conversion		**LQH2MC_02** 0806/1.0–82µH/90–485mA	**LQM21P** 0805/0.47–2.2µH/600–1300mA	
			LQH2MC_52 (Low profile type) 0806/1.0–22µH/130–595mA	**LQM2MP** 0806/0.47–4.7µH/1100–1600mA	
			LQH3NP_M0 1212/1.0–100µH/200–1400mA	**LQM2HP_J0** 1008/1.0–3.3µH/1000–1500mA	
			LQH3NP_J0 1212/1.0–47µH/200–1620mA	**LQM2HP_G0** 1008/0.47–4.7µH/1100–1800mA	
			LQH3NP_G0 1212/1.0–250µH/80–1525mA	**LQM2HP_E0** 1008/0.56µH/1500mA	
			LQH32P 1210/0.47–22µH/450–2550mA	**LQM31P_00** (Standard type) 1206/0.47–4.7µH/700–1400mA	
			LQH44P_P0 1515/1.0–22µH/790–2450mA	**LQM31P_C0** (Low profile type) 1206/0.47–2.2µH/900–1300mA	
			LQH44P_J0 1515/1.0–47µH/300–1530mA		
			LQH55P 2220/1.2–22µH/670–2600mA		
			LQH6PP 2424/1.0–100µH/0.8–4.3A		
			LQH88P 3131/1.0–100µH/1.0–8.0A		
		Choke	**LQH31C** 1206/0.12–100µH/80–970mA	**LQM18F** 0603/1.0–10µH/50–150mA	
			LQH32C (Standard type) 1210/0.15–560µH/60–1450mA	**LQM21D** 0805/1.0–47µH/7–60mA	
			LQH32C_53 (Low profile type) 1210/1.0–100µH/100–1000mA	**LQM21F** 0805/1.0–47µH/7–220mA	
			LQH43C 1812/1.0–470µH/90–1080mA	**LQM31F** 1206/10µH/70mA	
			LQH55D 2220/0.12–10000µH/0.05–6.0A		
			LQH66S 2525/0.27–10000µH/0.05–6.0A		
Signal Line	Operating Frequency?	Less than 100MHz General	**LQH31M** 1206/0.15–100µH	**LQM18N** 0603/47–2200nH	
			LQH32M 1210/1.0–560µH	**LQM21N** 0805/0.1–4.7µH	
			LQH43M(N) 1812/1.0–2200µH		
		Greater than 100MHz High Frequency	**LQW04A** 03015/1.1–33nH	**LQG15H** 0402/1.0–270nH	**LQP02T** 01005/0.4–18nH
			LQW15A 0402/1.3–120nH	**LQG18H** 0603/1.2–100nH	**LQP03T** 0201/0.6–120nH
			LQW18A 0603/2.2–470nH		**LQP15T** 0402/1.0–18nH
			LQW2BH 0805/2.7–470nH		**LQP15M** 0402/1.0–33nH
			LQW31H 1206/8.8–100nH		**LQP18M** 0603/1.3–100nH
			LQW21H 0805/0.47–2.2µH		
			LQH31H 1206/54–880nH		

Guidance of Digits in This Chart

●for **LQH2MC_02** 0806/1.0–82µH/90–485mA

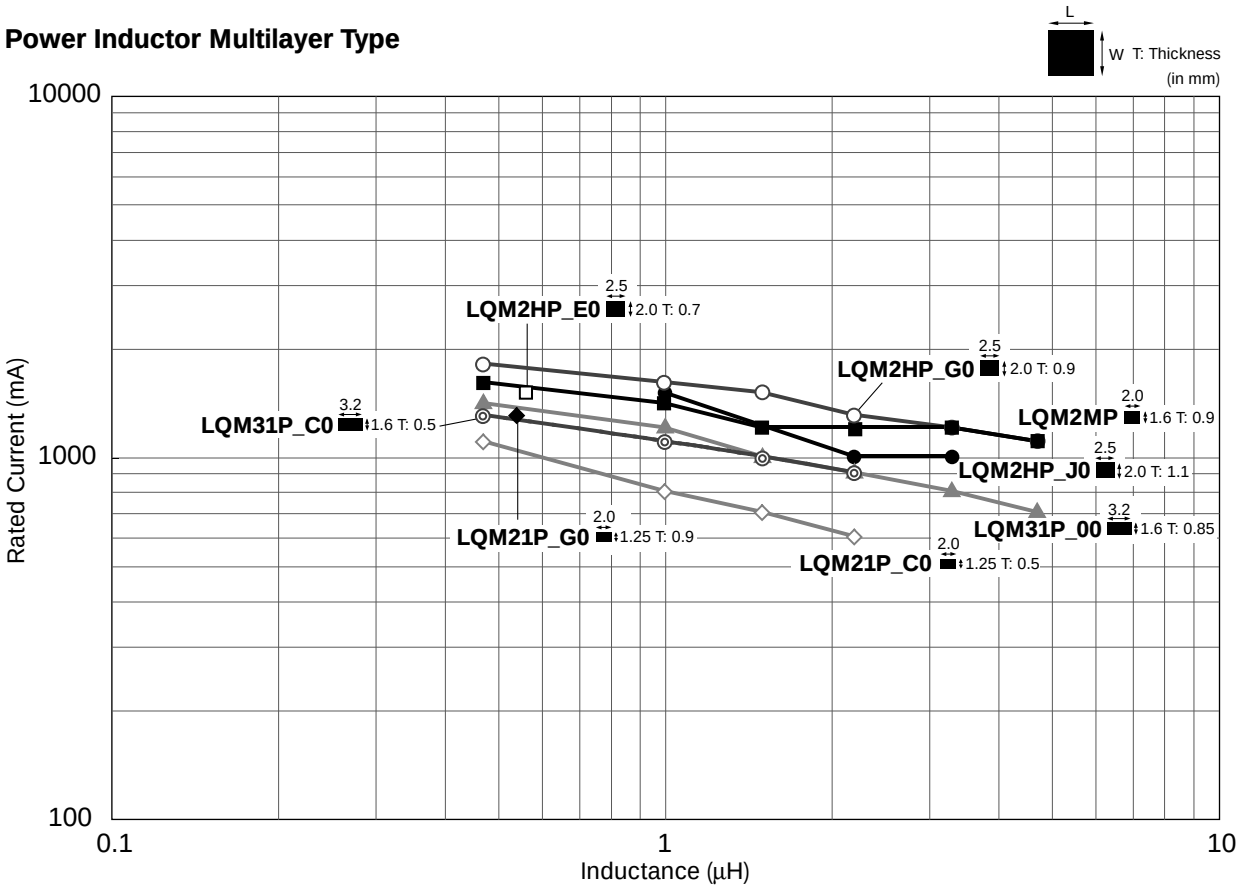
Size (inch) Inductance Rated Current

Product Guide by Thickness

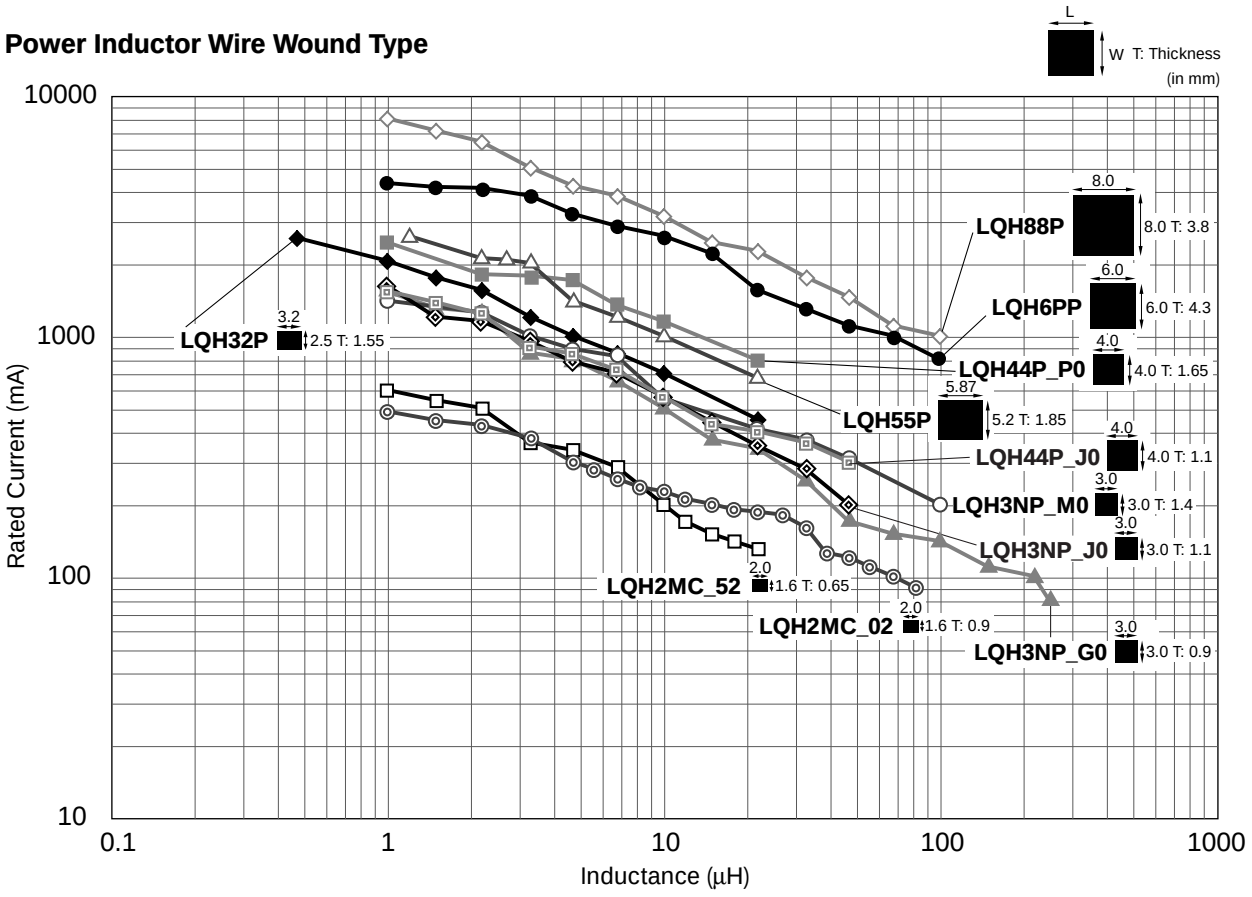
Which Thickness?	Power Inductor			
	Multilayer Type	Wire Wound Type	Multilayer Type for Choke	Wire Wound Type for Choke
0.2mm				
0.3mm				
0.35mm				
0.4mm				
0.5mm	LQM21P_C0 / LQM31P_C0			
0.65mm		LQH2MC_52		
0.7mm	LQM2HP_E0			
0.8mm			LQM18F	
0.85mm	LQM31P_00		LQM21D (1.0 to 10μH) / LQM21F_00	
0.9mm	LQM21P_G0 / LQM2HP_G0 / LQM2MP	LQH2MC_02 / LQH3NP_G0		
1.0mm			LQM31F	
1.1mm	LQM2HP_J0	LQH3NP_J0 / LQH44P_J0		
1.25mm			LQM21D (22 to 47μH) / LQM21F_70 / LQM21F_80	
1.4mm		LQH3NP_M0		
1.55mm		LQH32P		LQH32C_53
1.65mm		LQH44P_P0		
1.7mm				
1.8mm				LQH31C
1.85mm		LQH55P		
2.0mm				LQH32C_23/33
2.6mm				LQH43C
3.8mm		LQH88P		
4.3mm		LQH6PP		
4.7mm				LQH55D / LQH66S

Which Thickness?	Inductor for General Use		Inductor for High Frequency		
	Multilayer Type	Wire Wound Type	Multilayer Type	Film Type	Wire Wound Type
0.2mm				LQP02T	
0.3mm				LQP03T	
0.35mm				LQP15M	
0.4mm				LQP15T	LQW04A
0.5mm			LQG15HN / LQG15HS	LQP18M	LQW15A
0.65mm					
0.7mm					
0.8mm	LQM18N		LQG18H		LQW18A
0.85mm	LQM21N (0.1 to 2.2μH)				
0.9mm					LQW21H
1.0mm					
1.1mm					
1.25mm	LQM21N (2.7 to 4.7μH)				
1.4mm					
1.55mm					
1.65mm					
1.7mm					LQW2BH
1.8mm		LQH31M			LQH31H / LQW31H
1.85mm					
2.0mm		LQH32M			
2.6mm		LQH43M(N)			
3.8mm					
4.3mm					
4.7mm					

Power Inductor Multilayer Type



Power Inductor Wire Wound Type



Power Inductor Multilayer Type

LQM21P_G0 Series (0805 Size)

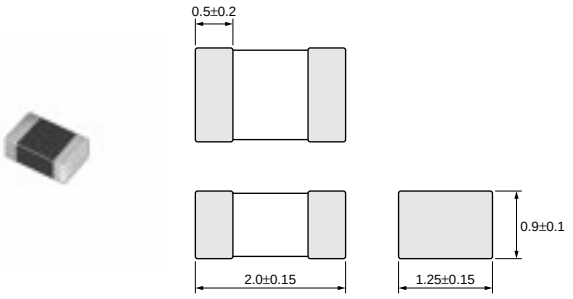
■ Features

1. Large rated current of 1300mA (at 0.54 micro H).
2. Small size in 2.0x1.25mm
   Low profile(h=1.0mm max.)
3. Low DC resistance.
4. Magnetically shielded structure.
5. Outstanding solder heat resistance, either flow or reflow soldering methods can be employed.

■ Applications

DC-DC converter circuits for mobile equipment.

■ Dimension



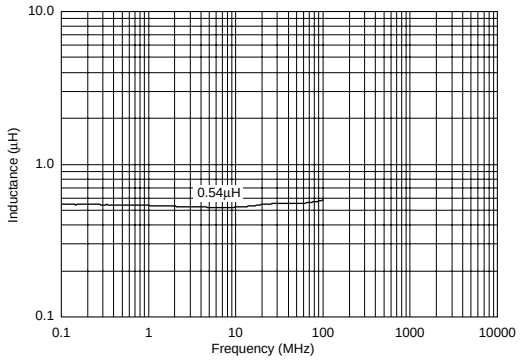
(in mm)

■ Rated Value (☐: packaging code)

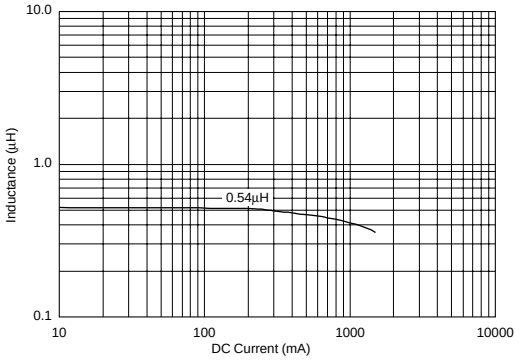
Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQM21PNR54MG0☐	0.54μH±20%	1MHz	1300mA	0.075ohm±25%	100MHz	Magnetic shield of ferrite

Operating Temperature Range: -55°C to +125°C

■ Inductance - Frequency Characteristics



■ Inductance - Current Characteristics



Power Inductor Multilayer Type

LQM21P_C0 Series (0805 Size)

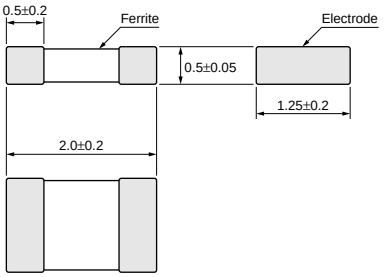
■ Features

1. Small size in 2.0x1.25mm
2. Low profile (h=0.55mm max.)
3. Large rated current of 1100mA
4. Magnetically shielded structure
5. Outstanding solder heat resistance, either flow or reflow soldering methods can be employed.

■ Applications

DC-DC converter circuits for mobile equipment

■ Dimension



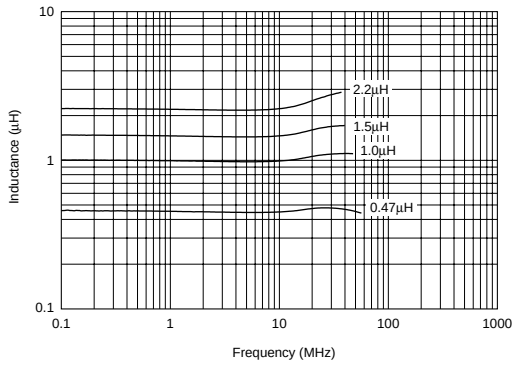
(in mm)

■ Rated Value (☐: packaging code)

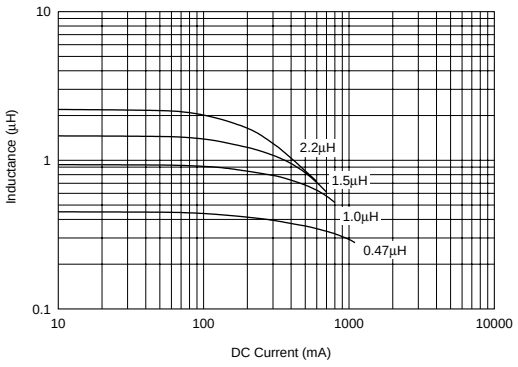
Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQM21PNR47MC0☐	0.47µH±20%	1MHz	1100mA	0.12ohm±25%	100MHz	Magnetic shield of ferrite
LQM21PN1R0MC0☐	1.0µH±20%	1MHz	800mA	0.19ohm±25%	90MHz	Magnetic shield of ferrite
LQM21PN1R5MC0☐	1.5µH±20%	1MHz	700mA	0.26ohm±25%	70MHz	Magnetic shield of ferrite
LQM21PN2R2MC0☐	2.2µH±20%	1MHz	600mA	0.34ohm±25%	50MHz	Magnetic shield of ferrite

Operating Temperature Range: -55°C to +125°C

■ Inductance - Frequency Characteristics



■ Inductance - Current Characteristics



Power Inductor Multilayer Type

LQM2MP_G0 Series (0806 Size)

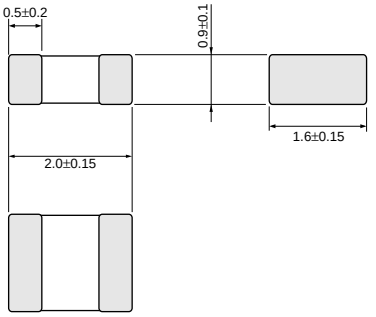
■ Features

1. Large rated current of 1400mA (1.0 micro H)
2. Small size in 2.0x1.6mm and low profile in 1.0mm max.
3. Low DC resistance is realized.
4. Magnetically shielded structure
5. Applicable soldering methods are both flow soldering and reflow soldering.

■ Applications

DC-DC converter circuits for mobile equipment

■ Dimension



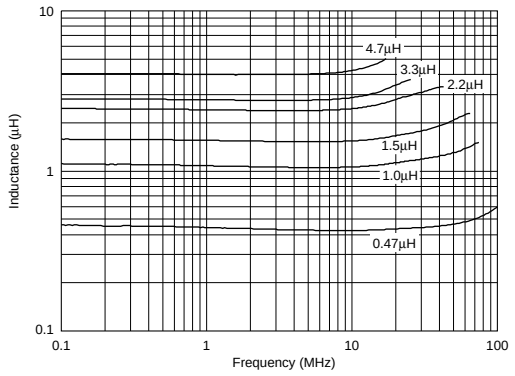
(in mm)

■ Rated Value (☐: packaging code)

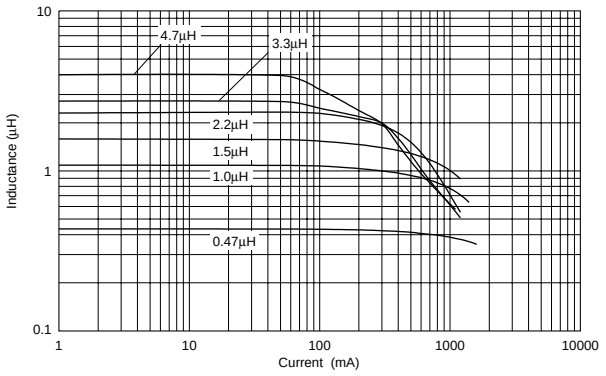
Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQM2MPNR47NG0☐	0.47μH±30%	1MHz	1600mA	0.06ohm±25%	100MHz	Magnetic shield of ferrite
LQM2MPN1R0NG0☐	1.0μH±30%	1MHz	1400mA	0.085ohm±25%	60MHz	Magnetic shield of ferrite
LQM2MPN1R5NG0☐	1.5μH±30%	1MHz	1200mA	0.11ohm±25%	50MHz	Magnetic shield of ferrite
LQM2MPN2R2NG0☐	2.2μH±30%	1MHz	1200mA	0.11ohm±25%	40MHz	Magnetic shield of ferrite
LQM2MPN3R3NG0☐	3.3μH±30%	1MHz	1200mA	0.12ohm±25%	30MHz	Magnetic shield of ferrite
LQM2MPN4R7NG0☐	4.7μH±30%	1MHz	1100mA	0.14ohm±25%	20MHz	Magnetic shield of ferrite

Operating Temperature Range: -55°C to +125°C

■ Inductance - Frequency Characteristics



■ Inductance - Current Characteristics



Power Inductor Multilayer Type

LQM2HP_J0 Series (1008 Size)

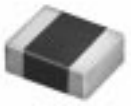
■ Features

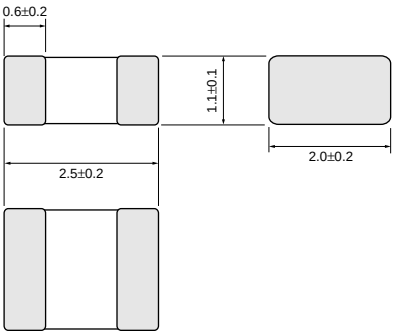
1. Large rated current of 1500mA (1.0 micro H)
2. Small size in 2.5x2.0mm and low profile in 1.2mm max.
3. Low DC resistance is realized.
4. Magnetically shielded structure
5. Applicable soldering methods are both flow soldering and reflow soldering.

■ Applications

DC-DC converter circuits for mobile equipment

■ Dimension





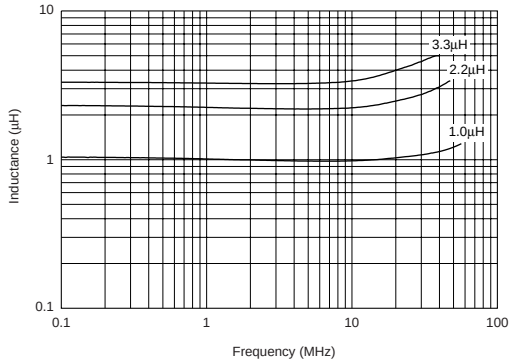
(in mm)

■ Rated Value (☐: packaging code)

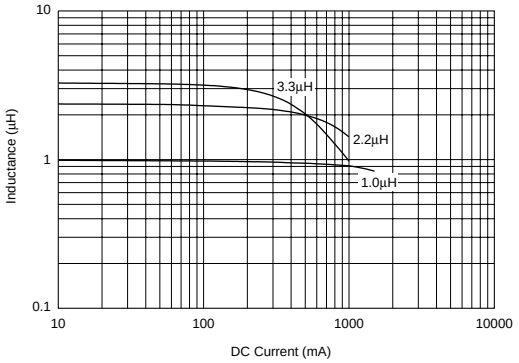
Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQM2HPN1R0MJ0☐	1.0µH±20%	1MHz	1500mA	0.09ohm±25%	70MHz	Magnetic shield of ferrite
LQM2HPN2R2MJ0☐	2.2µH±20%	1MHz	1000mA	0.12ohm±25%	40MHz	Magnetic shield of ferrite
LQM2HPN3R3MJ0☐	3.3µH±20%	1MHz	1000mA	0.12ohm±25%	30MHz	Magnetic shield of ferrite

Operating Temperature Range: -55°C to +125°C

■ Inductance - Frequency Characteristics



■ Inductance - Current Characteristics



Power Inductor Multilayer Type

LQM2HP_G0 Series (1008 Size)

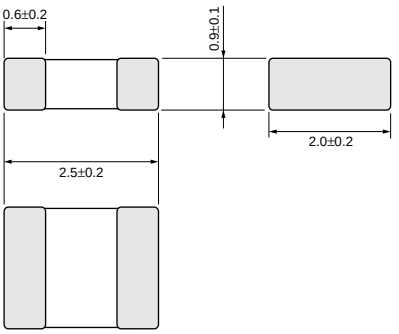
■ Features

1. Large rated current of 1600mA (1.0 micro H)
2. Small size in 2.5x2.0mm and low profile in 1.0mm max.
3. Low DC resistance is realized.
4. Magnetically shielded structure
5. Applicable soldering methods are both flow soldering and reflow soldering.

■ Applications

DC-DC converter circuits for mobile equipment

■ Dimension



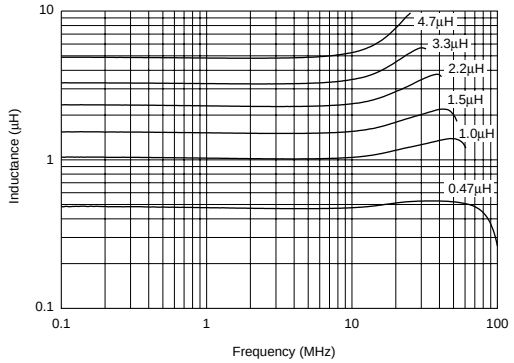
(in mm)

■ Rated Value (☐: packaging code)

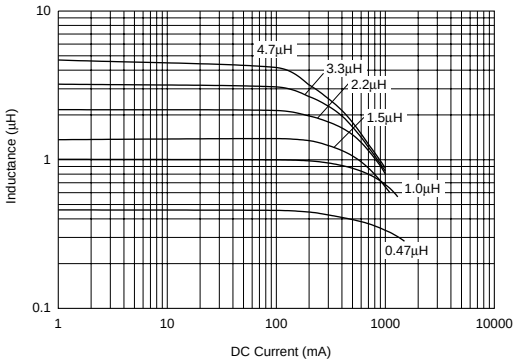
Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQM2HPNR47MG0☐	0.47µH±20%	1MHz	1800mA	0.04ohm±25%	100MHz	Magnetic shield of ferrite
LQM2HPN1R0MG0☐	1.0µH±20%	1MHz	1600mA	0.055ohm±25%	60MHz	Magnetic shield of ferrite
LQM2HPN1R5MG0☐	1.5µH±20%	1MHz	1500mA	0.07ohm±25%	50MHz	Magnetic shield of ferrite
LQM2HPN2R2MG0☐	2.2µH±20%	1MHz	1300mA	0.08ohm±25%	40MHz	Magnetic shield of ferrite
LQM2HPN3R3MG0☐	3.3µH±20%	1MHz	1200mA	0.10ohm±25%	30MHz	Magnetic shield of ferrite
LQM2HPN4R7MG0☐	4.7µH±20%	1MHz	1100mA	0.11ohm±25%	25MHz	Magnetic shield of ferrite

Operating Temperature Range: -55°C to +125°C

■ Inductance - Frequency Characteristics



■ Inductance - Current Characteristics



Power Inductor Multilayer Type

LQM2HP_E0 Series (1008 Size)

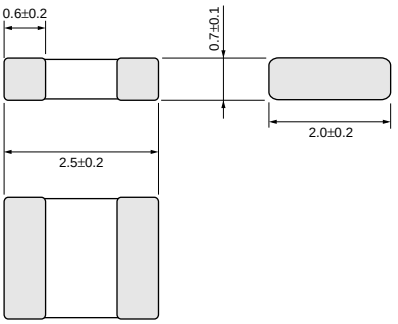
■ Features

1. Large rated current of 1500mA (0.56 micro H)
2. Small size in 2.5x2.0mm and low profile in 0.8mm max.
3. Low DC resistance is realized.
4. Magnetically shielded structure
5. Applicable soldering methods are both flow soldering and reflow soldering.

■ Applications

DC-DC converter circuits for mobile equipment

■ Dimension



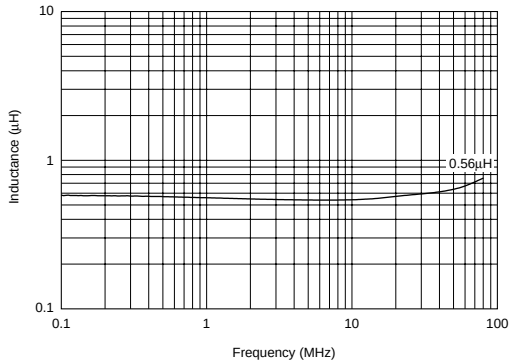
(in mm)

■ Rated Value (☐: packaging code)

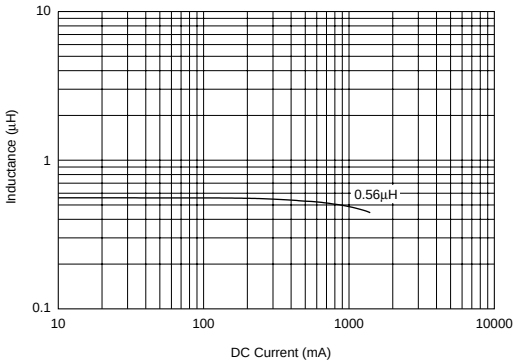
Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQM2HPNR56ME0☐	0.56µH±20%	1MHz	1500mA	0.06ohm±25%	70MHz	Magnetic shield of ferrite

Operating Temperature Range: -55°C to +125°C

■ Inductance - Frequency Characteristics



■ Inductance - Current Characteristics



Power Inductor Multilayer Type

LQM31P_00 Series (1206 Size)

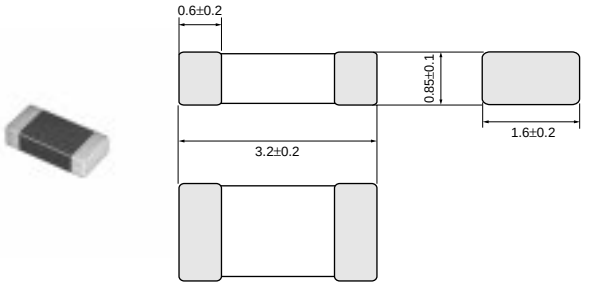
■ Features

1. Large rated current of 1400mA
2. Small size in 3.2x1.6mm and low profile (h=0.95mm max.)
3. Low DC resistance
4. Magnetically shielded structure
5. Applicable soldering methods are both flow soldering and reflow soldering.

■ Applications

DC-DC converter circuits for mobile equipment

■ Dimension



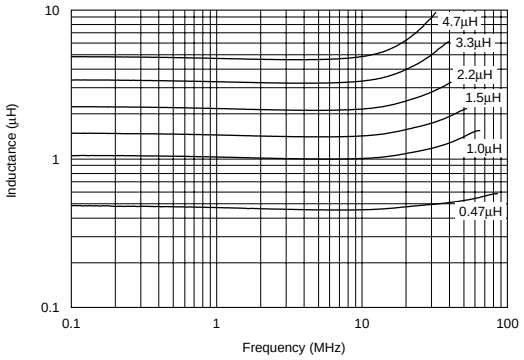
(in mm)

■ Rated Value (☐: packaging code)

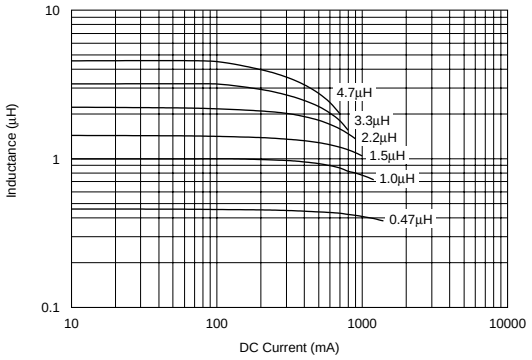
Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQM31PNR47M00☐	0.47µH±20%	1MHz	1400mA	0.07ohm±25%	80MHz	Magnetic shield of ferrite
LQM31PN1R0M00☐	1.0µH±20%	1MHz	1200mA	0.12ohm±25%	60MHz	Magnetic shield of ferrite
LQM31PN1R5M00☐	1.5µH±20%	1MHz	1000mA	0.14ohm±25%	50MHz	Magnetic shield of ferrite
LQM31PN2R2M00☐	2.2µH±20%	1MHz	900mA	0.19ohm±25%	40MHz	Magnetic shield of ferrite
LQM31PN3R3M00☐	3.3µH±20%	1MHz	800mA	0.24ohm±25%	30MHz	Magnetic shield of ferrite
LQM31PN4R7M00☐	4.7µH±20%	1MHz	700mA	0.30ohm±25%	25MHz	Magnetic shield of ferrite

Operating Temperature Range: -55°C to +125°C

■ Inductance - Frequency Characteristics



■ Inductance - Current Characteristics



Power Inductor Multilayer Type

LQM31P_C0 Series (1206 Size)

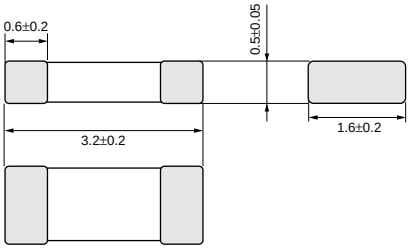
■ Features

1. Large rated current of 1100mA
2. Small size in 3.2x1.6mm and low profile (h=0.55mm max.)
3. Low DC resistance
4. Magnetically shielded structure
5. Applicable soldering methods are both flow soldering and reflow soldering.

■ Applications

DC-DC converter circuits for mobile equipment

■ Dimension



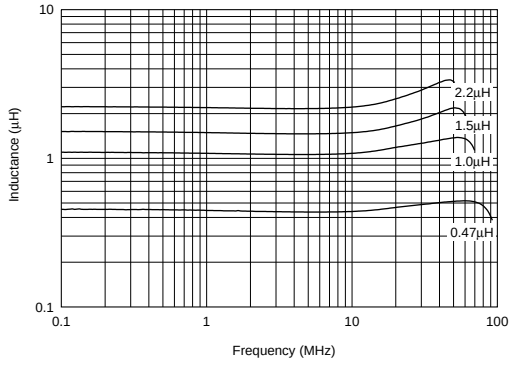
(in mm)

■ Rated Value (☐: packaging code)

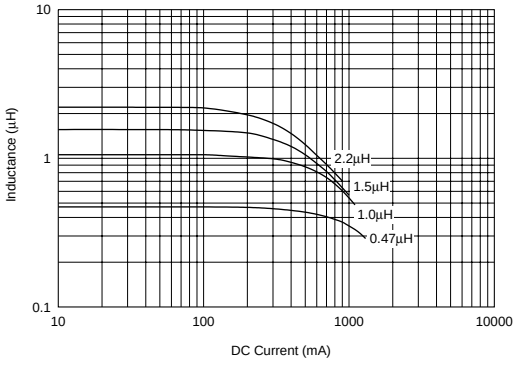
Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQM31PNR47MC0☐	0.47µH±20%	1MHz	1300mA	0.085ohm±25%	90MHz	Magnetic shield of ferrite
LQM31PN1R0MC0☐	1.0µH±20%	1MHz	1100mA	0.14ohm±25%	70MHz	Magnetic shield of ferrite
LQM31PN1R5MC0☐	1.5µH±20%	1MHz	1000mA	0.17ohm±25%	60MHz	Magnetic shield of ferrite
LQM31PN2R2MC0☐	2.2µH±20%	1MHz	900mA	0.25ohm±25%	50MHz	Magnetic shield of ferrite

Operating Temperature Range: -55°C to +125°C

■ Inductance - Frequency Characteristics



■ Inductance - Current Characteristics



Power Inductor Wire Wound Type

LQH2MC_02 Series (0806 Size)

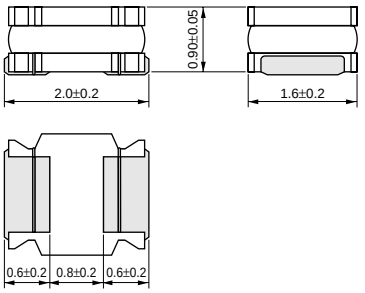
■ Features

1. Wire wound type with 0.95mm (max.) low-profile
2. Size: 2.0x1.6mm
3. Rated current: 485mA (1.0 micro H)
4. Wide inductance range: 1.0 to 82 micro H

■ Applications

For DC-DC converter

■ Dimension



(in mm)

■ Rated Value (☐: packaging code)

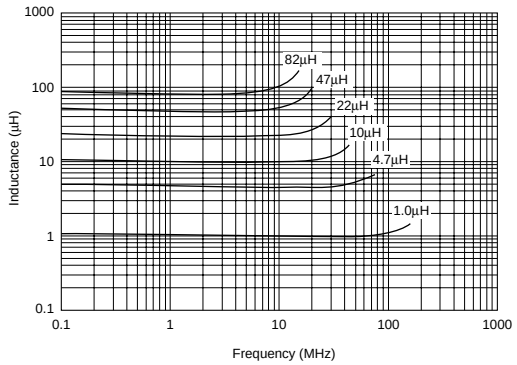
Part Number	Inductance	Inductance Test Frequency	*1 Allowable DC Current (Based on Temperature Rise)	*2 Allowable DC Current (Based on Inductance Change)	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH2MCN1R0M02☐	1.0µH±20%	1MHz	485mA	-	0.30ohm±30%	100MHz	No magnetic shield
LQH2MCN1R5M02☐	1.5µH±20%	1MHz	445mA	-	0.40ohm±30%	95MHz	No magnetic shield
LQH2MCN2R2M02☐	2.2µH±20%	1MHz	425mA	-	0.48ohm±30%	70MHz	No magnetic shield
LQH2MCN3R3M02☐	3.3µH±20%	1MHz	375mA	-	0.60ohm±30%	65MHz	No magnetic shield
LQH2MCN4R7M02☐	4.7µH±20%	1MHz	300mA	-	0.8ohm±30%	60MHz	No magnetic shield
LQH2MCN5R6M02☐	5.6µH±20%	1MHz	280mA	-	0.9ohm±30%	60MHz	No magnetic shield
LQH2MCN6R8M02☐	6.8µH±20%	1MHz	255mA	-	1.0ohm±30%	55MHz	No magnetic shield
LQH2MCN8R2M02☐	8.2µH±20%	1MHz	235mA	-	1.1ohm±30%	50MHz	No magnetic shield
LQH2MCN100K02☐	10µH±10%	1MHz	225mA	-	1.2ohm±30%	48MHz	No magnetic shield
LQH2MCN120K02☐	12µH±10%	1MHz	210mA	-	1.4ohm±30%	44MHz	No magnetic shield
LQH2MCN150K02☐	15µH±10%	1MHz	200mA	-	1.6ohm±30%	40MHz	No magnetic shield
LQH2MCN180K02☐	18µH±10%	1MHz	190mA	-	1.8ohm±30%	35MHz	No magnetic shield
LQH2MCN220K02☐	22µH±10%	1MHz	185mA	-	2.1ohm±30%	30MHz	No magnetic shield
LQH2MCN270K02☐	27µH±10%	1MHz	180mA	-	2.5ohm±30%	30MHz	No magnetic shield
LQH2MCN330K02☐	33µH±10%	1MHz	160mA	-	2.8ohm±30%	28MHz	No magnetic shield
LQH2MCN390K02☐	39µH±10%	1MHz	125mA	-	4.4ohm±30%	24MHz	No magnetic shield
LQH2MCN470K02☐	47µH±10%	1MHz	120mA	-	5.1ohm±30%	18MHz	No magnetic shield
LQH2MCN560K02☐	56µH±10%	1MHz	110mA	-	5.7ohm±30%	17MHz	No magnetic shield
LQH2MCN680K02☐	68µH±10%	1MHz	100mA	-	6.6ohm±30%	14MHz	No magnetic shield
LQH2MCN820K02☐	82µH±10%	1MHz	90mA	-	7.5ohm±30%	14MHz	No magnetic shield

Operating Temperature Range: -40°C to +85°C Only for reflow soldering.

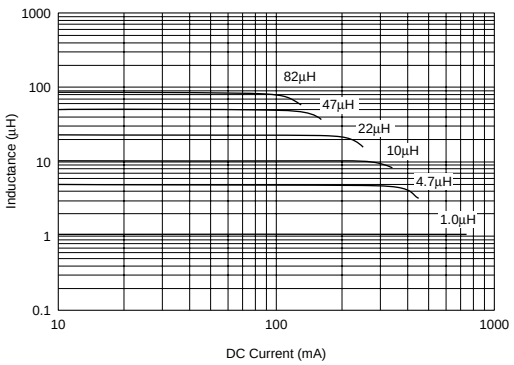
*1: When applied Allowable DC Current is applied to the Products, self-generation of heat will rise to 40°C or less.

*2: When applied Allowable DC Current is applied to the Products, Inductance will be within ±30% of nominal Inductance value.

■ Inductance - Frequency Characteristics (Typ.)



■ Inductance - Current Characteristics (Typ.)



Power Inductor Wire Wound Type

LQH2MC_52 Series (0806 Size)

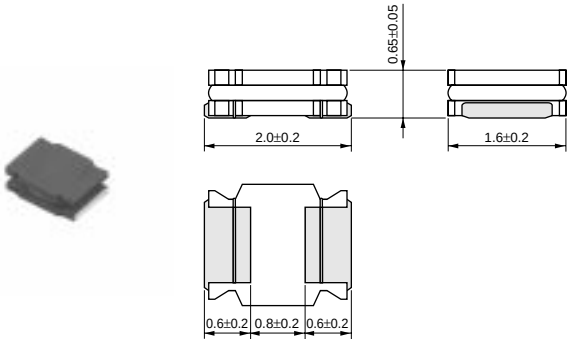
■ Features

1. Wire wound type with 0.70mm (max.) ultra low-profile
2. Size: 2.0x1.6mm
3. Rated current: 595mA (1.0 micro H)
4. Inductance range: 1.0 to 22 micro H

■ Applications

For DC-DC converter

■ Dimension



(in mm)

■ Rated Value (☐: packaging code)

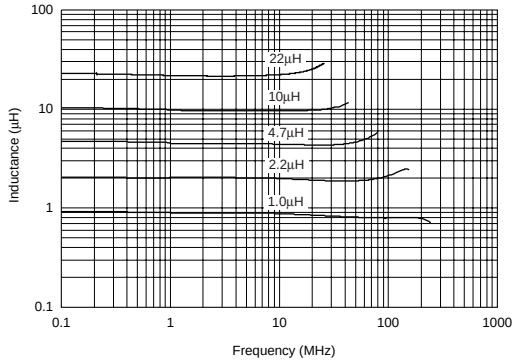
Part Number	Inductance	Inductance Test Frequency	*1 Allowable DC Current (Based on Temperature Rise)	*2 Allowable DC Current (Based on Inductance Change)	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH2MCN1R0M52☐	1.0μH±20%	1MHz	595mA	-	0.25ohm±30%	215MHz	No magnetic shield
LQH2MCN1R5M52☐	1.5μH±20%	1MHz	540mA	-	0.33ohm±30%	165MHz	No magnetic shield
LQH2MCN2R2M52☐	2.2μH±20%	1MHz	500mA	-	0.42ohm±30%	125MHz	No magnetic shield
LQH2MCN3R3M52☐	3.3μH±20%	1MHz	360mA	-	0.74ohm±30%	110MHz	No magnetic shield
LQH2MCN4R7M52☐	4.7μH±20%	1MHz	335mA	-	0.91ohm±30%	90MHz	No magnetic shield
LQH2MCN6R8M52☐	6.8μH±20%	1MHz	285mA	-	1.23ohm±30%	65MHz	No magnetic shield
LQH2MCN100M52☐	10μH±20%	1MHz	200mA	-	2.27ohm±30%	60MHz	No magnetic shield
LQH2MCN120M52☐	12μH±20%	1MHz	170mA	-	2.4ohm±30%	30MHz	No magnetic shield
LQH2MCN150M52☐	15μH±20%	1MHz	150mA	-	3.5ohm±30%	30MHz	No magnetic shield
LQH2MCN180M52☐	18μH±20%	1MHz	140mA	-	4.0ohm±30%	30MHz	No magnetic shield
LQH2MCN220M52☐	22μH±20%	1MHz	130mA	-	5.5ohm±30%	30MHz	No magnetic shield

Operating Temperature Range: -40°C to +85°C Only for reflow soldering.

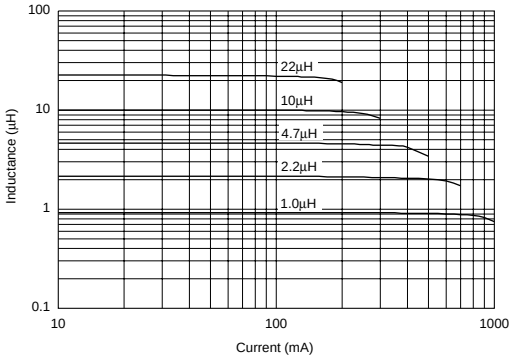
*1: When applied Allowable DC Current is applied to the Products, self-generation of heat will rise to 40°C or less.

*2: When applied Allowable DC Current is applied to the Products, Inductance will be within ±30% of nominal Inductance value.

■ Inductance - Frequency Characteristics (Typ.)



■ Inductance - Current Characteristics (Typ.)



Power Inductor Wire Wound Type

LQH3NP_M0 Series (1212 Size)

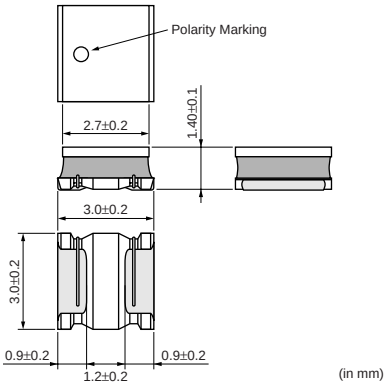
■ Features

1. Large rated current
   Based on Inductance change: 1400mA at 1.0 micro H
   Based on Temperature rise: 2050mA at 1.0 micro H
2. The series has an inductance range from 1.0 to 100 micro H.
3. Magnetically shielded structure.
4. Lead-free reflow soldering is available.

■ Applications

For DC-DC converter

■ Dimension



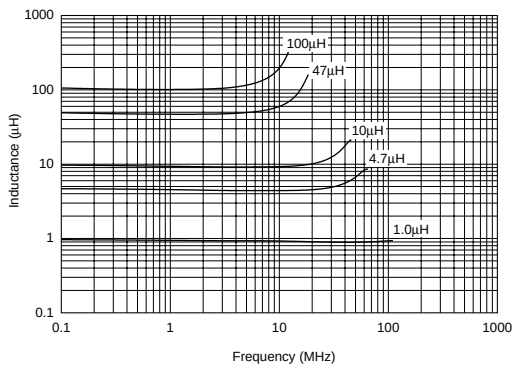
(in mm)

■ Rated Value (☐: packaging code)

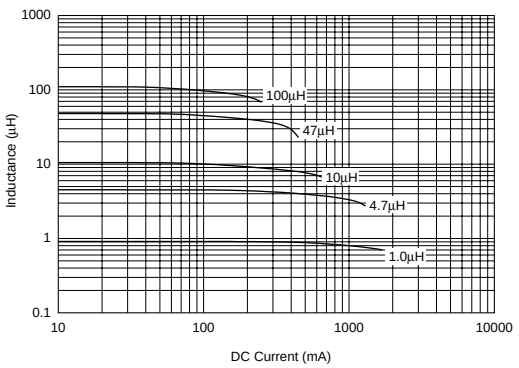
Part Number	Inductance	Inductance Test Frequency	*1 Allowable DC Current (Based on Temperature Rise)	*2 Allowable DC Current (Based on Inductance Change)	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH3NPN1R0MM0☐	1.0μH±20%	1MHz	2050mA	1400mA	0.044ohm±20%	130MHz	Magnetic shield of magnetic powder in resin
LQH3NPN1R0NM0☐	1.0μH±30%	1MHz	2050mA	1400mA	0.044ohm±20%	130MHz	Magnetic shield of magnetic powder in resin
LQH3NPN2R2MM0☐	2.2μH±20%	1MHz	1600mA	1250mA	0.073ohm±20%	90MHz	Magnetic shield of magnetic powder in resin
LQH3NPN2R2NM0☐	2.2μH±30%	1MHz	1600mA	1250mA	0.073ohm±20%	90MHz	Magnetic shield of magnetic powder in resin
LQH3NPN3R3MM0☐	3.3μH±20%	1MHz	1450mA	1000mA	0.092ohm±20%	75MHz	Magnetic shield of magnetic powder in resin
LQH3NPN3R3NM0☐	3.3μH±30%	1MHz	1450mA	1000mA	0.092ohm±20%	75MHz	Magnetic shield of magnetic powder in resin
LQH3NPN4R7MM0☐	4.7μH±20%	1MHz	1250mA	880mA	0.13ohm±20%	65MHz	Magnetic shield of magnetic powder in resin
LQH3NPN4R7NM0☐	4.7μH±30%	1MHz	1250mA	880mA	0.13ohm±20%	65MHz	Magnetic shield of magnetic powder in resin
LQH3NPN6R8MM0☐	6.8μH±20%	1MHz	1000mA	820mA	0.20ohm±20%	50MHz	Magnetic shield of magnetic powder in resin
LQH3NPN6R8NM0☐	6.8μH±30%	1MHz	1000mA	820mA	0.20ohm±20%	50MHz	Magnetic shield of magnetic powder in resin
LQH3NPN100MM0☐	10μH±20%	1MHz	870mA	550mA	0.26ohm±20%	45MHz	Magnetic shield of magnetic powder in resin
LQH3NPN100NM0☐	10μH±30%	1MHz	870mA	550mA	0.26ohm±20%	45MHz	Magnetic shield of magnetic powder in resin
LQH3NPN220MM0☐	22μH±20%	1MHz	650mA	410mA	0.51ohm±20%	28MHz	Magnetic shield of magnetic powder in resin
LQH3NPN330MM0☐	33μH±20%	1MHz	500mA	370mA	0.85ohm±20%	22MHz	Magnetic shield of magnetic powder in resin
LQH3NPN470MM0☐	47μH±20%	1MHz	410mA	310mA	1.25ohm±20%	18MHz	Magnetic shield of magnetic powder in resin
LQH3NPN101MM0☐	100μH±20%	1MHz	240mA	200mA	3.50ohm±20%	12MHz	Magnetic shield of magnetic powder in resin

Operating Temperature Range: -40°C to +85°C Only for reflow soldering.
*1: When applied Allowable DC Current is applied to the Products, self-generation of heat will rise to 40°C or less.
*2: When applied Allowable DC Current is applied to the Products, Inductance will be within ±30% of nominal Inductance value.

■ Inductance - Frequency Characteristics (Typ.)



■ Inductance - Current Characteristics (Typ.)



Power Inductor Wire Wound Type

LQH3NP_J0 Series (1212 Size)

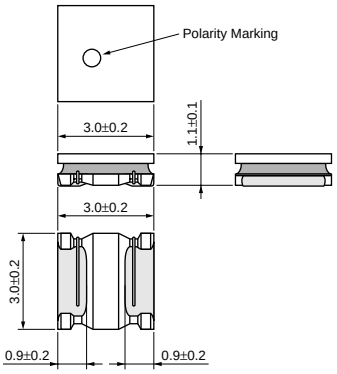
■ Features

1. Low profile (h=1.2mm max.)
2. Small size in 3.0x3.0mm
3. Large rated current of 1620mA (1.0 micro H)
4. Magnetically shielded structure
5. Lead-free reflow soldering is available.

■ Applications

For DC-DC converter

■ Dimension



(in mm)

■ Rated Value (☐: packaging code)

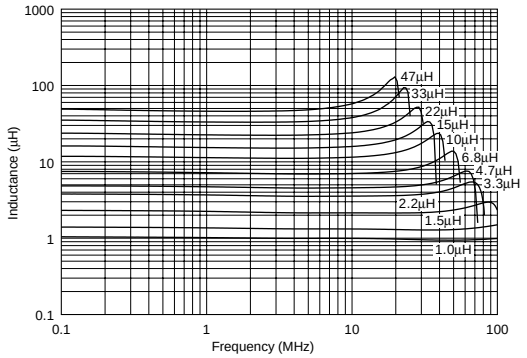
Part Number	Inductance	Inductance Test Frequency	*1 Allowable DC Current (Based on Temperature Rise)	*2 Allowable DC Current (Based on Inductance Change)	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH3NPN1R0NJ0☐	1.0μH±30%	1MHz	1620mA	1650mA	0.040ohm±20%	140MHz	Magnetic shield of magnetic powder in resin
LQH3NPN1R5NJ0☐	1.5μH±30%	1MHz	1500mA	1200mA	0.055ohm±20%	90MHz	Magnetic shield of magnetic powder in resin
LQH3NPN2R2NJ0☐	2.2μH±30%	1MHz	1460mA	1150mA	0.069ohm±20%	90MHz	Magnetic shield of magnetic powder in resin
LQH3NPN3R3NJ0☐	3.3μH±30%	1MHz	1270mA	950mA	0.105ohm±20%	70MHz	Magnetic shield of magnetic powder in resin
LQH3NPN4R7NJ0☐	4.7μH±30%	1MHz	1120mA	780mA	0.130ohm±20%	65MHz	Magnetic shield of magnetic powder in resin
LQH3NPN6R8NJ0☐	6.8μH±30%	1MHz	850mA	700mA	0.210ohm±20%	45MHz	Magnetic shield of magnetic powder in resin
LQH3NPN100NJ0☐	10μH±30%	1MHz	710mA	560mA	0.300ohm±20%	35MHz	Magnetic shield of magnetic powder in resin
LQH3NPN150NJ0☐	15μH±30%	1MHz	590mA	440mA	0.440ohm±20%	30MHz	Magnetic shield of magnetic powder in resin
LQH3NPN220MJ0☐	22μH±20%	1MHz	510mA	350mA	0.600ohm±20%	25MHz	Magnetic shield of magnetic powder in resin
LQH3NPN220NJ0☐	22μH±30%	1MHz	510mA	350mA	0.600ohm±20%	25MHz	Magnetic shield of magnetic powder in resin
LQH3NPN330MJ0☐	33μH±20%	1MHz	410mA	280mA	0.900ohm±20%	20MHz	Magnetic shield of magnetic powder in resin
LQH3NPN330NJ0☐	33μH±30%	1MHz	410mA	280mA	0.900ohm±20%	20MHz	Magnetic shield of magnetic powder in resin
LQH3NPN470MJ0☐	47μH±20%	1MHz	350mA	200mA	1.30ohm±20%	15MHz	Magnetic shield of magnetic powder in resin
LQH3NPN470NJ0☐	47μH±30%	1MHz	350mA	200mA	1.30ohm±20%	15MHz	Magnetic shield of magnetic powder in resin

Operating Temperature Range: -40 to +85°C Only for reflow soldering.

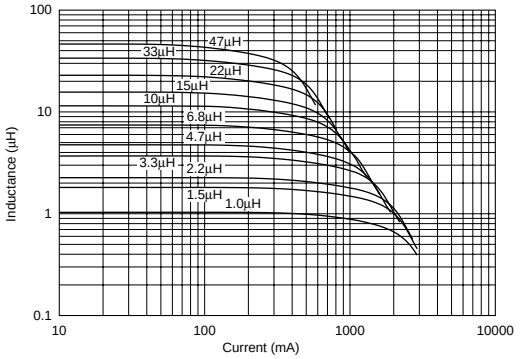
*1: When applied Allowable DC Current is applied to the Products, self-generation of heat will rise to 40°C or less.

*2: When applied Allowable DC Current is applied to the Products, Inductance will be within ±30% of nominal Inductance value.

■ Inductance-Frequency Characteristics (Typ.)



■ Inductance-Current Characteristics (Typ.)



Power Inductor Wire Wound Type

LQH3NP_G0 Series (1212 Size)

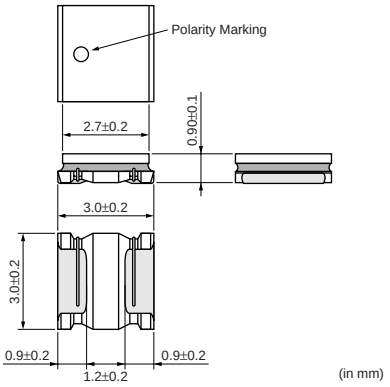
■ Features

1. Low profile (h=1.0mm max.)
2. Small size in 3.0x3.0mm
3. Large rated current of 1525mA (1.0 micro H)
4. Magnetically shielded structure
5. Lead-free reflow soldering is available.

■ Applications

For DC-DC converter

■ Dimension



(in mm)

■ Rated Value (☐: packaging code)

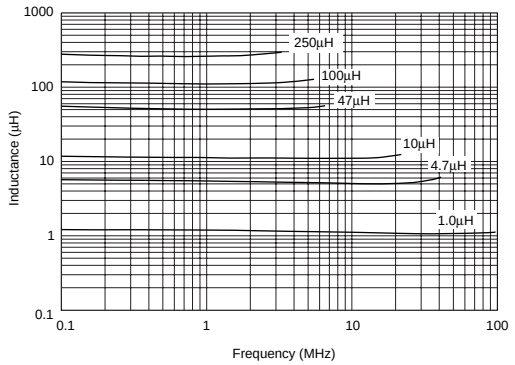
Part Number	Inductance	Inductance Test Frequency	*1 Allowable DC Current (Based on Temperature Rise)	*2 Allowable DC Current (Based on Inductance Change)	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH3NPN1R0NG0☐	1.0μH±30%	1MHz	1525mA	1650mA	0.08ohm±20%	160MHz	Magnetic shield of magnetic powder in resin
LQH3NPN1R5NG0☐	1.5μH±30%	1MHz	1470mA	1300mA	0.10ohm±20%	130MHz	Magnetic shield of magnetic powder in resin
LQH3NPN2R2NG0☐	2.2μH±30%	1MHz	1270mA	1250mA	0.14ohm±20%	100MHz	Magnetic shield of magnetic powder in resin
LQH3NPN3R3NG0☐	3.3μH±30%	1MHz	1130mA	850mA	0.18ohm±20%	75MHz	Magnetic shield of magnetic powder in resin
LQH3NPN4R7NG0☐	4.7μH±30%	1MHz	925mA	800mA	0.26ohm±20%	60MHz	Magnetic shield of magnetic powder in resin
LQH3NPN6R8NG0☐	6.8μH±30%	1MHz	710mA	650mA	0.45ohm±20%	48MHz	Magnetic shield of magnetic powder in resin
LQH3NPN100NG0☐	10μH±30%	1MHz	630mA	500mA	0.57ohm±20%	45MHz	Magnetic shield of magnetic powder in resin
LQH3NPN150NG0☐	15μH±30%	1MHz	475mA	370mA	0.91ohm±20%	35MHz	Magnetic shield of magnetic powder in resin
LQH3NPN220MG0☐	22μH±20%	1MHz	430mA	340mA	1.1ohm±20%	25MHz	Magnetic shield of magnetic powder in resin
LQH3NPN220NG0☐	22μH±30%	1MHz	430mA	340mA	1.1ohm±20%	25MHz	Magnetic shield of magnetic powder in resin
LQH3NPN330MG0☐	33μH±20%	1MHz	345mA	250mA	2.1ohm±20%	24MHz	Magnetic shield of magnetic powder in resin
LQH3NPN330NG0☐	33μH±30%	1MHz	345mA	250mA	2.1ohm±20%	24MHz	Magnetic shield of magnetic powder in resin
LQH3NPN470MG0☐	47μH±20%	1MHz	270mA	170mA	3.0ohm±20%	19MHz	Magnetic shield of magnetic powder in resin
LQH3NPN470NG0☐	47μH±30%	1MHz	270mA	170mA	3.0ohm±20%	19MHz	Magnetic shield of magnetic powder in resin
LQH3NPN680MG0☐	68μH±20%	1MHz	235mA	150mA	4.2ohm±20%	16MHz	Magnetic shield of magnetic powder in resin
LQH3NPN680NG0☐	68μH±30%	1MHz	235mA	150mA	4.2ohm±20%	16MHz	Magnetic shield of magnetic powder in resin
LQH3NPN101MG0☐	100μH±20%	1MHz	165mA	140mA	8.0ohm±20%	10MHz	Magnetic shield of magnetic powder in resin
LQH3NPN101NG0☐	100μH±30%	1MHz	165mA	140mA	8.0ohm±20%	10MHz	Magnetic shield of magnetic powder in resin
LQH3NPN151MG0☐	150μH±20%	1MHz	145mA	110mA	11.0ohm±20%	10MHz	Magnetic shield of magnetic powder in resin
LQH3NPN151NG0☐	150μH±30%	1MHz	145mA	110mA	11.0ohm±20%	10MHz	Magnetic shield of magnetic powder in resin
LQH3NPN221MG0☐	220μH±20%	1MHz	130mA	100mA	14.0ohm±20%	8.5MHz	Magnetic shield of magnetic powder in resin
LQH3NPN221NG0☐	220μH±30%	1MHz	130mA	100mA	14.0ohm±20%	8.5MHz	Magnetic shield of magnetic powder in resin
LQH3NPN251MG0☐	250μH±20%	1MHz	130mA	80mA	15.0ohm±20%	8.0MHz	Magnetic shield of magnetic powder in resin
LQH3NPN251NG0☐	250μH±30%	1MHz	130mA	80mA	15.0ohm±20%	8.0MHz	Magnetic shield of magnetic powder in resin

Operating Temperature Range: -40°C to +85°C Only for reflow soldering.

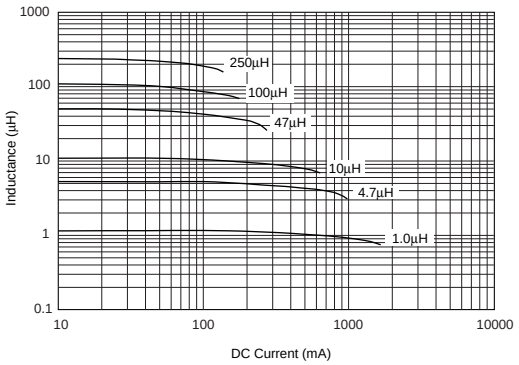
*1: When applied Allowable DC Current is applied to the Products, self-generation of heat will rise to 40°C or less.

*2: When applied Allowable DC Current is applied to the Products, Inductance will be within ±30% of nominal Inductance value.

■ Inductance - Frequency Characteristics (Typ.)



■ Inductance - Current Characteristics (Typ.)



Power Inductor Wire Wound Type

LQH32P_N0 Series (1210 Size)

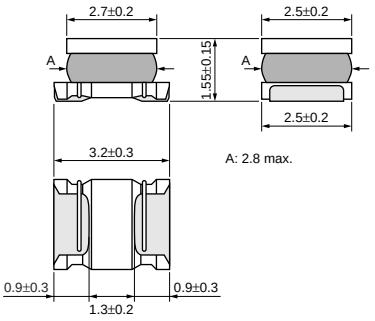
■ Features

1. Large allowable DC current of 2550mA (0.47 micro H)
2. The series has an inductance range from 0.47 to 22 micro H.
3. Magnetically shielded structure
4. Lead-free reflow soldering is available.

■ Applications

1. DSC, DVC, and 3.5/2.5 inch HDD
2. DC-DC converter for communication module of WiMAX

■ Dimension



(in mm)

■ Rated Value (☐: packaging code)

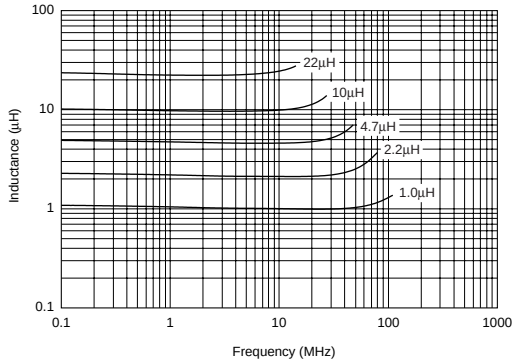
Part Number	Inductance	Inductance Test Frequency	*1 Allowable DC Current (Based on Temperature Rise)	*2 Allowable DC Current (Based on Inductance Change)	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH32PNR47NN0☐	0.47µH±30%	1MHz	2550mA	3400mA	0.03ohm±20%	100MHz	Magnetic shield of magnetic powder in resin
LQH32PN1R0NN0☐	1.0µH±30%	1MHz	2050mA	2300mA	0.045ohm±20%	100MHz	Magnetic shield of magnetic powder in resin
LQH32PN1R5NN0☐	1.5µH±30%	1MHz	1750mA	1750mA	0.057ohm±20%	70MHz	Magnetic shield of magnetic powder in resin
LQH32PN2R2NN0☐	2.2µH±30%	1MHz	1600mA	1550mA	0.076ohm±20%	70MHz	Magnetic shield of magnetic powder in resin
LQH32PN3R3NN0☐	3.3µH±30%	1MHz	1200mA	1250mA	0.12ohm±20%	50MHz	Magnetic shield of magnetic powder in resin
LQH32PN4R7NN0☐	4.7µH±30%	1MHz	1000mA	1000mA	0.18ohm±20%	40MHz	Magnetic shield of magnetic powder in resin
LQH32PN6R8NN0☐	6.8µH±30%	1MHz	850mA	850mA	0.24ohm±20%	40MHz	Magnetic shield of magnetic powder in resin
LQH32PN100MN0☐	10µH±20%	1MHz	700mA	750mA	0.38ohm±20%	30MHz	Magnetic shield of magnetic powder in resin
LQH32PN220MN0☐	22µH±20%	1MHz	450mA	500mA	0.81ohm±20%	20MHz	Magnetic shield of magnetic powder in resin

Operating Temperature Range: -40°C to +85°C Only for reflow soldering.

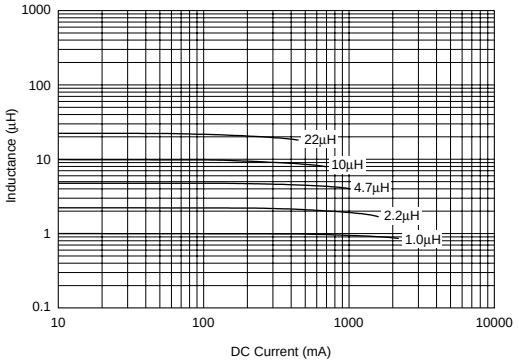
*1: When applied Allowable DC Current is applied to the Products, self-generation of heat will rise to 40°C or less.

*2: When applied Allowable DC Current is applied to the Products, Inductance will be within ±30% of nominal Inductance value.

■ Inductance - Frequency Characteristics (Typ.)



■ Inductance - Current Characteristics (Typ.)



Power Inductor Wire Wound Type

LQH44P_P0 Series (1515 Size)

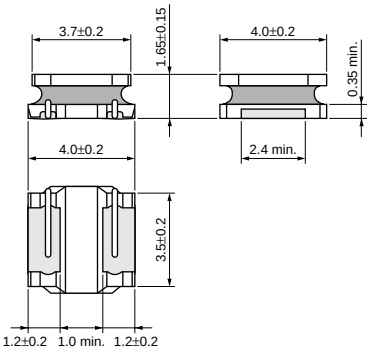
■ Features

1. Large rated current of 2450mA (at 1.0 micro H).
2. The series has an inductance range from 1.0 micro H to 22microH.
3. Magnetically shielded structure.
4. Reflow soldering methods can be employed.

■ Applications

For DC-DC converter

■ Dimension



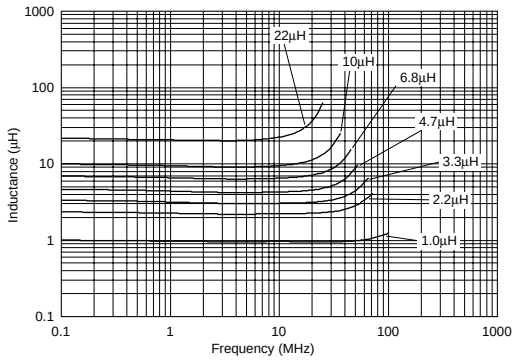
(in mm)

■ Rated Value (☐: packaging code)

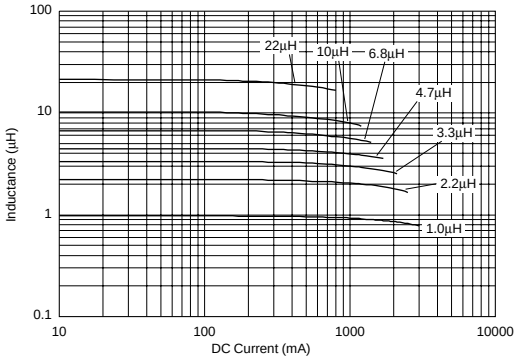
Part Number	Inductance	Inductance Test Frequency	*1 Allowable DC Current (Based on Temperature Rise)	*2 Allowable DC Current (Based on Inductance Change)	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH44PN1R0NP0☐	1.0μH±30%	1MHz	2450mA	2950mA	0.030ohm±20%	90MHz	Magnetic shield of magnetic powder in resin
LQH44PN2R2MP0☐	2.2μH±20%	1MHz	1800mA	2500mA	0.049ohm±20%	70MHz	Magnetic shield of magnetic powder in resin
LQH44PN3R3MP0☐	3.3μH±20%	1MHz	1770mA	2100mA	0.065ohm±20%	50MHz	Magnetic shield of magnetic powder in resin
LQH44PN4R7MP0☐	4.7μH±20%	1MHz	1700mA	1700mA	0.080ohm±20%	40MHz	Magnetic shield of magnetic powder in resin
LQH44PN6R8MP0☐	6.8μH±20%	1MHz	1340mA	1400mA	0.12ohm±20%	35MHz	Magnetic shield of magnetic powder in resin
LQH44PN100MP0☐	10μH±20%	1MHz	1170mA	1150mA	0.16ohm±20%	25MHz	Magnetic shield of magnetic powder in resin
LQH44PN220MP0☐	22μH±20%	1MHz	790mA	800mA	0.37ohm±20%	17MHz	Magnetic shield of magnetic powder in resin

Operating Temperature Range: -40 to +85°C Only for reflow soldering.
*1: When applied Allowable DC Current is applied to the Products, self-generation of heat will rise to 40°C or less.
*2: When applied Allowable DC Current is applied to the Products, Inductance will be within ±30% of nominal Inductance value.

■ Inductance-Frequency Characteristics (Typ.)



■ Inductance-Current Characteristics (Typ.)



Power Inductor Wire Wound Type

LQH44P_J0 Series (1515 Size)

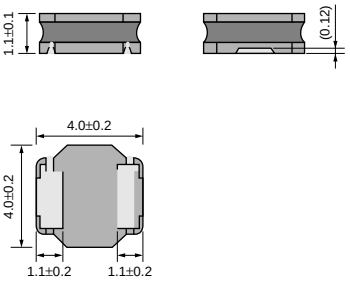
■ Features

1. Large rated current of 1530mA (at 1.0 micro H).
2. The series has an inductance range from 1.0 micro H to 47 micro H.
3. Magnetically shielded structure.
4. Reflow soldering methods can be employed.

■ Applications

For DC-DC converter

■ Dimension



(in mm)

■ Rated Value (☐: packaging code)

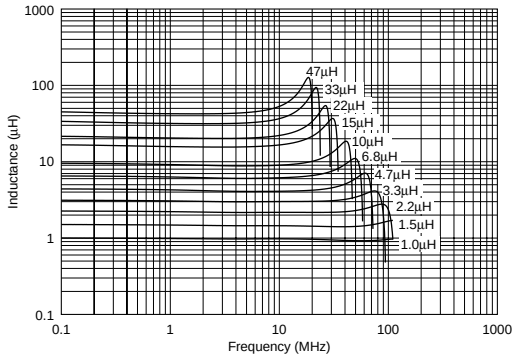
Part Number	Inductance	Inductance Test Frequency	*1 Allowable DC Current (Based on Temperature Rise)	*2 Allowable DC Current (Based on Inductance Change)	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH44PN1R0NJ0☐	1.0μH±30%	1MHz	1530mA	2000mA	0.048ohm±20%	120MHz	Magnetic shield of magnetic powder in resin
LQH44PN1R5MJ0☐	1.5μH±20%	1MHz	1380mA	1600mA	0.061ohm±20%	90MHz	Magnetic shield of magnetic powder in resin
LQH44PN2R2MJ0☐	2.2μH±20%	1MHz	1230mA	1320mA	0.074ohm±20%	68MHz	Magnetic shield of magnetic powder in resin
LQH44PN3R3MJ0☐	3.3μH±20%	1MHz	1000mA	900mA	0.088ohm±20%	55MHz	Magnetic shield of magnetic powder in resin
LQH44PN4R7MJ0☐	4.7μH±20%	1MHz	980mA	840mA	0.117ohm±20%	50MHz	Magnetic shield of magnetic powder in resin
LQH44PN6R8MJ0☐	6.8μH±20%	1MHz	860mA	720mA	0.143ohm±20%	38MHz	Magnetic shield of magnetic powder in resin
LQH44PN100MJ0☐	10μH±20%	1MHz	790mA	560mA	0.207ohm±20%	30MHz	Magnetic shield of magnetic powder in resin
LQH44PN150MJ0☐	15μH±20%	1MHz	610mA	430mA	0.385ohm±20%	25MHz	Magnetic shield of magnetic powder in resin
LQH44PN220MJ0☐	22μH±20%	1MHz	550mA	400mA	0.480ohm±20%	18MHz	Magnetic shield of magnetic powder in resin
LQH44PN330MJ0☐	33μH±20%	1MHz	430mA	360mA	0.740ohm±20%	15MHz	Magnetic shield of magnetic powder in resin
LQH44PN470MJ0☐	47μH±20%	1MHz	380mA	300mA	1.014ohm±20%	13MHz	Magnetic shield of magnetic powder in resin

Operating Temperature Range: -40 to +85°C Only for reflow soldering.

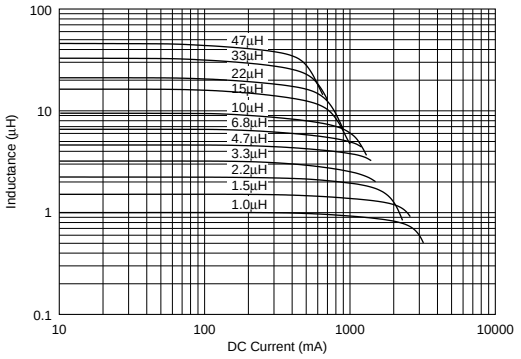
*1: When applied Allowable DC Current is applied to the Products, self-generation of heat will rise to 40°C or less.

*2: When applied Allowable DC Current is applied to the Products, Inductance will be within ±30% of nominal Inductance value.

■ Inductance-Frequency Characteristics (Typ.)



■ Inductance-Current Characteristics (Typ.)



Power Inductor Wire Wound Type

LQH55P Series (2220 Size)

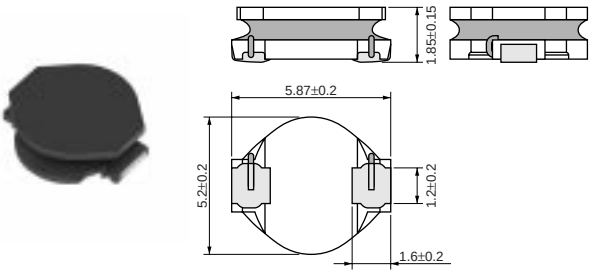
■ Features

1. Large rated current of 2600mA (at 1.2 micro H).
2. The series has an inductance range from 1.2 micro H to 22 micro H.
3. Magnetically shielded structure.
4. Reflow soldering methods can be employed.

■ Applications

For DC-DC converter

■ Dimension



(in mm)

■ Rated Value (☐: packaging code)

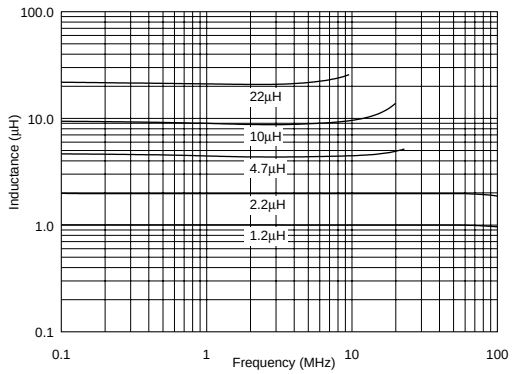
Part Number	Inductance	Inductance Test Frequency	*1 Allowable DC Current (Based on Temperature Rise)	*2 Allowable DC Current (Based on Inductance Change)	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH55PN1R2NR0☐	1.2μH±30%	100kHz	2900mA	2600mA	0.021ohm±20%	80MHz	Magnetic shield of magnetic powder in resin
LQH55PN2R2NR0☐	2.2μH±30%	100kHz	2500mA	2100mA	0.031ohm±20%	60MHz	Magnetic shield of magnetic powder in resin
LQH55PN2R7NR0☐	2.7μH±30%	100kHz	2150mA	2070mA	0.040ohm±20%	50MHz	Magnetic shield of magnetic powder in resin
LQH55PN3R3NR0☐	3.3μH±30%	100kHz	2000mA	2000mA	0.044ohm±20%	35MHz	Magnetic shield of magnetic powder in resin
LQH55PN4R7NR0☐	4.7μH±30%	100kHz	1750mA	1400mA	0.060ohm±20%	30MHz	Magnetic shield of magnetic powder in resin
LQH55PN6R8NR0☐	6.8μH±30%	100kHz	1450mA	1200mA	0.087ohm±20%	25MHz	Magnetic shield of magnetic powder in resin
LQH55PN100MR0☐	10μH±20%	100kHz	1250mA	1000mA	0.11ohm±20%	20MHz	Magnetic shield of magnetic powder in resin
LQH55PN220MR0☐	22μH±20%	100kHz	850mA	670mA	0.26ohm±20%	10MHz	Magnetic shield of magnetic powder in resin

Operating Temperature Range: -40°C to +85°C Only for reflow soldering.

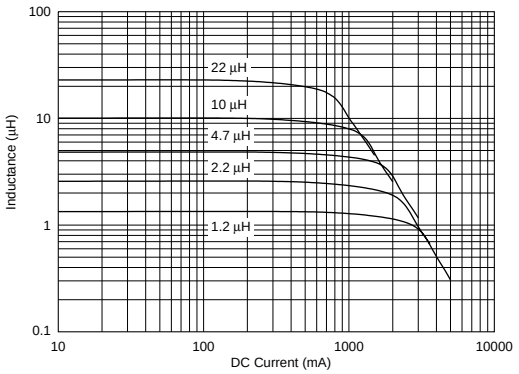
*1: When applied Allowable DC Current is applied to the Products, self-generation of heat will rise to 40°C or less.

*2: When applied Allowable DC Current is applied to the Products, Inductance will be within ±30% of nominal Inductance value.

■ Inductance - Frequency Characteristics (Typ.)



■ Inductance - Current Characteristics (Typ.)



Power Inductor Wire Wound Type

LQH6PP Series (2424 Size)

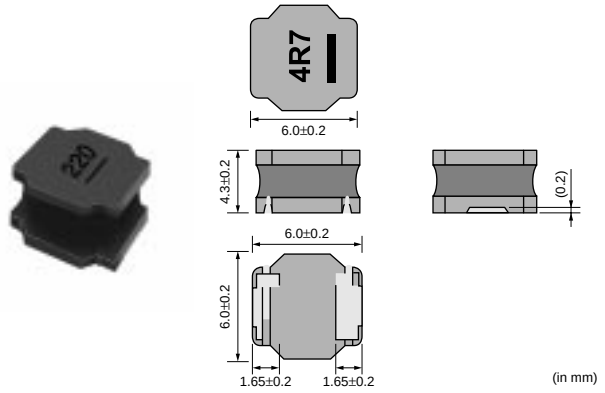
■ Features

1. Large rated current of 4.30A (at 1.0 micro H).
2. The series has an inductance range from 1.0 micro H to 100 micro H.
3. Magnetically shielded structure.
4. Reflow soldering methods can be employed.

■ Applications

For DC-DC converter

■ Dimension



■ Rated Value (☐: packaging code)

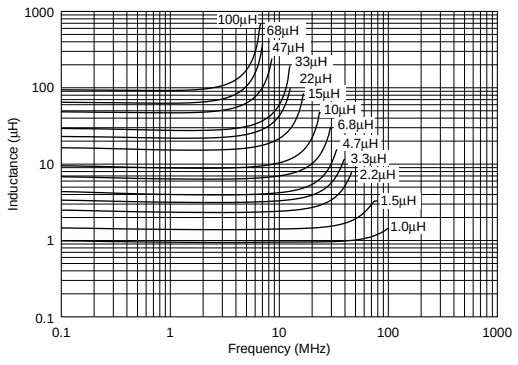
Part Number	Inductance	Inductance Test Frequency	*1 Allowable DC Current (Based on Temperature Rise)	*2 Allowable DC Current (Based on Inductance Change)	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH6PPN1R0N43☐	1.0μH±30%	100kHz	4.30A	7.50A	0.009ohm±30%	110MHz	Magnetic shield of magnetic powder in resin
LQH6PPN1R5N43☐	1.5μH±30%	100kHz	4.15A	6.50A	0.010ohm±30%	60MHz	Magnetic shield of magnetic powder in resin
LQH6PPN2R2N43☐	2.2μH±30%	100kHz	4.10A	5.60A	0.014ohm±30%	30MHz	Magnetic shield of magnetic powder in resin
LQH6PPN3R3N43☐	3.3μH±30%	100kHz	3.80A	4.50A	0.016ohm±30%	30MHz	Magnetic shield of magnetic powder in resin
LQH6PPN4R7M43☐	4.7μH±20%	100kHz	3.20A	4.00A	0.020ohm±30%	25MHz	Magnetic shield of magnetic powder in resin
LQH6PPN6R8M43☐	6.8μH±20%	100kHz	2.85A	3.20A	0.028ohm±30%	20MHz	Magnetic shield of magnetic powder in resin
LQH6PPN100M43☐	10μH±20%	100kHz	2.60A	2.60A	0.044ohm±30%	15MHz	Magnetic shield of magnetic powder in resin
LQH6PPN150M43☐	15μH±20%	100kHz	2.20A	2.20A	0.065ohm±30%	10MHz	Magnetic shield of magnetic powder in resin
LQH6PPN220M43☐	22μH±20%	100kHz	1.55A	1.70A	0.108ohm±30%	10MHz	Magnetic shield of magnetic powder in resin
LQH6PPN330M43☐	33μH±20%	100kHz	1.29A	1.60A	0.137ohm±30%	6MHz	Magnetic shield of magnetic powder in resin
LQH6PPN470M43☐	47μH±20%	100kHz	1.10A	1.25A	0.230ohm±30%	6MHz	Magnetic shield of magnetic powder in resin
LQH6PPN680M43☐	68μH±20%	100kHz	1.00A	1.10A	0.289ohm±30%	5MHz	Magnetic shield of magnetic powder in resin
LQH6PPN101M43☐	100μH±20%	100kHz	0.80A	0.92A	0.436ohm±30%	3MHz	Magnetic shield of magnetic powder in resin

Operating Temperature Range: -40 to +85°C Only for reflow soldering.

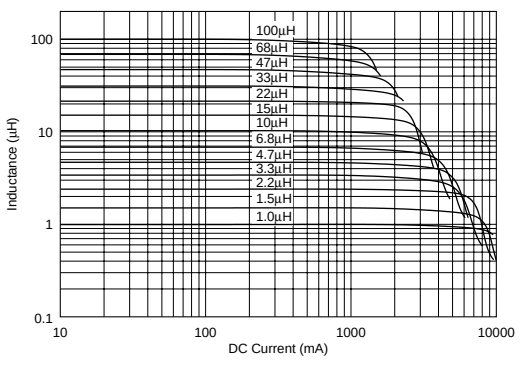
*1: When applied Allowable DC Current is applied to the Products, self-generation of heat will rise to 40°C or less.

*2: When applied Allowable DC Current is applied to the Products, Inductance will be within ±30% of nominal Inductance value.

■ Inductance-Frequency Characteristics (Typ.)



■ Inductance-Current Characteristics (Typ.)



Power Inductor Wire Wound Type

LQH88P Series (3131 Size)

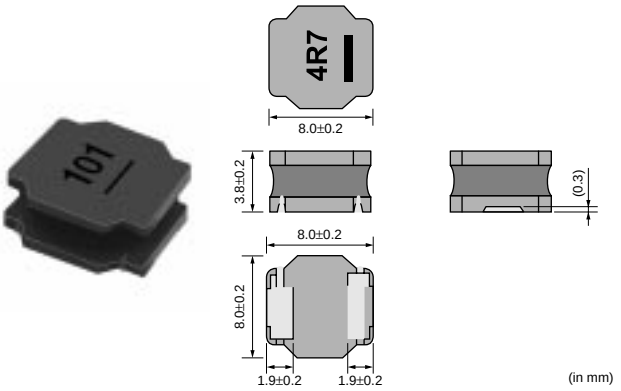
■ Features

1. Large rated current of 8.00A (at 1.0 micro H).
2. The series has an inductance range from 1.0 micro H to 100 micro H.
3. Magnetically shielded structure.
4. Reflow soldering methods can be employed.

■ Applications

For DC-DC converter

■ Dimension



■ Rated Value (☐: packaging code)

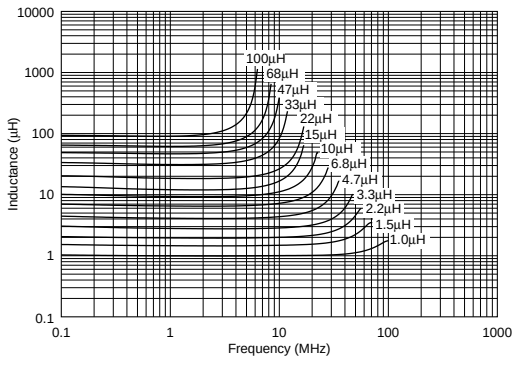
Part Number	Inductance	Inductance Test Frequency	*1 Allowable DC Current (Based on Temperature Rise)	*2 Allowable DC Current (Based on Inductance Change)	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH88PN1R0N38☐	1.0μH±30%	100kHz	8.00A	11.20A	0.006ohm±30%	100MHz	Magnetic shield of magnetic powder in resin
LQH88PN1R5N38☐	1.5μH±30%	100kHz	7.10A	8.50A	0.008ohm±30%	60MHz	Magnetic shield of magnetic powder in resin
LQH88PN2R2N38☐	2.2μH±30%	100kHz	6.40A	8.00A	0.009ohm±30%	50MHz	Magnetic shield of magnetic powder in resin
LQH88PN3R3N38☐	3.3μH±30%	100kHz	5.00A	7.00A	0.013ohm±30%	35MHz	Magnetic shield of magnetic powder in resin
LQH88PN4R7N38☐	4.7μH±30%	100kHz	4.20A	6.00A	0.017ohm±30%	30MHz	Magnetic shield of magnetic powder in resin
LQH88PN6R8N38☐	6.8μH±30%	100kHz	3.80A	4.50A	0.022ohm±30%	20MHz	Magnetic shield of magnetic powder in resin
LQH88PN100M38☐	10μH±20%	100kHz	3.15A	3.60A	0.029ohm±30%	18MHz	Magnetic shield of magnetic powder in resin
LQH88PN150M38☐	15μH±20%	100kHz	2.45A	3.00A	0.041ohm±30%	13MHz	Magnetic shield of magnetic powder in resin
LQH88PN220M38☐	22μH±20%	100kHz	2.25A	2.70A	0.066ohm±30%	10MHz	Magnetic shield of magnetic powder in resin
LQH88PN330M38☐	33μH±20%	100kHz	1.75A	1.90A	0.095ohm±30%	9MHz	Magnetic shield of magnetic powder in resin
LQH88PN470M38☐	47μH±20%	100kHz	1.45A	1.50A	0.157ohm±30%	7MHz	Magnetic shield of magnetic powder in resin
LQH88PN680M38☐	68μH±20%	100kHz	1.10A	1.25A	0.190ohm±30%	7MHz	Magnetic shield of magnetic powder in resin
LQH88PN101M38☐	100μH±20%	100kHz	1.00A	1.00A	0.265ohm±30%	4MHz	Magnetic shield of magnetic powder in resin

Operating Temperature Range: -40 to +85°C Only for reflow soldering.

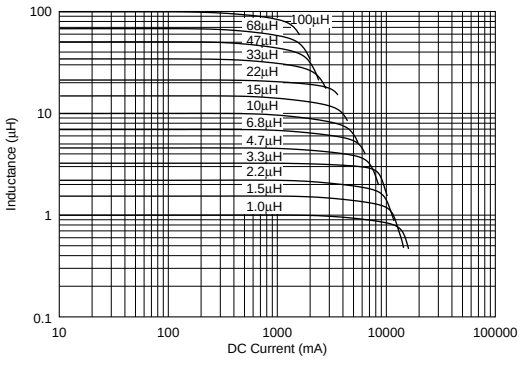
*1: When applied Allowable DC Current is applied to the Products, self-generation of heat will rise to 40°C or less.

*2: When applied Allowable DC Current is applied to the Products, Inductance will be within ±30% of nominal Inductance value.

■ Inductance-Frequency Characteristics (Typ.)



■ Inductance-Current Characteristics (Typ.)



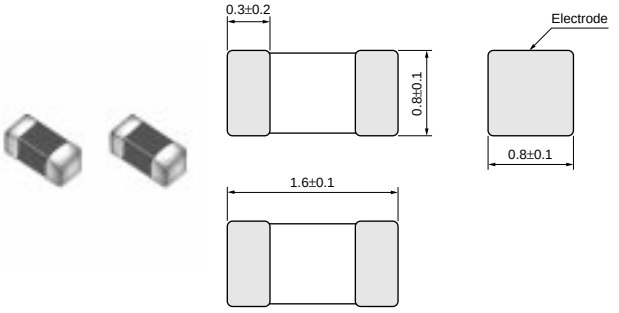
Power Inductor Multilayer Type for Choke

LQM18F Series (0603 Size)

■ Features

1. Ultra small size in 1.6x0.8mm and lightweight.
2. Special ferrite material, whose inductance change caused by bias current is small, enables large rated current of 50mA at 10 micro H.
3. The lowest DC resistance
4. Magnetically shielded structure enables good crosstalk characteristics.
5. Both flow and reflow soldering methods can be employed due to high heat resistant electrode structure.

■ Dimension



(in mm)

■ Applications

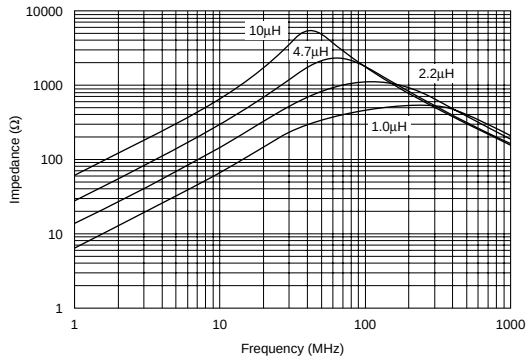
Choke circuits in DC power line of compact mobile equipment such as mobile phones, digital still cameras, digital video cameras, and music players.

■ Rated Value (☐: packaging code)

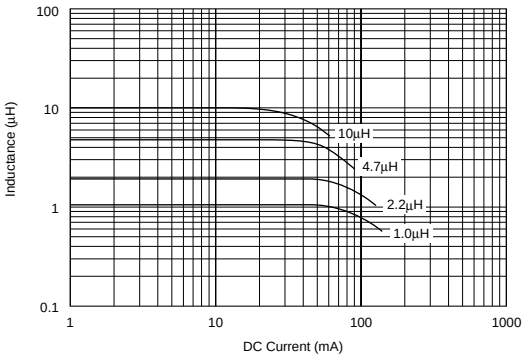
Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQM18FN1R0M00☐	1.0μH±20%	1MHz	150mA	0.20ohm±30%	120MHz	Magnetic shield of ferrite
LQM18FN2R2M00☐	2.2μH±20%	1MHz	120mA	0.40ohm±30%	80MHz	Magnetic shield of ferrite
LQM18FN4R7M00☐	4.7μH±20%	1MHz	80mA	0.60ohm±30%	50MHz	Magnetic shield of ferrite
LQM18FN100M00☐	10μH±20%	1MHz	50mA	0.90ohm±30%	30MHz	Magnetic shield of ferrite

Operating Temperature Range: -55°C to +125°C

■ Impedance - Frequency Characteristics



■ Inductance - Current Characteristics



Power Inductor Multilayer Type for Choke

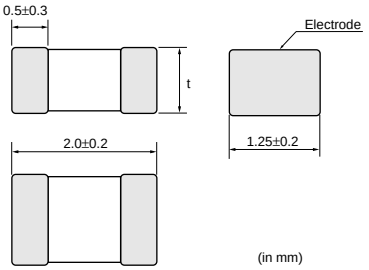
LQM21D Series (0805 Size)

LQM21D series consists of magnetically shielded chip inductors. It has less than half the DC resistance of our conventional monolithic chip inductors as well as high inductance.

■ Features

1. The inductors have very low DC resistance.
2. The series has an inductance range of 1.0 micro H to 47 micro H.
3. Magnetically shielded structure provides excellent crosstalk characteristics.
4. Compact (2.0x1.25mm) and lightweight
5. Applicable soldering methods are both flow soldering and reflow soldering.

■ Dimension



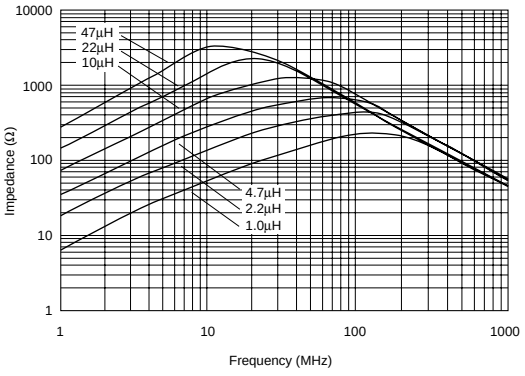
Dimension of t	Inductance: 1.0 to 10μH	0.85±0.2
	Inductance: 22 to 47μH	1.25±0.2

■ Rated Value (□: packaging code)

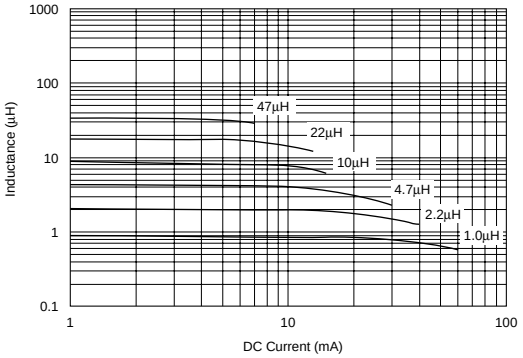
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQM21DN1R0N00□	1.0μH±30%	1MHz	60mA	0.10ohm	75MHz	Magnetic shield of ferrite
LQM21DN2R2N00□	2.2μH±30%	1MHz	40mA	0.17ohm	50MHz	Magnetic shield of ferrite
LQM21DN4R7N00□	4.7μH±30%	1MHz	30mA	0.30ohm	35MHz	Magnetic shield of ferrite
LQM21DN100N00□	10μH±30%	1MHz	15mA	0.50ohm	24MHz	Magnetic shield of ferrite
LQM21DN220N00□	22μH±30%	1MHz	13mA	0.65ohm	16MHz	Magnetic shield of ferrite
LQM21DN470N00□	47μH±30%	1MHz	7mA	1.20ohm	7.5MHz	Magnetic shield of ferrite

Operating Temperature Range: -40°C to +85°C

■ Impedance - Frequency Characteristics



■ Inductance - Current Characteristics



Power Inductor Multilayer Type for Choke

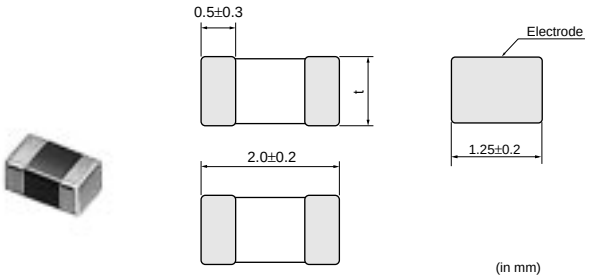
LQM21F_00 Series (0805 Size)

LQM21F series consists of magnetically shielded chip inductors based on Murata's technologies of multilayer process and magnetic materials. Excellent direct current characteristics are realized by using magnetic materials which have excellent saturation characteristics. The inductance of LQM21F is four times as large as that of conventional items.

■ Features

1. LQM21F series is suitable for power line inductors for choke because of its excellent direct current characteristics. The series has larger rated current (60mA at 10 micro H) than conventional rated current.
2. Low DC resistance is realized.
3. The crosstalk characteristics are excellent because of the use of magnetically shielded structure.
4. Small size (2.0x1.25mm) and lightweight
5. Applicable soldering methods are both flow soldering and reflow soldering.

■ Dimension



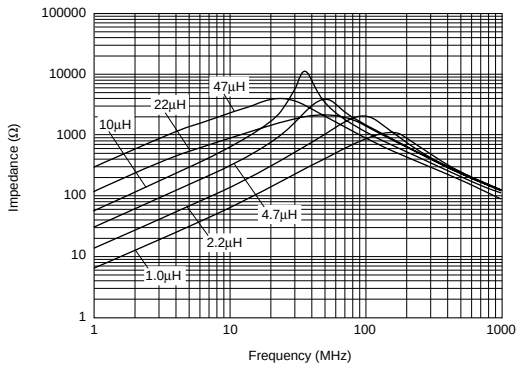
Dimension of t	Inductance: 1.0 to 2.2µH	0.85±0.2
	Inductance: 4.7 to 47µH	1.25±0.2

■ Rated Value (☐: packaging code)

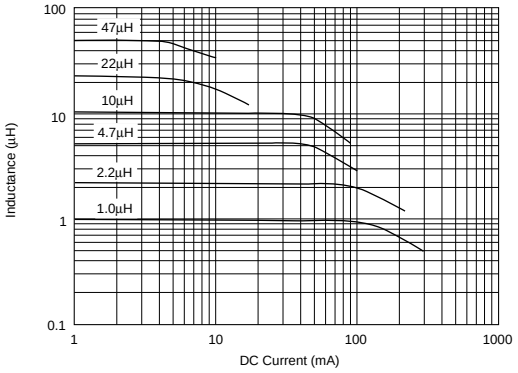
Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQM21FN1R0N00☐	1.0µH±30%	1MHz	220mA	0.20ohm±30%	105MHz	Magnetic shield of ferrite
LQM21FN2R2N00☐	2.2µH±30%	1MHz	150mA	0.28ohm±30%	70MHz	Magnetic shield of ferrite
LQM21FN4R7N00☐	4.7µH±30%	1MHz	80mA	0.30ohm±30%	25MHz	Magnetic shield of ferrite
LQM21FN100N00☐	10µH±30%	1MHz	60mA	0.50ohm±30%	15MHz	Magnetic shield of ferrite
LQM21FN220N00☐	22µH±30%	1MHz	13mA	0.35ohm±30%	15MHz	Magnetic shield of ferrite
LQM21FN470N00☐	47µH±30%	1MHz	7mA	0.60ohm±30%	7.5MHz	Magnetic shield of ferrite

Operating Temperature Range: -40°C to +85°C

■ Impedance - Frequency Characteristics



■ Inductance - Current Characteristics



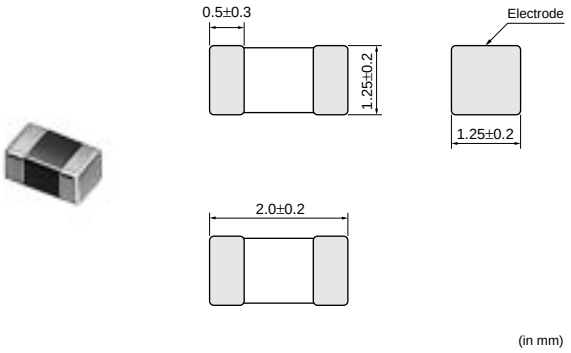
Power Inductor Multilayer Type for Choke

LQM21F_70 Series (0805 Size)

■ Features

Rated Current is larger than previous (LQM21F_00) series.
Rated Current: 100mA (10 micro H)

■ Dimension



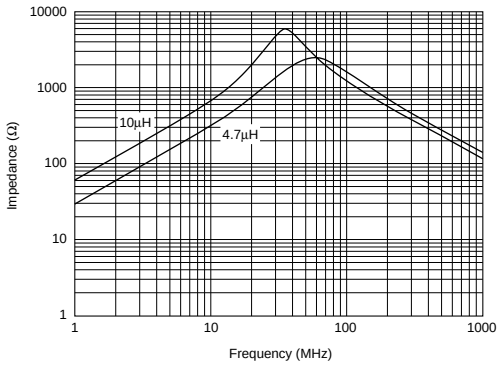
(in mm)

■ Rated Value (☐: packaging code)

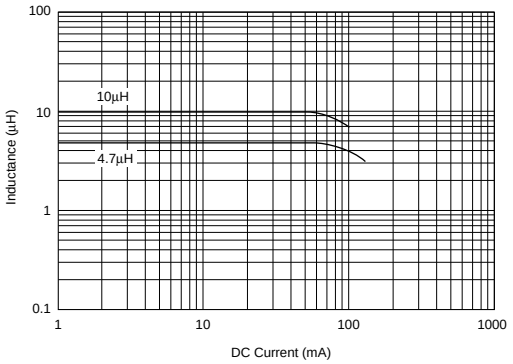
Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQM21FN4R7M70☐	4.7μH±20%	1MHz	120mA	0.35ohm±30%	25MHz	Magnetic shield of ferrite
LQM21FN100M70☐	10μH±20%	1MHz	100mA	0.60ohm±30%	15MHz	Magnetic shield of ferrite

Operating Temperature Range: -55°C to +125°C

■ Impedance - Frequency Characteristics



■ Inductance - Current Characteristics



Power Inductor Multilayer Type for Choke

LQM21F_80 Series (0805 Size)

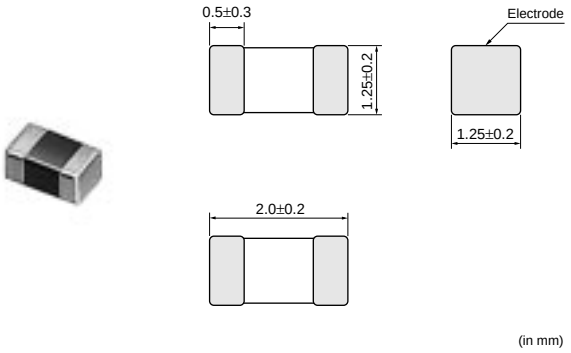
■ Features

1. Low DC resistance is realized.
   LQM21F_80 series reduces about 50% DC resistance in comparison with LQM21F_70 series.
2. Small size in 2.0x1.25mm and large rated current of 120mA (4.7 micro H).
3. Magnetically shielded structure
4. Applicable soldering methods are both flow soldering and reflow soldering.

■ Applications

Choke circuits in DC power line of compact mobile equipment such as mobile phones, DSC, DVC.

■ Dimension



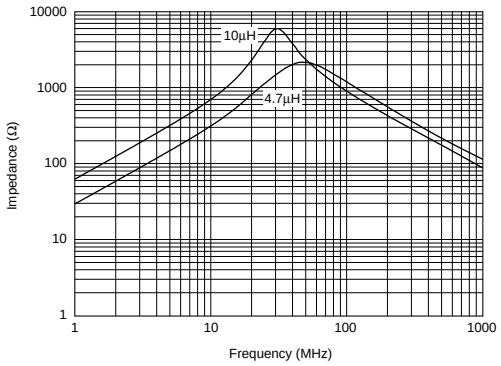
(in mm)

■ Rated Value (☐: packaging code)

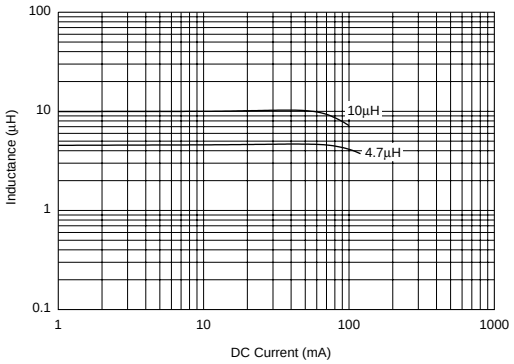
Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQM21FN4R7M80☐	4.7μH±20%	1MHz	120mA	0.18ohm±30%	25MHz	Magnetic shield of ferrite
LQM21FN100M80☐	10μH±20%	1MHz	100mA	0.30ohm±30%	15MHz	Magnetic shield of ferrite

Operating Temperature Range: -55°C to +125°C

■ Impedance - Frequency Characteristics



■ Inductance - Current Characteristics



Power Inductor Multilayer Type for Choke

LQM31F Series (1206 Size)

LQM31F series consists of magnetically shielded chip inductors based on Murata's technologies of multilayer process and magnetic materials. Excellent direct current characteristics and low DC resistance are realized by using magnetic materials which have excellent saturation characteristics and high permeability.

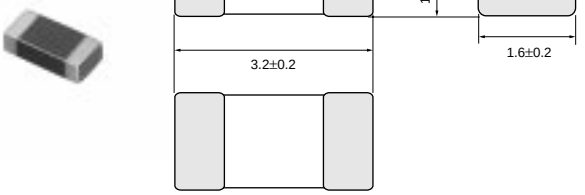
■ Features

1. LQM31F series is suitable for power line inductors for choke because of its excellent direct current characteristics and large rated current (70mA at 10 micro H).
2. Low DC resistance is realized.
3. The crosstalk characteristics are excellent because of magnetically shielded structure.
4. Low profile 1.0mm
5. Applicable soldering methods are both flow soldering and reflow soldering.

■ Applications

Circuits for DC power line choke of telecommunications equipment such as PDAs, Note-PCs, DSC, MD and DVD-RAM

■ Dimension



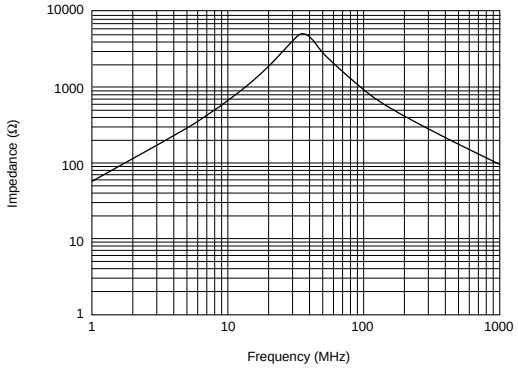
(in mm)

■ Rated Value (☐: packaging code)

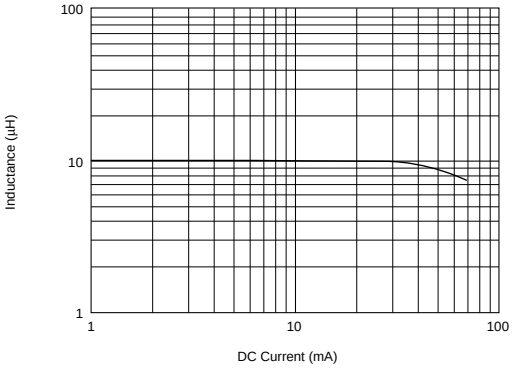
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQM31FN100M00☐	10μH±20%	1MHz	70mA	0.50ohm	20MHz	Magnetic shield of ferrite

Operating Temperature Range: -40°C to +85°C

■ Impedance - Frequency Characteristics



■ Inductance - Current Characteristics



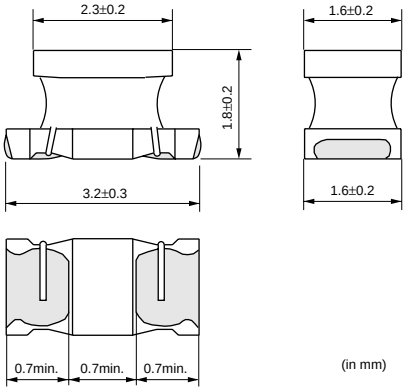
Power Inductor Wire Wound Type for Choke

LQH31C Series (1206 Size)

■ Features

LQH31C series consists of miniature chip inductors with low DC resistance, high current capacity, and high impedance characteristics. It is suitable for use as inductors for choke in DC power supply circuits. High rated current up to 970mA is available.

■ Dimension

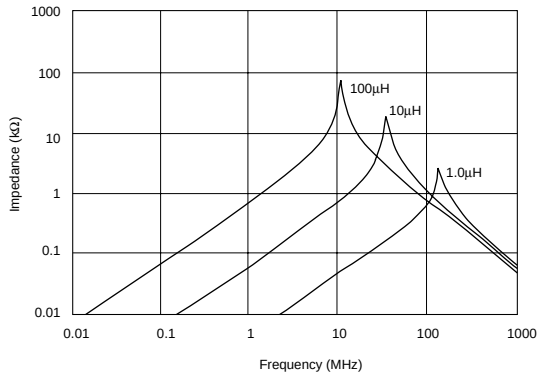


■ Rated Value (☐: packaging code)

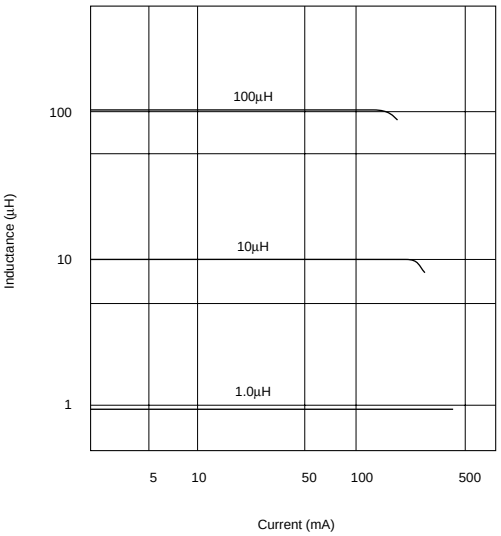
Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH31CNR12M03☐	0.12µH±20%	1MHz	970mA	0.08ohm±40%	250MHz	No magnetic shield
LQH31CNR22M03☐	0.22µH±20%	1MHz	850mA	0.1ohm±40%	250MHz	No magnetic shield
LQH31CNR47M03☐	0.47µH±20%	1MHz	700mA	0.15ohm±40%	180MHz	No magnetic shield
LQH31CN1R0M03☐	1.0µH±20%	1MHz	510mA	0.28ohm±30%	100MHz	No magnetic shield
LQH31CN2R2M03☐	2.2µH±20%	1MHz	430mA	0.41ohm±30%	50MHz	No magnetic shield
LQH31CN4R7M03☐	4.7µH±20%	1MHz	340mA	0.65ohm±30%	31MHz	No magnetic shield
LQH31CN100K03☐	10µH±10%	1MHz	230mA	1.3ohm±30%	20MHz	No magnetic shield
LQH31CN220K03☐	22µH±10%	1MHz	160mA	3.0ohm±30%	14MHz	No magnetic shield
LQH31CN470K03☐	47µH±10%	1MHz	100mA	8.0ohm±30%	10MHz	No magnetic shield
LQH31CN101K03☐	100µH±10%	1MHz	80mA	12ohm±30%	7MHz	No magnetic shield

Operating Temperature Range: -40°C to +85°C

■ Impedance - Frequency Characteristics (Typ.)



■ Inductance - Current Characteristics (Typ.)

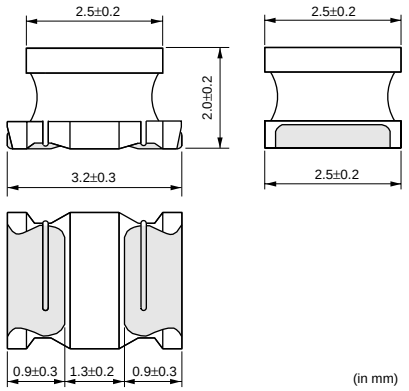


Power Inductor Wire Wound Type for Choke

LQH32C_23/LQH32C_33 Series (1210 Size)

LQH32C_23/_33 series consists of miniature chip inductors with low DC resistance, high current capacity, and high inductance characteristics. These features are made possible by the development of Murata's innovative automatic wire wound techniques.

■ Dimension



(in mm)

■ Features

1. Low DC resistance, high rated current and high inductance. Inductance: 0.15 to 560 micro H.
2. The series exhibits low voltage drops and small variations in inductance with respect to temperature rise and DC current level. This makes them excellent for use as power supply line inductors for choke.
3. The series has excellent solder heat resistance. Both flow and reflow soldering methods can be employed.

LQH32C_23 Series

■ Rated Value (☐: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH32CN1R0M23☐	1.0μH±20%	1MHz	800mA	0.09ohm±30%	96MHz	No magnetic shield
LQH32CN2R2M23☐	2.2μH±20%	1MHz	600mA	0.13ohm±30%	64MHz	No magnetic shield
LQH32CN4R7M23☐	4.7μH±20%	1MHz	450mA	0.2ohm±30%	43MHz	No magnetic shield
LQH32CN100K23☐	10μH±10%	1MHz	300mA	0.44ohm±30%	26MHz	No magnetic shield
LQH32CN220K23☐	22μH±10%	1MHz	250mA	0.71ohm±30%	19MHz	No magnetic shield
LQH32CN470K23☐	47μH±10%	1MHz	170mA	1.3ohm±30%	15MHz	No magnetic shield
LQH32CN101K23☐	100μH±10%	1MHz	100mA	3.5ohm±30%	10MHz	No magnetic shield
LQH32CN221K23☐	220μH±10%	1MHz	70mA	8.4ohm±30%	6.8MHz	No magnetic shield
LQH32CN331K23☐	330μH±10%	1MHz	60mA	10ohm±30%	5.6MHz	No magnetic shield
LQH32CN391K23☐	390μH±10%	1MHz	60mA	17ohm±30%	5MHz	No magnetic shield
LQH32CN471K23☐	470μH±10%	1kHz	60mA	19ohm±30%	5MHz	No magnetic shield
LQH32CN561K23☐	560μH±10%	1kHz	60mA	22ohm±30%	5MHz	No magnetic shield

Operating Temperature Range: -40°C to +85°C

LQH32C_33 Series (Low DC Resistance Type)

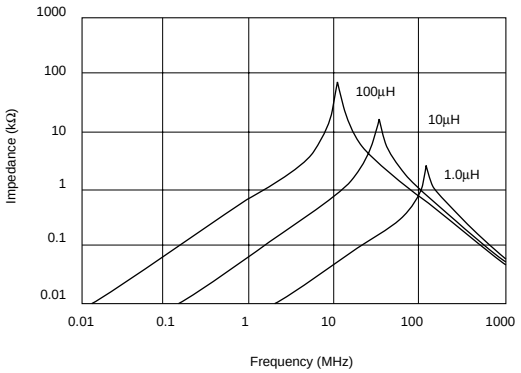
■ Rated Value (☐: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH32CNR15M33☐	0.15μH±20%	1MHz	1450mA	0.028ohm±30%	400MHz	No magnetic shield
LQH32CNR27M33☐	0.27μH±20%	1MHz	1250mA	0.034ohm±30%	250MHz	No magnetic shield
LQH32CNR47M33☐	0.47μH±20%	1MHz	1100mA	0.042ohm±30%	150MHz	No magnetic shield
LQH32CN1R0M33☐	1.0μH±20%	1MHz	1000mA	0.06ohm±30%	100MHz	No magnetic shield
LQH32CN2R2M33☐	2.2μH±20%	1MHz	790mA	0.097ohm±30%	64MHz	No magnetic shield
LQH32CN4R7M33☐	4.7μH±20%	1MHz	650mA	0.15ohm±30%	43MHz	No magnetic shield
LQH32CN100K33☐	10μH±10%	1MHz	450mA	0.3ohm±30%	26MHz	No magnetic shield

Operating Temperature Range: -40°C to +85°C

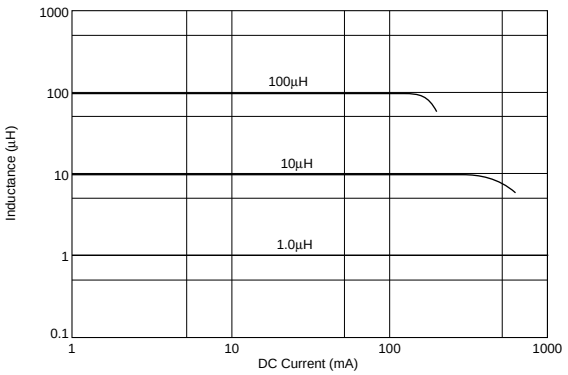
■ Impedance - Frequency Characteristics (Typ.)

LQH32C_23/LQH32C_33



■ Inductance - Current Characteristics (Typ.)

LQH32C_23/LQH32C_33

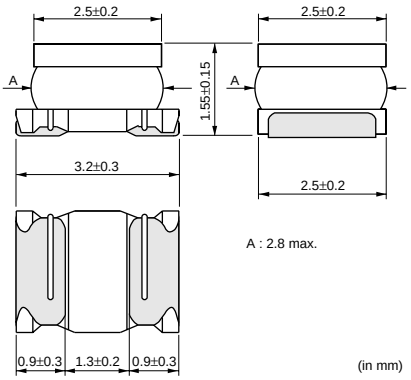


Power Inductor Wire Wound Type for Choke

LQH32C_53 Series (1210 Size)

LQH32C_53 series consists of miniature chip inductors with low DC resistance, high current capacity, and high inductance characteristics. These features are made possible by the development of Murata's innovative wire wound techniques. They are excellent for use as inductors for choke in DC power supply circuits.
The LQH32C_53 series has achieved Max 1.7mm height and high rated current.

■ Dimension



■ Features

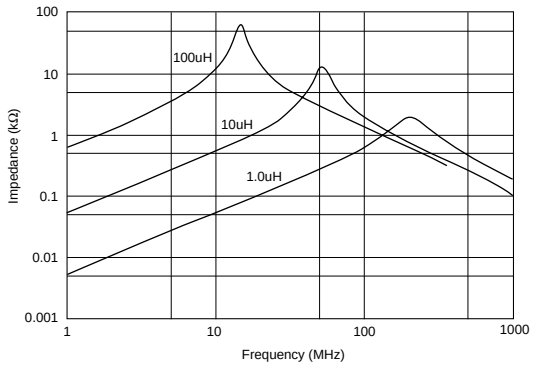
1. The series has a wide inductance range of 1.0 to 100 micro H.
2. The series exhibits low voltage drops and small variations in inductance with respect to temperature rise and DC current level. This makes them excellent for use as power supply line inductors for choke.
3. The series has excellent solder heat resistance. Both flow and reflow soldering methods can be employed.

■ Rated Value (☐: packaging code)

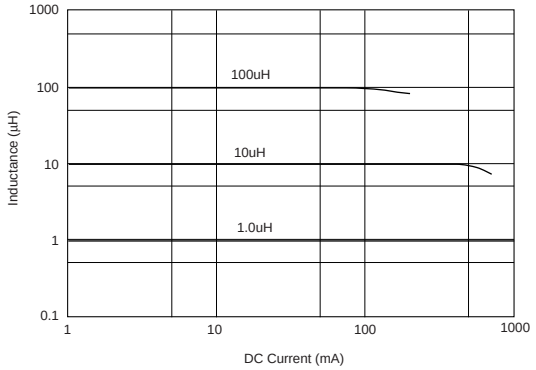
Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH32CN1R0M53☐	1.0µH±20%	1MHz	1000mA	0.060ohm±30%	100MHz	No magnetic shield
LQH32CN2R2M53☐	2.2µH±20%	1MHz	790mA	0.097ohm±30%	64MHz	No magnetic shield
LQH32CN3R3M53☐	3.3µH±20%	1MHz	710mA	0.12ohm±30%	50MHz	No magnetic shield
LQH32CN4R7M53☐	4.7µH±20%	1MHz	650mA	0.15ohm±30%	43MHz	No magnetic shield
LQH32CN6R8M53☐	6.8µH±20%	1MHz	540mA	0.25ohm±30%	32MHz	No magnetic shield
LQH32CN100K53☐	10µH±10%	1MHz	450mA	0.30ohm±30%	26MHz	No magnetic shield
LQH32CN150K53☐	15µH±10%	1MHz	300mA	0.58ohm±30%	26MHz	No magnetic shield
LQH32CN220K53☐	22µH±10%	1MHz	250mA	0.71ohm±30%	19MHz	No magnetic shield
LQH32CN330K53☐	33µH±10%	1MHz	200mA	1.1ohm±30%	17MHz	No magnetic shield
LQH32CN470K53☐	47µH±10%	1MHz	170mA	1.3ohm±30%	15MHz	No magnetic shield
LQH32CN680K53☐	68µH±10%	1MHz	130mA	2.2ohm±30%	12MHz	No magnetic shield
LQH32CN101K53☐	100µH±10%	1MHz	100mA	3.5ohm±30%	10MHz	No magnetic shield

Operating Temperature Range: -40°C to +85°C

■ Impedance - Frequency Characteristics (Typ.)



■ Inductance - Current Characteristics (Typ.)



Power Inductor Wire Wound Type for Choke

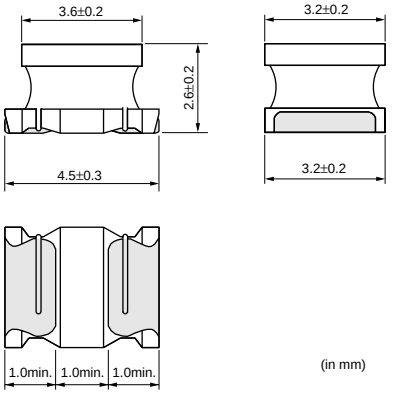
LQH43C Series (1812 Size)

LQH43C series consists of miniature chip inductors with low DC resistance, high current capacity, and high impedance characteristics. It is suitable for use as inductors for choke in DC power supply circuits.

■ Features

1. Various inductance ranges are available.
2. The series exhibits low voltage drops and small change in inductance with respect to temperature rise and DC current level. This makes them excellent to use as power supply line inductors for choke.
3. Small size 4.5x3.2mm and realized low height 2.8mm max.
4. The series has excellent solder heat resistance. Both flow and reflow soldering methods can be employed.

■ Dimension



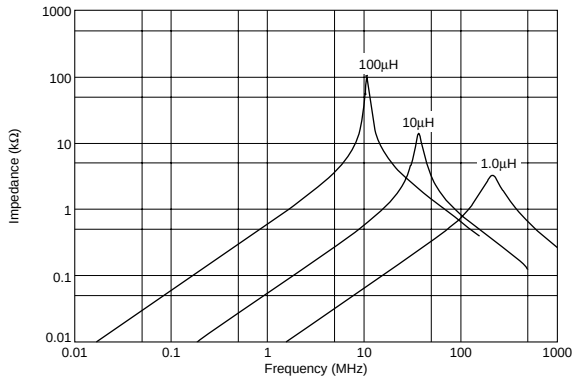
(in mm)

■ Rated Value (☐: packaging code)

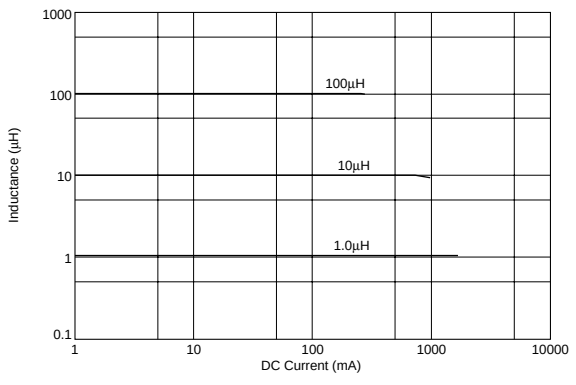
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH43CN1R0M03☐	1.0µH±20%	1MHz	1080mA	0.08ohm	100MHz	No magnetic shield
LQH43CN1R5M03☐	1.5µH±20%	1MHz	1000mA	0.09ohm	85MHz	No magnetic shield
LQH43CN2R2M03☐	2.2µH±20%	1MHz	900mA	0.11ohm	60MHz	No magnetic shield
LQH43CN3R3M03☐	3.3µH±20%	1MHz	800mA	0.13ohm	47MHz	No magnetic shield
LQH43CN4R7M03☐	4.7µH±20%	1MHz	750mA	0.15ohm	35MHz	No magnetic shield
LQH43CN6R8M03☐	6.8µH±20%	1MHz	720mA	0.20ohm	30MHz	No magnetic shield
LQH43CN100K03☐	10µH±10%	1MHz	650mA	0.24ohm	23MHz	No magnetic shield
LQH43CN150K03☐	15µH±10%	1MHz	570mA	0.32ohm	20MHz	No magnetic shield
LQH43CN220K03☐	22µH±10%	1MHz	420mA	0.6ohm	15MHz	No magnetic shield
LQH43CN330K03☐	33µH±10%	1MHz	310mA	1.0ohm	12MHz	No magnetic shield
LQH43CN470K03☐	47µH±10%	1MHz	280mA	1.1ohm	10MHz	No magnetic shield
LQH43CN680K03☐	68µH±10%	1MHz	220mA	1.7ohm	8.4MHz	No magnetic shield
LQH43CN101K03☐	100µH±10%	1MHz	190mA	2.2ohm	6.8MHz	No magnetic shield
LQH43CN151K03☐	150µH±10%	1MHz	130mA	3.5ohm	5.5MHz	No magnetic shield
LQH43CN221K03☐	220µH±10%	1MHz	110mA	4.0ohm	4.5MHz	No magnetic shield
LQH43CN331K03☐	330µH±10%	1MHz	100mA	6.8ohm	3.6MHz	No magnetic shield
LQH43CN471K03☐	470µH±10%	1kHz	90mA	8.5ohm	3.0MHz	No magnetic shield

Operating Temperature Range: -40°C to +85°C

■ Impedance - Frequency Characteristics (Typ.)



■ Inductance - Current Characteristics (Typ.)



Power Inductor Wire Wound Type for Choke

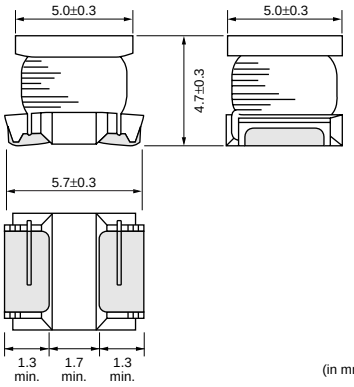
LQH55D Series (2220 Size)

LQH55D series is wire wound type inductors for choke by using high performance thick wire wound technology.

■ Features

1. Low direct current resistance, large current capacity and large inductance
2. For DC-DC converters and DC power supply circuits

■ Dimension



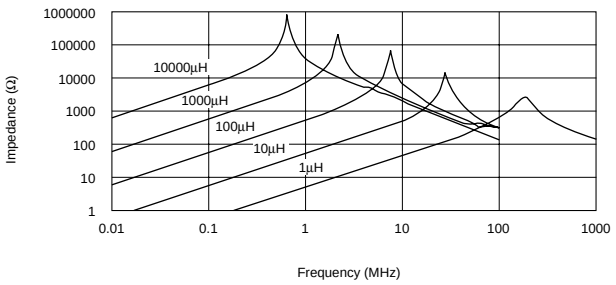
(in mm)

■ Rated Value (☐: packaging code)

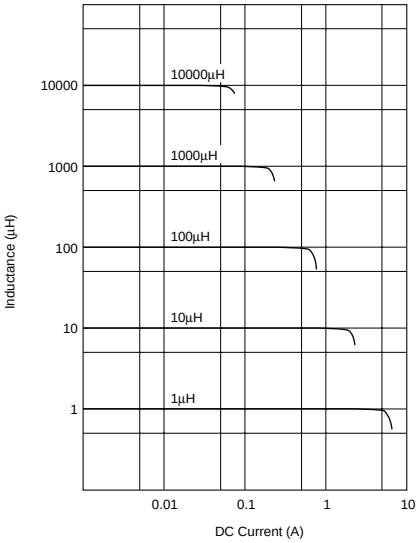
Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH55DNR12M03☐	0.12µH±20%	1MHz	6000mA	0.0098ohm 0.007ohm±40%	450MHz	No magnetic shield
LQH55DNR27M03☐	0.27µH±20%	1MHz	5300mA	0.014ohm 0.010ohm±40%	300MHz	No magnetic shield
LQH55DNR47M03☐	0.47µH±20%	1MHz	4800mA	0.0182ohm 0.013ohm±40%	200MHz	No magnetic shield
LQH55DN1R0M03☐	1.0µH±20%	1MHz	4000mA	0.0266ohm 0.019ohm±40%	150MHz	No magnetic shield
LQH55DN1R5M03☐	1.5µH±20%	1MHz	3700mA	0.0308ohm 0.022ohm±40%	110MHz	No magnetic shield
LQH55DN2R2M03☐	2.2µH±20%	1MHz	3200mA	0.0406ohm 0.029ohm±40%	80MHz	No magnetic shield
LQH55DN3R3M03☐	3.3µH±20%	1MHz	2900mA	0.0504ohm 0.036ohm±40%	40MHz	No magnetic shield
LQH55DN4R7M03☐	4.7µH±20%	1MHz	2700mA	0.0574ohm 0.041ohm±40%	30MHz	No magnetic shield
LQH55DN6R8M03☐	6.8µH±20%	1MHz	2000mA	0.1036ohm 0.074ohm±40%	25MHz	No magnetic shield
LQH55DN100M03☐	10µH±20%	1MHz	1700mA	0.1302ohm 0.093ohm±40%	20MHz	No magnetic shield
LQH55DN150M03☐	15µH±20%	1MHz	1400mA	0.21ohm 0.15ohm±40%	17MHz	No magnetic shield
LQH55DN220M03☐	22µH±20%	1MHz	1200mA	0.266ohm 0.19ohm±40%	15MHz	No magnetic shield
LQH55DN330M03☐	33µH±20%	1MHz	900mA	0.448ohm 0.32ohm±40%	12MHz	No magnetic shield
LQH55DN470M03☐	47µH±20%	1MHz	800mA	0.56ohm 0.40ohm±40%	10MHz	No magnetic shield
LQH55DN680M03☐	68µH±20%	1MHz	640mA	0.938ohm 0.67ohm±40%	7.6MHz	No magnetic shield
LQH55DN101M03☐	100µH±20%	100kHz	560mA	1.204ohm 0.86ohm±40%	6.5MHz	No magnetic shield
LQH55DN151M03☐	150µH±20%	100kHz	420mA	2.66ohm 1.9ohm±40%	5.0MHz	No magnetic shield
LQH55DN221M03☐	220µH±20%	100kHz	320mA	3.36ohm 2.4ohm±40%	4.0MHz	No magnetic shield
LQH55DN331M03☐	330µH±20%	100kHz	270mA	6.16ohm 4.4ohm±40%	3.1MHz	No magnetic shield
LQH55DN471M03☐	470µH±20%	100kHz	240mA	7.56ohm 5.4ohm±40%	2.4MHz	No magnetic shield
LQH55DN681M03☐	680µH±20%	100kHz	190mA	11.34ohm 8.1ohm±40%	1.9MHz	No magnetic shield
LQH55DN102M03☐	1000µH±20%	10kHz	150mA	14.42ohm 10.3ohm±40%	1.7MHz	No magnetic shield
LQH55DN222M03☐	2200µH±20%	10kHz	100mA	30.1ohm 21.5ohm±40%	1.2MHz	No magnetic shield
LQH55DN472M03☐	4700µH±20%	10kHz	70mA	61.04ohm 43.6ohm±40%	0.8MHz	No magnetic shield
LQH55DN103M03☐	10000µH±20%	10kHz	50mA	140ohm 100ohm±40%	0.5MHz	No magnetic shield

Operating Temperature Range: -40 to +80°C Only for reflow soldering.

■ Impedance-Frequency Characteristics (Typ.)



■ Inductance-Current Characteristics (Typ.)



Power Inductor Wire Wound Type for Choke

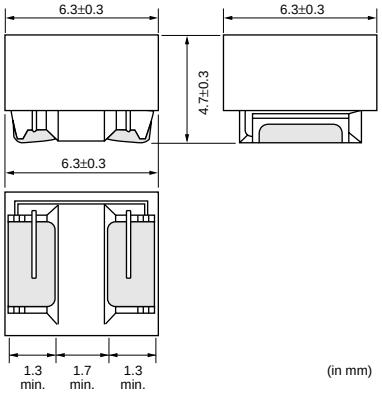
LQH66S Series (2525 Size)

LQH66S series is magnetic shielded type inductors for choke by using high performance thick wire wound technology.

■ Features

1. Low direct current resistance, large current capacity and large inductance
2. High density mounting
3. For DC-DC converters and DC power supply circuits

■ Dimension



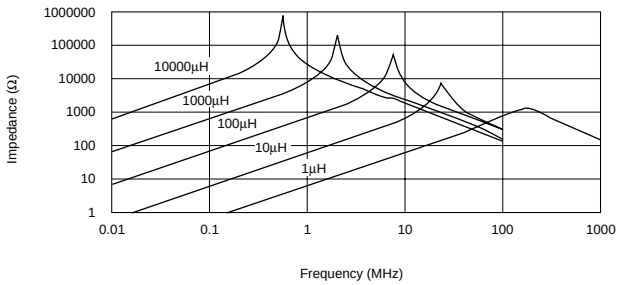
(in mm)

■ Rated Value (☐: packaging code)

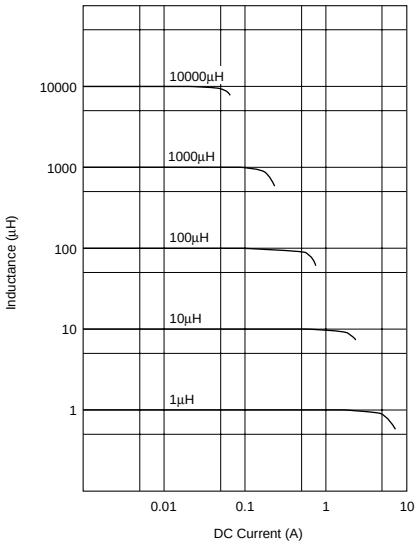
Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH66SNR27M03☐	0.27µH±20%	1MHz	6000mA	0.0098ohm 0.007ohm±40%	300MHz	Magnetic shield of ferrite
LQH66SNR68M03☐	0.68µH±20%	1MHz	5300mA	0.014ohm 0.010ohm±40%	180MHz	Magnetic shield of ferrite
LQH66SN1R0M03☐	1.0µH±20%	1MHz	4700mA	0.0182ohm 0.013ohm±40%	150MHz	Magnetic shield of ferrite
LQH66SN1R5M03☐	1.5µH±20%	1MHz	3800mA	0.0224ohm 0.016ohm±40%	110MHz	Magnetic shield of ferrite
LQH66SN2R2M03☐	2.2µH±20%	1MHz	3300mA	0.0266ohm 0.019ohm±40%	80MHz	Magnetic shield of ferrite
LQH66SN3R3M03☐	3.3µH±20%	1MHz	2600mA	0.0308ohm 0.022ohm±40%	40MHz	Magnetic shield of ferrite
LQH66SN4R7M03☐	4.7µH±20%	1MHz	2200mA	0.035ohm 0.025ohm±40%	30MHz	Magnetic shield of ferrite
LQH66SN6R8M03☐	6.8µH±20%	1MHz	1800mA	0.0406ohm 0.029ohm±40%	25MHz	Magnetic shield of ferrite
LQH66SN100M03☐	10µH±20%	1MHz	1600mA	0.0504ohm 0.036ohm±40%	20MHz	Magnetic shield of ferrite
LQH66SN150M03☐	15µH±20%	1MHz	1300mA	0.0966ohm 0.069ohm±40%	17MHz	Magnetic shield of ferrite
LQH66SN220M03☐	22µH±20%	1MHz	1100mA	0.1218ohm 0.087ohm±40%	15MHz	Magnetic shield of ferrite
LQH66SN330M03☐	33µH±20%	1MHz	860mA	0.196ohm 0.14ohm±40%	12MHz	Magnetic shield of ferrite
LQH66SN470M03☐	47µH±20%	1MHz	760mA	0.238ohm 0.17ohm±40%	10MHz	Magnetic shield of ferrite
LQH66SN680M03☐	68µH±20%	1MHz	600mA	0.406ohm 0.29ohm±40%	7.6MHz	Magnetic shield of ferrite
LQH66SN101M03☐	100µH±20%	100kHz	520mA	0.504ohm 0.36ohm±40%	6.5MHz	Magnetic shield of ferrite
LQH66SN151M03☐	150µH±20%	100kHz	420mA	0.882ohm 0.63ohm±40%	5.0MHz	Magnetic shield of ferrite
LQH66SN221M03☐	220µH±20%	100kHz	350mA	1.106ohm 0.79ohm±40%	4.0MHz	Magnetic shield of ferrite
LQH66SN331M03☐	330µH±20%	100kHz	280mA	2.52ohm 1.8ohm±40%	3.2MHz	Magnetic shield of ferrite
LQH66SN471M03☐	470µH±20%	100kHz	240mA	3.08ohm 2.2ohm±40%	2.5MHz	Magnetic shield of ferrite
LQH66SN681M03☐	680µH±20%	100kHz	200mA	5.46ohm 3.9ohm±40%	2.0MHz	Magnetic shield of ferrite
LQH66SN102M03☐	1000µH±20%	10kHz	160mA	6.86ohm 4.9ohm±40%	1.7MHz	Magnetic shield of ferrite
LQH66SN222M03☐	2200µH±20%	10kHz	100mA	13.16ohm 9.4ohm±40%	1.2MHz	Magnetic shield of ferrite
LQH66SN472M03☐	4700µH±20%	10kHz	70mA	27.3ohm 19.5ohm±40%	0.8MHz	Magnetic shield of ferrite
LQH66SN103M03☐	10000µH±20%	10kHz	50mA	55.58ohm 39.7ohm±40%	0.5MHz	Magnetic shield of ferrite

Operating Temperature Range: -40 to +85°C Only for reflow soldering.

■ Impedance-Frequency Characteristics (Typ.)



■ Inductance-Current Characteristics (Typ.)



Inductor for General Use Multilayer Type

muRata

LQM18N Series (0603 Size)

2

LQM18N series consisting of magnetically shielded chip inductors was developed by using original multilayer process technology and magnetic materials.
Compact size is suitable for high density mounting.
Shielded construction is not affected by interference from peripheral components.

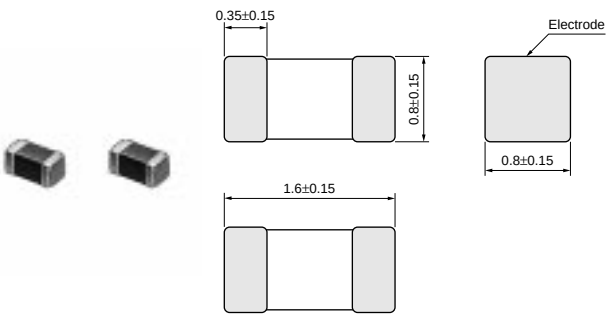
■ Features

1. Magnetically shielded structure provides excellent characteristics in crosstalk and magnetic coupling.
2. Compact size (1.6x0.8mm) and lightweight
3. The external electrodes with nickel barrier structure provide excellent solder heat resistance. Applicable soldering methods are both flow soldering and reflow soldering.

■ Applications

1. Resonance circuit, traps, filter circuits
2. RF choke in telecommunications equipment, cordless phones, radio equipment

■ Dimension



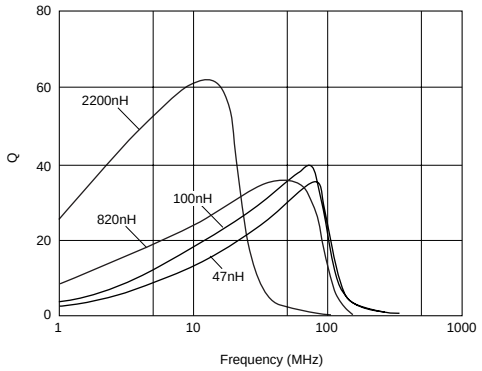
(in mm)

■ Rated Value (☐: packaging code)

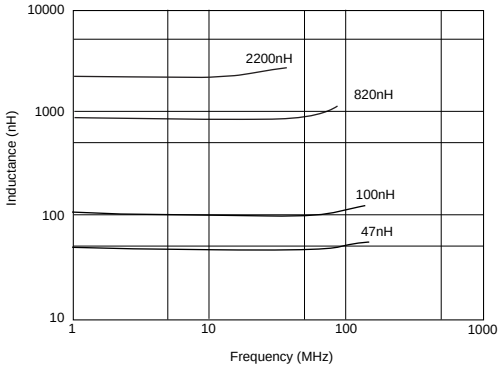
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQM18NN47NM00☐	47nH±20%	50MHz	50mA	0.30ohm	10	50MHz	260MHz	Magnetic shield of ferrite
LQM18NN68NM00☐	68nH±20%	50MHz	50mA	0.30ohm	10	50MHz	250MHz	Magnetic shield of ferrite
LQM18NN82NM00☐	82nH±20%	50MHz	50mA	0.30ohm	10	50MHz	245MHz	Magnetic shield of ferrite
LQM18NNR10K00☐	100nH±10%	25MHz	50mA	0.50ohm	15	25MHz	240MHz	Magnetic shield of ferrite
LQM18NNR12K00☐	120nH±10%	25MHz	50mA	0.50ohm	15	25MHz	205MHz	Magnetic shield of ferrite
LQM18NNR15K00☐	150nH±10%	25MHz	50mA	0.60ohm	15	25MHz	180MHz	Magnetic shield of ferrite
LQM18NNR18K00☐	180nH±10%	25MHz	50mA	0.60ohm	15	25MHz	165MHz	Magnetic shield of ferrite
LQM18NNR22K00☐	220nH±10%	25MHz	50mA	0.80ohm	15	25MHz	150MHz	Magnetic shield of ferrite
LQM18NNR27K00☐	270nH±10%	25MHz	50mA	0.80ohm	15	25MHz	136MHz	Magnetic shield of ferrite
LQM18NNR33K00☐	330nH±10%	25MHz	35mA	0.85ohm	15	25MHz	125MHz	Magnetic shield of ferrite
LQM18NNR39K00☐	390nH±10%	25MHz	35mA	1.00ohm	15	25MHz	110MHz	Magnetic shield of ferrite
LQM18NNR47K00☐	470nH±10%	25MHz	35mA	1.35ohm	15	25MHz	105MHz	Magnetic shield of ferrite
LQM18NNR56K00☐	560nH±10%	25MHz	35mA	1.55ohm	15	25MHz	95MHz	Magnetic shield of ferrite
LQM18NNR68K00☐	680nH±10%	25MHz	35mA	1.70ohm	15	25MHz	90MHz	Magnetic shield of ferrite
LQM18NNR82K00☐	820nH±10%	25MHz	35mA	2.10ohm	15	25MHz	85MHz	Magnetic shield of ferrite
LQM18NN1R0K00☐	1000nH±10%	10MHz	25mA	0.60ohm	35	10MHz	75MHz	Magnetic shield of ferrite
LQM18NN1R2K00☐	1200nH±10%	10MHz	25mA	0.80ohm	35	10MHz	65MHz	Magnetic shield of ferrite
LQM18NN1R5K00☐	1500nH±10%	10MHz	25mA	0.80ohm	35	10MHz	60MHz	Magnetic shield of ferrite
LQM18NN1R8K00☐	1800nH±10%	10MHz	25mA	0.95ohm	35	10MHz	55MHz	Magnetic shield of ferrite
LQM18NN2R2K00☐	2200nH±10%	10MHz	15mA	1.15ohm	35	10MHz	50MHz	Magnetic shield of ferrite

Operating Temperature Range: -40°C to +85°C

■ Q - Frequency Characteristics (Typ.)



■ Inductance - Frequency Characteristics (Typ.)



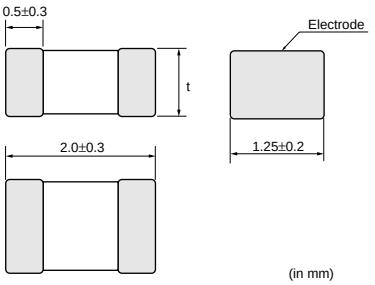
Inductor for General Use Multilayer Type

LQM21N Series (0805 Size)

■ Features

LQM21N series consists of magnetically shielded chip inductors developed using Murata's original multilayer process technology and magnetic materials. The miniature size of 2.0x1.25mm enables compact design of electric equipment. Inductance range from 0.1 micro H to 4.7 micro H is available.

■ Dimension



(in mm)

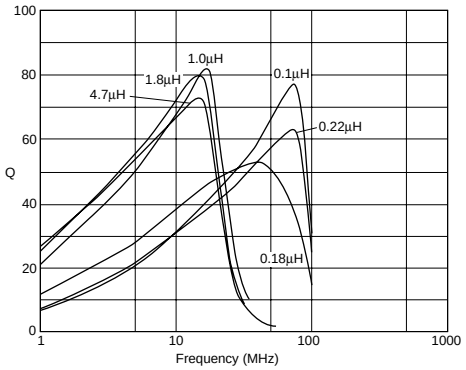
Dimension of t	Inductance: 0.1 to 2.2µH	0.85±0.2
	Inductance: 2.7 to 4.7µH	1.25±0.2

■ Rated Value (☐: packaging code)

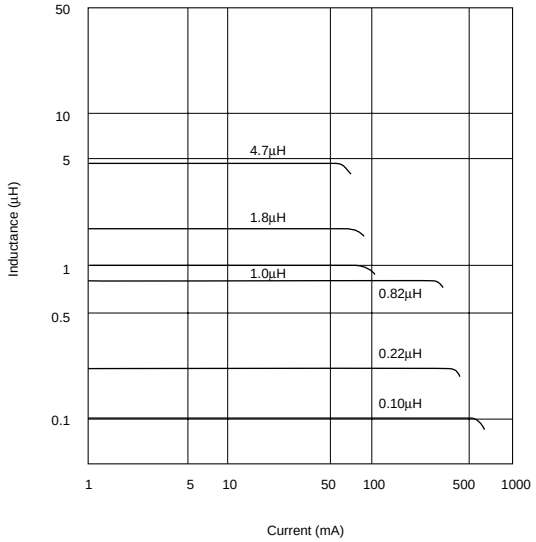
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQM21NNR10K10☐	0.1µH±10%	25MHz	250mA	0.26ohm	20	25MHz	340MHz	Magnetic shield of ferrite
LQM21NNR12K10☐	0.12µH±10%	25MHz	250mA	0.29ohm	20	25MHz	310MHz	Magnetic shield of ferrite
LQM21NNR15K10☐	0.15µH±10%	25MHz	250mA	0.32ohm	20	25MHz	270MHz	Magnetic shield of ferrite
LQM21NNR18K10☐	0.18µH±10%	25MHz	250mA	0.35ohm	20	25MHz	250MHz	Magnetic shield of ferrite
LQM21NNR22K10☐	0.22µH±10%	25MHz	250mA	0.38ohm	20	25MHz	220MHz	Magnetic shield of ferrite
LQM21NNR27K10☐	0.27µH±10%	25MHz	250mA	0.42ohm	20	25MHz	200MHz	Magnetic shield of ferrite
LQM21NNR33K10☐	0.33µH±10%	25MHz	250mA	0.48ohm	20	25MHz	180MHz	Magnetic shield of ferrite
LQM21NNR39K10☐	0.39µH±10%	25MHz	200mA	0.53ohm	25	25MHz	165MHz	Magnetic shield of ferrite
LQM21NNR47K10☐	0.47µH±10%	25MHz	200mA	0.57ohm	25	25MHz	150MHz	Magnetic shield of ferrite
LQM21NNR56K10☐	0.56µH±10%	25MHz	150mA	0.63ohm	25	25MHz	140MHz	Magnetic shield of ferrite
LQM21NNR68K10☐	0.68µH±10%	25MHz	150mA	0.72ohm	25	25MHz	125MHz	Magnetic shield of ferrite
LQM21NNR82K10☐	0.82µH±10%	25MHz	150mA	0.81ohm	25	25MHz	115MHz	Magnetic shield of ferrite
LQM21NN1R0K10☐	1µH±10%	10MHz	50mA	0.40ohm	45	10MHz	107MHz	Magnetic shield of ferrite
LQM21NN1R2K10☐	1.2µH±10%	10MHz	50mA	0.47ohm	45	10MHz	97MHz	Magnetic shield of ferrite
LQM21NN1R5K10☐	1.5µH±10%	10MHz	50mA	0.50ohm	45	10MHz	87MHz	Magnetic shield of ferrite
LQM21NN1R8K10☐	1.8µH±10%	10MHz	50mA	0.57ohm	45	10MHz	80MHz	Magnetic shield of ferrite
LQM21NN2R2K10☐	2.2µH±10%	10MHz	30mA	0.63ohm	45	10MHz	71MHz	Magnetic shield of ferrite
LQM21NN2R7K10☐	2.7µH±10%	10MHz	30mA	0.69ohm	45	10MHz	66MHz	Magnetic shield of ferrite
LQM21NN3R3K10☐	3.3µH±10%	10MHz	30mA	0.80ohm	45	10MHz	59MHz	Magnetic shield of ferrite
LQM21NN3R9K10☐	3.9µH±10%	10MHz	30mA	0.89ohm	45	10MHz	53MHz	Magnetic shield of ferrite
LQM21NN4R7K10☐	4.7µH±10%	10MHz	30mA	1.00ohm	45	10MHz	47MHz	Magnetic shield of ferrite

Operating Temperature Range: -40°C to +85°C

■ Q - Frequency Characteristics (Typ.)



■ Inductance - Current Characteristics (Typ.)



Inductor for General Use Wire Wound Type

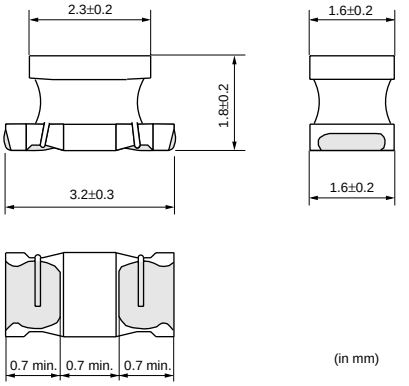
LQH31M Series (1206 Size)

LQH31M series consists of wire wound type chip inductors using Murata's original ferrite core and automatic wire wound technology.

■ Features

1. Wide inductance range from 0.15 to 100 micro H
2. High Q value at high frequencies and low DC resistance
3. Small size (3.2x1.6x1.8mm) and tight pitch mounting
4. Low DC resistance and large current
5. Both flow and reflow soldering heat resistance

■ Dimension



(in mm)

■ Rated Value (☐: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH31MNR15K03☐	0.15µH±10%	1MHz	250mA	0.39ohm±40%	20	25MHz	250MHz	No magnetic shield
LQH31MNR22K03☐	0.22µH±10%	1MHz	240mA	0.43ohm±40%	20	25MHz	250MHz	No magnetic shield
LQH31MNR33K03☐	0.33µH±10%	1MHz	230mA	0.45ohm±40%	30	25MHz	250MHz	No magnetic shield
LQH31MNR47K03☐	0.47µH±10%	1MHz	215mA	0.83ohm±40%	30	25MHz	200MHz	No magnetic shield
LQH31MNR56K03☐	0.56µH±10%	1MHz	200mA	0.61ohm±40%	30	25MHz	180MHz	No magnetic shield
LQH31MNR68K03☐	0.68µH±10%	1MHz	190mA	0.67ohm±40%	30	25MHz	160MHz	No magnetic shield
LQH31MNR82K03☐	0.82µH±10%	1MHz	185mA	0.73ohm±40%	30	25MHz	120MHz	No magnetic shield
LQH31MN1R0K03☐	1.0µH±10%	1MHz	175mA	0.49ohm±30%	35	10MHz	100MHz	No magnetic shield
LQH31MN1R2J03☐	1.2µH±5%	1MHz	165mA	0.37ohm±30%	35	10MHz	90MHz	No magnetic shield
LQH31MN1R2K03☐	1.2µH±10%	1MHz	165mA	0.9ohm±30%	35	10MHz	90MHz	No magnetic shield
LQH31MN1R5J03☐	1.5µH±5%	1MHz	155mA	1.0ohm±30%	35	10MHz	75MHz	No magnetic shield
LQH31MN1R5K03☐	1.5µH±10%	1MHz	155mA	1.0ohm±30%	35	10MHz	75MHz	No magnetic shield
LQH31MN1R8J03☐	1.8µH±5%	1MHz	150mA	1.6ohm±30%	35	10MHz	60MHz	No magnetic shield
LQH31MN1R8K03☐	1.8µH±10%	1MHz	150mA	1.6ohm±30%	35	10MHz	60MHz	No magnetic shield
LQH31MN2R2J03☐	2.2µH±5%	1MHz	140mA	0.7ohm±30%	35	10MHz	50MHz	No magnetic shield
LQH31MN2R2K03☐	2.2µH±10%	1MHz	140mA	0.7ohm±30%	35	10MHz	50MHz	No magnetic shield
LQH31MN2R7J03☐	2.7µH±5%	1MHz	135mA	0.55ohm±30%	35	10MHz	43MHz	No magnetic shield
LQH31MN2R7K03☐	2.7µH±10%	1MHz	135mA	0.55ohm±30%	35	10MHz	43MHz	No magnetic shield
LQH31MN3R3J03☐	3.3µH±5%	1MHz	130mA	0.61ohm±30%	35	8MHz	38MHz	No magnetic shield
LQH31MN3R3K03☐	3.3µH±10%	1MHz	130mA	0.61ohm±30%	35	8MHz	38MHz	No magnetic shield
LQH31MN3R9J03☐	3.9µH±5%	1MHz	125mA	1.5ohm±30%	35	8MHz	35MHz	No magnetic shield
LQH31MN3R9K03☐	3.9µH±10%	1MHz	125mA	1.5ohm±30%	35	8MHz	35MHz	No magnetic shield
LQH31MN4R7J03☐	4.7µH±5%	1MHz	120mA	1.7ohm±30%	35	8MHz	31MHz	No magnetic shield
LQH31MN4R7K03☐	4.7µH±10%	1MHz	120mA	1.7ohm±30%	35	8MHz	31MHz	No magnetic shield
LQH31MN5R6J03☐	5.6µH±5%	1MHz	115mA	1.8ohm±30%	35	8MHz	28MHz	No magnetic shield
LQH31MN5R6K03☐	5.6µH±10%	1MHz	115mA	1.8ohm±30%	35	8MHz	28MHz	No magnetic shield
LQH31MN6R8J03☐	6.8µH±5%	1MHz	110mA	2.0ohm±30%	35	8MHz	25MHz	No magnetic shield
LQH31MN6R8K03☐	6.8µH±10%	1MHz	110mA	2.0ohm±30%	35	8MHz	25MHz	No magnetic shield
LQH31MN8R2J03☐	8.2µH±5%	1MHz	105mA	2.2ohm±30%	35	8MHz	23MHz	No magnetic shield
LQH31MN8R2K03☐	8.2µH±10%	1MHz	105mA	2.2ohm±30%	35	8MHz	23MHz	No magnetic shield
LQH31MN100J03☐	10µH±5%	1MHz	100mA	2.5ohm±30%	35	5MHz	20MHz	No magnetic shield

Operating Temperature Range: -40°C to +85°C

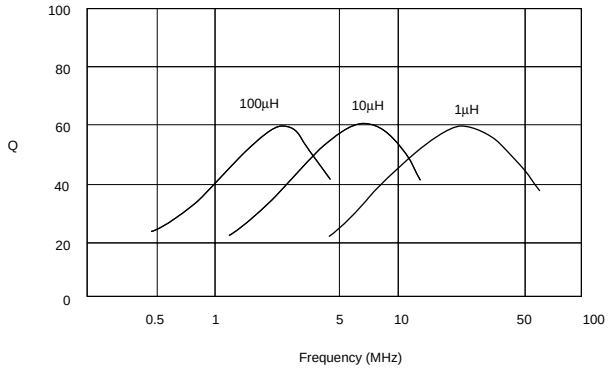
Continued on the following page.

Continued from the preceding page.

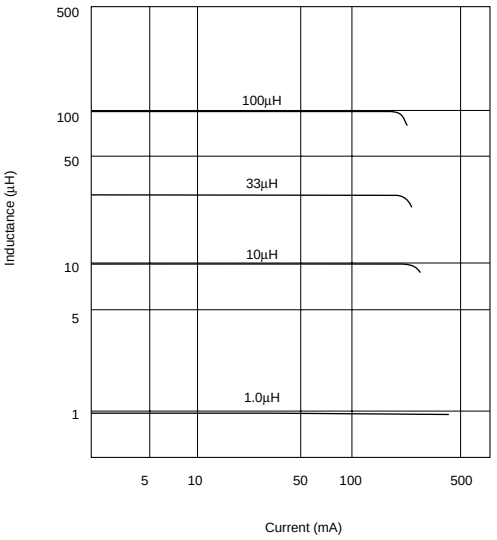
Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH31MN100K03□	10µH±10%	1MHz	100mA	2.5ohm±30%	35	5MHz	20MHz	No magnetic shield
LQH31MN120J03□	12µH±5%	1MHz	95mA	2.7ohm±30%	35	5MHz	18MHz	No magnetic shield
LQH31MN120K03□	12µH±10%	1MHz	95mA	2.7ohm±30%	35	5MHz	18MHz	No magnetic shield
LQH31MN150J03□	15µH±5%	1MHz	90mA	3.0ohm±30%	35	5MHz	16MHz	No magnetic shield
LQH31MN150K03□	15µH±10%	1MHz	90mA	3.0ohm±30%	35	5MHz	16MHz	No magnetic shield
LQH31MN180J03□	18µH±5%	1MHz	85mA	3.4ohm±30%	35	5MHz	15MHz	No magnetic shield
LQH31MN180K03□	18µH±10%	1MHz	85mA	3.4ohm±30%	35	5MHz	15MHz	No magnetic shield
LQH31MN220J03□	22µH±5%	1MHz	85mA	3.1ohm±30%	40	2.5MHz	14MHz	No magnetic shield
LQH31MN220K03□	22µH±10%	1MHz	85mA	3.1ohm±30%	40	2.5MHz	14MHz	No magnetic shield
LQH31MN270J03□	27µH±5%	1MHz	85mA	3.4ohm±30%	40	2.5MHz	13MHz	No magnetic shield
LQH31MN270K03□	27µH±10%	1MHz	85mA	3.4ohm±30%	40	2.5MHz	13MHz	No magnetic shield
LQH31MN330J03□	33µH±5%	1MHz	80mA	3.8ohm±30%	40	2.5MHz	12MHz	No magnetic shield
LQH31MN330K03□	33µH±10%	1MHz	80mA	3.8ohm±30%	40	2.5MHz	12MHz	No magnetic shield
LQH31MN390J03□	39µH±5%	1MHz	55mA	7.2ohm±30%	40	2.5MHz	11MHz	No magnetic shield
LQH31MN390K03□	39µH±10%	1MHz	55mA	7.2ohm±30%	40	2.5MHz	11MHz	No magnetic shield
LQH31MN470J03□	47µH±5%	1MHz	55mA	8.0ohm±30%	40	2.5MHz	10MHz	No magnetic shield
LQH31MN470K03□	47µH±10%	1MHz	55mA	8.0ohm±30%	40	2.5MHz	10MHz	No magnetic shield
LQH31MN560J03□	56µH±5%	1MHz	50mA	8.9ohm±30%	40	2.5MHz	9MHz	No magnetic shield
LQH31MN560K03□	56µH±10%	1MHz	50mA	8.9ohm±30%	40	2.5MHz	9MHz	No magnetic shield
LQH31MN680J03□	68µH±5%	1MHz	50mA	9.9ohm±30%	40	2.5MHz	8.5MHz	No magnetic shield
LQH31MN680K03□	68µH±10%	1MHz	50mA	9.9ohm±30%	40	2.5MHz	8.5MHz	No magnetic shield
LQH31MN820J03□	82µH±5%	1MHz	45mA	11ohm±30%	40	2.5MHz	7.5MHz	No magnetic shield
LQH31MN820K03□	82µH±10%	1MHz	45mA	11ohm±30%	40	2.5MHz	7.5MHz	No magnetic shield
LQH31MN101J03□	100µH±5%	1MHz	45mA	12ohm±30%	40	2.5MHz	7MHz	No magnetic shield
LQH31MN101K03□	100µH±10%	1MHz	45mA	12ohm±30%	40	2.5MHz	7MHz	No magnetic shield

Operating Temperature Range: -40°C to +85°C

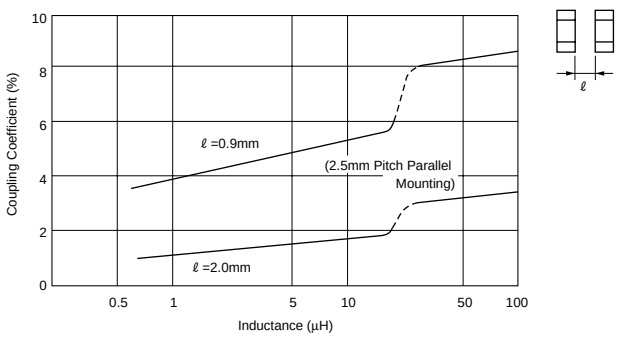
■ Q - Frequency Characteristics (Typ.)



■ Inductance - Current Characteristics (Typ.)



■ Coupling Coefficient



Inductor for General Use Wire Wound Type

muRata

LQH32M Series (1210 Size)

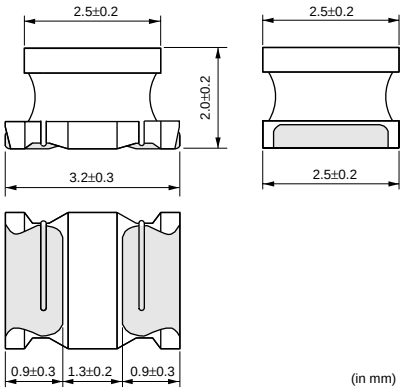
2

LQH32M series consists of miniature chip inductors wire wound on a special ferrite core.

■ Features

1. High Q value at high frequencies and low DC resistance
2. Wide inductance range from 1.0 to 560 micro H

■ Dimension



(in mm)

■ Rated Value (☐: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH32MN1R0M23☐	1.0μH±20%	1MHz	445mA	0.5ohm	20	1MHz	100MHz	No magnetic shield
LQH32MN1R2M23☐	1.2μH±20%	1MHz	425mA	0.6ohm	20	1MHz	100MHz	No magnetic shield
LQH32MN1R5K23☐	1.5μH±10%	1MHz	400mA	0.6ohm	20	1MHz	75MHz	No magnetic shield
LQH32MN1R8K23☐	1.8μH±10%	1MHz	390mA	0.7ohm	20	1MHz	60MHz	No magnetic shield
LQH32MN2R2K23☐	2.2μH±10%	1MHz	370mA	0.8ohm	20	1MHz	50MHz	No magnetic shield
LQH32MN2R7K23☐	2.7μH±10%	1MHz	320mA	0.9ohm	20	1MHz	43MHz	No magnetic shield
LQH32MN3R3K23☐	3.3μH±10%	1MHz	300mA	1.0ohm	20	1MHz	38MHz	No magnetic shield
LQH32MN3R9K23☐	3.9μH±10%	1MHz	290mA	1.1ohm	20	1MHz	35MHz	No magnetic shield
LQH32MN4R7K23☐	4.7μH±10%	1MHz	270mA	1.2ohm	20	1MHz	31MHz	No magnetic shield
LQH32MN5R6K23☐	5.6μH±10%	1MHz	250mA	1.3ohm	20	1MHz	28MHz	No magnetic shield
LQH32MN6R8K23☐	6.8μH±10%	1MHz	240mA	1.5ohm	20	1MHz	25MHz	No magnetic shield
LQH32MN8R2K23☐	8.2μH±10%	1MHz	225mA	1.6ohm	20	1MHz	23MHz	No magnetic shield
LQH32MN100J23☐	10μH±5%	1MHz	190mA	1.8ohm	35	1MHz	20MHz	No magnetic shield
LQH32MN100K23☐	10μH±10%	1MHz	190mA	1.8ohm	35	1MHz	20MHz	No magnetic shield
LQH32MN120J23☐	12μH±5%	1MHz	180mA	2.0ohm	35	1MHz	18MHz	No magnetic shield
LQH32MN120K23☐	12μH±10%	1MHz	180mA	2.0ohm	35	1MHz	18MHz	No magnetic shield
LQH32MN150J23☐	15μH±5%	1MHz	170mA	2.2ohm	35	1MHz	16MHz	No magnetic shield
LQH32MN150K23☐	15μH±10%	1MHz	170mA	2.2ohm	35	1MHz	16MHz	No magnetic shield
LQH32MN180J23☐	18μH±5%	1MHz	165mA	2.5ohm	35	1MHz	15MHz	No magnetic shield
LQH32MN180K23☐	18μH±10%	1MHz	165mA	2.5ohm	35	1MHz	15MHz	No magnetic shield
LQH32MN220J23☐	22μH±5%	1MHz	150mA	2.8ohm	35	1MHz	14MHz	No magnetic shield
LQH32MN220K23☐	22μH±10%	1MHz	150mA	2.8ohm	35	1MHz	14MHz	No magnetic shield
LQH32MN270J23☐	27μH±5%	1MHz	125mA	3.1ohm	35	1MHz	13MHz	No magnetic shield
LQH32MN270K23☐	27μH±10%	1MHz	125mA	3.1ohm	35	1MHz	13MHz	No magnetic shield
LQH32MN330J23☐	33μH±5%	1MHz	115mA	3.5ohm	40	1MHz	12MHz	No magnetic shield
LQH32MN330K23☐	33μH±10%	1MHz	115mA	3.5ohm	40	1MHz	12MHz	No magnetic shield
LQH32MN390J23☐	39μH±5%	1MHz	110mA	3.9ohm	40	1MHz	11MHz	No magnetic shield
LQH32MN390K23☐	39μH±10%	1MHz	110mA	3.9ohm	40	1MHz	11MHz	No magnetic shield
LQH32MN470J23☐	47μH±5%	1MHz	100mA	4.3ohm	40	1MHz	11MHz	No magnetic shield
LQH32MN470K23☐	47μH±10%	1MHz	100mA	4.3ohm	40	1MHz	11MHz	No magnetic shield
LQH32MN560J23☐	56μH±5%	1MHz	85mA	4.9ohm	40	1MHz	10MHz	No magnetic shield

Operating Temperature Range: -40°C to +85°C

Continued on the following page.

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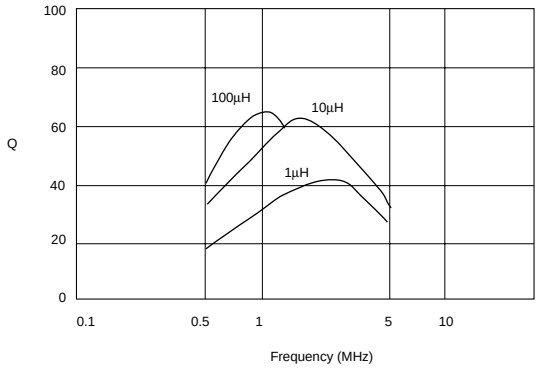
Continued from the preceding page.

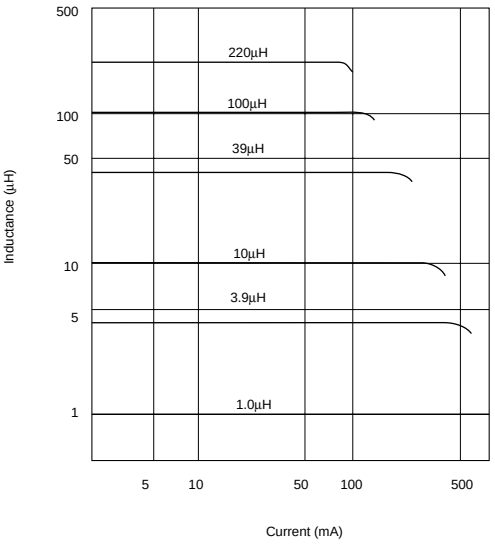
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH32MN560K23□	56μH±10%	1MHz	85mA	4.9ohm	40	1MHz	10MHz	No magnetic shield
LQH32MN680J23□	68μH±5%	1MHz	80mA	5.5ohm	40	1MHz	9MHz	No magnetic shield
LQH32MN680K23□	68μH±10%	1MHz	80mA	5.5ohm	40	1MHz	9MHz	No magnetic shield
LQH32MN820J23□	82μH±5%	1MHz	70mA	6.2ohm	40	1MHz	8.5MHz	No magnetic shield
LQH32MN820K23□	82μH±10%	1MHz	70mA	6.2ohm	40	1MHz	8.5MHz	No magnetic shield
LQH32MN101J23□	100μH±5%	1MHz	80mA	7.0ohm	40	796kHz	8MHz	No magnetic shield
LQH32MN101K23□	100μH±10%	1MHz	80mA	7.0ohm	40	796kHz	8MHz	No magnetic shield
LQH32MN121J23□	120μH±5%	1MHz	75mA	8.0ohm	40	796kHz	7.5MHz	No magnetic shield
LQH32MN121K23□	120μH±10%	1MHz	75mA	8.0ohm	40	796kHz	7.5MHz	No magnetic shield
LQH32MN151J23□	150μH±5%	1MHz	70mA	9.3ohm	40	796kHz	7MHz	No magnetic shield
LQH32MN151K23□	150μH±10%	1MHz	70mA	9.3ohm	40	796kHz	7MHz	No magnetic shield
LQH32MN181J23□	180μH±5%	1MHz	65mA	10.2ohm	40	796kHz	6MHz	No magnetic shield
LQH32MN181K23□	180μH±10%	1MHz	65mA	10.2ohm	40	796kHz	6MHz	No magnetic shield
LQH32MN221J23□	220μH±5%	1MHz	65mA	11.8ohm	40	796kHz	5.5MHz	No magnetic shield
LQH32MN221K23□	220μH±10%	1MHz	65mA	11.8ohm	40	796kHz	5.5MHz	No magnetic shield
LQH32MN271J23□	270μH±5%	1MHz	65mA	12.5ohm	40	796kHz	5MHz	No magnetic shield
LQH32MN271K23□	270μH±10%	1MHz	65mA	12.5ohm	40	796kHz	5MHz	No magnetic shield
LQH32MN331J23□	330μH±5%	1MHz	65mA	13.0ohm	40	796kHz	5MHz	No magnetic shield
LQH32MN331K23□	330μH±10%	1MHz	65mA	13.0ohm	40	796kHz	5MHz	No magnetic shield
LQH32MN391J23□	390μH±5%	1MHz	50mA	22.0ohm	50	796kHz	5MHz	No magnetic shield
LQH32MN391K23□	390μH±10%	1MHz	50mA	22.0ohm	50	796kHz	5MHz	No magnetic shield
LQH32MN471J23□	470μH±5%	1kHz	45mA	25.0ohm	50	796kHz	5MHz	No magnetic shield
LQH32MN471K23□	470μH±10%	1kHz	45mA	25.0ohm	50	796kHz	5MHz	No magnetic shield
LQH32MN561J23□	560μH±5%	1kHz	40mA	28.0ohm	50	796kHz	5MHz	No magnetic shield
LQH32MN561K23□	560μH±10%	1kHz	40mA	28.0ohm	50	796kHz	5MHz	No magnetic shield

Operating Temperature Range: -40°C to +85°C

■ Q - Frequency Characteristics (Typ.)



■ Inductance - Current Characteristics (Typ.)



Inductor for General Use Wire Wound Type

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LQH43M/LQH43N Series (1812 Size)

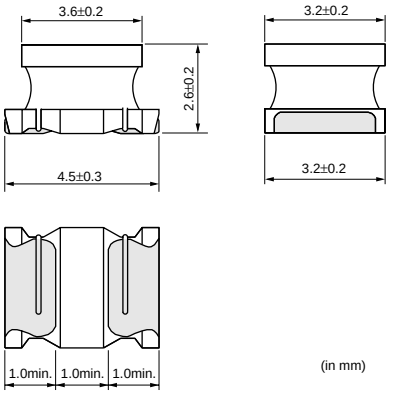
2

LQH43M/N series consists of wire wound type chip inductors for general use by Murata's original automatic wire wound technology and ferrite core.

■ Features

1. High Q value at high frequency and low DC resistance
2. Wide inductance range from 1.0 to 2200 micro H
3. Large current and large inductance

■ Dimension



(in mm)

■ Rated Value (☐: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH43MN1R0M03☐	1.0µH±20%	1MHz	500mA	0.20ohm	20	1MHz	120MHz	No magnetic shield
LQH43MN1R2M03☐	1.2µH±20%	1MHz	500mA	0.20ohm	20	1MHz	100MHz	No magnetic shield
LQH43MN1R5M03☐	1.5µH±20%	1MHz	500mA	0.30ohm	20	1MHz	85MHz	No magnetic shield
LQH43MN1R8M03☐	1.8µH±20%	1MHz	500mA	0.30ohm	20	1MHz	75MHz	No magnetic shield
LQH43MN2R2M03☐	2.2µH±20%	1MHz	500mA	0.30ohm	20	1MHz	62MHz	No magnetic shield
LQH43MN2R7M03☐	2.7µH±20%	1MHz	500mA	0.32ohm	20	1MHz	53MHz	No magnetic shield
LQH43MN3R3M03☐	3.3µH±20%	1MHz	500mA	0.35ohm	20	1MHz	47MHz	No magnetic shield
LQH43MN3R9M03☐	3.9µH±20%	1MHz	500mA	0.38ohm	20	1MHz	41MHz	No magnetic shield
LQH43MN4R7K03☐	4.7µH±10%	1MHz	500mA	0.40ohm	30	1MHz	38MHz	No magnetic shield
LQH43MN5R6K03☐	5.6µH±10%	1MHz	500mA	0.47ohm	30	1MHz	33MHz	No magnetic shield
LQH43MN6R8K03☐	6.8µH±10%	1MHz	450mA	0.50ohm	30	1MHz	31MHz	No magnetic shield
LQH43MN8R2K03☐	8.2µH±10%	1MHz	450mA	0.56ohm	30	1MHz	27MHz	No magnetic shield
LQH43MN100J03☐	10µH±5%	1MHz	400mA	0.56ohm	35	1MHz	23MHz	No magnetic shield
LQH43MN100K03☐	10µH±10%	1MHz	400mA	0.56ohm	35	1MHz	23MHz	No magnetic shield
LQH43MN120J03☐	12µH±5%	1MHz	380mA	0.62ohm	35	1MHz	21MHz	No magnetic shield
LQH43MN120K03☐	12µH±10%	1MHz	380mA	0.62ohm	35	1MHz	21MHz	No magnetic shield
LQH43MN150J03☐	15µH±5%	1MHz	360mA	0.73ohm	35	1MHz	19MHz	No magnetic shield
LQH43MN150K03☐	15µH±10%	1MHz	360mA	0.73ohm	35	1MHz	19MHz	No magnetic shield
LQH43MN180J03☐	18µH±5%	1MHz	340mA	0.82ohm	35	1MHz	17MHz	No magnetic shield
LQH43MN180K03☐	18µH±10%	1MHz	340mA	0.82ohm	35	1MHz	17MHz	No magnetic shield
LQH43MN220J03☐	22µH±5%	1MHz	320mA	0.94ohm	35	1MHz	15MHz	No magnetic shield
LQH43MN220K03☐	22µH±10%	1MHz	320mA	0.94ohm	35	1MHz	15MHz	No magnetic shield
LQH43MN270J03☐	27µH±5%	1MHz	300mA	1.1ohm	35	1MHz	14MHz	No magnetic shield
LQH43MN270K03☐	27µH±10%	1MHz	300mA	1.1ohm	35	1MHz	14MHz	No magnetic shield
LQH43MN330J03☐	33µH±5%	1MHz	270mA	1.2ohm	35	1MHz	12MHz	No magnetic shield
LQH43MN330K03☐	33µH±10%	1MHz	270mA	1.2ohm	35	1MHz	12MHz	No magnetic shield
LQH43MN390J03☐	39µH±5%	1MHz	240mA	1.4ohm	35	1MHz	11MHz	No magnetic shield
LQH43MN390K03☐	39µH±10%	1MHz	240mA	1.4ohm	35	1MHz	11MHz	No magnetic shield
LQH43MN470J03☐	47µH±5%	1MHz	220mA	1.5ohm	35	1MHz	10MHz	No magnetic shield
LQH43MN470K03☐	47µH±10%	1MHz	220mA	1.5ohm	35	1MHz	10MHz	No magnetic shield
LQH43MN560J03☐	56µH±5%	1MHz	200mA	1.7ohm	35	1MHz	9.3MHz	No magnetic shield

Operating Temperature Range: -40°C to +85°C

Continued on the following page.

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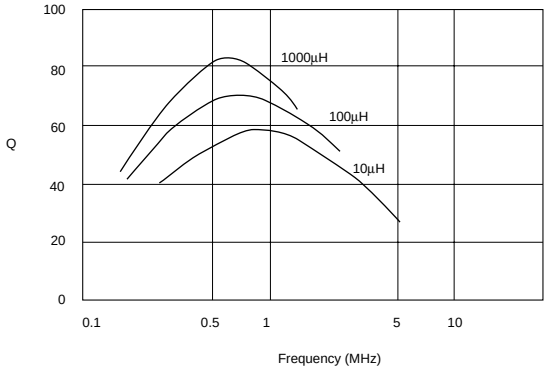
Continued from the preceding page.

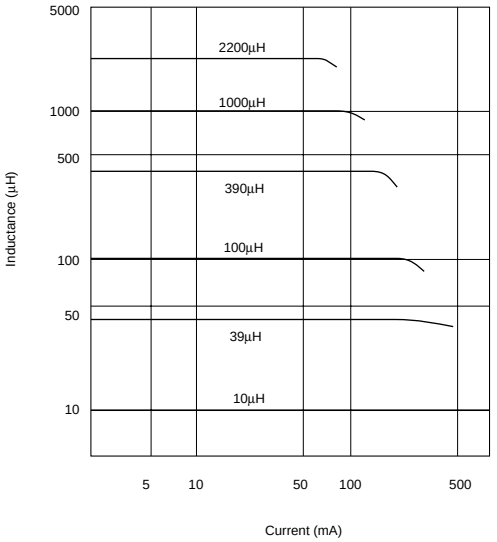
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)	Class of Magnetic Shield
LQH43MN560K03□	56μH±10%	1MHz	200mA	1.7ohm	35	1MHz	9.3MHz	No magnetic shield
LQH43MN680J03□	68μH±5%	1MHz	180mA	1.9ohm	35	1MHz	8.4MHz	No magnetic shield
LQH43MN680K03□	68μH±10%	1MHz	180mA	1.9ohm	35	1MHz	8.4MHz	No magnetic shield
LQH43MN820J03□	82μH±5%	1MHz	170mA	2.2ohm	35	1MHz	7.5MHz	No magnetic shield
LQH43MN820K03□	82μH±10%	1MHz	170mA	2.2ohm	35	1MHz	7.5MHz	No magnetic shield
LQH43MN101J03□	100μH±5%	1MHz	160mA	2.5ohm	40	796kHz	6.8MHz	No magnetic shield
LQH43MN101K03□	100μH±10%	1MHz	160mA	2.5ohm	40	796kHz	6.8MHz	No magnetic shield
LQH43MN121J03□	120μH±5%	1MHz	150mA	3.0ohm	40	796kHz	6.2MHz	No magnetic shield
LQH43MN121K03□	120μH±10%	1MHz	150mA	3.0ohm	40	796kHz	6.2MHz	No magnetic shield
LQH43MN151J03□	150μH±5%	1MHz	130mA	3.7ohm	40	796kHz	5.5MHz	No magnetic shield
LQH43MN151K03□	150μH±10%	1MHz	130mA	3.7ohm	40	796kHz	5.5MHz	No magnetic shield
LQH43MN181J03□	180μH±5%	1MHz	120mA	4.5ohm	40	796kHz	5MHz	No magnetic shield
LQH43MN181K03□	180μH±10%	1MHz	120mA	4.5ohm	40	796kHz	5MHz	No magnetic shield
LQH43MN221J03□	220μH±5%	1MHz	110mA	5.4ohm	40	796kHz	4.5MHz	No magnetic shield
LQH43MN221K03□	220μH±10%	1MHz	110mA	5.4ohm	40	796kHz	4.5MHz	No magnetic shield
LQH43MN271J03□	270μH±5%	1MHz	100mA	6.8ohm	40	796kHz	4MHz	No magnetic shield
LQH43MN271K03□	270μH±10%	1MHz	100mA	6.8ohm	40	796kHz	4MHz	No magnetic shield
LQH43MN331J03□	330μH±5%	1MHz	95mA	8.2ohm	40	796kHz	3.6MHz	No magnetic shield
LQH43MN331K03□	330μH±10%	1MHz	95mA	8.2ohm	40	796kHz	3.6MHz	No magnetic shield
LQH43MN391J03□	390μH±5%	1MHz	90mA	9.7ohm	40	796kHz	3.3MHz	No magnetic shield
LQH43MN391K03□	390μH±10%	1MHz	90mA	9.7ohm	40	796kHz	3.3MHz	No magnetic shield
LQH43MN471J03□	470μH±5%	1kHz	80mA	11.8ohm	40	796kHz	3MHz	No magnetic shield
LQH43MN471K03□	470μH±10%	1kHz	80mA	11.8ohm	40	796kHz	3MHz	No magnetic shield
LQH43MN561J03□	560μH±5%	1kHz	70mA	14.5ohm	40	796kHz	2.7MHz	No magnetic shield
LQH43MN561K03□	560μH±10%	1kHz	70mA	14.5ohm	40	796kHz	2.7MHz	No magnetic shield
LQH43MN681J03□	680μH±5%	1kHz	65mA	17.0ohm	40	796kHz	2.5MHz	No magnetic shield
LQH43MN681K03□	680μH±10%	1kHz	65mA	17.0ohm	40	796kHz	2.5MHz	No magnetic shield
LQH43MN821J03□	820μH±5%	1kHz	60mA	20.5ohm	40	796kHz	2.2MHz	No magnetic shield
LQH43MN821K03□	820μH±10%	1kHz	60mA	20.5ohm	40	796kHz	2.2MHz	No magnetic shield
LQH43MN102J03□	1000μH±5%	1kHz	50mA	25.0ohm	40	252kHz	2MHz	No magnetic shield
LQH43MN102K03□	1000μH±10%	1kHz	50mA	25.0ohm	40	252kHz	2MHz	No magnetic shield
LQH43MN122J03□	1200μH±5%	1kHz	45mA	30.0ohm	40	252kHz	1.8MHz	No magnetic shield
LQH43MN122K03□	1200μH±10%	1kHz	45mA	30.0ohm	40	252kHz	1.8MHz	No magnetic shield
LQH43MN152J03□	1500μH±5%	1kHz	40mA	37.0ohm	40	252kHz	1.6MHz	No magnetic shield
LQH43MN152K03□	1500μH±10%	1kHz	40mA	37.0ohm	40	252kHz	1.6MHz	No magnetic shield
LQH43NN182J03□	1800μH±5%	1kHz	35mA	45.0ohm	40	252kHz	1.5MHz	No magnetic shield
LQH43NN182K03□	1800μH±10%	1kHz	35mA	45.0ohm	40	252kHz	1.5MHz	No magnetic shield
LQH43NN222J03□	2200μH±5%	1kHz	30mA	50.0ohm	40	252kHz	1.3MHz	No magnetic shield
LQH43NN222K03□	2200μH±10%	1kHz	30mA	50.0ohm	40	252kHz	1.3MHz	No magnetic shield

Operating Temperature Range: -40°C to +85°C

■ Q - Frequency Characteristics (Typ.)



■ Inductance - Current Characteristics (Typ.)



Inductor for High Frequency Multilayer Type

LQG15HN Series (0402 Size)

LQG15HN series is comprised of chip inductors specifically designed for high frequency applications. LQG15H series is designed to realize stable characteristics in high frequency range applying integrated multilayer process. The integrated multilayer process enables a wide range of inductance values with tight tolerance.

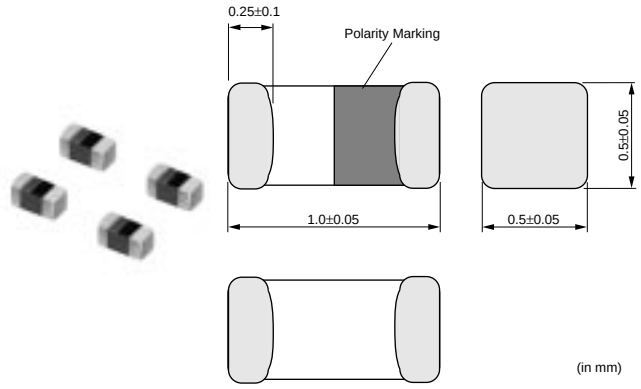
■ Features

1. High-Q, stable inductance in high frequency is achieved by the original structure that minimizes stray capacitance. It is suitable for the high frequency circuits of mobile communication equipment.
2. The small size of LQG15H (1.0x0.5x0.5mm) is suitable for small and low profile mobile equipment.
3. The external electrodes with nickel barrier structure provide excellent solder heat resistance.
4. Wide variation in inductance value
   1-10nH (E24 step)
   10-120nH (E12 step)

■ Applications

1. High frequency circuits of mobile phones such as PA, ANT, VCO, SAW, etc.
2. Mobile phones
3. "Bluetooth"
4. W-LAN
5. High frequency circuits in general

■ Dimension



■ Rated Value (□: packaging code)

Part Number	*1 Inductance	Test Frequency	Rated Current	Max. of DC Resistance	*1 Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQG15HN1N0S02□	1.0nH±0.3nH	100MHz	300mA	0.10ohm	8	100MHz	6000MHz
LQG15HN1N1S02□	1.1nH±0.3nH	100MHz	300mA	0.10ohm	8	100MHz	6000MHz
LQG15HN1N2S02□	1.2nH±0.3nH	100MHz	300mA	0.10ohm	8	100MHz	6000MHz
LQG15HN1N3S02□	1.3nH±0.3nH	100MHz	300mA	0.10ohm	8	100MHz	6000MHz
LQG15HN1N5S02□	1.5nH±0.3nH	100MHz	300mA	0.10ohm	8	100MHz	6000MHz
LQG15HN1N6S02□	1.6nH±0.3nH	100MHz	300mA	0.10ohm	8	100MHz	6000MHz
LQG15HN1N8S02□	1.8nH±0.3nH	100MHz	300mA	0.10ohm	8	100MHz	6000MHz
LQG15HN2N0S02□	2.0nH±0.3nH	100MHz	300mA	0.12ohm	8	100MHz	6000MHz
LQG15HN2N2S02□	2.2nH±0.3nH	100MHz	300mA	0.15ohm	8	100MHz	6000MHz
LQG15HN2N4S02□	2.4nH±0.3nH	100MHz	300mA	0.16ohm	8	100MHz	6000MHz
LQG15HN2N7S02□	2.7nH±0.3nH	100MHz	300mA	0.17ohm	8	100MHz	6000MHz
LQG15HN3N0S02□	3.0nH±0.3nH	100MHz	300mA	0.18ohm	8	100MHz	6000MHz
LQG15HN3N3S02□	3.3nH±0.3nH	100MHz	300mA	0.19ohm	8	100MHz	6000MHz
LQG15HN3N6S02□	3.6nH±0.3nH	100MHz	300mA	0.19ohm	8	100MHz	6000MHz
LQG15HN3N9S02□	3.9nH±0.3nH	100MHz	300mA	0.19ohm	8	100MHz	6000MHz

Operating Temperature Range: -55°C to +125°C Only for reflow soldering.

*1 For the procedure to correct the error caused by test fixture, please refer to "Notice (Measuring Method)" on page 105.

Continued on the following page.

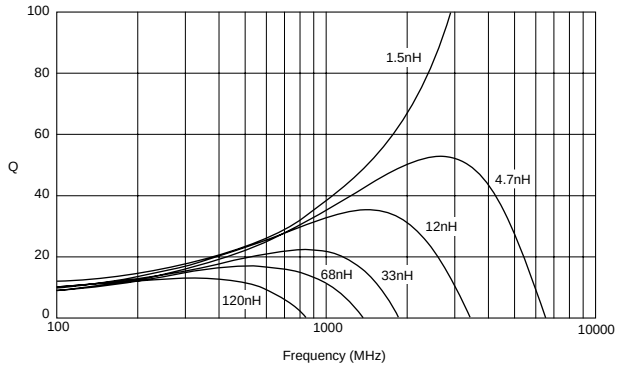
Continued from the preceding page.

Part Number	*1 Inductance	Test Frequency	Rated Current	Max. of DC Resistance	*1 Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQG15HN4N3S02□	4.3nH±0.3nH	100MHz	300mA	0.21ohm	8	100MHz	6000MHz
LQG15HN4N7S02□	4.7nH±0.3nH	100MHz	300mA	0.23ohm	8	100MHz	6000MHz
LQG15HN5N1S02□	5.1nH±0.3nH	100MHz	300mA	0.24ohm	8	100MHz	6000MHz
LQG15HN5N6S02□	5.6nH±0.3nH	100MHz	300mA	0.26ohm	8	100MHz	5300MHz
LQG15HN6N2S02□	6.2nH±0.3nH	100MHz	300mA	0.27ohm	8	100MHz	4300MHz
LQG15HN6N8J02□	6.8nH±5%	100MHz	300mA	0.29ohm	8	100MHz	4200MHz
LQG15HN7N5J02□	7.5nH±5%	100MHz	300mA	0.31ohm	8	100MHz	3900MHz
LQG15HN8N2J02□	8.2nH±5%	100MHz	300mA	0.33ohm	8	100MHz	3600MHz
LQG15HN9N1J02□	9.1nH±5%	100MHz	300mA	0.34ohm	8	100MHz	3400MHz
LQG15HN10NJ02□	10nH±5%	100MHz	300mA	0.35ohm	8	100MHz	3200MHz
LQG15HN12NJ02□	12nH±5%	100MHz	300mA	0.41ohm	8	100MHz	2800MHz
LQG15HN15NJ02□	15nH±5%	100MHz	300mA	0.46ohm	8	100MHz	2300MHz
LQG15HN18NJ02□	18nH±5%	100MHz	300mA	0.51ohm	8	100MHz	2100MHz
LQG15HN22NJ02□	22nH±5%	100MHz	300mA	0.58ohm	8	100MHz	1800MHz
LQG15HN27NJ02□	27nH±5%	100MHz	300mA	0.67ohm	8	100MHz	1600MHz
LQG15HN33NJ02□	33nH±5%	100MHz	200mA	0.67ohm	8	100MHz	1500MHz
LQG15HN39NJ02□	39nH±5%	100MHz	200mA	1.06ohm	8	100MHz	1200MHz
LQG15HN47NJ02□	47nH±5%	100MHz	200mA	1.15ohm	8	100MHz	1000MHz
LQG15HN56NJ02□	56nH±5%	100MHz	200mA	1.20ohm	8	100MHz	800MHz
LQG15HN68NJ02□	68nH±5%	100MHz	180mA	1.25ohm	8	100MHz	800MHz
LQG15HN82NJ02□	82nH±5%	100MHz	150mA	1.60ohm	8	100MHz	600MHz
LQG15HNR10J02□	100nH±5%	100MHz	150mA	1.60ohm	8	100MHz	600MHz
LQG15HNR12J02□	120nH±5%	100MHz	150mA	1.60ohm	8	100MHz	600MHz

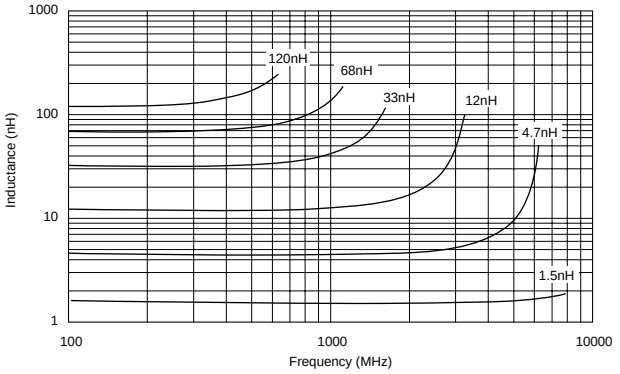
Operating Temperature Range: -55°C to +125°C Only for reflow soldering.

*1 For the procedure to correct the error caused by test fixture, please refer to "Notice (Measuring Method)" on page 105.

■ Q - Frequency Characteristics (Typ.)



■ Inductance - Frequency Characteristics (Typ.)

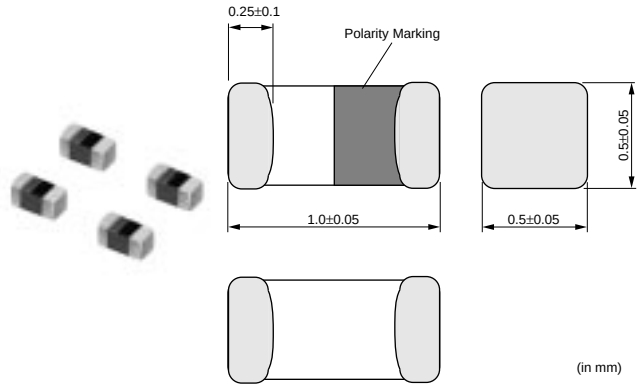


Inductor for High Frequency Multilayer Type

LQG15HS Series (0402 Size)

LQG15HS series is comprised of chip inductors specifically designed for high frequency applications. LQG15H series is designed to realize stable characteristics in high frequency range applying integrated multilayer process. The integrated multilayer process enables a wide range of inductance values with tight tolerance.
Since recent mobile phones install color LCDs and camera modules, the power consumption becomes higher. In order to reduce power consumption a low DC resistance is strongly required. LQG15HS has achieved the lowest DC resistance.

■ Dimension



■ Features

1. High-Q, stable inductance in high frequency is achieved by the original structure that minimizes stray capacitance. It is suitable for the high frequency circuits of mobile communication equipment.
2. The small size of LQG15H (1.0x0.5x0.5mm) is suitable for small and low profile mobile equipment.
3. The external electrodes with nickel barrier structure provide excellent solder heat resistance.
4. Wide variation in inductance value
   1-10nH (E24 step)
   10-270nH (E12 step)

■ Applications

1. High frequency circuits of mobile phones such as PA, ANT, VCO, SAW, etc.
2. Mobile phones
3. "Bluetooth"
4. W-LAN
5. High frequency circuits in general

■ Supplements

For the product with tight inductance tolerance, please contact our local sales or product engineers.

■ Rated Value (☐: packaging code)

Part Number	*1 Inductance	Test Frequency	Rated Current	Max. of DC Resistance	*1 Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQG15HS1N0S02☐	1.0nH±0.3nH	100MHz	300mA	0.07ohm	8	100MHz	10000MHz
LQG15HS1N1S02☐	1.1nH±0.3nH	100MHz	300mA	0.09ohm	8	100MHz	6000MHz
LQG15HS1N2S02☐	1.2nH±0.3nH	100MHz	300mA	0.09ohm	8	100MHz	6000MHz
LQG15HS1N3S02☐	1.3nH±0.3nH	100MHz	300mA	0.09ohm	8	100MHz	6000MHz
LQG15HS1N5S02☐	1.5nH±0.3nH	100MHz	300mA	0.1ohm	8	100MHz	6000MHz
LQG15HS1N6S02☐	1.6nH±0.3nH	100MHz	300mA	0.1ohm	8	100MHz	6000MHz

Operating Temperature Range: -55°C to +125°C Only for reflow soldering.
*1 For the procedure to correct the error caused by test fixture, please refer to "Notice (Measuring Method)" on page 105.

Continued on the following page.

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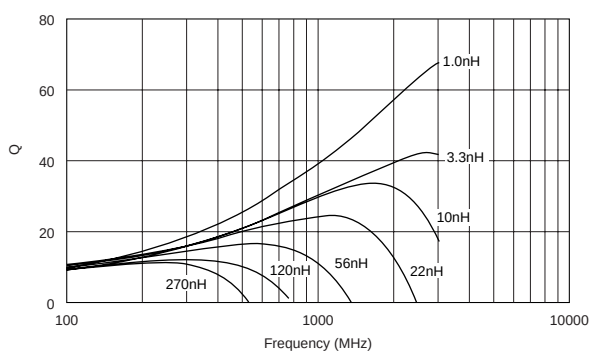
Part Number	*1 Inductance	Test Frequency	Rated Current	Max. of DC Resistance	*1 Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQG15HS1N8S02□	1.8nH±0.3nH	100MHz	300mA	0.1ohm	8	100MHz	6000MHz
LQG15HS2N0S02□	2.0nH±0.3nH	100MHz	300mA	0.1ohm	8	100MHz	6000MHz
LQG15HS2N2S02□	2.2nH±0.3nH	100MHz	300mA	0.12ohm	8	100MHz	6000MHz
LQG15HS2N4S02□	2.4nH±0.3nH	100MHz	300mA	0.15ohm	8	100MHz	6000MHz
LQG15HS2N7S02□	2.7nH±0.3nH	100MHz	300mA	0.15ohm	8	100MHz	6000MHz
LQG15HS3N0S02□	3.0nH±0.3nH	100MHz	300mA	0.17ohm	8	100MHz	6000MHz
LQG15HS3N3S02□	3.3nH±0.3nH	100MHz	300mA	0.17ohm	8	100MHz	6000MHz
LQG15HS3N6S02□	3.6nH±0.3nH	100MHz	300mA	0.18ohm	8	100MHz	6000MHz
LQG15HS3N9S02□	3.9nH±0.3nH	100MHz	300mA	0.18ohm	8	100MHz	6000MHz
LQG15HS4N3S02□	4.3nH±0.3nH	100MHz	300mA	0.18ohm	8	100MHz	6000MHz
LQG15HS4N7S02□	4.7nH±0.3nH	100MHz	300mA	0.18ohm	8	100MHz	6000MHz
LQG15HS5N1S02□	5.1nH±0.3nH	100MHz	300mA	0.2ohm	8	100MHz	5300MHz
LQG15HS5N6S02□	5.6nH±0.3nH	100MHz	300mA	0.2ohm	8	100MHz	4500MHz
LQG15HS6N2S02□	6.2nH±0.3nH	100MHz	300mA	0.22ohm	8	100MHz	4500MHz
LQG15HS6N8J02□	6.8nH±5%	100MHz	300mA	0.24ohm	8	100MHz	4500MHz
LQG15HS7N5J02□	7.5nH±5%	100MHz	300mA	0.24ohm	8	100MHz	4200MHz
LQG15HS8N2J02□	8.2nH±5%	100MHz	300mA	0.24ohm	8	100MHz	3700MHz
LQG15HS9N1J02□	9.1nH±5%	100MHz	300mA	0.26ohm	8	100MHz	3400MHz
LQG15HS10NJ02□	10nH±5%	100MHz	300mA	0.26ohm	8	100MHz	3400MHz
LQG15HS12NJ02□	12nH±5%	100MHz	300mA	0.28ohm	8	100MHz	3000MHz
LQG15HS15NJ02□	15nH±5%	100MHz	300mA	0.32ohm	8	100MHz	2500MHz
LQG15HS18NJ02□	18nH±5%	100MHz	300mA	0.36ohm	8	100MHz	2200MHz
LQG15HS22NJ02□	22nH±5%	100MHz	300mA	0.42ohm	8	100MHz	1900MHz
LQG15HS27NJ02□	27nH±5%	100MHz	300mA	0.46ohm	8	100MHz	1700MHz
LQG15HS33NJ02□	33nH±5%	100MHz	200mA	0.58ohm	8	100MHz	1600MHz
LQG15HS39NJ02□	39nH±5%	100MHz	200mA	0.65ohm	8	100MHz	1200MHz
LQG15HS47NJ02□	47nH±5%	100MHz	200mA	0.72ohm	8	100MHz	1000MHz
LQG15HS56NJ02□	56nH±5%	100MHz	200mA	0.82ohm	8	100MHz	800MHz
LQG15HS68NJ02□	68nH±5%	100MHz	180mA	0.92ohm	8	100MHz	800MHz
LQG15HS82NJ02□	82nH±5%	100MHz	150mA	1.2ohm	8	100MHz	700MHz
LQG15HSR10J02□	100nH±5%	100MHz	150mA	1.25ohm	8	100MHz	600MHz
LQG15HSR12J02□	120nH±5%	100MHz	150mA	1.3ohm	8	100MHz	600MHz
LQG15HSR15J02□	150nH±5%	100MHz	140mA	2.99ohm	8	100MHz	550MHz
LQG15HSR18J02□	180nH±5%	100MHz	130mA	3.38ohm	8	100MHz	500MHz
LQG15HSR22J02□	220nH±5%	100MHz	120mA	3.77ohm	8	100MHz	450MHz
LQG15HSR27J02□	270nH±5%	100MHz	110mA	4.94ohm	8	100MHz	400MHz

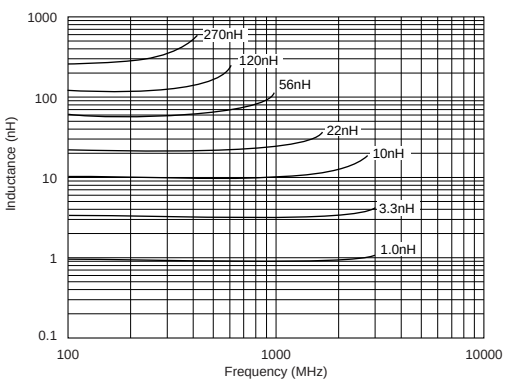
Operating Temperature Range: -55°C to +125°C Only for reflow soldering.

*1 For the procedure to correct the error caused by test fixture, please refer to "Notice (Measuring Method)" on page 105.

■ Q - Frequency Characteristics (Typ.)



■ Inductance - Frequency Characteristics (Typ.)



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■ Reference Data

E4991&16197A

Part Number	Inductance (nH) 100MHz	Q (typ.)					Rdc (Ω typ.)	SRF (MHz typ.)
		800MHz	900MHz	1.8GHz	2.0GHz	2.4GHz		
LQG15HS1N0S02	1.0	32	34	51	54	57	0.03	11700
LQG15HS1N1S02	1.1	35	37	59	62	64		10000
LQG15HS1N2S02	1.2	34	36	56	58	60		8600
LQG15HS1N3S02	1.3	34	36	56	57	58		7000
LQG15HS1N5S02	1.5	31	34	50	53	55	0.04	9700
LQG15HS1N6S02	1.6	31	33	50	52	54		8600
LQG15HS1N8S02	1.8	31	33	48	49	50		7500
LQG15HS2N0S02	2.0	31	32	47	48	49		6400
LQG15HS2N2S02	2.2	32	34	48	49	50	0.05	6200
LQG15HS2N4S02	2.4	32	34	51	52	52	0.07	10000
LQG15HS2N7S02	2.7	31	33	49	50	50	0.08	8700
LQG15HS3N0S02	3.0	32	34	49	51	50	0.09	8000
LQG15HS3N3S02	3.3	31	33	46	47	46		6700
LQG15HS3N6S02	3.6	31	33	45	47	46	0.10	8000
LQG15HS3N9S02	3.9	31	33	49	47	46		7500
LQG15HS4N3S02	4.3	31	33	44	45	44		6500
LQG15HS4N7S02	4.7	31	33	42	43	42	0.12	6200
LQG15HS5N1S02	5.1	31	33	44	45	42	0.13	5800
LQG15HS5N6S02	5.6	30	32	41	40	38		5000
LQG15HS6N2S02	6.2	29	31	41	41	38	0.16	5100
LQG15HS6N8J02	6.8	29	30	40	40	37	0.17	4900
LQG15HS7N5J02	7.5	28	29	38	37	34		4500
LQG15HS8N2J02	8.2	27	29	35	34	29		4100
LQG15HS9N1J02	9.1	27	29	36	35	31	0.18	
LQG15HS10NJ02	10	27	29	35	33	28		3900
LQG15HS12NJ02	12	26	27	28	24	18		3200
LQG15HS15NJ02	15	26	27	25	21	13	0.22	2900
LQG15HS18NJ02	18	25	25	22	18	-	0.26	2800
LQG15HS22NJ02	22	23	24	16	-	-	0.30	2500
LQG15HS27NJ02	27	21	21	-	-	-	0.33	2000
LQG15HS33NJ02	33	20	20	-	-	-	0.40	1900
LQG15HS39NJ02	39	19	18	-	-	-	0.44	1700
LQG15HS47NJ02	47	17	16	-	-	-	0.48	1500
LQG15HS56NJ02	56	15	13	-	-	-	0.55	1300
LQG15HS68NJ02	68	12	10	-	-	-	0.63	1200
LQG15HS82NJ02	82	9	6	-	-	-	0.77	1100
LQG15HSR10J02	100	-	-	-	-	-	0.92	900
LQG15HSR12J02	120	-	-	-	-	-	1.00	800

Inductor for High Frequency Multilayer Type

LQG18H Series (0603 Size)

LQG18H series is designed to realize stable characteristics in high frequency range applying integrated multilayer process.

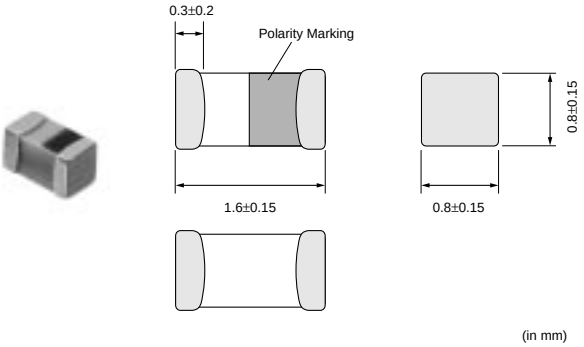
■ Features

1. High-Q, stable inductance in high frequency is achieved by the original structure that minimizes stray capacitance. It is suitable for the high frequency circuits of mobile communication equipment.
2. Small size of LQG18H (1.6x0.8x0.8mm) is suitable for small, handy equipment, especially for card size equipment.
3. The external electrodes with nickel barrier structure provide excellent solder heat resistance.

■ Applications

1. High frequency circuits of mobile phones such as PA, ANT, VCO, SAW, etc.
2. Mobile phones
3. "Bluetooth"
4. W-LAN
5. High frequency circuits in general

■ Dimension



(in mm)

■ Rated Value (☐: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQG18HN1N2S00☐	1.2nH±0.3nH	100MHz	500mA	0.10ohm	12	100MHz	6000MHz
LQG18HN1N5S00☐	1.5nH±0.3nH	100MHz	500mA	0.10ohm	12	100MHz	6000MHz
LQG18HN1N8S00☐	1.8nH±0.3nH	100MHz	500mA	0.10ohm	12	100MHz	6000MHz
LQG18HN2N2S00☐	2.2nH±0.3nH	100MHz	500mA	0.10ohm	12	100MHz	6000MHz
LQG18HN2N7S00☐	2.7nH±0.3nH	100MHz	500mA	0.15ohm	12	100MHz	6000MHz
LQG18HN3N3S00☐	3.3nH±0.3nH	100MHz	500mA	0.15ohm	12	100MHz	6000MHz
LQG18HN3N9S00☐	3.9nH±0.3nH	100MHz	450mA	0.15ohm	12	100MHz	6000MHz
LQG18HN4N7S00☐	4.7nH±0.3nH	100MHz	450mA	0.20ohm	12	100MHz	6000MHz
LQG18HN5N6S00☐	5.6nH±0.3nH	100MHz	430mA	0.20ohm	12	100MHz	5000MHz
LQG18HN6N8J00☐	6.8nH±5%	100MHz	430mA	0.25ohm	12	100MHz	5000MHz
LQG18HN8N2J00☐	8.2nH±5%	100MHz	400mA	0.25ohm	12	100MHz	4000MHz
LQG18HN10NJ00☐	10nH±5%	100MHz	400mA	0.30ohm	12	100MHz	3500MHz
LQG18HN12NJ00☐	12nH±5%	100MHz	400mA	0.35ohm	12	100MHz	3000MHz
LQG18HN15NJ00☐	15nH±5%	100MHz	350mA	0.40ohm	12	100MHz	2800MHz
LQG18HN18NJ00☐	18nH±5%	100MHz	350mA	0.45ohm	12	100MHz	2600MHz
LQG18HN22NJ00☐	22nH±5%	100MHz	300mA	0.50ohm	12	100MHz	2300MHz
LQG18HN27NJ00☐	27nH±5%	100MHz	300mA	0.55ohm	12	100MHz	2000MHz
LQG18HN33NJ00☐	33nH±5%	100MHz	300mA	0.60ohm	12	100MHz	1700MHz
LQG18HN39NJ00☐	39nH±5%	100MHz	300mA	0.65ohm	12	100MHz	1500MHz
LQG18HN47NJ00☐	47nH±5%	100MHz	300mA	0.70ohm	12	100MHz	1200MHz
LQG18HN56NJ00☐	56nH±5%	100MHz	300mA	0.75ohm	12	100MHz	1100MHz

Operating Temperature Range: -40°C to +85°C Only for reflow soldering.

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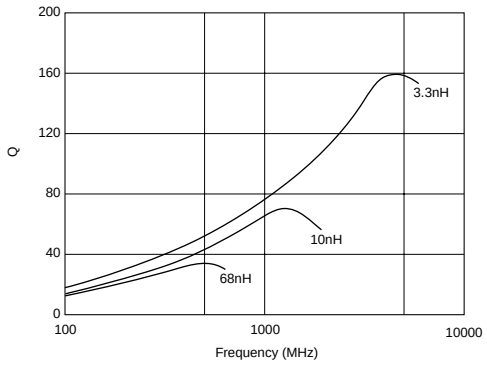
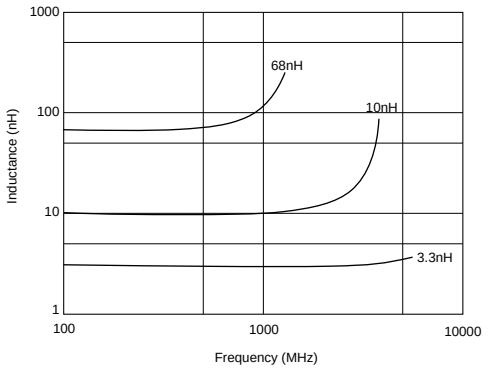
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQG18HN68NJ00□	68nH±5%	100MHz	300mA	0.80ohm	12	100MHz	1000MHz
LQG18HN82NJ00□	82nH±5%	100MHz	300mA	0.85ohm	12	100MHz	900MHz
LQG18HNR10J00□	100nH±5%	100MHz	300mA	0.90ohm	12	100MHz	800MHz

Operating Temperature Range: -40°C to +85°C Only for reflow soldering.

■ Q - Frequency Characteristics (Typ.)



■ Inductance - Frequency Characteristics (Typ.)



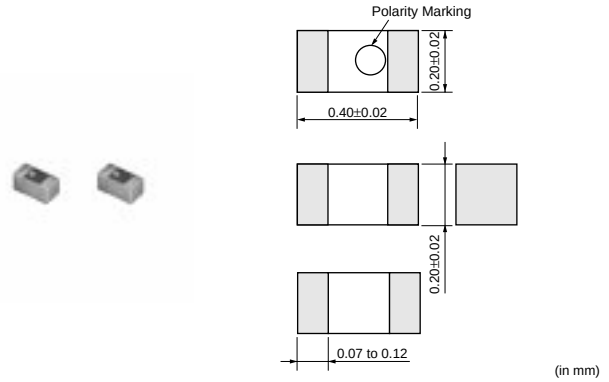
3

Inductor for High Frequency Film Type

LQP02T Series (01005 Size)

LQP02T series is ultra small size (01005) chip inductor, which is developed using highly advanced micro processing technology. This inductor reduces 50% of mounting area from that of 0201 size inductor. High Q value and stable inductance characteristics in high frequency range contributes to high performance equipment.

■ Dimension



(in mm)

■ Features

1. Ultra small size 0.4x0.2x0.2mm
2. High Q value and stable inductance
3. Inductance value 0.4 to 18nH
4. Inductance tolerance (+-0.3nH, +-5%)

■ Applications

1. High frequency circuits of mobile phones such as PA, ANT, VCO, SAW etc.
2. Mobile phones such as GSM, CDMA, PDC etc.
3. Digital TV Tuner
4. W-LAN
5. "Bluetooth"
6. High frequency circuits in general

■ Rated Value (□: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQP02TN0N4S02□	0.4nH±0.3nH	500MHz	320mA	0.60ohm	8	500MHz	6000MHz
LQP02TN0N5S02□	0.5nH±0.3nH	500MHz	320mA	0.60ohm	8	500MHz	6000MHz
LQP02TN0N6S02□	0.6nH±0.3nH	500MHz	320mA	0.60ohm	8	500MHz	6000MHz
LQP02TN0N7S02□	0.7nH±0.3nH	500MHz	320mA	0.60ohm	8	500MHz	6000MHz
LQP02TN0N8S02□	0.8nH±0.3nH	500MHz	320mA	0.60ohm	8	500MHz	6000MHz
LQP02TN0N9S02□	0.9nH±0.3nH	500MHz	320mA	0.60ohm	8	500MHz	6000MHz
LQP02TN1N0S02□	1.0nH±0.3nH	500MHz	220mA	0.90ohm	8	500MHz	6000MHz
LQP02TN1N1S02□	1.1nH±0.3nH	500MHz	220mA	0.90ohm	8	500MHz	6000MHz
LQP02TN1N2S02□	1.2nH±0.3nH	500MHz	220mA	0.90ohm	8	500MHz	6000MHz
LQP02TN1N3S02□	1.3nH±0.3nH	500MHz	220mA	0.90ohm	8	500MHz	6000MHz
LQP02TN1N5S02□	1.5nH±0.3nH	500MHz	220mA	0.90ohm	8	500MHz	6000MHz
LQP02TN1N6S02□	1.6nH±0.3nH	500MHz	220mA	0.90ohm	8	500MHz	6000MHz
LQP02TN1N8S02□	1.8nH±0.3nH	500MHz	200mA	1.35ohm	8	500MHz	6000MHz
LQP02TN2N0S02□	2.0nH±0.3nH	500MHz	200mA	1.35ohm	8	500MHz	6000MHz
LQP02TN2N2S02□	2.2nH±0.3nH	500MHz	200mA	1.35ohm	8	500MHz	6000MHz
LQP02TN2N4S02□	2.4nH±0.3nH	500MHz	200mA	1.35ohm	8	500MHz	6000MHz
LQP02TN2N7S02□	2.7nH±0.3nH	500MHz	200mA	1.35ohm	8	500MHz	6000MHz
LQP02TN3N0S02□	3.0nH±0.3nH	500MHz	200mA	1.35ohm	8	500MHz	6000MHz
LQP02TN3N3S02□	3.3nH±0.3nH	500MHz	180mA	1.65ohm	8	500MHz	6000MHz
LQP02TN3N6S02□	3.6nH±0.3nH	500MHz	180mA	1.65ohm	8	500MHz	6000MHz
LQP02TN3N9S02□	3.9nH±0.3nH	500MHz	180mA	1.65ohm	8	500MHz	6000MHz
LQP02TN4N3S02□	4.3nH±0.3nH	500MHz	180mA	1.65ohm	8	500MHz	6000MHz

Operating Temperature Range: -40 to +85°C Only for reflow soldering.

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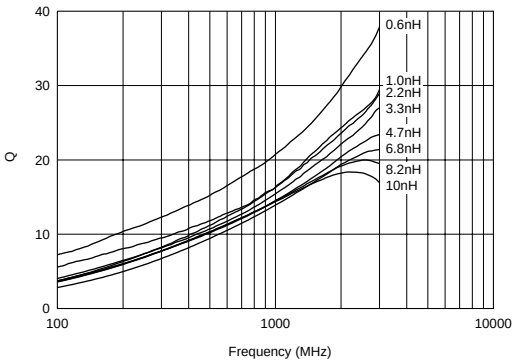
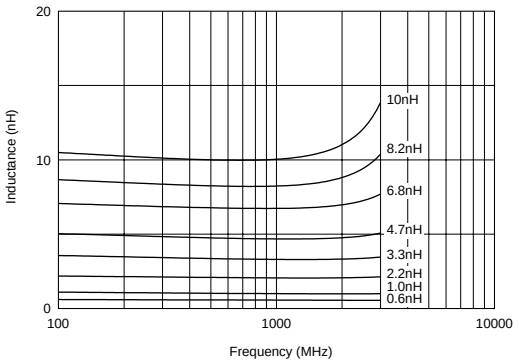
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQP02TN4N7S02□	4.7nH±0.3nH	500MHz	160mA	2.10ohm	8	500MHz	6000MHz
LQP02TN5N1S02□	5.1nH±0.3nH	500MHz	160mA	2.10ohm	8	500MHz	6000MHz
LQP02TN5N6S02□	5.6nH±0.3nH	500MHz	140mA	2.40ohm	8	500MHz	6000MHz
LQP02TN6N2J02□	6.2nH±5%	500MHz	140mA	2.40ohm	8	500MHz	5500MHz
LQP02TN6N8J02□	6.8nH±5%	500MHz	140mA	2.85ohm	8	500MHz	5500MHz
LQP02TN7N5J02□	7.5nH±5%	500MHz	140mA	2.85ohm	8	500MHz	4500MHz
LQP02TN8N2J02□	8.2nH±5%	500MHz	140mA	3.15ohm	8	500MHz	5000MHz
LQP02TN9N1J02□	9.1nH±5%	500MHz	140mA	3.15ohm	8	500MHz	4000MHz
LQP02TN10NJ02□	10nH±5%	500MHz	140mA	3.60ohm	8	500MHz	4000MHz
LQP02TN12NJ02□	12nH±5%	500MHz	140mA	3.90ohm	7	500MHz	3500MHz
LQP02TN15NJ02□	15nH±5%	500MHz	140mA	4.35ohm	7	500MHz	3000MHz
LQP02TN18NJ02□	18nH±5%	500MHz	140mA	4.80ohm	7	500MHz	2500MHz

Operating Temperature Range: -40 to +85°C Only for reflow soldering.

■ Q-Frequency Characteristics (Typ.)



■ Inductance-Frequency Characteristics (Typ.)



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■ Reference Data

E4991A & 16197A

Part Number	Inductance (nH) (Typ.)					Q (Typ.)				
	800MHz	900MHz	1.8GHz	2.0GHz	2.4GHz	800MHz	900MHz	1.8GHz	2.0GHz	2.4GHz
LQP02TN0N4	0.4	0.4	0.4	0.4	0.4	15	16	26	28	30
LQP02TN0N5	0.5	0.5	0.5	0.5	0.5	15	16	24	26	28
LQP02TN0N6	0.6	0.6	0.6	0.6	0.6	15	16	24	26	28
LQP02TN0N7	0.7	0.7	0.7	0.7	0.7	15	15	23	24	26
LQP02TN0N8	0.8	0.8	0.8	0.8	0.8	14	15	23	24	26
LQP02TN0N9	0.9	0.9	0.9	0.9	0.9	14	15	23	24	26
LQP02TN1N0	1.0	1.0	1.0	1.0	1.0	14	15	23	24	26
LQP02TN1N1	1.1	1.1	1.1	1.1	1.1	14	15	23	24	26
LQP02TN1N2	1.2	1.2	1.2	1.2	1.2	14	15	23	24	26
LQP02TN1N3	1.3	1.3	1.3	1.3	1.3	14	15	23	24	26
LQP02TN1N5	1.5	1.5	1.5	1.5	1.5	14	15	23	24	26
LQP02TN1N6	1.6	1.6	1.6	1.6	1.6	14	15	23	24	26
LQP02TN1N8	1.8	1.8	1.8	1.8	1.8	14	15	23	24	26
LQP02TN2N0	2.0	2.0	2.0	2.0	2.0	14	15	22	23	25
LQP02TN2N2	2.2	2.2	2.2	2.2	2.2	14	15	22	23	25
LQP02TN2N4	2.4	2.4	2.4	2.4	2.4	14	15	22	23	25
LQP02TN2N7	2.7	2.7	2.7	2.7	2.7	14	15	22	23	25
LQP02TN3N0	3.0	3.0	3.0	3.0	3.0	13	14	21	22	23
LQP02TN3N3	3.3	3.3	3.3	3.3	3.3	13	14	21	22	24
LQP02TN3N6	3.6	3.6	3.6	3.6	3.6	13	14	20	21	23
LQP02TN3N9	3.9	3.9	3.9	3.9	3.9	13	14	20	21	23
LQP02TN4N3	4.3	4.3	4.3	4.3	4.3	13	14	19	20	22
LQP02TN4N7	4.7	4.7	4.7	4.7	4.8	13	14	19	20	22
LQP02TN5N1	5.1	5.1	5.0	5.1	5.2	13	14	18	19	21
LQP02TN5N6	5.6	5.6	5.6	5.7	5.9	13	14	18	19	21
LQP02TN6N2	6.2	6.2	6.1	6.2	6.3	13	14	18	19	21
LQP02TN6N8	6.8	6.8	6.9	7.0	7.2	13	14	18	19	21
LQP02TN7N5	7.5	7.5	7.4	7.5	7.9	13	14	18	19	20
LQP02TN8N2	8.2	8.2	8.6	8.8	9.3	13	14	18	19	20
LQP02TN9N1	9.1	9.2	9.7	9.7	10.0	13	14	18	19	20
LQP02TN10N	10	10	11	11	12	13	14	17	18	18
LQP02TN12N	13	13	14	15	16	13	14	17	18	18
LQP02TN15N	15	15	18	19	22	12	13	18	18	17
LQP02TN18N	18	18	23	25	31	12	12	14	12	11

Inductor for High Frequency Film Type

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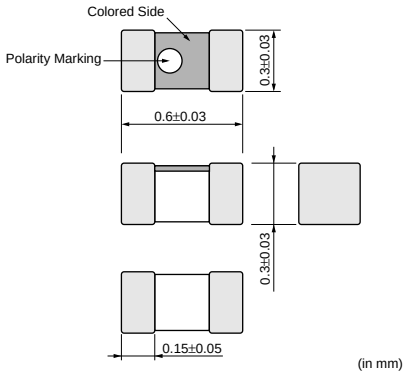
LQP03T_02 Series (0201 Size)

LQP03T_02 type has inductance value of 0.6 to 120nH. This improvement enables easy impedance matching at both RF and IF circuits, and compact high frequency designing.
Also, its highest class Q characteristic compared to other 0201 size inductors, resulting from Murata's miniature manufacturing technology, enables higher performance and smaller packaging of equipment.

■ Dimension



(in mm)

■ Features

1. Ultra small and thin size 0.6x0.3x0.3mm (EIA: 0201)
2. High Q value from our old goods
3. Inductance value 0.6 to 120nH
4. Inductance tolerance +-0.2nH, +-5%
5. Sn Electrode

■ Applications

1. High frequency circuits of mobile phones such as PA, ANT, VCO, etc.
2. Mobile phones such as GSM, CDMA, PDC, etc.
3. "Bluetooth"
4. W-LAN
5. General high frequency circuits

■ Rated Value (☐: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)	Operating Temperature Range
LQP03TN0N6C02☐	0.6nH±0.2nH	500MHz	850mA	0.07ohm	14	500MHz	6000MHz	-55 to +125°C
LQP03TN0N7C02☐	0.7nH±0.2nH	500MHz	800mA	0.08ohm	14	500MHz	6000MHz	-55 to +125°C
LQP03TN0N8C02☐	0.8nH±0.2nH	500MHz	800mA	0.08ohm	14	500MHz	6000MHz	-55 to +125°C
LQP03TN0N9C02☐	0.9nH±0.2nH	500MHz	750mA	0.10ohm	14	500MHz	6000MHz	-55 to +125°C
LQP03TN1N0C02☐	1.0nH±0.2nH	500MHz	750mA	0.10ohm	14	500MHz	6000MHz	-55 to +125°C
LQP03TN1N1C02☐	1.1nH±0.2nH	500MHz	750mA	0.10ohm	14	500MHz	6000MHz	-55 to +125°C
LQP03TN1N2C02☐	1.2nH±0.2nH	500MHz	750mA	0.10ohm	14	500MHz	6000MHz	-55 to +125°C
LQP03TN1N3C02☐	1.3nH±0.2nH	500MHz	600mA	0.15ohm	14	500MHz	6000MHz	-55 to +125°C
LQP03TN1N5C02☐	1.5nH±0.2nH	500MHz	600mA	0.15ohm	14	500MHz	6000MHz	-55 to +125°C
LQP03TN1N6C02☐	1.6nH±0.2nH	500MHz	600mA	0.15ohm	14	500MHz	6000MHz	-55 to +125°C
LQP03TN1N8C02☐	1.8nH±0.2nH	500MHz	600mA	0.15ohm	14	500MHz	6000MHz	-55 to +125°C
LQP03TN2N0C02☐	2.0nH±0.2nH	500MHz	600mA	0.15ohm	14	500MHz	6000MHz	-55 to +125°C
LQP03TN2N2C02☐	2.2nH±0.2nH	500MHz	600mA	0.15ohm	14	500MHz	6000MHz	-55 to +125°C
LQP03TN2N4C02☐	2.4nH±0.2nH	500MHz	500mA	0.20ohm	14	500MHz	6000MHz	-55 to +125°C
LQP03TN2N7C02☐	2.7nH±0.2nH	500MHz	500mA	0.20ohm	14	500MHz	6000MHz	-55 to +125°C
LQP03TN3N0C02☐	3.0nH±0.2nH	500MHz	450mA	0.25ohm	14	500MHz	6000MHz	-55 to +125°C
LQP03TN3N3C02☐	3.3nH±0.2nH	500MHz	450mA	0.25ohm	14	500MHz	6000MHz	-55 to +125°C
LQP03TN3N6C02☐	3.6nH±0.2nH	500MHz	400mA	0.30ohm	14	500MHz	6000MHz	-55 to +125°C
LQP03TN3N9C02☐	3.9nH±0.2nH	500MHz	400mA	0.30ohm	14	500MHz	5700MHz	-55 to +125°C
LQP03TN5N1J02☐	5.1nH±5%	500MHz	350mA	0.40ohm	14	500MHz	4200MHz	-55 to +125°C
LQP03TN5N6J02☐	5.6nH±5%	500MHz	350mA	0.40ohm	14	500MHz	4000MHz	-55 to +125°C

Only for reflow soldering.

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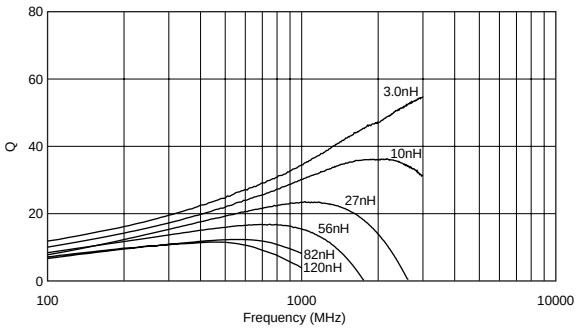
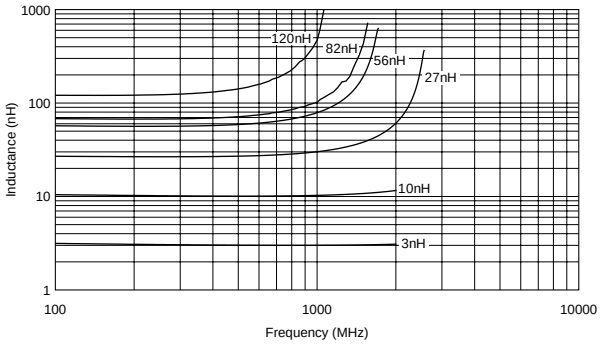
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)	Operating Temperature Range
LQP03TN6N2J02□	6.2nH±5%	500MHz	300mA	0.60ohm	14	500MHz	4000MHz	-55 to +125°C
LQP03TN6N8J02□	6.8nH±5%	500MHz	300mA	0.60ohm	14	500MHz	3900MHz	-55 to +125°C
LQP03TN7N5J02□	7.5nH±5%	500MHz	300mA	0.60ohm	14	500MHz	3700MHz	-55 to +125°C
LQP03TN8N2J02□	8.2nH±5%	500MHz	250mA	0.70ohm	14	500MHz	3600MHz	-55 to +125°C
LQP03TN9N1J02□	9.1nH±5%	500MHz	250mA	0.70ohm	14	500MHz	3300MHz	-55 to +125°C
LQP03TN10NJ02□	10nH±5%	500MHz	250mA	0.70ohm	14	500MHz	3200MHz	-55 to +125°C
LQP03TN12NJ02□	12nH±5%	500MHz	250mA	0.70ohm	12	500MHz	2900MHz	-55 to +125°C
LQP03TN15NJ02□	15nH±5%	500MHz	250mA	0.70ohm	12	500MHz	2600MHz	-55 to +125°C
LQP03TN22NJ02□	22nH±5%	500MHz	150mA	1.90ohm	12	500MHz	2200MHz	-55 to +125°C
LQP03TN27NJ02□	27nH±5%	500MHz	140mA	2.30ohm	12	500MHz	2000MHz	-55 to +125°C
LQP03TN33NJ02□	33nH±5%	300MHz	120mA	2.95ohm	9	300MHz	1700MHz	-55 to +125°C
LQP03TN39NJ02□	39nH±5%	300MHz	120mA	3.00ohm	9	300MHz	1500MHz	-55 to +125°C
LQP03TN47NJ02□	47nH±5%	300MHz	100mA	3.60ohm	9	300MHz	1300MHz	-55 to +125°C
LQP03TN56NJ02□	56nH±5%	300MHz	100mA	3.90ohm	9	300MHz	1200MHz	-55 to +125°C
LQP03TN68NJ02□	68nH±5%	300MHz	50mA	8.00ohm	8	300MHz	1100MHz	-40 to +85°C
LQP03TN82NJ02□	82nH±5%	300MHz	50mA	10.0ohm	8	300MHz	1000MHz	-40 to +85°C
LQP03TNR10J02□	100nH±5%	300MHz	40mA	10.0ohm	8	300MHz	900MHz	-40 to +85°C
LQP03TNR12J02□	120nH±5%	300MHz	40mA	12.0ohm	8	300MHz	800MHz	-40 to +85°C

Only for reflow soldering.

■ Q-Frequency Characteristics (Typ.)



■ Inductance-Frequency Characteristics (Typ.)



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■ Reference Data

E4991A & 16197A

Part Number	Inductance (nH) (typ.)					Q (Typ.)				
	800MHz	900MHz	1.8GHz	2.0GHz	2.4GHz	800MHz	900MHz	1.8GHz	2.0GHz	2.4GHz
LQP03TN0N6	0.6	0.6	0.6	0.6	0.6	50 min.	54 min.	70 min.	73 min.	77 min.
LQP03TN0N7	0.7	0.7	0.7	0.7	0.7	50 min.	54 min.	70 min.	73 min.	77 min.
LQP03TN0N8	0.8	0.8	0.8	0.8	0.8	50 min.	54 min.	70 min.	73 min.	77 min.
LQP03TN0N9	0.9	0.9	0.9	0.9	0.9	50 min.	54 min.	70 min.	73 min.	77 min.
LQP03TN1N0	1.0	1.0	1.0	1.0	1.0	50 min.	54 min.	70 min.	73 min.	77 min.
LQP03TN1N1	1.1	1.1	1.1	1.1	1.1	50 min.	54 min.	70 min.	73 min.	77 min.
LQP03TN1N2	1.2	1.2	1.2	1.2	1.2	50	54	70	73	77
LQP03TN1N3	1.3	1.3	1.3	1.3	1.3	48	52	67	72	74
LQP03TN1N5	1.5	1.5	1.5	1.5	1.5	45	48	63	66	69
LQP03TN1N6	1.6	1.6	1.6	1.6	1.6	43	47	57	64	67
LQP03TN1N8	1.8	1.8	1.8	1.8	1.8	36	38	50	53	55
LQP03TN2N0	2.0	2.0	2.0	2.0	2.0	38	40	52	54	57
LQP03TN2N2	2.2	2.2	2.2	2.2	2.2	28	35	49	52	54
LQP03TN2N4	2.4	2.4	2.4	2.4	2.4	36	38	50	53	56
LQP03TN2N7	2.7	2.7	2.7	2.7	2.7	28	30	40	42	44
LQP03TN3N0	3.0	3.0	3.0	3.0	3.0	28	29	39	41	43
LQP03TN3N3	3.3	3.3	3.3	3.3	3.4	29	31	42	43	45
LQP03TN3N6	3.6	3.6	3.6	3.7	3.7	31	33	43	45	47
LQP03TN3N9	3.9	3.9	3.9	4.0	4.1	29	31	41	43	45
LQP03TN4N3	4.3	4.3	4.3	4.4	4.5	28	30	40	42	44
LQP03TN4N7	4.7	4.7	4.8	4.9	5.1	28	30	40	42	43
LQP03TN5N1	5.1	5.1	5.2	5.3	5.5	26	28	37	39	40
LQP03TN5N6	5.6	5.6	5.8	5.9	6.1	22	24	32	33	33
LQP03TN6N2	6.2	6.2	6.5	6.6	6.9	20	21	27	28	28
LQP03TN6N8	6.8	6.8	7.1	7.4	7.7	21	22	29	30	30
LQP03TN7N5	7.5	7.5	7.9	8.2	8.7	21	22	28	30	29
LQP03TN8N2	8.2	8.2	8.6	9.1	9.6	18	19	25	25	24
LQP03TN9N1	9.1	9.1	9.9	10	11	20	21	26	26	25
LQP03TN10N	10	10	11	12	13	21	22	28	28	27
LQP03TN12N	12	12	13	14	16	21	22	27	27	25
LQP03TN15N	15	15	18	19	23	21	21	25	24	22
LQP03TN18N	18	18	24	-	-	18	19	20	-	-
LQP03TN22N	22	23	32	-	-	16	17	16	-	-
LQP03TN27N	28	29	47	-	-	15	15	13	-	-
LQP03TN33N	35	36	-	-	-	18	19	-	-	-
LQP03TN39N	42	44	-	-	-	15	15	-	-	-
LQP03TN47N	55	58	-	-	-	14	14	-	-	-
LQP03TN56N	63	67	-	-	-	13	13	-	-	-

Inductor for High Frequency Film Type

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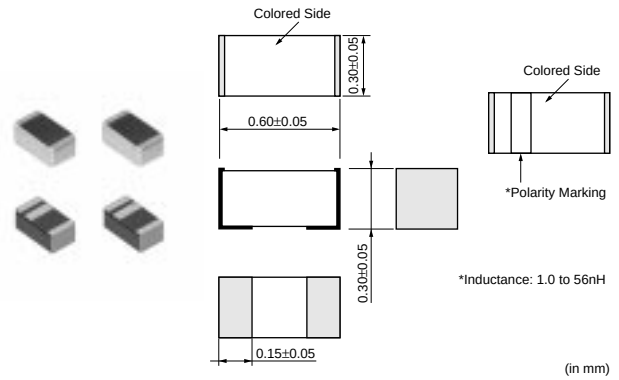
LQP03T_00 Series (0201 Size)

LQP03T_00 series offers ultra small size using Murata's miniature manufacturing technology.
By this, LQP03T_00 series contributes to miniaturization of equipment.
Also, its highest class Q characteristic compared to other Monolithic inductors, enables higher performance of equipment.
Furthermore, it enables easy impedance matching at both RF and IF circuits, and compact high frequency circuit designing, because it realizes 0.1nH step at 0.6 to 3.9nH and E24 step at 4.3 to 10nH.

■ Dimension



■ Features

1. Ultra small size 0.6x0.3x0.3mm
2. High Q value in high frequency range
3. 0.1nH step
   0.6 to 3.9nH: +-0.1nH, +-0.2nH
   E24 step
   4.3 to 10nH: +-3%
   E12 step
   4.7 to 27nH: +-3%, +-5%
   33 to 56nH: +-5%
4. Sn Electrode

■ Applications

1. High frequency circuits of mobile phones such as PA, ANT, VCO, SAW, etc.
2. Mobile phones
3. "Bluetooth"
4. W-LAN
5. High frequency circuits in general

■ Rated Value (□: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQP03TN0N6B00□	0.6nH±0.1nH	500MHz	840mA	0.08ohm	13	500MHz	6000MHz
LQP03TN0N6C00□	0.6nH±0.2nH	500MHz	840mA	0.08ohm	13	500MHz	6000MHz
LQP03TN0N7B00□	0.7nH±0.1nH	500MHz	820mA	0.09ohm	13	500MHz	6000MHz
LQP03TN0N8B00□	0.8nH±0.1nH	500MHz	820mA	0.09ohm	13	500MHz	6000MHz
LQP03TN0N8C00□	0.8nH±0.2nH	500MHz	820mA	0.09ohm	13	500MHz	6000MHz
LQP03TN0N9B00□	0.9nH±0.1nH	500MHz	800mA	0.10ohm	13	500MHz	6000MHz
LQP03TN1N0B00□	1.0nH±0.1nH	500MHz	800mA	0.10ohm	13	500MHz	6000MHz
LQP03TN1N0C00□	1.0nH±0.2nH	500MHz	800mA	0.10ohm	13	500MHz	6000MHz
LQP03TN1N1B00□	1.1nH±0.1nH	500MHz	560mA	0.13ohm	13	500MHz	6000MHz
LQP03TN1N2B00□	1.2nH±0.1nH	500MHz	560mA	0.13ohm	13	500MHz	6000MHz
LQP03TN1N2C00□	1.2nH±0.2nH	500MHz	560mA	0.13ohm	13	500MHz	6000MHz
LQP03TN1N3B00□	1.3nH±0.1nH	500MHz	560mA	0.16ohm	13	500MHz	6000MHz
LQP03TN1N4B00□	1.4nH±0.1nH	500MHz	560mA	0.16ohm	13	500MHz	6000MHz
LQP03TN1N5B00□	1.5nH±0.1nH	500MHz	560mA	0.16ohm	13	500MHz	6000MHz

Operating Temperature Range: -40 to +85°C Only for reflow soldering.

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Continued from the preceding page.

Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQP03TN1N5C00□	1.5nH±0.2nH	500MHz	560mA	0.16ohm	13	500MHz	6000MHz
LQP03TN1N6B00□	1.6nH±0.1nH	500MHz	560mA	0.16ohm	13	500MHz	6000MHz
LQP03TN1N7B00□	1.7nH±0.1nH	500MHz	560mA	0.16ohm	13	500MHz	6000MHz
LQP03TN1N8B00□	1.8nH±0.1nH	500MHz	560mA	0.16ohm	13	500MHz	6000MHz
LQP03TN1N8C00□	1.8nH±0.2nH	500MHz	560mA	0.16ohm	13	500MHz	6000MHz
LQP03TN1N9B00□	1.9nH±0.1nH	500MHz	440mA	0.18ohm	13	500MHz	6000MHz
LQP03TN2N0B00□	2.0nH±0.1nH	500MHz	440mA	0.18ohm	13	500MHz	6000MHz
LQP03TN2N1B00□	2.1nH±0.1nH	500MHz	440mA	0.18ohm	13	500MHz	6000MHz
LQP03TN2N2B00□	2.2nH±0.1nH	500MHz	440mA	0.18ohm	13	500MHz	6000MHz
LQP03TN2N2C00□	2.2nH±0.2nH	500MHz	440mA	0.18ohm	13	500MHz	6000MHz
LQP03TN2N3B00□	2.3nH±0.1nH	500MHz	440mA	0.21ohm	13	500MHz	6000MHz
LQP03TN2N4B00□	2.4nH±0.1nH	500MHz	440mA	0.21ohm	13	500MHz	6000MHz
LQP03TN2N5B00□	2.5nH±0.1nH	500MHz	440mA	0.21ohm	13	500MHz	6000MHz
LQP03TN2N6B00□	2.6nH±0.1nH	500MHz	440mA	0.21ohm	13	500MHz	6000MHz
LQP03TN2N7B00□	2.7nH±0.1nH	500MHz	440mA	0.21ohm	13	500MHz	6000MHz
LQP03TN2N7C00□	2.7nH±0.2nH	500MHz	440mA	0.21ohm	13	500MHz	6000MHz
LQP03TN2N8B00□	2.8nH±0.1nH	500MHz	440mA	0.21ohm	13	500MHz	6000MHz
LQP03TN2N9B00□	2.9nH±0.1nH	500MHz	440mA	0.21ohm	13	500MHz	6000MHz
LQP03TN3N0B00□	3.0nH±0.1nH	500MHz	380mA	0.30ohm	13	500MHz	6000MHz
LQP03TN3N1B00□	3.1nH±0.1nH	500MHz	380mA	0.30ohm	13	500MHz	6000MHz
LQP03TN3N2B00□	3.2nH±0.1nH	500MHz	380mA	0.30ohm	13	500MHz	6000MHz
LQP03TN3N3B00□	3.3nH±0.1nH	500MHz	380mA	0.30ohm	13	500MHz	6000MHz
LQP03TN3N3C00□	3.3nH±0.2nH	500MHz	380mA	0.30ohm	13	500MHz	6000MHz
LQP03TN3N4B00□	3.4nH±0.1nH	500MHz	380mA	0.30ohm	13	500MHz	6000MHz
LQP03TN3N5B00□	3.5nH±0.1nH	500MHz	380mA	0.30ohm	13	500MHz	6000MHz
LQP03TN3N6B00□	3.6nH±0.1nH	500MHz	340mA	0.45ohm	13	500MHz	6000MHz
LQP03TN3N7B00□	3.7nH±0.1nH	500MHz	340mA	0.45ohm	13	500MHz	6000MHz
LQP03TN3N8B00□	3.8nH±0.1nH	500MHz	340mA	0.45ohm	13	500MHz	6000MHz
LQP03TN3N9B00□	3.9nH±0.1nH	500MHz	340mA	0.45ohm	13	500MHz	6000MHz
LQP03TN3N9C00□	3.9nH±0.2nH	500MHz	340mA	0.45ohm	13	500MHz	6000MHz
LQP03TN4N3H00□	4.3nH±3%	500MHz	320mA	0.55ohm	13	500MHz	6000MHz
LQP03TN4N7H00□	4.7nH±3%	500MHz	320mA	0.55ohm	13	500MHz	6000MHz
LQP03TN4N7J00□	4.7nH±5%	500MHz	320mA	0.55ohm	13	500MHz	6000MHz
LQP03TN5N1H00□	5.1nH±3%	500MHz	280mA	0.68ohm	13	500MHz	6000MHz
LQP03TN5N6H00□	5.6nH±3%	500MHz	280mA	0.68ohm	13	500MHz	6000MHz
LQP03TN5N6J00□	5.6nH±5%	500MHz	280mA	0.68ohm	13	500MHz	6000MHz
LQP03TN6N2H00□	6.2nH±3%	500MHz	260mA	0.75ohm	13	500MHz	6000MHz
LQP03TN6N8H00□	6.8nH±3%	500MHz	260mA	0.75ohm	13	500MHz	6000MHz
LQP03TN6N8J00□	6.8nH±5%	500MHz	260mA	0.75ohm	13	500MHz	6000MHz
LQP03TN7N5H00□	7.5nH±3%	500MHz	220mA	0.86ohm	13	500MHz	5500MHz
LQP03TN8N2H00□	8.2nH±3%	500MHz	220mA	0.86ohm	13	500MHz	5500MHz
LQP03TN8N2J00□	8.2nH±5%	500MHz	220mA	0.86ohm	13	500MHz	5500MHz
LQP03TN9N1H00□	9.1nH±3%	500MHz	200mA	1.10ohm	13	500MHz	4500MHz
LQP03TN10NH00□	10nH±3%	500MHz	200mA	1.10ohm	13	500MHz	4500MHz
LQP03TN10NJ00□	10nH±5%	500MHz	200mA	1.10ohm	13	500MHz	4500MHz
LQP03TN12NH00□	12nH±3%	500MHz	180mA	1.25ohm	11	500MHz	3700MHz
LQP03TN12NJ00□	12nH±5%	500MHz	180mA	1.25ohm	11	500MHz	3700MHz
LQP03TN15NH00□	15nH±3%	500MHz	180mA	1.40ohm	11	500MHz	3300MHz
LQP03TN15NJ00□	15nH±5%	500MHz	180mA	1.40ohm	11	500MHz	3300MHz
LQP03TN18NH00□	18nH±3%	500MHz	160mA	1.60ohm	11	500MHz	3100MHz
LQP03TN18NJ00□	18nH±5%	500MHz	160mA	1.60ohm	11	500MHz	3100MHz

Operating Temperature Range: -40 to +85°C Only for reflow soldering.

Continued on the following page.

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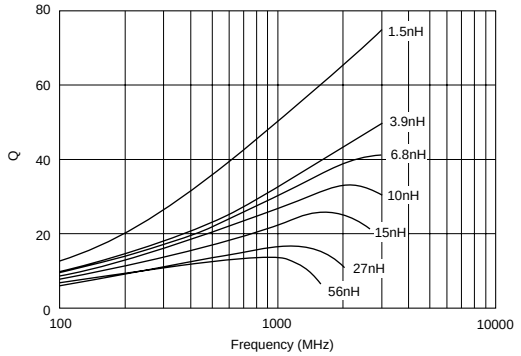
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQP03TN22NH00□	22nH±3%	500MHz	140mA	2.55ohm	11	500MHz	2800MHz
LQP03TN22NJ00□	22nH±5%	500MHz	140mA	2.55ohm	11	500MHz	2800MHz
LQP03TN27NH00□	27nH±3%	500MHz	140mA	2.90ohm	11	500MHz	2500MHz
LQP03TN27NJ00□	27nH±5%	500MHz	140mA	2.90ohm	11	500MHz	2500MHz
LQP03TN33NJ00□	33nH±5%	300MHz	120mA	2.95ohm	8	300MHz	2000MHz
LQP03TN39NJ00□	39nH±5%	300MHz	120mA	3.35ohm	8	300MHz	1800MHz
LQP03TN47NJ00□	47nH±5%	300MHz	100mA	3.60ohm	8	300MHz	1600MHz
LQP03TN56NJ00□	56nH±5%	300MHz	100mA	4.30ohm	8	300MHz	1400MHz

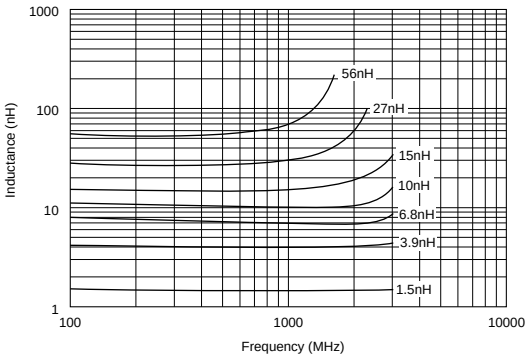
Operating Temperature Range: -40 to +85°C Only for reflow soldering.

3

■ Q-Frequency Characteristics (Typ.)



■ Inductance-Frequency Characteristics (Typ.)



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■ Reference Data

E4991A & 16197A

Part Number	Inductance (nH) (typ.)					Q (Typ.)				
	800MHz	900MHz	1.8GHz	2.0GHz	2.4GHz	800MHz	900MHz	1.8GHz	2.0GHz	2.4GHz
LQP03TN0N6	0.6	0.6	0.6	0.6	0.6	50 min.	54 min.	70 min.	73 min.	77 min.
LQP03TN0N7	0.7	0.7	0.7	0.7	0.7	50 min.	54 min.	70 min.	73 min.	77 min.
LQP03TN0N8	0.8	0.8	0.8	0.8	0.8	50 min.	54 min.	70 min.	73 min.	77 min.
LQP03TN0N9	0.9	0.9	0.9	0.9	0.9	50 min.	54 min.	70 min.	73 min.	77 min.
LQP03TN1N0	1.0	1.0	1.0	1.0	1.0	50 min.	54 min.	70 min.	73 min.	77 min.
LQP03TN1N1	1.1	1.1	1.1	1.1	1.1	50 min.	54 min.	70 min.	73 min.	77 min.
LQP03TN1N2	1.2	1.2	1.2	1.2	1.2	50	54	70	73	77
LQP03TN1N3	1.3	1.3	1.3	1.3	1.3	48	52	67	72	74
LQP03TN1N5	1.5	1.5	1.5	1.5	1.5	45	48	63	66	69
LQP03TN1N6	1.6	1.6	1.6	1.6	1.6	43	47	57	64	67
LQP03TN1N8	1.8	1.8	1.8	1.8	1.8	36	38	50	53	55
LQP03TN2N0	2.0	2.0	2.0	2.0	2.0	38	40	52	54	57
LQP03TN2N2	2.2	2.2	2.2	2.2	2.2	28	35	49	52	54
LQP03TN2N4	2.4	2.4	2.4	2.4	2.4	36	38	50	53	56
LQP03TN2N7	2.7	2.7	2.7	2.7	2.7	28	30	40	42	44
LQP03TN3N0	3.0	3.0	3.0	3.0	3.0	28	29	39	41	43
LQP03TN3N3	3.3	3.3	3.3	3.3	3.4	29	31	42	43	45
LQP03TN3N6	3.6	3.6	3.6	3.7	3.7	31	33	43	45	47
LQP03TN3N9	3.9	3.9	3.9	4.0	4.1	29	31	41	43	45
LQP03TN4N3	4.3	4.3	4.3	4.4	4.5	28	30	40	42	44
LQP03TN4N7	4.7	4.7	4.8	4.9	5.1	28	30	40	42	43
LQP03TN5N1	5.1	5.1	5.2	5.3	5.5	26	28	37	39	40
LQP03TN5N6	5.6	5.6	5.8	5.9	6.1	22	24	32	33	33
LQP03TN6N2	6.2	6.2	6.5	6.6	6.9	20	21	27	28	28
LQP03TN6N8	6.8	6.8	7.1	7.4	7.7	21	22	29	30	30
LQP03TN7N5	7.5	7.5	7.9	8.2	8.7	21	22	28	30	29
LQP03TN8N2	8.2	8.2	8.6	9.1	9.6	18	19	25	25	24
LQP03TN9N1	9.1	9.1	9.9	10	11	20	21	26	26	25
LQP03TN10N	10	10	11	12	13	21	22	28	28	27
LQP03TN12N	12	12	13	14	16	21	22	27	27	25
LQP03TN15N	15	15	18	19	23	21	21	25	24	22
LQP03TN18N	18	18	24	-	-	18	19	20	-	-
LQP03TN22N	22	23	32	-	-	16	17	16	-	-
LQP03TN27N	28	29	47	-	-	15	15	13	-	-
LQP03TN33N	35	36	-	-	-	18	19	-	-	-
LQP03TN39N	42	44	-	-	-	15	15	-	-	-
LQP03TN47N	55	58	-	-	-	14	14	-	-	-
LQP03TN56N	63	67	-	-	-	13	13	-	-	-

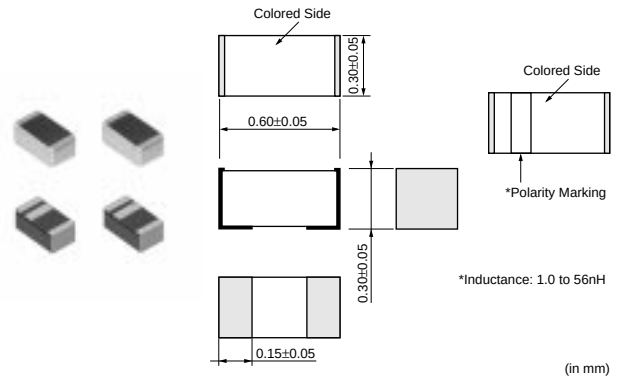
Inductor for High Frequency Film Type

muRata

LQP03T_04 Series (0201 Size)

LQP03T_04 series offers ultra small size using Murata's miniature manufacturing technology.
By this, LQP03T_04 series contributes to miniaturization of equipment.
Also, its highest class Q characteristic compared to other Monolithic inductors, enables higher performance of equipment.
Furthermore, it enables easy impedance matching at both RF and IF circuits, and compact high frequency circuit designing because it realizes 0.1nH step at 0.6 to 3.9nH and E24 step at 4.3 to 10nH.

■ Dimension



(in mm)

■ Features

1. Ultra small size 0.6x0.3x0.3mm
2. High Q value in high frequency range
3. 0.1nH step
   0.6 to 3.9nH: +-0.1nH, +-0.2nH
   E24 step
   4.3 to 10nH: +-3%
   E12 step
   4.7 to 27nH: +-3%, +-5%
   33 to 56nH: +-5%
4. Au Electrode

■ Applications

1. High frequency circuits of mobile phones such as PA, ANT, VCO, SAW, etc.
2. Mobile phone
3. "Bluetooth"
4. W-LAN
5. High frequency circuits in general

■ Rated Value (□: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQP03TN0N6B04□	0.6nH±0.1nH	500MHz	420mA	0.08ohm	13	500MHz	6000MHz
LQP03TN0N6C04□	0.6nH±0.2nH	500MHz	420mA	0.08ohm	13	500MHz	6000MHz
LQP03TN0N7B04□	0.7nH±0.1nH	500MHz	410mA	0.09ohm	13	500MHz	6000MHz
LQP03TN0N8B04□	0.8nH±0.1nH	500MHz	410mA	0.09ohm	13	500MHz	6000MHz
LQP03TN0N8C04□	0.8nH±0.2nH	500MHz	410mA	0.09ohm	13	500MHz	6000MHz
LQP03TN0N9B04□	0.9nH±0.1nH	500MHz	400mA	0.10ohm	13	500MHz	6000MHz
LQP03TN1N0B04□	1.0nH±0.1nH	500MHz	400mA	0.10ohm	13	500MHz	6000MHz
LQP03TN1N0C04□	1.0nH±0.2nH	500MHz	400mA	0.10ohm	13	500MHz	6000MHz
LQP03TN1N1B04□	1.1nH±0.1nH	500MHz	280mA	0.13ohm	13	500MHz	6000MHz
LQP03TN1N2B04□	1.2nH±0.1nH	500MHz	280mA	0.13ohm	13	500MHz	6000MHz
LQP03TN1N2C04□	1.2nH±0.2nH	500MHz	280mA	0.13ohm	13	500MHz	6000MHz
LQP03TN1N3B04□	1.3nH±0.1nH	500MHz	280mA	0.16ohm	13	500MHz	6000MHz
LQP03TN1N4B04□	1.4nH±0.1nH	500MHz	280mA	0.16ohm	13	500MHz	6000MHz
LQP03TN1N5B04□	1.5nH±0.1nH	500MHz	280mA	0.16ohm	13	500MHz	6000MHz

Operating Temperature Range: -40 to +85°C Only for reflow soldering.

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Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQP03TN1N5C04□	1.5nH±0.2nH	500MHz	280mA	0.16ohm	13	500MHz	6000MHz
LQP03TN1N6B04□	1.6nH±0.1nH	500MHz	280mA	0.16ohm	13	500MHz	6000MHz
LQP03TN1N7B04□	1.7nH±0.1nH	500MHz	280mA	0.16ohm	13	500MHz	6000MHz
LQP03TN1N8B04□	1.8nH±0.1nH	500MHz	280mA	0.16ohm	13	500MHz	6000MHz
LQP03TN1N8C04□	1.8nH±0.2nH	500MHz	280mA	0.16ohm	13	500MHz	6000MHz
LQP03TN1N9B04□	1.9nH±0.1nH	500MHz	220mA	0.18ohm	13	500MHz	6000MHz
LQP03TN2N0B04□	2.0nH±0.1nH	500MHz	220mA	0.18ohm	13	500MHz	6000MHz
LQP03TN2N1B04□	2.1nH±0.1nH	500MHz	220mA	0.18ohm	13	500MHz	6000MHz
LQP03TN2N2B04□	2.2nH±0.1nH	500MHz	220mA	0.18ohm	13	500MHz	6000MHz
LQP03TN2N2C04□	2.2nH±0.2nH	500MHz	220mA	0.18ohm	13	500MHz	6000MHz
LQP03TN2N3B04□	2.3nH±0.1nH	500MHz	220mA	0.20ohm	13	500MHz	6000MHz
LQP03TN2N4B04□	2.4nH±0.1nH	500MHz	220mA	0.20ohm	13	500MHz	6000MHz
LQP03TN2N5B04□	2.5nH±0.1nH	500MHz	220mA	0.20ohm	13	500MHz	6000MHz
LQP03TN2N6B04□	2.6nH±0.1nH	500MHz	220mA	0.20ohm	13	500MHz	6000MHz
LQP03TN2N7B04□	2.7nH±0.1nH	500MHz	220mA	0.20ohm	13	500MHz	6000MHz
LQP03TN2N7C04□	2.7nH±0.2nH	500MHz	220mA	0.20ohm	13	500MHz	6000MHz
LQP03TN2N8B04□	2.8nH±0.1nH	500MHz	220mA	0.20ohm	13	500MHz	6000MHz
LQP03TN2N9B04□	2.9nH±0.1nH	500MHz	220mA	0.20ohm	13	500MHz	6000MHz
LQP03TN3N0B04□	3.0nH±0.1nH	500MHz	190mA	0.20ohm	13	500MHz	6000MHz
LQP03TN3N1B04□	3.1nH±0.1nH	500MHz	190mA	0.20ohm	13	500MHz	6000MHz
LQP03TN3N2B04□	3.2nH±0.1nH	500MHz	190mA	0.20ohm	13	500MHz	6000MHz
LQP03TN3N3B04□	3.3nH±0.1nH	500MHz	190mA	0.20ohm	13	500MHz	6000MHz
LQP03TN3N3C04□	3.3nH±0.2nH	500MHz	190mA	0.20ohm	13	500MHz	6000MHz
LQP03TN3N4B04□	3.4nH±0.1nH	500MHz	190mA	0.30ohm	13	500MHz	6000MHz
LQP03TN3N5B04□	3.5nH±0.1nH	500MHz	190mA	0.30ohm	13	500MHz	6000MHz
LQP03TN3N6B04□	3.6nH±0.1nH	500MHz	170mA	0.30ohm	13	500MHz	6000MHz
LQP03TN3N7B04□	3.7nH±0.1nH	500MHz	170mA	0.30ohm	13	500MHz	6000MHz
LQP03TN3N8B04□	3.8nH±0.1nH	500MHz	170mA	0.30ohm	13	500MHz	6000MHz
LQP03TN3N9B04□	3.9nH±0.1nH	500MHz	170mA	0.30ohm	13	500MHz	6000MHz
LQP03TN3N9C04□	3.9nH±0.2nH	500MHz	170mA	0.30ohm	13	500MHz	6000MHz
LQP03TN4N3H04□	4.3nH±3%	500MHz	160mA	0.40ohm	13	500MHz	6000MHz
LQP03TN4N7H04□	4.7nH±3%	500MHz	160mA	0.40ohm	13	500MHz	6000MHz
LQP03TN4N7J04□	4.7nH±5%	500MHz	160mA	0.40ohm	13	500MHz	6000MHz
LQP03TN5N1H04□	5.1nH±3%	500MHz	140mA	0.55ohm	13	500MHz	6000MHz
LQP03TN5N6H04□	5.6nH±3%	500MHz	140mA	0.55ohm	13	500MHz	6000MHz
LQP03TN5N6J04□	5.6nH±5%	500MHz	140mA	0.55ohm	13	500MHz	6000MHz
LQP03TN6N2H04□	6.2nH±3%	500MHz	130mA	0.60ohm	13	500MHz	6000MHz
LQP03TN6N2J04□	6.2nH±5%	500MHz	130mA	0.60ohm	13	500MHz	6000MHz
LQP03TN6N8H04□	6.8nH±3%	500MHz	130mA	0.60ohm	13	500MHz	6000MHz
LQP03TN6N8J04□	6.8nH±5%	500MHz	130mA	0.60ohm	13	500MHz	6000MHz
LQP03TN7N5H04□	7.5nH±3%	500MHz	110mA	0.65ohm	13	500MHz	5500MHz
LQP03TN7N5J04□	7.5nH±5%	500MHz	110mA	0.65ohm	13	500MHz	5500MHz
LQP03TN8N2H04□	8.2nH±3%	500MHz	110mA	0.86ohm	13	500MHz	5500MHz
LQP03TN8N2J04□	8.2nH±5%	500MHz	110mA	0.86ohm	13	500MHz	5500MHz
LQP03TN9N1H04□	9.1nH±3%	500MHz	100mA	1.10ohm	13	500MHz	4500MHz
LQP03TN9N1J04□	9.1nH±5%	500MHz	100mA	1.10ohm	13	500MHz	4500MHz
LQP03TN10NH04□	10nH±3%	500MHz	100mA	1.10ohm	13	500MHz	4500MHz
LQP03TN10NJ04□	10nH±5%	500MHz	100mA	1.10ohm	13	500MHz	4500MHz
LQP03TN12NH04□	12nH±3%	500MHz	90mA	1.15ohm	11	500MHz	3700MHz
LQP03TN12NJ04□	12nH±5%	500MHz	90mA	1.15ohm	11	500MHz	3700MHz
LQP03TN15NH04□	15nH±3%	500MHz	90mA	1.40ohm	11	500MHz	3300MHz

Operating Temperature Range: -40 to +85°C Only for reflow soldering.

Continued on the following page.

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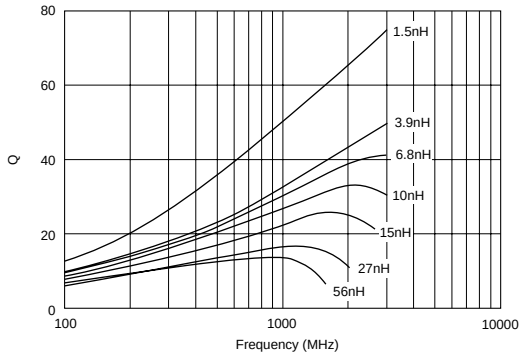
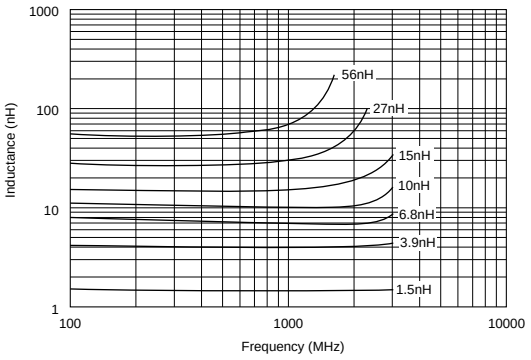
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQP03TN15NJ04□	15nH±5%	500MHz	90mA	1.40ohm	11	500MHz	3300MHz
LQP03TN18NH04□	18nH±3%	500MHz	80mA	1.60ohm	11	500MHz	3100MHz
LQP03TN18NJ04□	18nH±5%	500MHz	80mA	1.60ohm	11	500MHz	3100MHz
LQP03TN22NH04□	22nH±3%	500MHz	70mA	2.55ohm	11	500MHz	2800MHz
LQP03TN22NJ04□	22nH±5%	500MHz	70mA	2.55ohm	11	500MHz	2800MHz
LQP03TN27NH04□	27nH±3%	500MHz	70mA	2.90ohm	11	500MHz	2500MHz
LQP03TN27NJ04□	27nH±5%	500MHz	70mA	2.90ohm	11	500MHz	2500MHz
LQP03TN33NJ04□	33nH±5%	300MHz	60mA	2.95ohm	8	300MHz	2000MHz
LQP03TN39NJ04□	39nH±5%	300MHz	60mA	3.35ohm	8	300MHz	1800MHz
LQP03TN47NJ04□	47nH±5%	300MHz	50mA	3.60ohm	8	300MHz	1600MHz
LQP03TN56NJ04□	56nH±5%	300MHz	50mA	4.30ohm	8	300MHz	1400MHz

Operating Temperature Range: -40 to +85°C Only for reflow soldering.

■ Q-Frequency Characteristics (Typ.)



■ Inductance-Frequency Characteristics (Typ.)



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■ Reference Data

E4991A & 16197A

Part Number	Inductance (nH) (Typ.)					Q (Typ.)				
	800MHz	900MHz	1.8GHz	2.0GHz	2.4GHz	800MHz	900MHz	1.8GHz	2.0GHz	2.4GHz
LQP03TN0N6	0.6	0.6	0.6	0.6	0.6	50 min.	54 min.	70 min.	73 min.	77 min.
LQP03TN0N7	0.7	0.7	0.7	0.7	0.7	50 min.	54 min.	70 min.	73 min.	77 min.
LQP03TN0N8	0.8	0.8	0.8	0.8	0.8	50 min.	54 min.	70 min.	73 min.	77 min.
LQP03TN0N9	0.9	0.9	0.9	0.9	0.9	50 min.	54 min.	70 min.	73 min.	77 min.
LQP03TN1N0	1.0	1.0	1.0	1.0	1.0	50 min.	54 min.	70 min.	73 min.	77 min.
LQP03TN1N1	1.1	1.1	1.1	1.1	1.1	50 min.	54 min.	70 min.	73 min.	77 min.
LQP03TN1N2	1.2	1.2	1.2	1.2	1.2	50	54	70	73	77
LQP03TN1N3	1.3	1.3	1.3	1.3	1.3	48	52	67	72	74
LQP03TN1N5	1.5	1.5	1.5	1.5	1.5	45	48	63	66	69
LQP03TN1N6	1.6	1.6	1.6	1.6	1.6	43	47	57	64	67
LQP03TN1N8	1.8	1.8	1.8	1.8	1.8	36	38	50	53	55
LQP03TN2N0	2.0	2.0	2.0	2.0	2.0	38	40	52	54	57
LQP03TN2N2	2.2	2.2	2.2	2.2	2.2	28	35	49	52	54
LQP03TN2N4	2.4	2.4	2.4	2.4	2.4	36	38	50	53	56
LQP03TN2N7	2.7	2.7	2.7	2.7	2.7	28	30	40	42	44
LQP03TN3N0	3.0	3.0	3.0	3.0	3.0	28	29	39	41	43
LQP03TN3N3	3.3	3.3	3.3	3.3	3.4	29	31	42	43	45
LQP03TN3N6	3.6	3.6	3.6	3.7	3.7	31	33	43	45	47
LQP03TN3N9	3.9	3.9	3.9	4.0	4.1	29	31	41	43	45
LQP03TN4N3	4.3	4.3	4.3	4.4	4.5	28	30	40	42	44
LQP03TN4N7	4.7	4.7	4.8	4.9	5.1	28	30	40	42	43
LQP03TN5N1	5.1	5.1	5.2	5.3	5.5	26	28	37	39	40
LQP03TN5N6	5.6	5.6	5.8	5.9	6.1	26	28	36	38	39
LQP03TN6N8	6.8	6.8	7.1	7.4	7.7	26	28	36	38	39
LQP03TN8N2	8.2	8.2	8.6	9.1	9.6	26	28	36	37	38
LQP03TN10N	10	10	11	12	13	24	25	32	32	32
LQP03TN12N	12	12	13	14	16	21	22	27	27	25
LQP03TN15N	15	15	18	19	23	21	21	25	24	22
LQP03TN18N	18	18	24	-	-	18	19	20	-	-
LQP03TN22N	22	23	32	-	-	16	17	16	-	-
LQP03TN27N	28	29	47	-	-	15	15	13	-	-
LQP03TN33N	35	36	-	-	-	18	19	-	-	-
LQP03TN39N	42	44	-	-	-	15	15	-	-	-
LQP03TN47N	55	58	-	-	-	14	14	-	-	-
LQP03TN56N	63	67	-	-	-	13	13	-	-	-

Inductor for High Frequency Film Type

LQP15T Series (0402 Size)

LQP15T series offers High Q value, tight inductance tolerance within a small/thin package using Murata's original film engineering technology.

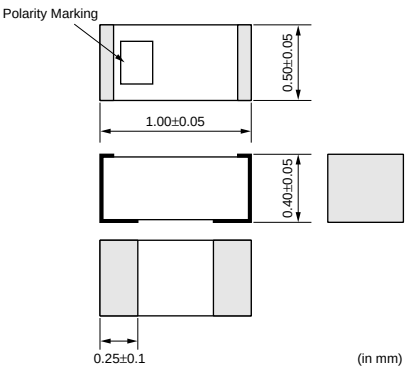
■ Features

1. High Q value
2. Tight inductance tolerance (+-0.1nH, +-0.2nH, +-3%)
3. Ultra small and thin size (0402 size, height 0.4mm)
4. Low DC resistance

■ Applications

1. High frequency circuits of mobile phones such as PA, ANT, VCO, SAW, etc.
2. Mobile phones
3. "Bluetooth"
4. W-LAN
5. High frequency circuits in general

■ Dimension



■ Rated Value (☐: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQP15TN1N0B02☐	1.0nH±0.1nH	500MHz	300mA	0.1ohm	17	500MHz	6000MHz
LQP15TN1N0C02☐	1.0nH±0.2nH	500MHz	300mA	0.1ohm	17	500MHz	6000MHz
LQP15TN1N1B02☐	1.1nH±0.1nH	500MHz	300mA	0.1ohm	17	500MHz	6000MHz
LQP15TN1N1C02☐	1.1nH±0.2nH	500MHz	300mA	0.1ohm	17	500MHz	6000MHz
LQP15TN1N2B02☐	1.2nH±0.1nH	500MHz	300mA	0.1ohm	17	500MHz	6000MHz
LQP15TN1N2C02☐	1.2nH±0.2nH	500MHz	300mA	0.1ohm	17	500MHz	6000MHz
LQP15TN1N3B02☐	1.3nH±0.1nH	500MHz	300mA	0.15ohm	17	500MHz	6000MHz
LQP15TN1N3C02☐	1.3nH±0.2nH	500MHz	300mA	0.15ohm	17	500MHz	6000MHz
LQP15TN1N5B02☐	1.5nH±0.1nH	500MHz	300mA	0.15ohm	17	500MHz	6000MHz
LQP15TN1N5C02☐	1.5nH±0.2nH	500MHz	300mA	0.15ohm	17	500MHz	6000MHz
LQP15TN1N6B02☐	1.6nH±0.1nH	500MHz	250mA	0.15ohm	17	500MHz	6000MHz
LQP15TN1N6C02☐	1.6nH±0.2nH	500MHz	250mA	0.15ohm	17	500MHz	6000MHz
LQP15TN1N8B02☐	1.8nH±0.1nH	500MHz	250mA	0.15ohm	17	500MHz	6000MHz
LQP15TN1N8C02☐	1.8nH±0.2nH	500MHz	250mA	0.15ohm	17	500MHz	6000MHz
LQP15TN2N0C02☐	2.0nH±0.2nH	500MHz	220mA	0.2ohm	17	500MHz	6000MHz
LQP15TN2N2C02☐	2.2nH±0.2nH	500MHz	220mA	0.2ohm	17	500MHz	6000MHz
LQP15TN2N4C02☐	2.4nH±0.2nH	500MHz	220mA	0.2ohm	17	500MHz	6000MHz
LQP15TN2N7C02☐	2.7nH±0.2nH	500MHz	220mA	0.2ohm	17	500MHz	6000MHz
LQP15TN3N0C02☐	3.0nH±0.2nH	500MHz	190mA	0.3ohm	17	500MHz	5500MHz
LQP15TN3N3C02☐	3.3nH±0.2nH	500MHz	190mA	0.3ohm	17	500MHz	5500MHz
LQP15TN3N6C02☐	3.6nH±0.2nH	500MHz	170mA	0.3ohm	17	500MHz	5500MHz
LQP15TN3N9C02☐	3.9nH±0.2nH	500MHz	170mA	0.4ohm	17	500MHz	5500MHz
LQP15TN4N7C02☐	4.7nH±0.2nH	500MHz	160mA	0.5ohm	17	500MHz	5000MHz
LQP15TN5N6C02☐	5.6nH±0.2nH	500MHz	140mA	0.6ohm	17	500MHz	4500MHz
LQP15TN6N8H02☐	6.8nH±3%	500MHz	130mA	0.7ohm	17	500MHz	3500MHz
LQP15TN8N2H02☐	8.2nH±3%	500MHz	110mA	0.8ohm	17	500MHz	3000MHz
LQP15TN10NH02☐	10nH±3%	500MHz	100mA	1.0ohm	17	500MHz	2500MHz

Operating Temperature Range: -40°C to +85°C Only for reflow soldering.

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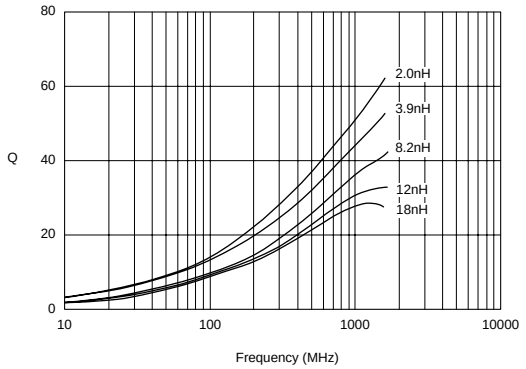
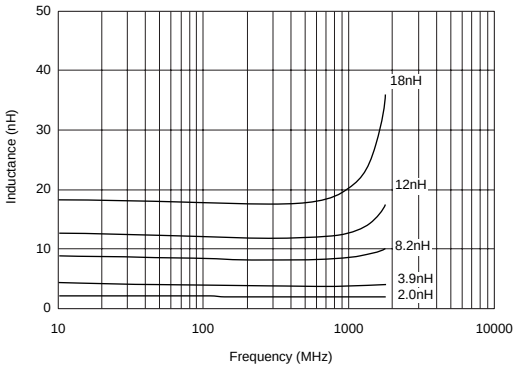
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQP15TN12NH02□	12nH±3%	500MHz	90mA	1.0ohm	17	500MHz	2500MHz
LQP15TN15NH02□	15nH±3%	500MHz	90mA	1.3ohm	17	500MHz	2000MHz
LQP15TN18NH02□	18nH±3%	500MHz	80mA	1.5ohm	17	500MHz	1500MHz

Operating Temperature Range: -40°C to +85°C Only for reflow soldering.

■ Q-Frequency Characteristics (Typ.)



■ Inductance-Frequency Characteristics (Typ.)



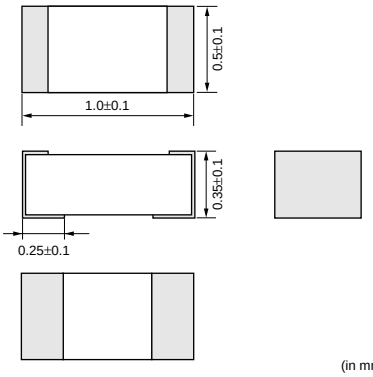
Inductor for High Frequency Film Type

LQP15M Series (0402 Size)

■ Features

1. Tight inductance tolerance (+-0.05nH, +-0.1nH, +-2%) realized by Murata's original film technology. Various inductance values enable assembly with no tuning.
2. Ultra small size 0402 inductor which is low profile and lightest weight in the world enables miniaturizing of mobile telecommunications equipment. LQP15M series weighs 0.6mg/pc. while multilayer type inductor weighs 0.9mg/pc.
3. High Q at high frequency range.
4. High self-resonant frequency due to low stray capacitance and narrow inductance distribution provides stable inductance in high frequency circuits such as telecommunications equipment.

■ Dimension



(in mm)

■ Applications

1. High frequency circuits of mobile phones such as PA, ANT, VCO, SAW, etc.
2. Mobile phones
3. "Bluetooth"
4. W-LAN
5. High frequency circuits in general

■ Rated Value (☐: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQP15MN1N0B02☐	1.0nH±0.1nH	500MHz	400mA	0.1ohm	13	500MHz	6000MHz
LQP15MN1N0W02☐	1.0nH±0.05nH	500MHz	400mA	0.1ohm	13	500MHz	6000MHz
LQP15MN1N1B02☐	1.1nH±0.1nH	500MHz	390mA	0.1ohm	13	500MHz	6000MHz
LQP15MN1N1W02☐	1.1nH±0.05nH	500MHz	390mA	0.1ohm	13	500MHz	6000MHz
LQP15MN1N2B02☐	1.2nH±0.1nH	500MHz	390mA	0.1ohm	13	500MHz	6000MHz
LQP15MN1N2W02☐	1.2nH±0.05nH	500MHz	390mA	0.1ohm	13	500MHz	6000MHz
LQP15MN1N3B02☐	1.3nH±0.1nH	500MHz	280mA	0.2ohm	13	500MHz	6000MHz
LQP15MN1N3W02☐	1.3nH±0.05nH	500MHz	280mA	0.2ohm	13	500MHz	6000MHz
LQP15MN1N4W02☐	1.4nH±0.05nH	500MHz	280mA	0.2ohm	13	500MHz	6000MHz
LQP15MN1N5B02☐	1.5nH±0.1nH	500MHz	280mA	0.2ohm	13	500MHz	6000MHz
LQP15MN1N5W02☐	1.5nH±0.05nH	500MHz	280mA	0.2ohm	13	500MHz	6000MHz
LQP15MN1N6B02☐	1.6nH±0.1nH	500MHz	220mA	0.3ohm	13	500MHz	6000MHz
LQP15MN1N6W02☐	1.6nH±0.05nH	500MHz	220mA	0.3ohm	13	500MHz	6000MHz
LQP15MN1N7W02☐	1.7nH±0.05nH	500MHz	280mA	0.2ohm	13	500MHz	6000MHz
LQP15MN1N8B02☐	1.8nH±0.1nH	500MHz	280mA	0.2ohm	13	500MHz	6000MHz
LQP15MN1N8W02☐	1.8nH±0.05nH	500MHz	280mA	0.2ohm	13	500MHz	6000MHz
LQP15MN1N9W02☐	1.9nH±0.05nH	500MHz	220mA	0.3ohm	13	500MHz	6000MHz
LQP15MN2N0B02☐	2.0nH±0.1nH	500MHz	220mA	0.3ohm	13	500MHz	6000MHz
LQP15MN2N0W02☐	2.0nH±0.05nH	500MHz	220mA	0.3ohm	13	500MHz	6000MHz
LQP15MN2N1W02☐	2.1nH±0.05nH	500MHz	220mA	0.3ohm	13	500MHz	6000MHz
LQP15MN2N2B02☐	2.2nH±0.1nH	500MHz	220mA	0.3ohm	13	500MHz	6000MHz
LQP15MN2N2W02☐	2.2nH±0.05nH	500MHz	220mA	0.3ohm	13	500MHz	6000MHz

Operating Temperature Range: -40°C to +85°C Only for reflow soldering.

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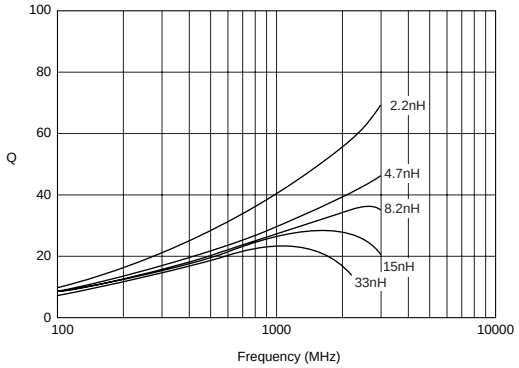
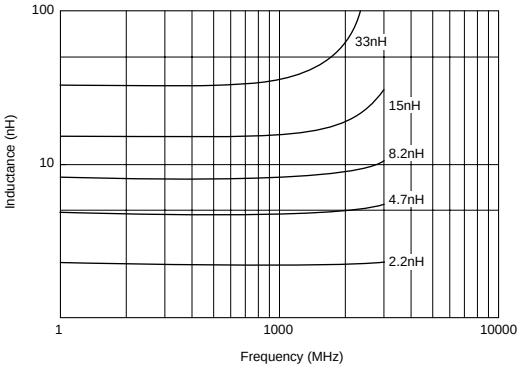
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQP15MN2N3W02□	2.3nH±0.05nH	500MHz	220mA	0.3ohm	13	500MHz	6000MHz
LQP15MN2N4B02□	2.4nH±0.1nH	500MHz	220mA	0.3ohm	13	500MHz	6000MHz
LQP15MN2N4W02□	2.4nH±0.05nH	500MHz	220mA	0.3ohm	13	500MHz	6000MHz
LQP15MN2N5W02□	2.5nH±0.05nH	500MHz	220mA	0.3ohm	13	500MHz	6000MHz
LQP15MN2N6W02□	2.6nH±0.05nH	500MHz	220mA	0.3ohm	13	500MHz	6000MHz
LQP15MN2N7B02□	2.7nH±0.1nH	500MHz	220mA	0.3ohm	13	500MHz	6000MHz
LQP15MN2N7W02□	2.7nH±0.05nH	500MHz	220mA	0.3ohm	13	500MHz	6000MHz
LQP15MN2N8W02□	2.8nH±0.05nH	500MHz	190mA	0.4ohm	13	500MHz	6000MHz
LQP15MN2N9W02□	2.9nH±0.05nH	500MHz	190mA	0.4ohm	13	500MHz	6000MHz
LQP15MN3N0B02□	3.0nH±0.1nH	500MHz	190mA	0.4ohm	13	500MHz	6000MHz
LQP15MN3N0W02□	3.0nH±0.05nH	500MHz	190mA	0.4ohm	13	500MHz	6000MHz
LQP15MN3N1W02□	3.1nH±0.05nH	500MHz	190mA	0.4ohm	13	500MHz	6000MHz
LQP15MN3N2W02□	3.2nH±0.05nH	500MHz	190mA	0.4ohm	13	500MHz	6000MHz
LQP15MN3N3B02□	3.3nH±0.1nH	500MHz	190mA	0.4ohm	13	500MHz	6000MHz
LQP15MN3N3W02□	3.3nH±0.05nH	500MHz	190mA	0.4ohm	13	500MHz	6000MHz
LQP15MN3N4W02□	3.4nH±0.05nH	500MHz	170mA	0.5ohm	13	500MHz	6000MHz
LQP15MN3N5W02□	3.5nH±0.05nH	500MHz	170mA	0.5ohm	13	500MHz	6000MHz
LQP15MN3N6B02□	3.6nH±0.1nH	500MHz	170mA	0.5ohm	13	500MHz	6000MHz
LQP15MN3N6W02□	3.6nH±0.05nH	500MHz	170mA	0.5ohm	13	500MHz	6000MHz
LQP15MN3N7W02□	3.7nH±0.05nH	500MHz	170mA	0.5ohm	13	500MHz	6000MHz
LQP15MN3N8W02□	3.8nH±0.05nH	500MHz	170mA	0.5ohm	13	500MHz	6000MHz
LQP15MN3N9B02□	3.9nH±0.1nH	500MHz	170mA	0.5ohm	13	500MHz	6000MHz
LQP15MN3N9W02□	3.9nH±0.05nH	500MHz	170mA	0.5ohm	13	500MHz	6000MHz
LQP15MN4N3B02□	4.3nH±0.1nH	500MHz	160mA	0.6ohm	13	500MHz	6000MHz
LQP15MN4N7B02□	4.7nH±0.1nH	500MHz	160mA	0.6ohm	13	500MHz	6000MHz
LQP15MN5N1B02□	5.1nH±0.1nH	500MHz	140mA	0.7ohm	13	500MHz	6000MHz
LQP15MN5N6B02□	5.6nH±0.1nH	500MHz	140mA	0.7ohm	13	500MHz	6000MHz
LQP15MN6N2B02□	6.2nH±0.1nH	500MHz	130mA	0.9ohm	13	500MHz	6000MHz
LQP15MN6N8B02□	6.8nH±0.1nH	500MHz	130mA	0.9ohm	13	500MHz	6000MHz
LQP15MN7N5B02□	7.5nH±0.1nH	500MHz	110mA	1.1ohm	13	500MHz	5500MHz
LQP15MN8N2B02□	8.2nH±0.1nH	500MHz	110mA	1.1ohm	13	500MHz	5500MHz
LQP15MN9N1B02□	9.1nH±0.1nH	500MHz	100mA	1.3ohm	13	500MHz	4500MHz
LQP15MN10NG02□	10nH±2%	500MHz	100mA	1.3ohm	13	500MHz	4500MHz
LQP15MN12NG02□	12nH±2%	500MHz	90mA	1.6ohm	13	500MHz	3700MHz
LQP15MN15NG02□	15nH±2%	500MHz	90mA	1.8ohm	13	500MHz	3300MHz
LQP15MN18NG02□	18nH±2%	500MHz	80mA	2.0ohm	13	500MHz	3100MHz
LQP15MN22NG02□	22nH±2%	500MHz	70mA	2.6ohm	13	500MHz	2800MHz
LQP15MN27NG02□	27nH±2%	500MHz	70mA	3.1ohm	13	500MHz	2500MHz
LQP15MN33NG02□	33nH±2%	500MHz	60mA	3.8ohm	13	500MHz	2100MHz

Operating Temperature Range: -40°C to +85°C Only for reflow soldering.

■ Q - Frequency Characteristics (Typ.)



■ Inductance - Frequency Characteristics (Typ.)



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■ Reference Data

E4991A+16197A

Part Number	Inductance (nH) (Typ.)					Q (Typ.)				
	800MHz	900MHz	1.8GHz	2.0GHz	2.4GHz	800MHz	900MHz	1.8GHz	2.0GHz	2.4GHz
LQP15MN1N0	1.0	1.0	1.0	1.0	1.0	50	55	73	76	85
LQP15MN1N1	1.1	1.1	1.1	1.1	1.1	44	47	70	76	83
LQP15MN1N2	1.2	1.2	1.2	1.2	1.2	43	47	69	76	82
LQP15MN1N3	1.3	1.3	1.3	1.3	1.3	39	43	56	60	65
LQP15MN1N4	1.4	1.4	1.4	1.4	1.4	39	41	51	54	58
LQP15MN1N5	1.5	1.5	1.5	1.5	1.5	38	40	49	51	54
LQP15MN1N6	1.6	1.6	1.6	1.6	1.6	26	28	37	39	42
LQP15MN1N7	1.7	1.7	1.7	1.7	1.7	37	40	48	49	53
LQP15MN1N8	1.8	1.8	1.8	1.8	1.8	35	37	46	49	52
LQP15MN1N9	1.9	1.9	1.9	1.9	1.9	34	36	46	49	52
LQP15MN2N0	2.0	2.0	2.0	2.0	2.0	34	36	47	50	53
LQP15MN2N1	2.1	2.1	2.1	2.1	2.1	35	37	47	49	53
LQP15MN2N2	2.2	2.2	2.2	2.2	2.2	36	38	48	51	56
LQP15MN2N3	2.3	2.3	2.3	2.3	2.3	36	38	47	49	53
LQP15MN2N4	2.4	2.4	2.4	2.4	2.4	35	37	47	49	52
LQP15MN2N5	2.5	2.5	2.5	2.5	2.5	35	37	47	49	53
LQP15MN2N6	2.6	2.6	2.6	2.6	2.6	35	37	47	49	52
LQP15MN2N7	2.7	2.7	2.7	2.7	2.7	35	37	48	49	53
LQP15MN2N8	2.8	2.8	2.8	2.8	2.8	35	37	47	49	53
LQP15MN2N9	2.9	2.9	2.9	2.9	2.9	33	35	44	46	49
LQP15MN3N0	3.0	3.0	3.0	3.0	3.0	29	31	41	44	48
LQP15MN3N1	3.1	3.1	3.1	3.1	3.1	28	29	39	42	45
LQP15MN3N2	3.2	3.2	3.2	3.2	3.2	27	28	35	36	38
LQP15MN3N3	3.3	3.3	3.3	3.3	3.4	28	29	38	39	43
LQP15MN3N4	3.4	3.4	3.4	3.4	3.5	28	29	37	39	41
LQP15MN3N5	3.5	3.5	3.5	3.5	3.6	28	29	37	38	40
LQP15MN3N6	3.6	3.6	3.6	3.7	3.7	27	28	35	39	41
LQP15MN3N7	3.7	3.7	3.7	3.8	3.8	27	28	35	38	41
LQP15MN3N8	3.8	3.8	3.8	3.9	3.9	28	29	38	39	42
LQP15MN3N9	3.9	3.9	3.9	4.0	4.0	28	29	37	38	41
LQP15MN4N3	4.3	4.3	4.3	4.4	4.5	28	30	38	40	42
LQP15MN4N7	4.7	4.7	4.8	4.9	5.1	28	29	38	39	41
LQP15MN5N1	5.1	5.1	5.2	5.3	5.5	26	28	36	38	40
LQP15MN5N6	5.6	5.6	5.8	6.0	6.2	23	25	32	33	34
LQP15MN6N2	6.2	6.2	6.5	6.6	6.9	23	25	32	33	34
LQP15MN6N8	6.8	6.8	7.1	7.4	7.7	24	26	33	34	35
LQP15MN7N5	7.5	7.5	7.9	8.2	8.6	24	25	32	33	34
LQP15MN8N2	8.2	8.2	8.7	9.0	9.5	24	25	32	33	34
LQP15MN9N1	9.1	9.1	9.8	10	11	23	25	31	32	33
LQP15MN10N	10	10	11	12	13	24	26	30	31	31
LQP15MN12N	12	12	13	14	16	25	26	29	29	28
LQP15MN15N	15	15	18	19	23	23	25	26	27	25
LQP15MN18N	18	18	23	-	-	22	23	24	-	-
LQP15MN22N	22	23	29	-	-	22	23	22	-	-
LQP15MN27N	28	28	38	-	-	22	23	21	-	-
LQP15MN33N	34	35	-	-	-	21	22	-	-	-

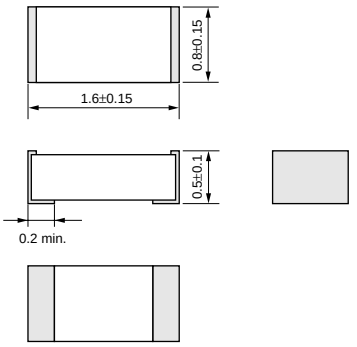
Inductor for High Frequency Film Type

LQP18M Series (0603 Size)

■ Features

1. Tight inductance tolerance (+-0.2nH, +-2%) realized by Murata's original film technology. Various inductance values enable assembly with no tuning.
2. Small size of LQP18M series is suitable for small handheld equipment, especially for card size equipment.
3. High Q at high frequency range.
4. High self-resonant frequency due to low stray capacitance and narrow inductance distribution provides stable inductance in high frequency circuits such as telecommunications equipment.

■ Dimension



(in mm)

■ Applications

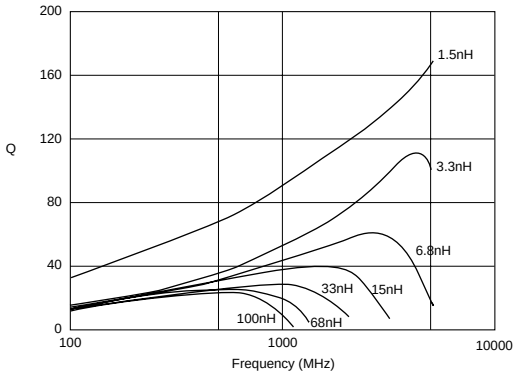
1. High frequency circuits of mobile phones such as PA, ANT, VCO, SAW, etc.
2. Mobile phones
3. "Bluetooth"
4. W-LAN
5. High frequency circuits in general

■ Rated Value (□: packaging code)

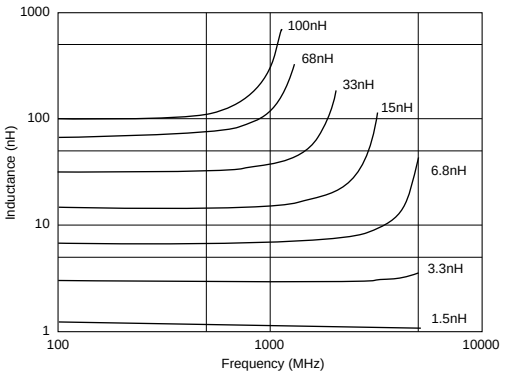
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQP18MN1N3C02□	1.3nH±0.2nH	500MHz	300mA	0.3ohm	17	500MHz	6000MHz
LQP18MN1N5C02□	1.5nH±0.2nH	500MHz	300mA	0.3ohm	17	500MHz	6000MHz
LQP18MN1N8C02□	1.8nH±0.2nH	500MHz	250mA	0.4ohm	17	500MHz	6000MHz
LQP18MN2N2C02□	2.2nH±0.2nH	500MHz	250mA	0.4ohm	17	500MHz	6000MHz
LQP18MN2N7C02□	2.7nH±0.2nH	500MHz	250mA	0.4ohm	17	500MHz	6000MHz
LQP18MN3N3C02□	3.3nH±0.2nH	500MHz	250mA	0.4ohm	17	500MHz	6000MHz
LQP18MN3N9C02□	3.9nH±0.2nH	500MHz	200mA	0.5ohm	17	500MHz	5900MHz
LQP18MN4N7C02□	4.7nH±0.2nH	500MHz	200mA	0.5ohm	17	500MHz	5200MHz
LQP18MN5N6C02□	5.6nH±0.2nH	500MHz	200mA	0.6ohm	17	500MHz	4700MHz
LQP18MN6N8C02□	6.8nH±0.2nH	500MHz	200mA	0.7ohm	17	500MHz	4300MHz
LQP18MN8N2C02□	8.2nH±0.2nH	500MHz	150mA	0.8ohm	17	500MHz	3600MHz
LQP18MN10NG02□	10nH±2%	500MHz	150mA	1.0ohm	17	500MHz	3400MHz
LQP18MN12NG02□	12nH±2%	500MHz	150mA	1.0ohm	17	500MHz	3000MHz
LQP18MN15NG02□	15nH±2%	500MHz	150mA	1.3ohm	17	500MHz	2700MHz
LQP18MN18NG02□	18nH±2%	500MHz	100mA	1.5ohm	17	500MHz	2300MHz
LQP18MN22NG02□	22nH±2%	500MHz	100mA	1.9ohm	17	500MHz	2100MHz
LQP18MN27NG02□	27nH±2%	500MHz	100mA	2.4ohm	17	500MHz	1900MHz
LQP18MN33NG02□	33nH±2%	500MHz	100mA	2.8ohm	17	500MHz	1700MHz
LQP18MN39NG02□	39nH±2%	500MHz	100mA	2.8ohm	17	500MHz	1400MHz
LQP18MN47NG02□	47nH±2%	300MHz	100mA	2.2ohm	17	300MHz	1200MHz
LQP18MN56NG02□	56nH±2%	300MHz	50mA	3.4ohm	17	300MHz	1000MHz
LQP18MN68NG02□	68nH±2%	300MHz	50mA	3.5ohm	17	300MHz	900MHz
LQP18MN82NG02□	82nH±2%	300MHz	50mA	4.6ohm	17	300MHz	800MHz
LQP18MNR10G02□	100nH±2%	300MHz	50mA	6.1ohm	17	300MHz	700MHz

Operating Temperature Range: -40°C to +85°C Only for reflow soldering.

■ Q - Frequency Characteristics (Typ.)



■ Inductance - Frequency Characteristics (Typ.)



Inductor for High Frequency Wire Wound Type Air Core (Horizontal Wire Wound)

muRata

LQW04A Series (03015 Size)

LQW04A series consists of air core chip inductor using a miniature alumina core.
LQW04A series has high Q value in high frequency range and high self-resonant frequency. It is suitable for high frequency circuits which are used in telecommunications equipment.

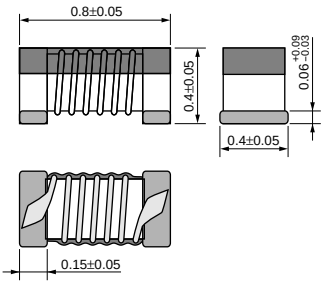
■ Features

1. Horizontal wire wound structure.
2. The subminiature dimensions (0.8x0.4mm) allow high density mounting, and 0.4mm low profile.
3. The high self-resonant frequency realizes high Q value and stable inductance at high frequency.
4. Low DC resistance design is ideal for low loss, high output and low power consumption.
5. Resin-coated surface enables excellent mounting.

■ Applications

1. High frequency module of mobile phones such as PA, ANT, VCO, SAW, etc.
2. Mobile phones
3. Digital TV tuner
4. W-LAN
5. "Bluetooth"
6. High frequency circuits in general

■ Dimension



(in mm)

■ Rated Value (☐: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQW04AN1N1C00☐	1.1nH±0.2nH	100MHz	990mA	0.03ohm	15	250MHz	20.0GHz
LQW04AN1N1D00☐	1.1nH±0.5nH	100MHz	990mA	0.03ohm	15	250MHz	20.0GHz
LQW04AN1N8C00☐	1.8nH±0.2nH	100MHz	700mA	0.06ohm	15	250MHz	17.0GHz
LQW04AN1N8D00☐	1.8nH±0.5nH	100MHz	700mA	0.06ohm	15	250MHz	17.0GHz
LQW04AN2N7C00☐	2.7nH±0.2nH	100MHz	570mA	0.07ohm	15	250MHz	15.0GHz
LQW04AN2N7D00☐	2.7nH±0.5nH	100MHz	570mA	0.07ohm	15	250MHz	15.0GHz
LQW04AN3N0C00☐	3.0nH±0.2nH	100MHz	620mA	0.07ohm	15	250MHz	13.0GHz
LQW04AN3N0D00☐	3.0nH±0.5nH	100MHz	620mA	0.07ohm	15	250MHz	13.0GHz
LQW04AN3N6C00☐	3.6nH±0.2nH	100MHz	530mA	0.10ohm	15	250MHz	13.0GHz
LQW04AN3N6D00☐	3.6nH±0.5nH	100MHz	530mA	0.10ohm	15	250MHz	13.0GHz
LQW04AN3N9C00☐	3.9nH±0.2nH	100MHz	530mA	0.10ohm	15	250MHz	12.0GHz
LQW04AN3N9D00☐	3.9nH±0.5nH	100MHz	530mA	0.10ohm	15	250MHz	12.0GHz
LQW04AN4N3C00☐	4.3nH±0.2nH	100MHz	530mA	0.10ohm	15	250MHz	11.0GHz
LQW04AN4N3D00☐	4.3nH±0.5nH	100MHz	530mA	0.10ohm	15	250MHz	11.0GHz
LQW04AN4N7C00☐	4.7nH±0.2nH	100MHz	440mA	0.14ohm	20	250MHz	10.0GHz
LQW04AN4N7D00☐	4.7nH±0.5nH	100MHz	440mA	0.14ohm	20	250MHz	10.0GHz
LQW04AN5N1C00☐	5.1nH±0.2nH	100MHz	470mA	0.12ohm	20	250MHz	10.0GHz
LQW04AN5N1D00☐	5.1nH±0.5nH	100MHz	470mA	0.12ohm	20	250MHz	10.0GHz
LQW04AN5N6C00☐	5.6nH±0.2nH	100MHz	470mA	0.12ohm	20	250MHz	9.0GHz

Operating Temperature Range: -55°C to +125°C Only for reflow soldering.

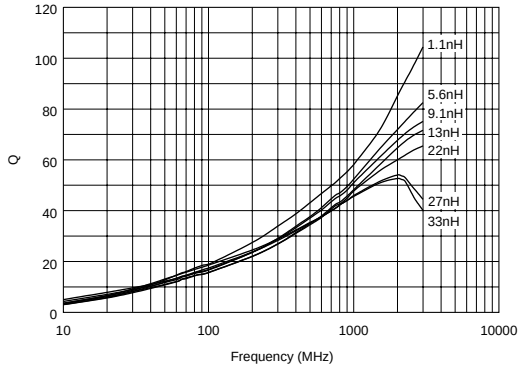
Continued on the following page.

Continued from the preceding page.

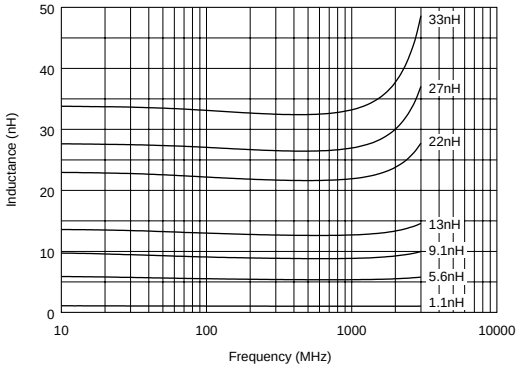
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQW04AN5N6D00□	5.6nH±0.5nH	100MHz	470mA	0.12ohm	20	250MHz	9.0GHz
LQW04AN6N2C00□	6.2nH±0.2nH	100MHz	390mA	0.19ohm	20	250MHz	9.0GHz
LQW04AN6N2D00□	6.2nH±0.5nH	100MHz	390mA	0.19ohm	20	250MHz	9.0GHz
LQW04AN6N8C00□	6.8nH±0.2nH	100MHz	440mA	0.14ohm	20	250MHz	9.0GHz
LQW04AN6N8D00□	6.8nH±0.5nH	100MHz	440mA	0.14ohm	20	250MHz	9.0GHz
LQW04AN7N5C00□	7.5nH±0.2nH	100MHz	440mA	0.14ohm	20	250MHz	8.0GHz
LQW04AN7N5D00□	7.5nH±0.5nH	100MHz	440mA	0.14ohm	20	250MHz	8.0GHz
LQW04AN8N2C00□	8.2nH±0.2nH	100MHz	350mA	0.23ohm	20	250MHz	8.0GHz
LQW04AN8N2D00□	8.2nH±0.5nH	100MHz	350mA	0.23ohm	20	250MHz	8.0GHz
LQW04AN9N1C00□	9.1nH±0.2nH	100MHz	400mA	0.16ohm	20	250MHz	7.0GHz
LQW04AN9N1D00□	9.1nH±0.5nH	100MHz	400mA	0.16ohm	20	250MHz	7.0GHz
LQW04AN10NH00□	10nH±3%	100MHz	330mA	0.26ohm	20	250MHz	7.0GHz
LQW04AN10NJ00□	10nH±5%	100MHz	330mA	0.26ohm	20	250MHz	7.0GHz
LQW04AN11NH00□	11nH±3%	100MHz	310mA	0.28ohm	15	250MHz	7.0GHz
LQW04AN11NJ00□	11nH±5%	100MHz	310mA	0.28ohm	15	250MHz	7.0GHz
LQW04AN12NH00□	12nH±3%	100MHz	310mA	0.28ohm	15	250MHz	6.0GHz
LQW04AN12NJ00□	12nH±5%	100MHz	310mA	0.28ohm	15	250MHz	6.0GHz
LQW04AN13NH00□	13nH±3%	100MHz	280mA	0.34ohm	15	250MHz	6.0GHz
LQW04AN13NJ00□	13nH±5%	100MHz	280mA	0.34ohm	15	250MHz	6.0GHz
LQW04AN15NH00□	15nH±3%	100MHz	240mA	0.48ohm	15	250MHz	5.5GHz
LQW04AN15NJ00□	15nH±5%	100MHz	240mA	0.48ohm	15	250MHz	5.5GHz
LQW04AN16NH00□	16nH±3%	100MHz	270mA	0.38ohm	15	250MHz	5.5GHz
LQW04AN16NJ00□	16nH±5%	100MHz	270mA	0.38ohm	15	250MHz	5.5GHz
LQW04AN18NH00□	18nH±3%	100MHz	220mA	0.54ohm	15	250MHz	5.0GHz
LQW04AN18NJ00□	18nH±5%	100MHz	220mA	0.54ohm	15	250MHz	5.0GHz
LQW04AN19NH00□	19nH±3%	100MHz	160mA	0.73ohm	15	250MHz	5.0GHz
LQW04AN19NJ00□	19nH±5%	100MHz	160mA	0.73ohm	15	250MHz	5.0GHz
LQW04AN20NH00□	20nH±3%	100MHz	210mA	0.56ohm	15	250MHz	5.0GHz
LQW04AN20NJ00□	20nH±5%	100MHz	210mA	0.56ohm	15	250MHz	5.0GHz
LQW04AN22NH00□	22nH±3%	100MHz	200mA	0.63ohm	15	250MHz	5.0GHz
LQW04AN22NJ00□	22nH±5%	100MHz	200mA	0.63ohm	15	250MHz	5.0GHz
LQW04AN23NH00□	23nH±3%	100MHz	160mA	0.95ohm	15	250MHz	4.0GHz
LQW04AN23NJ00□	23nH±5%	100MHz	160mA	0.95ohm	15	250MHz	4.0GHz
LQW04AN24NH00□	24nH±3%	100MHz	160mA	0.95ohm	15	250MHz	4.0GHz
LQW04AN24NJ00□	24nH±5%	100MHz	160mA	0.95ohm	15	250MHz	4.0GHz
LQW04AN25NH00□	25nH±3%	100MHz	160mA	0.95ohm	15	250MHz	4.0GHz
LQW04AN25NJ00□	25nH±5%	100MHz	160mA	0.95ohm	15	250MHz	4.0GHz
LQW04AN27NH00□	27nH±3%	100MHz	160mA	0.95ohm	15	250MHz	4.0GHz
LQW04AN27NJ00□	27nH±5%	100MHz	160mA	0.95ohm	15	250MHz	4.0GHz
LQW04AN33NH00□	33nH±3%	100MHz	140mA	1.11ohm	15	250MHz	4.0GHz
LQW04AN33NJ00□	33nH±5%	100MHz	140mA	1.11ohm	15	250MHz	4.0GHz

Operating Temperature Range: -55°C to +125°C Only for reflow soldering.

■ Q - Frequency Characteristics (Typ.)



■ Inductance - Frequency Characteristics (Typ.)



■ Reference Data

E4991A & 16197A

Part Number	Inductance (nH)	Q (Typ.)						
	Nominal	300MHz	800MHz	900MHz	1.5GHz	1.8GHz	2.0GHz	2.4GHz
LQW04AN1N1	1.1	32	61	65	72	79	85	92
LQW04AN1N8	1.8	30	48	52	67	75	80	88
LQW04AN2N7	2.7	28	46	50	65	70	75	85
LQW04AN3N0	3.0	29	47	50	65	70	75	85
LQW04AN3N6	3.6	28	46	48	64	69	72	78
LQW04AN3N9	3.9	27	46	48	64	69	72	79
LQW04AN4N3	4.3	29	47	50	64	69	73	79
LQW04AN4N7	4.7	26	43	45	58	63	67	72
LQW04AN5N1	5.1	30	47	49	62	69	72	80
LQW04AN5N6	5.6	29	47	49	62	69	72	79
LQW04AN6N2	6.2	26	42	45	58	63	65	70
LQW04AN6N8	6.8	28	45	48	60	66	68	74
LQW04AN7N5	7.5	28	45	47	60	66	67	70
LQW04AN8N2	8.2	27	43	45	57	61	63	67
LQW04AN9N1	9.1	28	45	47	58	65	66	68
LQW04AN10N	10	27	43	46	56	61	63	65
LQW04AN11N	11	27	43	46	58	63	65	67
LQW04AN12N	12	28	44	47	58	63	64	66
LQW04AN13N	13	27	44	46	58	62	64	66
LQW04AN15N	15	27	43	45	55	59	60	61
LQW04AN16N	16	27	43	47	56	60	61	61
LQW04AN18N	18	27	42	45	55	57	58	57
LQW04AN20N	20	27	42	45	54	57	58	55
LQW04AN22N	22	27	42	46	54	56	57	55
LQW04AN27N	27	30	42	44	50	51	50	47
LQW04AN33N	33	30	43	45	52	52	50	47

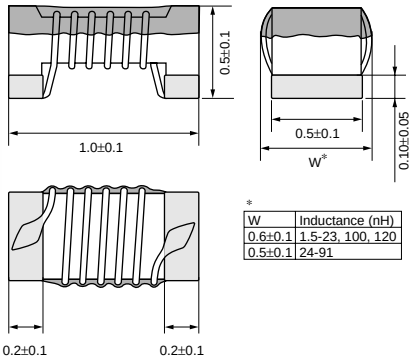
Inductor for High Frequency Wire Wound Type Air Core (Horizontal Wire Wound)

muRata

LQW15A_00 Series (0402 Size)

LQW15A series consists of air core chip inductor using a miniature alumina core.
The tight inductance tolerance (+-0.2nH, +-3%) is available due to Murata's original wire wound technology.
LQW15A series has high Q value in high frequency range and high self-resonant frequency. It is suitable for high frequency circuits which are used in telecommunications equipment.

■ Dimension



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W	Inductance (nH)
0.6±0.1	1.5-23, 100, 120
0.5±0.1	24-91

(in mm)

■ Features

1. Horizontal wire wound structure enables tight inductance tolerance (+-0.2nH, +-3%), and tolerance of +-0.1nH, +-2% is available.
2. Wide variation in inductance value.
3. The subminiature dimensions (1.0x0.5mm) allow high density mounting.
4. The high self-resonant frequency realizes high Q value and stable inductance at high frequency.
5. Low DC resistance design is ideal for low loss, high output and low power consumption.
6. Resin-coated surface enables excellent mounting.

■ Applications

1. High frequency circuits of mobile phones such as PA, ANT, VCO, SAW, etc.
2. Mobile phones
3. "Bluetooth"
4. W-LAN
5. High frequency circuits in general

■ Rated Value (□: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQW15AN1N5B00□	1.5nH±0.1nH	100MHz	1000mA	0.03ohm	10	250MHz	18.0GHz
LQW15AN1N5C00□	1.5nH±0.2nH	100MHz	1000mA	0.03ohm	10	250MHz	18.0GHz
LQW15AN1N5D00□	1.5nH±0.5nH	100MHz	1000mA	0.03ohm	10	250MHz	18.0GHz
LQW15AN2N4B00□	2.4nH±0.1nH	100MHz	850mA	0.05ohm	20	250MHz	15.0GHz
LQW15AN2N4C00□	2.4nH±0.2nH	100MHz	850mA	0.05ohm	20	250MHz	15.0GHz
LQW15AN2N4D00□	2.4nH±0.5nH	100MHz	850mA	0.05ohm	20	250MHz	15.0GHz
LQW15AN2N5B00□	2.5nH±0.1nH	100MHz	850mA	0.05ohm	20	250MHz	15.0GHz
LQW15AN2N5C00□	2.5nH±0.2nH	100MHz	850mA	0.05ohm	20	250MHz	15.0GHz
LQW15AN2N5D00□	2.5nH±0.5nH	100MHz	850mA	0.05ohm	20	250MHz	15.0GHz
LQW15AN2N7B00□	2.7nH±0.1nH	100MHz	850mA	0.05ohm	20	250MHz	15.0GHz
LQW15AN2N7C00□	2.7nH±0.2nH	100MHz	850mA	0.05ohm	20	250MHz	15.0GHz
LQW15AN2N7D00□	2.7nH±0.5nH	100MHz	850mA	0.05ohm	20	250MHz	15.0GHz
LQW15AN2N9B00□	2.9nH±0.1nH	100MHz	750mA	0.07ohm	20	250MHz	15.0GHz
LQW15AN2N9C00□	2.9nH±0.2nH	100MHz	750mA	0.07ohm	20	250MHz	15.0GHz
LQW15AN2N9D00□	2.9nH±0.5nH	100MHz	750mA	0.07ohm	20	250MHz	15.0GHz
LQW15AN3N9B00□	3.9nH±0.1nH	100MHz	750mA	0.07ohm	25	250MHz	10.0GHz

Operating Temperature Range: -55°C to +125°C Only for reflow soldering.

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Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQW15AN3N9C00□	3.9nH±0.2nH	100MHz	750mA	0.07ohm	25	250MHz	10.0GHz
LQW15AN3N9D00□	3.9nH±0.5nH	100MHz	750mA	0.07ohm	25	250MHz	10.0GHz
LQW15AN4N1B00□	4.1nH±0.1nH	100MHz	750mA	0.07ohm	25	250MHz	10.0GHz
LQW15AN4N1C00□	4.1nH±0.2nH	100MHz	750mA	0.07ohm	25	250MHz	10.0GHz
LQW15AN4N1D00□	4.1nH±0.5nH	100MHz	750mA	0.07ohm	25	250MHz	10.0GHz
LQW15AN4N3B00□	4.3nH±0.1nH	100MHz	750mA	0.07ohm	25	250MHz	10.0GHz
LQW15AN4N3C00□	4.3nH±0.2nH	100MHz	750mA	0.07ohm	25	250MHz	10.0GHz
LQW15AN4N3D00□	4.3nH±0.5nH	100MHz	750mA	0.07ohm	25	250MHz	10.0GHz
LQW15AN4N7B00□	4.7nH±0.1nH	100MHz	750mA	0.07ohm	25	250MHz	8.0GHz
LQW15AN4N7C00□	4.7nH±0.2nH	100MHz	750mA	0.07ohm	25	250MHz	8.0GHz
LQW15AN4N7D00□	4.7nH±0.5nH	100MHz	750mA	0.07ohm	25	250MHz	8.0GHz
LQW15AN5N1B00□	5.1nH±0.1nH	100MHz	600mA	0.12ohm	25	250MHz	8.0GHz
LQW15AN5N1C00□	5.1nH±0.2nH	100MHz	600mA	0.12ohm	25	250MHz	8.0GHz
LQW15AN5N1D00□	5.1nH±0.5nH	100MHz	600mA	0.12ohm	25	250MHz	8.0GHz
LQW15AN5N8B00□	5.8nH±0.1nH	100MHz	700mA	0.12ohm	25	250MHz	8.0GHz
LQW15AN5N8C00□	5.8nH±0.2nH	100MHz	700mA	0.12ohm	25	250MHz	8.0GHz
LQW15AN5N8D00□	5.8nH±0.5nH	100MHz	700mA	0.12ohm	25	250MHz	8.0GHz
LQW15AN6N2B00□	6.2nH±0.1nH	100MHz	700mA	0.09ohm	25	250MHz	8.0GHz
LQW15AN6N2C00□	6.2nH±0.2nH	100MHz	700mA	0.09ohm	25	250MHz	8.0GHz
LQW15AN6N2D00□	6.2nH±0.5nH	100MHz	700mA	0.09ohm	25	250MHz	8.0GHz
LQW15AN6N8G00□	6.8nH±2%	100MHz	700mA	0.09ohm	25	250MHz	6.0GHz
LQW15AN6N8H00□	6.8nH±3%	100MHz	700mA	0.09ohm	25	250MHz	6.0GHz
LQW15AN6N8J00□	6.8nH±5%	100MHz	700mA	0.09ohm	25	250MHz	6.0GHz
LQW15AN7N3G00□	7.3nH±2%	100MHz	570mA	0.13ohm	25	250MHz	6.0GHz
LQW15AN7N3H00□	7.3nH±3%	100MHz	570mA	0.13ohm	25	250MHz	6.0GHz
LQW15AN7N3J00□	7.3nH±5%	100MHz	570mA	0.13ohm	25	250MHz	6.0GHz
LQW15AN7N5G00□	7.5nH±2%	100MHz	570mA	0.13ohm	25	250MHz	6.0GHz
LQW15AN7N5H00□	7.5nH±3%	100MHz	570mA	0.13ohm	25	250MHz	6.0GHz
LQW15AN7N5J00□	7.5nH±5%	100MHz	570mA	0.13ohm	25	250MHz	6.0GHz
LQW15AN8N2G00□	8.2nH±2%	100MHz	540mA	0.14ohm	25	250MHz	5.5GHz
LQW15AN8N2H00□	8.2nH±3%	100MHz	540mA	0.14ohm	25	250MHz	5.5GHz
LQW15AN8N2J00□	8.2nH±5%	100MHz	540mA	0.14ohm	25	250MHz	5.5GHz
LQW15AN8N7G00□	8.7nH±2%	100MHz	540mA	0.14ohm	25	250MHz	5.5GHz
LQW15AN8N7H00□	8.7nH±3%	100MHz	540mA	0.14ohm	25	250MHz	5.5GHz
LQW15AN8N7J00□	8.7nH±5%	100MHz	540mA	0.14ohm	25	250MHz	5.5GHz
LQW15AN9N1G00□	9.1nH±2%	100MHz	540mA	0.14ohm	25	250MHz	5.5GHz
LQW15AN9N1H00□	9.1nH±3%	100MHz	540mA	0.14ohm	25	250MHz	5.5GHz
LQW15AN9N1J00□	9.1nH±5%	100MHz	540mA	0.14ohm	25	250MHz	5.5GHz
LQW15AN9N5G00□	9.5nH±2%	100MHz	540mA	0.14ohm	25	250MHz	5.5GHz
LQW15AN9N5H00□	9.5nH±3%	100MHz	540mA	0.14ohm	25	250MHz	5.5GHz
LQW15AN9N5J00□	9.5nH±5%	100MHz	540mA	0.14ohm	25	250MHz	5.5GHz
LQW15AN10NG00□	10nH±2%	100MHz	500mA	0.17ohm	25	250MHz	5.5GHz
LQW15AN10NH00□	10nH±3%	100MHz	500mA	0.17ohm	25	250MHz	5.5GHz
LQW15AN10NJ00□	10nH±5%	100MHz	500mA	0.17ohm	25	250MHz	5.5GHz
LQW15AN11NG00□	11nH±2%	100MHz	500mA	0.14ohm	30	250MHz	5.5GHz
LQW15AN11NH00□	11nH±3%	100MHz	500mA	0.14ohm	30	250MHz	5.5GHz
LQW15AN11NJ00□	11nH±5%	100MHz	500mA	0.14ohm	30	250MHz	5.5GHz
LQW15AN12NG00□	12nH±2%	100MHz	500mA	0.14ohm	30	250MHz	5.5GHz
LQW15AN12NH00□	12nH±3%	100MHz	500mA	0.14ohm	30	250MHz	5.5GHz
LQW15AN12NJ00□	12nH±5%	100MHz	500mA	0.14ohm	30	250MHz	5.5GHz
LQW15AN13NG00□	13nH±2%	100MHz	430mA	0.21ohm	25	250MHz	5.0GHz

Operating Temperature Range: -55°C to +125°C Only for reflow soldering.

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Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQW15AN13NH00□	13nH±3%	100MHz	430mA	0.21ohm	25	250MHz	5.0GHz
LQW15AN13NJ00□	13nH±5%	100MHz	430mA	0.21ohm	25	250MHz	5.0GHz
LQW15AN15NG00□	15nH±2%	100MHz	460mA	0.16ohm	30	250MHz	5.0GHz
LQW15AN15NH00□	15nH±3%	100MHz	460mA	0.16ohm	30	250MHz	5.0GHz
LQW15AN15NJ00□	15nH±5%	100MHz	460mA	0.16ohm	30	250MHz	5.0GHz
LQW15AN16NG00□	16nH±2%	100MHz	370mA	0.24ohm	25	250MHz	4.5GHz
LQW15AN16NH00□	16nH±3%	100MHz	370mA	0.24ohm	25	250MHz	4.5GHz
LQW15AN16NJ00□	16nH±5%	100MHz	370mA	0.24ohm	25	250MHz	4.5GHz
LQW15AN18NG00□	18nH±2%	100MHz	370mA	0.27ohm	25	250MHz	4.5GHz
LQW15AN18NH00□	18nH±3%	100MHz	370mA	0.27ohm	25	250MHz	4.5GHz
LQW15AN18NJ00□	18nH±5%	100MHz	370mA	0.27ohm	25	250MHz	4.5GHz
LQW15AN19NG00□	19nH±2%	100MHz	370mA	0.27ohm	25	250MHz	4.5GHz
LQW15AN19NH00□	19nH±3%	100MHz	370mA	0.27ohm	25	250MHz	4.5GHz
LQW15AN19NJ00□	19nH±5%	100MHz	370mA	0.27ohm	25	250MHz	4.5GHz
LQW15AN20NG00□	20nH±2%	100MHz	370mA	0.27ohm	25	250MHz	4.0GHz
LQW15AN20NH00□	20nH±3%	100MHz	370mA	0.27ohm	25	250MHz	4.0GHz
LQW15AN20NJ00□	20nH±5%	100MHz	370mA	0.27ohm	25	250MHz	4.0GHz
LQW15AN22NG00□	22nH±2%	100MHz	310mA	0.30ohm	25	250MHz	4.0GHz
LQW15AN22NH00□	22nH±3%	100MHz	310mA	0.30ohm	25	250MHz	4.0GHz
LQW15AN22NJ00□	22nH±5%	100MHz	310mA	0.30ohm	25	250MHz	4.0GHz
LQW15AN23NG00□	23nH±2%	100MHz	310mA	0.30ohm	25	250MHz	3.8GHz
LQW15AN23NH00□	23nH±3%	100MHz	310mA	0.30ohm	25	250MHz	3.8GHz
LQW15AN23NJ00□	23nH±5%	100MHz	310mA	0.30ohm	25	250MHz	3.8GHz
LQW15AN24NG00□	24nH±2%	100MHz	280mA	0.52ohm	25	250MHz	3.5GHz
LQW15AN24NH00□	24nH±3%	100MHz	280mA	0.52ohm	25	250MHz	3.5GHz
LQW15AN24NJ00□	24nH±5%	100MHz	280mA	0.52ohm	25	250MHz	3.5GHz
LQW15AN27NG00□	27nH±2%	100MHz	280mA	0.52ohm	25	250MHz	3.5GHz
LQW15AN27NH00□	27nH±3%	100MHz	280mA	0.52ohm	25	250MHz	3.5GHz
LQW15AN27NJ00□	27nH±5%	100MHz	280mA	0.52ohm	25	250MHz	3.5GHz
LQW15AN30NG00□	30nH±2%	100MHz	270mA	0.58ohm	25	250MHz	3.3GHz
LQW15AN30NH00□	30nH±3%	100MHz	270mA	0.58ohm	25	250MHz	3.3GHz
LQW15AN30NJ00□	30nH±5%	100MHz	270mA	0.58ohm	25	250MHz	3.3GHz
LQW15AN33NG00□	33nH±2%	100MHz	260mA	0.63ohm	25	250MHz	3.2GHz
LQW15AN33NH00□	33nH±3%	100MHz	260mA	0.63ohm	25	250MHz	3.2GHz
LQW15AN33NJ00□	33nH±5%	100MHz	260mA	0.63ohm	25	250MHz	3.2GHz
LQW15AN36NG00□	36nH±2%	100MHz	260mA	0.63ohm	25	250MHz	3.1GHz
LQW15AN36NH00□	36nH±3%	100MHz	260mA	0.63ohm	25	250MHz	3.1GHz
LQW15AN36NJ00□	36nH±5%	100MHz	260mA	0.63ohm	25	250MHz	3.1GHz
LQW15AN39NG00□	39nH±2%	100MHz	250mA	0.70ohm	25	250MHz	3.0GHz
LQW15AN39NH00□	39nH±3%	100MHz	250mA	0.70ohm	25	250MHz	3.0GHz
LQW15AN39NJ00□	39nH±5%	100MHz	250mA	0.70ohm	25	250MHz	3.0GHz
LQW15AN40NG00□	40nH±2%	100MHz	250mA	0.70ohm	25	250MHz	3.0GHz
LQW15AN40NH00□	40nH±3%	100MHz	250mA	0.70ohm	25	250MHz	3.0GHz
LQW15AN40NJ00□	40nH±5%	100MHz	250mA	0.70ohm	25	250MHz	3.0GHz
LQW15AN43NG00□	43nH±2%	100MHz	250mA	0.70ohm	25	250MHz	3.0GHz
LQW15AN43NH00□	43nH±3%	100MHz	250mA	0.70ohm	25	250MHz	3.0GHz
LQW15AN43NJ00□	43nH±5%	100MHz	250mA	0.70ohm	25	250MHz	3.0GHz
LQW15AN47NG00□	47nH±2%	100MHz	210mA	1.08ohm	25	200MHz	2.9GHz
LQW15AN47NH00□	47nH±3%	100MHz	210mA	1.08ohm	25	200MHz	2.9GHz
LQW15AN47NJ00□	47nH±5%	100MHz	210mA	1.08ohm	25	200MHz	2.9GHz
LQW15AN51NG00□	51nH±2%	100MHz	210mA	1.08ohm	25	200MHz	2.85GHz

Operating Temperature Range: -55°C to +125°C Only for reflow soldering.

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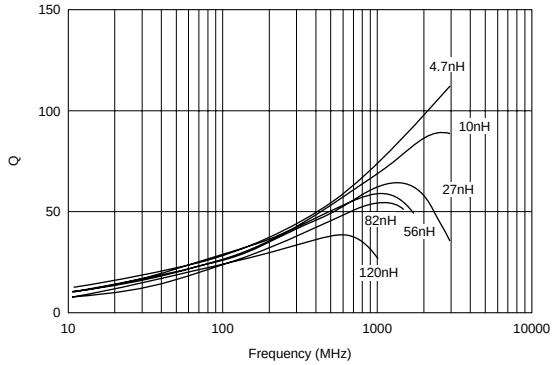
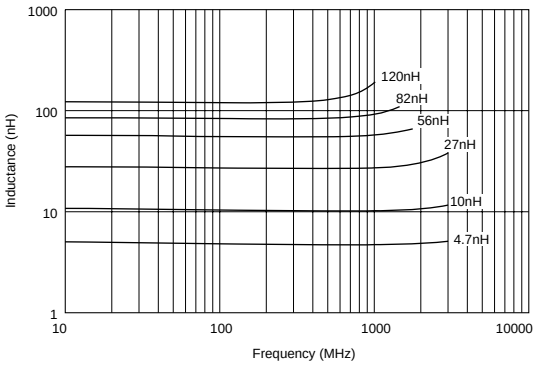
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQW15AN51NH00□	51nH±3%	100MHz	210mA	1.08ohm	25	200MHz	2.85GHz
LQW15AN51NJ00□	51nH±5%	100MHz	210mA	1.08ohm	25	200MHz	2.85GHz
LQW15AN56NG00□	56nH±2%	100MHz	200mA	1.17ohm	25	200MHz	2.8GHz
LQW15AN56NH00□	56nH±3%	100MHz	200mA	1.17ohm	25	200MHz	2.8GHz
LQW15AN56NJ00□	56nH±5%	100MHz	200mA	1.17ohm	25	200MHz	2.8GHz
LQW15AN62NG00□	62nH±2%	100MHz	145mA	1.82ohm	20	200MHz	2.6GHz
LQW15AN62NH00□	62nH±3%	100MHz	145mA	1.82ohm	20	200MHz	2.6GHz
LQW15AN62NJ00□	62nH±5%	100MHz	145mA	1.82ohm	20	200MHz	2.6GHz
LQW15AN68NG00□	68nH±2%	100MHz	140mA	1.96ohm	20	200MHz	2.5GHz
LQW15AN68NJ00□	68nH±5%	100MHz	140mA	1.96ohm	20	200MHz	2.5GHz
LQW15AN72NG00□	72nH±2%	100MHz	135mA	2.10ohm	20	150MHz	2.5GHz
LQW15AN72NJ00□	72nH±5%	100MHz	135mA	2.10ohm	20	150MHz	2.5GHz
LQW15AN75NG00□	75nH±2%	100MHz	135mA	2.10ohm	20	150MHz	2.4GHz
LQW15AN75NJ00□	75nH±5%	100MHz	135mA	2.10ohm	20	150MHz	2.4GHz
LQW15AN82NG00□	82nH±2%	100MHz	130mA	2.24ohm	20	150MHz	2.3GHz
LQW15AN82NJ00□	82nH±5%	100MHz	130mA	2.24ohm	20	150MHz	2.3GHz
LQW15AN91NG00□	91nH±2%	100MHz	125mA	2.38ohm	20	150MHz	2.1GHz
LQW15AN91NJ00□	91nH±5%	100MHz	125mA	2.38ohm	20	150MHz	2.1GHz
LQW15ANR10J00□	100nH±5%	100MHz	120mA	2.52ohm	20	150MHz	1.5GHz
LQW15ANR12J00□	120nH±5%	100MHz	110mA	2.66ohm	20	150MHz	1.0GHz

Operating Temperature Range: -55°C to +125°C Only for reflow soldering.

■ Q - Frequency Characteristics (Typ.)



■ Inductance - Frequency Characteristics (Typ.)



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■ Reference Data

LQW15A_00

E4991A & 16197A

Part Number	Inductance (nH)	Q (Typ.)						
	Nominal	300MHz	800MHz	900MHz	1.5GHz	1.8GHz	2.0GHz	2.4GHz
LQW15AN1N5	1.5	30	55	60	65	90	100	115
LQW15AN2N4	2.4	40	65	67	80	98	108	120
LQW15AN2N5	2.5	40	65	67	88	90	100	110
LQW15AN2N7	2.7	40	67	73	85	100	105	120
LQW15AN2N9	2.9	33	53	58	75	80	85	92
LQW15AN3N9	3.9	35	58	61	82	88	92	100
LQW15AN4N1	4.1	35	58	61	82	88	92	100
LQW15AN4N3	4.3	35	58	61	90	88	92	100
LQW15AN4N7	4.7	40	65	67	85	88	92	95
LQW15AN5N1	5.1	35	60	65	78	85	90	95
LQW15AN5N8	5.8	40	63	67	85	88	92	105
LQW15AN6N2	6.2	40	63	65	80	90	95	105
LQW15AN6N8	6.8	45	70	72	90	96	100	103
LQW15AN7N3	7.3	38	58	63	75	88	90	92
LQW15AN7N5	7.5	38	58	63	75	88	90	92
LQW15AN8N2	8.2	40	62	67	80	90	95	102
LQW15AN8N7	8.7	40	60	62	80	85	90	92
LQW15AN9N1	9.1	40	62	68	85	90	92	95
LQW15AN9N5	9.5	40	62	68	85	90	92	95
LQW15AN10N	10	38	60	65	75	82	85	84
LQW15AN11N	11	40	65	70	90	105	110	120
LQW15AN12N	12	40	60	62	80	85	90	91
LQW15AN13N	13	40	60	62	70	72	71	67
LQW15AN15N	15	40	60	65	80	85	88	90
LQW15AN16N	16	40	60	63	80	90	100	110
LQW15AN18N	18	40	63	65	80	88	87	85
LQW15AN19N	19	37	57	62	78	80	82	83
LQW15AN20N	20	37	57	62	78	80	82	83
LQW15AN22N	22	35	55	58	73	75	78	-
LQW15AN23N	23	35	55	58	73	75	78	-
LQW15AN24N	24	35	50	50	48	42	-	-
LQW15AN27N	27	35	55	56	60	58	-	-
LQW15AN30N	30	35	55	58	65	68	-	-
LQW15AN33N	33	35	55	56	60	53	-	-
LQW15AN36N	36	35	52	52	48	42	-	-
LQW15AN39N	39	35	55	56	62	-	-	-
LQW15AN40N	40	35	55	56	62	-	-	-
LQW15AN43N	43	35	55	56	62	-	-	-
LQW15AN47N	47	34	52	54	60	-	-	-
LQW15AN51N	51	34	52	54	60	-	-	-
LQW15AN56N	56	36	53	55	50	-	-	-
LQW15AN62N	62	33	51	52	-	-	-	-
LQW15AN68N	68	35	49	52	-	-	-	-
LQW15AN72N	72	33	49	52	-	-	-	-
LQW15AN75N	75	33	49	52	-	-	-	-
LQW15AN82N	82	35	49	50	-	-	-	-
LQW15AN91N	91	35	52	53	-	-	-	-
LQW15ANR10	100	30	43	43	-	-	-	-
LQW15ANR12	120	28	30	23	-	-	-	-

Inductor for High Frequency Wire Wound Type Air Core (Horizontal Wire Wound)

muRata

LQW15A_10 Series (High Q/Low DC Resistance Type) (0402 Size)

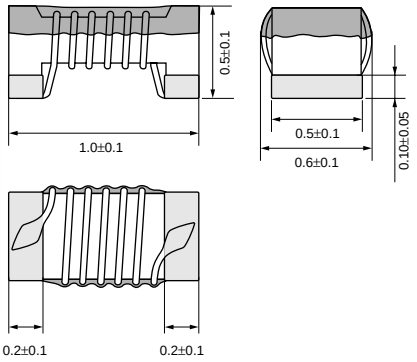
■ Features

Lower DC resistance approximately by 50% than current type. Higher Q by 20%, larger rated current by 20%.
Inductance range: 1.3 to 5.6nH
Inductance tolerance: +-0.2 or 0.5nH
Q (Typ.): 83 to 122 (at 1GHz)
DC Resistance: 0.017 to 0.051 ohm
Rated Current: 800 to 1200mA

■ Applications

1. Mobile phones
2. Higher Q -- Matching circuit for antenna, SAWFIL
3. Lower Rdc -- Inductors for choke in IF circuits,
   RF circuits like PA
   Equipment with high frequency circuits
   (Wireless LAN, etc.)

■ Dimension



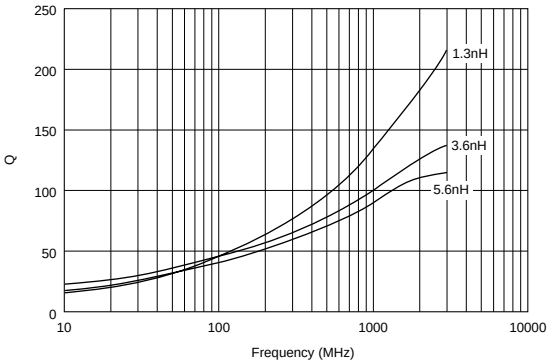
(in mm)

■ Rated Value (☐: packaging code)

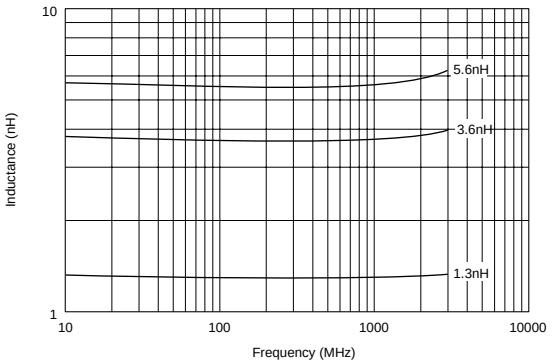
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQW15AN1N3C10☐	1.3nH±0.2nH	100MHz	1200mA	0.017ohm	20	250MHz	16.0GHz
LQW15AN1N3D10☐	1.3nH±0.5nH	100MHz	1200mA	0.017ohm	20	250MHz	16.0GHz
LQW15AN2N2C10☐	2.2nH±0.2nH	100MHz	1000mA	0.027ohm	25	250MHz	14.0GHz
LQW15AN2N2D10☐	2.2nH±0.5nH	100MHz	1000mA	0.027ohm	25	250MHz	14.0GHz
LQW15AN2N4D10☐	2.4nH±0.5nH	100MHz	1000mA	0.027ohm	25	250MHz	14.0GHz
LQW15AN3N3D10☐	3.3nH±0.5nH	100MHz	900mA	0.040ohm	30	250MHz	12.0GHz
LQW15AN3N4C10☐	3.4nH±0.2nH	100MHz	900mA	0.040ohm	30	250MHz	12.0GHz
LQW15AN3N4D10☐	3.4nH±0.5nH	100MHz	900mA	0.040ohm	30	250MHz	12.0GHz
LQW15AN3N6C10☐	3.6nH±0.2nH	100MHz	900mA	0.040ohm	30	250MHz	9.5GHz
LQW15AN3N6D10☐	3.6nH±0.5nH	100MHz	900mA	0.040ohm	30	250MHz	9.5GHz
LQW15AN3N9D10☐	3.9nH±0.5nH	100MHz	900mA	0.040ohm	30	250MHz	7.0GHz
LQW15AN4N7D10☐	4.7nH±0.5nH	100MHz	800mA	0.051ohm	30	250MHz	8.0GHz
LQW15AN5N1C10☐	5.1nH±0.2nH	100MHz	800mA	0.051ohm	30	250MHz	8.0GHz
LQW15AN5N1D10☐	5.1nH±0.5nH	100MHz	800mA	0.051ohm	30	250MHz	8.0GHz
LQW15AN5N6C10☐	5.6nH±0.2nH	100MHz	800mA	0.051ohm	30	250MHz	8.0GHz
LQW15AN5N6D10☐	5.6nH±0.5nH	100MHz	800mA	0.051ohm	30	250MHz	8.0GHz

Operating Temperature Range: -55°C to +125°C Only for reflow soldering.

■ Q - Frequency Characteristics (Typ.)



■ Inductance - Frequency Characteristics (Typ.)



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■ Reference Data

LQW15A_10

E4991A & 16197A

Part Number	Inductance (nH)	Q (Typ.)						
	Nominal	800MHz	900MHz	1.0GHz	1.5GHz	1.8GHz	2.0GHz	2.4GHz
LQW15AN1N3	1.3	90	95	100	130	145	160	180
LQW15AN2N2	2.2	85	90	95	115	130	140	160
LQW15AN2N4	2.4	80	85	90	110	130	140	160
LQW15AN3N3	3.3	80	85	90	110	120	128	140
LQW15AN3N4	3.4	80	85	90	110	120	128	140
LQW15AN3N6	3.6	73	75	85	100	110	115	130
LQW15AN3N9	3.9	75	80	83	95	110	115	120
LQW15AN4N7	4.7	75	80	85	100	113	120	132
LQW15AN5N1	5.1	75	80	85	100	110	115	128
LQW15AN5N6	5.6	70	75	78	95	100	105	110

Inductor for High Frequency Wire Wound Type Air Core (Horizontal Wire Wound)

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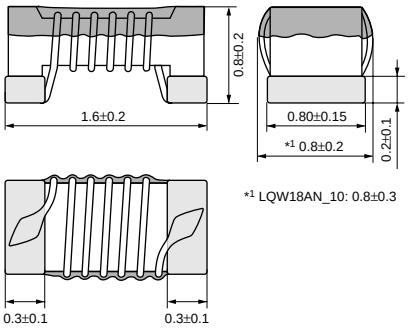
LQW18A_00 Series (0603 Size)

■ Features

1. Broad range of inductance (2.2nH to 470nH) with E24 step line up.
2. Horizontal wire wound structure enables tight inductance tolerance (+-0.2nH, +-2%). Stable circuit operation is possible.
3. The subminiature dimensions (1.6x0.8mm) allow high density mounting.
4. The high self-resonant frequency realizes high Q value and stable inductance at high frequency.
5. Low DC resistance design is ideal for low loss, high output and low power consumption.
6. Resin-coated surface enables excellent mounting.

■ Dimension



(in mm)

■ Applications

1. High frequency circuits of mobile phones such as PA, ANT, VCO, SAW, etc.
2. Mobile phones
3. "Bluetooth"
4. W-LAN
5. High frequency circuits in general

■ Rated Value (☐: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQW18AN2N2D00☐	2.2nH±0.5nH	100MHz	700mA	0.049ohm	16	250MHz	6000MHz
LQW18AN3N6C00☐	3.6nH±0.2nH	100MHz	850mA	0.059ohm	25	250MHz	6000MHz
LQW18AN3N6D00☐	3.6nH±0.5nH	100MHz	850mA	0.059ohm	25	250MHz	6000MHz
LQW18AN3N9C00☐	3.9nH±0.2nH	100MHz	850mA	0.059ohm	35	250MHz	6000MHz
LQW18AN3N9D00☐	3.9nH±0.5nH	100MHz	850mA	0.059ohm	35	250MHz	6000MHz
LQW18AN4N3C00☐	4.3nH±0.2nH	100MHz	850mA	0.059ohm	35	250MHz	6000MHz
LQW18AN4N3D00☐	4.3nH±0.5nH	100MHz	850mA	0.059ohm	35	250MHz	6000MHz
LQW18AN4N7D00☐	4.7nH±0.5nH	100MHz	850mA	0.059ohm	35	250MHz	6000MHz
LQW18AN5N6C00☐	5.6nH±0.2nH	100MHz	750mA	0.082ohm	35	250MHz	6000MHz
LQW18AN5N6D00☐	5.6nH±0.5nH	100MHz	750mA	0.082ohm	35	250MHz	6000MHz
LQW18AN6N2C00☐	6.2nH±0.2nH	100MHz	750mA	0.082ohm	35	250MHz	6000MHz
LQW18AN6N2D00☐	6.2nH±0.5nH	100MHz	750mA	0.082ohm	35	250MHz	6000MHz
LQW18AN6N8C00☐	6.8nH±0.2nH	100MHz	750mA	0.082ohm	35	250MHz	6000MHz
LQW18AN6N8D00☐	6.8nH±0.5nH	100MHz	750mA	0.082ohm	35	250MHz	6000MHz
LQW18AN7N5D00☐	7.5nH±0.5nH	100MHz	750mA	0.082ohm	35	250MHz	6000MHz
LQW18AN8N2D00☐	8.2nH±0.5nH	100MHz	650mA	0.11ohm	35	250MHz	6000MHz
LQW18AN8N7D00☐	8.7nH±0.5nH	100MHz	650mA	0.11ohm	35	250MHz	6000MHz
LQW18AN9N1D00☐	9.1nH±0.5nH	100MHz	650mA	0.11ohm	35	250MHz	6000MHz
LQW18AN9N5D00☐	9.5nH±0.5nH	100MHz	650mA	0.11ohm	35	250MHz	6000MHz
LQW18AN10NG00☐	10nH±2%	100MHz	650mA	0.11ohm	35	250MHz	6000MHz
LQW18AN10NJ00☐	10nH±5%	100MHz	650mA	0.11ohm	35	250MHz	6000MHz
LQW18AN11NG00☐	11nH±2%	100MHz	650mA	0.11ohm	35	250MHz	6000MHz
LQW18AN11NJ00☐	11nH±5%	100MHz	650mA	0.11ohm	35	250MHz	6000MHz

Operating Temperature Range: -55°C to +125°C Only for reflow soldering.

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Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQW18AN12NG00□	12nH±2%	100MHz	600mA	0.13ohm	35	250MHz	6000MHz
LQW18AN12NJ00□	12nH±5%	100MHz	600mA	0.13ohm	35	250MHz	6000MHz
LQW18AN13NG00□	13nH±2%	100MHz	600mA	0.13ohm	35	250MHz	6000MHz
LQW18AN13NJ00□	13nH±5%	100MHz	600mA	0.13ohm	35	250MHz	6000MHz
LQW18AN15NG00□	15nH±2%	100MHz	600mA	0.13ohm	40	250MHz	6000MHz
LQW18AN15NJ00□	15nH±5%	100MHz	600mA	0.13ohm	40	250MHz	6000MHz
LQW18AN16NG00□	16nH±2%	100MHz	550mA	0.16ohm	40	250MHz	5500MHz
LQW18AN16NJ00□	16nH±5%	100MHz	550mA	0.16ohm	40	250MHz	5500MHz
LQW18AN18NG00□	18nH±2%	100MHz	550mA	0.16ohm	40	250MHz	5500MHz
LQW18AN18NJ00□	18nH±5%	100MHz	550mA	0.16ohm	40	250MHz	5500MHz
LQW18AN20NG00□	20nH±2%	100MHz	550mA	0.16ohm	40	250MHz	4900MHz
LQW18AN20NJ00□	20nH±5%	100MHz	550mA	0.16ohm	40	250MHz	4900MHz
LQW18AN22NG00□	22nH±2%	100MHz	500mA	0.17ohm	40	250MHz	4600MHz
LQW18AN22NJ00□	22nH±5%	100MHz	500mA	0.17ohm	40	250MHz	4600MHz
LQW18AN24NG00□	24nH±2%	100MHz	500mA	0.21ohm	40	250MHz	3800MHz
LQW18AN24NJ00□	24nH±5%	100MHz	500mA	0.21ohm	40	250MHz	3800MHz
LQW18AN27NG00□	27nH±2%	100MHz	440mA	0.21ohm	40	250MHz	3700MHz
LQW18AN27NJ00□	27nH±5%	100MHz	440mA	0.21ohm	40	250MHz	3700MHz
LQW18AN30NG00□	30nH±2%	100MHz	420mA	0.23ohm	40	250MHz	3300MHz
LQW18AN30NJ00□	30nH±5%	100MHz	420mA	0.23ohm	40	250MHz	3300MHz
LQW18AN33NG00□	33nH±2%	100MHz	420mA	0.23ohm	40	250MHz	3200MHz
LQW18AN33NJ00□	33nH±5%	100MHz	420mA	0.23ohm	40	250MHz	3200MHz
LQW18AN36NG00□	36nH±2%	100MHz	400mA	0.26ohm	40	250MHz	2900MHz
LQW18AN36NJ00□	36nH±5%	100MHz	400mA	0.26ohm	40	250MHz	2900MHz
LQW18AN39NG00□	39nH±2%	100MHz	400mA	0.26ohm	40	250MHz	2800MHz
LQW18AN39NJ00□	39nH±5%	100MHz	400mA	0.26ohm	40	250MHz	2800MHz
LQW18AN43NG00□	43nH±2%	100MHz	380mA	0.29ohm	40	200MHz	2700MHz
LQW18AN43NJ00□	43nH±5%	100MHz	380mA	0.29ohm	40	200MHz	2700MHz
LQW18AN47NG00□	47nH±2%	100MHz	380mA	0.29ohm	38	200MHz	2600MHz
LQW18AN47NJ00□	47nH±5%	100MHz	380mA	0.29ohm	38	200MHz	2600MHz
LQW18AN51NG00□	51nH±2%	100MHz	370mA	0.33ohm	38	200MHz	2500MHz
LQW18AN51NJ00□	51nH±5%	100MHz	370mA	0.33ohm	38	200MHz	2500MHz
LQW18AN56NG00□	56nH±2%	100MHz	360mA	0.35ohm	38	200MHz	2400MHz
LQW18AN56NJ00□	56nH±5%	100MHz	360mA	0.35ohm	38	200MHz	2400MHz
LQW18AN62NG00□	62nH±2%	100MHz	280mA	0.51ohm	38	200MHz	2300MHz
LQW18AN62NJ00□	62nH±5%	100MHz	280mA	0.51ohm	38	200MHz	2300MHz
LQW18AN68NG00□	68nH±2%	100MHz	340mA	0.38ohm	38	200MHz	2200MHz
LQW18AN68NJ00□	68nH±5%	100MHz	340mA	0.38ohm	38	200MHz	2200MHz
LQW18AN72NG00□	72nH±2%	100MHz	270mA	0.56ohm	34	150MHz	2100MHz
LQW18AN72NJ00□	72nH±5%	100MHz	270mA	0.56ohm	34	150MHz	2100MHz
LQW18AN75NG00□	75nH±2%	100MHz	270mA	0.56ohm	34	150MHz	2050MHz
LQW18AN75NJ00□	75nH±5%	100MHz	270mA	0.56ohm	34	150MHz	2050MHz
LQW18AN82NG00□	82nH±2%	100MHz	250mA	0.60ohm	34	150MHz	2000MHz
LQW18AN82NJ00□	82nH±5%	100MHz	250mA	0.60ohm	34	150MHz	2000MHz
LQW18AN91NG00□	91nH±2%	100MHz	230mA	0.64ohm	34	150MHz	1900MHz
LQW18AN91NJ00□	91nH±5%	100MHz	230mA	0.64ohm	34	150MHz	1900MHz
LQW18ANR10G00□	100nH±2%	100MHz	220mA	0.68ohm	34	150MHz	1800MHz
LQW18ANR10J00□	100nH±5%	100MHz	220mA	0.68ohm	34	150MHz	1800MHz
LQW18ANR11G00□	110nH±2%	100MHz	200mA	1.2ohm	32	150MHz	1700MHz
LQW18ANR11J00□	110nH±5%	100MHz	200mA	1.2ohm	32	150MHz	1700MHz
LQW18ANR12G00□	120nH±2%	100MHz	180mA	1.3ohm	32	150MHz	1600MHz

Operating Temperature Range: -55°C to +125°C Only for reflow soldering.

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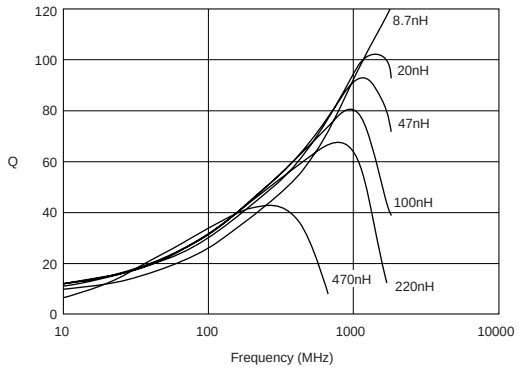
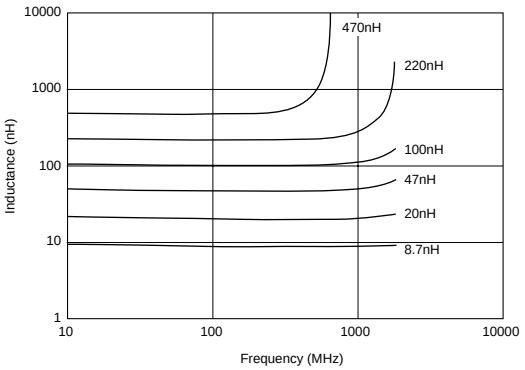
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQW18ANR12J00□	120nH±5%	100MHz	180mA	1.3ohm	32	150MHz	1600MHz
LQW18ANR13G00□	130nH±2%	100MHz	170mA	1.4ohm	32	150MHz	1450MHz
LQW18ANR13J00□	130nH±5%	100MHz	170mA	1.4ohm	32	150MHz	1450MHz
LQW18ANR15G00□	150nH±2%	100MHz	160mA	1.5ohm	32	150MHz	1400MHz
LQW18ANR15J00□	150nH±5%	100MHz	160mA	1.5ohm	32	150MHz	1400MHz
LQW18ANR16G00□	160nH±2%	100MHz	150mA	2.1ohm	32	150MHz	1350MHz
LQW18ANR16J00□	160nH±5%	100MHz	150mA	2.1ohm	32	150MHz	1350MHz
LQW18ANR18G00□	180nH±2%	100MHz	140mA	2.2ohm	25	100MHz	1300MHz
LQW18ANR18J00□	180nH±5%	100MHz	140mA	2.2ohm	25	100MHz	1300MHz
LQW18ANR20G00□	200nH±2%	100MHz	120mA	2.4ohm	25	100MHz	1250MHz
LQW18ANR20J00□	200nH±5%	100MHz	120mA	2.4ohm	25	100MHz	1250MHz
LQW18ANR22G00□	220nH±2%	100MHz	120mA	2.5ohm	25	100MHz	1200MHz
LQW18ANR22J00□	220nH±5%	100MHz	120mA	2.5ohm	25	100MHz	1200MHz
LQW18ANR27G00□	270nH±2%	100MHz	110mA	3.4ohm	30	100MHz	960MHz
LQW18ANR27J00□	270nH±5%	100MHz	110mA	3.4ohm	30	100MHz	960MHz
LQW18ANR33G00□	330nH±2%	100MHz	85mA	5.5ohm	30	100MHz	800MHz
LQW18ANR33J00□	330nH±5%	100MHz	85mA	5.5ohm	30	100MHz	800MHz
LQW18ANR39G00□	390nH±2%	100MHz	80mA	6.2ohm	30	100MHz	800MHz
LQW18ANR39J00□	390nH±5%	100MHz	80mA	6.2ohm	30	100MHz	800MHz
LQW18ANR47G00□	470nH±2%	100MHz	75mA	7.0ohm	30	100MHz	700MHz
LQW18ANR47J00□	470nH±5%	100MHz	75mA	7.0ohm	30	100MHz	700MHz

Operating Temperature Range: -55°C to +125°C Only for reflow soldering.

■ Q - Frequency Characteristics (Typ.)



■ Inductance - Frequency Characteristics (Typ.)



Inductor for High Frequency Wire Wound Type Air Core (Horizontal Wire Wound)

muRata

LQW18A_10 Series (High Q/Low DC Resistance Type) (0603 Size)

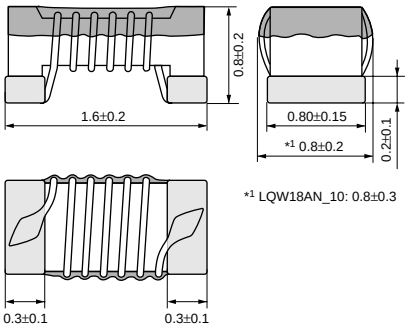
■ Features

DC Resistance is about 50% less than current type.
Q is about 10% higher, and allowable current is about 20% higher than current type. Tight inductance tolerance is available.

■ Applications

Mobile phone and Base station etc.
Higher Q -- Matching circuit for antenna, SAWFIL
Lower Rdc -- Choke coil for IF, RF circuit like PA
Equipment with high frequency circuits
(Wireless LAN etc.)

■ Dimension



*1 LQW18AN_10: 0.8±0.3

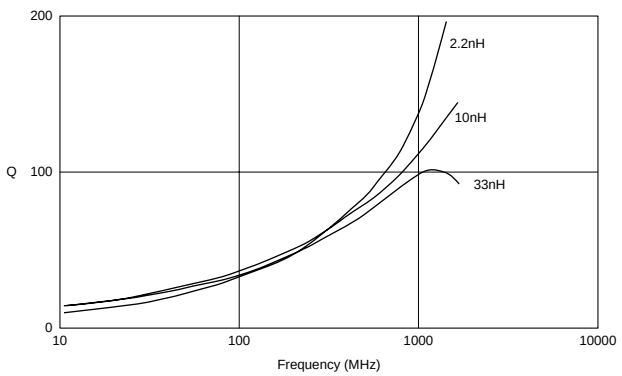
(in mm)

■ Rated Value (☐: packaging code)

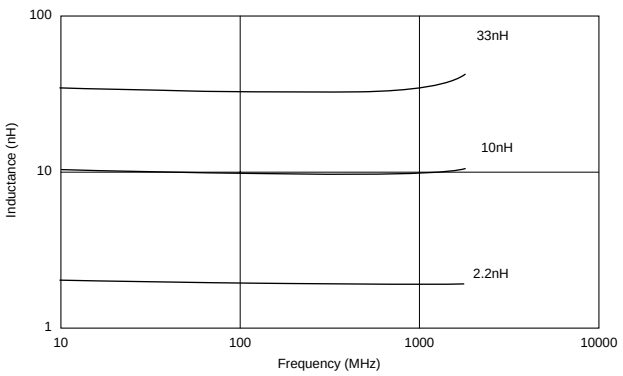
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQW18AN2N2D10☐	2.2nH±0.5nH	100MHz	1400mA	0.018ohm	25	250MHz	18000MHz
LQW18AN3N9C10☐	3.9nH±0.2nH	100MHz	1000mA	0.032ohm	38	250MHz	11000MHz
LQW18AN3N9D10☐	3.9nH±0.5nH	100MHz	1000mA	0.032ohm	38	250MHz	11000MHz
LQW18AN5N6D10☐	5.6nH±0.5nH	100MHz	900mA	0.045ohm	38	250MHz	10000MHz
LQW18AN6N8C10☐	6.8nH±0.2nH	100MHz	900mA	0.045ohm	38	250MHz	7000MHz
LQW18AN6N8D10☐	6.8nH±0.5nH	100MHz	900mA	0.045ohm	38	250MHz	7000MHz
LQW18AN8N2D10☐	8.2nH±0.5nH	100MHz	800mA	0.058ohm	38	250MHz	7000MHz
LQW18AN10NG10☐	10nH±2%	100MHz	800mA	0.058ohm	38	250MHz	5000MHz
LQW18AN10NJ10☐	10nH±5%	100MHz	800mA	0.058ohm	38	250MHz	5000MHz
LQW18AN12NG10☐	12nH±2%	100MHz	750mA	0.071ohm	38	250MHz	5000MHz
LQW18AN12NJ10☐	12nH±5%	100MHz	750mA	0.071ohm	38	250MHz	5000MHz
LQW18AN15NJ10☐	15nH±5%	100MHz	700mA	0.085ohm	42	250MHz	4500MHz
LQW18AN18NG10☐	18nH±2%	100MHz	700mA	0.085ohm	42	250MHz	3500MHz
LQW18AN18NJ10☐	18nH±5%	100MHz	700mA	0.085ohm	42	250MHz	3500MHz
LQW18AN22NG10☐	22nH±2%	100MHz	640mA	0.099ohm	42	250MHz	3200MHz
LQW18AN22NJ10☐	22nH±5%	100MHz	640mA	0.099ohm	42	250MHz	3200MHz
LQW18AN27NG10☐	27nH±2%	100MHz	590mA	0.116ohm	42	250MHz	2800MHz
LQW18AN27NJ10☐	27nH±5%	100MHz	590mA	0.116ohm	42	250MHz	2800MHz
LQW18AN33NJ10☐	33nH±5%	100MHz	550mA	0.132ohm	42	250MHz	2500MHz

Operating Temperature Range: -55°C to +125°C

■ Q - Frequency Characteristics (Typ.)



■ Inductance - Frequency Characteristics (Typ.)



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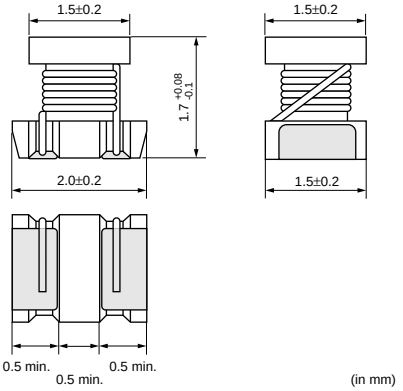
Inductor for High Frequency Wire Wound Type Air Core (Vertical Wire Wound)

muRata

LQW2BH Series (0805 Size)

LQW2BH series consists of air-core chip inductor using a sub-miniature alumina core as a bobbin.
The series has excellent solder heat resistance.
Applicable soldering methods are both flow soldering and reflow soldering.

■ Dimension



(in mm)

■ Features (LQW2BH_03)

1. Inductance: 3.3 to 470nH (Wide inductance ranges)
2. High self-resonant frequency characteristics
3. High Q value and highly stable inductance in high frequency
4. Low DC resistance and large rated current

■ Features (LQW2BH_13)

LQW2BH_13 using thick wire has higher Q value than existing LQW2BH_03 series.

1. Inductance: 2.7 to 27nH
2. DC resistance: 0.02 to 0.06 ohm
3. Q value: 85 to 95 (Typ.) at 800MHz
4. Rated current: 900 to 1900mA

■ Applications

1. High frequency circuit in telecommunications equipment
2. Impedance Matching
   - PA module
   - SAW filter
3. Resonance circuit
   - VCO

LQW2BH_03 Series

■ Rated Value (☐: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQW2BHN3N3D03☐	3.3nH±0.5nH	100MHz	910mA	0.05ohm	10	250MHz	6000MHz
LQW2BHN6N8D03☐	6.8nH±0.5nH	100MHz	680mA	0.11ohm	20	250MHz	5400MHz
LQW2BHN8N2D03☐	8.2nH±0.5nH	100MHz	630mA	0.12ohm	20	250MHz	3900MHz
LQW2BHN10NJ03☐	10nH±5%	100MHz	1320mA	0.03ohm	30	250MHz	3300MHz
LQW2BHN12NJ03☐	12nH±5%	100MHz	680mA	0.11ohm	30	250MHz	3200MHz
LQW2BHN15NJ03☐	15nH±5%	100MHz	630mA	0.12ohm	30	250MHz	2700MHz
LQW2BHN18NJ03☐	18nH±5%	100MHz	690mA	0.10ohm	30	250MHz	2600MHz
LQW2BHN22NJ03☐	22nH±5%	100MHz	720mA	0.09ohm	30	250MHz	2100MHz
LQW2BHN27NJ03☐	27nH±5%	100MHz	540mA	0.17ohm	40	250MHz	2300MHz
LQW2BHN33NG03☐	33nH±2%	100MHz	570mA	0.15ohm	40	250MHz	1900MHz
LQW2BHN33NJ03☐	33nH±5%	100MHz	570mA	0.15ohm	40	250MHz	1900MHz
LQW2BHN39NG03☐	39nH±2%	100MHz	730mA	0.09ohm	40	250MHz	1700MHz
LQW2BHN39NJ03☐	39nH±5%	100MHz	730mA	0.09ohm	40	250MHz	1700MHz
LQW2BHN47NG03☐	47nH±2%	100MHz	450mA	0.23ohm	40	200MHz	1600MHz

Operating Temperature Range: -40°C to +85°C

Continued on the following page.

muRata

Continued from the preceding page.

Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQW2BHN47NJ03□	47nH±5%	100MHz	450mA	0.23ohm	40	200MHz	1600MHz
LQW2BHN56NG03□	56nH±2%	100MHz	430mA	0.26ohm	40	200MHz	1500MHz
LQW2BHN56NJ03□	56nH±5%	100MHz	430mA	0.26ohm	40	200MHz	1500MHz
LQW2BHN68NG03□	68nH±2%	100MHz	460mA	0.23ohm	40	200MHz	1200MHz
LQW2BHN68NJ03□	68nH±5%	100MHz	460mA	0.23ohm	40	200MHz	1200MHz
LQW2BHN82NG03□	82nH±2%	100MHz	320mA	0.42ohm	40	150MHz	1100MHz
LQW2BHN82NJ03□	82nH±5%	100MHz	320mA	0.42ohm	40	150MHz	1100MHz
LQW2BHNR10G03□	100nH±2%	100MHz	270mA	0.55ohm	35	150MHz	900MHz
LQW2BHNR10J03□	100nH±5%	100MHz	350mA	0.38ohm	40	150MHz	900MHz
LQW2BHNR12G03□	120nH±2%	100MHz	320mA	0.40ohm	40	150MHz	750MHz
LQW2BHNR12J03□	120nH±5%	100MHz	320mA	0.40ohm	40	150MHz	750MHz
LQW2BHNR15G03□	150nH±2%	100MHz	260mA	0.68ohm	30	150MHz	350MHz
LQW2BHNR15J03□	150nH±5%	100MHz	390mA	0.47ohm	30	150MHz	350MHz
LQW2BHNR18G03□	180nH±2%	100MHz	250mA	0.71ohm	35	100MHz	700MHz
LQW2BHNR18J03□	180nH±5%	100MHz	250mA	0.71ohm	35	100MHz	700MHz
LQW2BHNR22G03□	220nH±2%	100MHz	240mA	0.70ohm	35	100MHz	500MHz
LQW2BHNR22J03□	220nH±5%	100MHz	240mA	0.70ohm	35	100MHz	500MHz
LQW2BHNR27J03□	270nH±5%	10MHz	190mA	2.00ohm	15	25.2MHz	550MHz
LQW2BHNR27K03□	270nH±10%	10MHz	190mA	2.00ohm	15	25.2MHz	550MHz
LQW2BHNR33J03□	330nH±5%	10MHz	180mA	2.20ohm	15	25.2MHz	500MHz
LQW2BHNR33K03□	330nH±10%	10MHz	180mA	2.20ohm	15	25.2MHz	500MHz
LQW2BHNR39J03□	390nH±5%	10MHz	170mA	2.50ohm	15	25.2MHz	400MHz
LQW2BHNR39K03□	390nH±10%	10MHz	170mA	2.50ohm	15	25.2MHz	400MHz
LQW2BHNR47J03□	470nH±5%	10MHz	160mA	2.80ohm	15	25.2MHz	350MHz
LQW2BHNR47K03□	470nH±10%	10MHz	160mA	2.80ohm	15	25.2MHz	350MHz

Operating Temperature Range: -40°C to +85°C

LQW2BH_13 Series (High Q/Low DC Resistance Type)

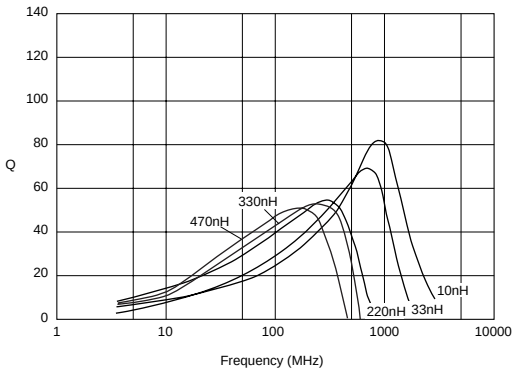
■ Rated Value (□: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQW2BHN2N7D13□	2.7nH±0.5nH	100MHz	1900mA	0.02ohm	20	250MHz	6000MHz
LQW2BHN3N1D13□	3.1nH±0.5nH	100MHz	1800mA	0.02ohm	20	250MHz	6000MHz
LQW2BHN3N3D13□	3.3nH±0.5nH	100MHz	1700mA	0.02ohm	20	250MHz	6000MHz
LQW2BHN5N6D13□	5.6nH±0.5nH	100MHz	1500mA	0.02ohm	35	250MHz	6000MHz
LQW2BHN6N8D13□	6.8nH±0.5nH	100MHz	1400mA	0.02ohm	35	250MHz	5400MHz
LQW2BHN8N6D13□	8.6nH±0.5nH	100MHz	1300mA	0.03ohm	35	250MHz	3900MHz
LQW2BHN10NJ13□	10nH±5%	100MHz	1320mA	0.03ohm	35	250MHz	3300MHz
LQW2BHN12NK13□	12nH±10%	100MHz	1100mA	0.04ohm	40	250MHz	3200MHz
LQW2BHN15NK13□	15nH±10%	100MHz	1000mA	0.04ohm	40	250MHz	3100MHz
LQW2BHN18NK13□	18.8nH±10%	100MHz	1000mA	0.05ohm	40	250MHz	2600MHz
LQW2BHN21NK13□	21nH±10%	100MHz	950mA	0.05ohm	40	250MHz	2200MHz
LQW2BHN27NK13□	27nH±10%	100MHz	900mA	0.06ohm	40	250MHz	1800MHz

Operating Temperature Range: -40°C to +85°C

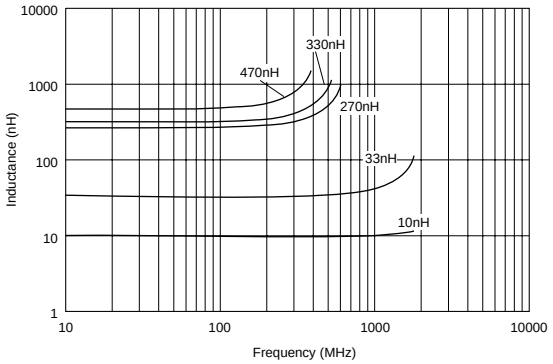
■ Q - Frequency Characteristics (Typ.)

LQW2BH_03



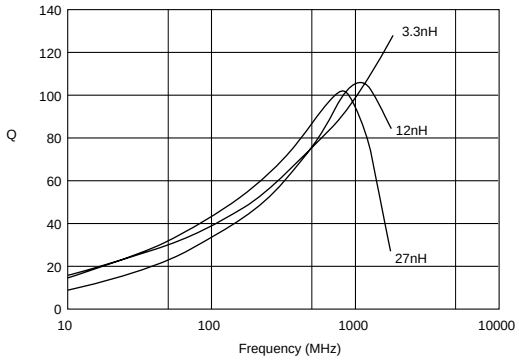
■ Inductance - Frequency Characteristics (Typ.)

LQW2BH_03



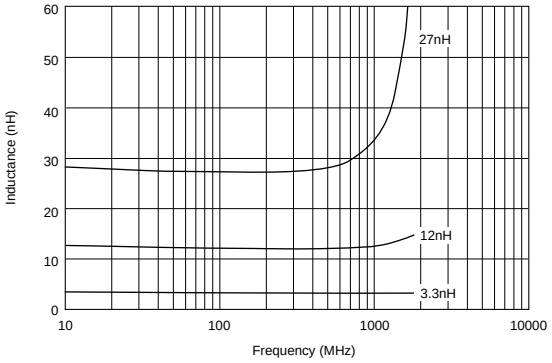
■ Q - Frequency Characteristics (Typ.)

LQW2BH_13



■ Inductance - Frequency Characteristics (Typ.)

LQW2BH_13



Inductor for High Frequency Wire Wound Type Air Core (Vertical Wire Wound)

muRata

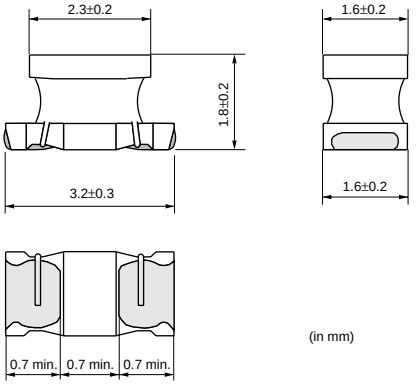
LQW31H Series (1206 Size)

LQW31H series is alumina core type chip inductor for high frequency circuit. Its low dc resistance and high Q due to wire wound structure are suitable for handheld telecommunications equipment.

■ Features

1. Inductance range from 8.8 to 100nH.
2. Because of the high self-resonant frequency, it can be used in high frequency range.
3. Tight inductance tolerance (+-5%)

■ Dimension



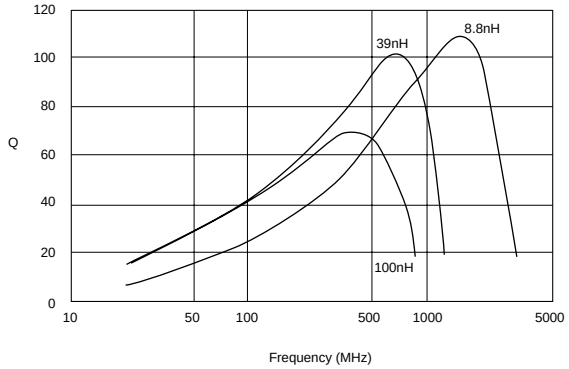
(in mm)

■ Rated Value (☐: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQW31HN8N8J03☐	8.8nH±5%	100MHz	750mA	0.029ohm±40%	50	436MHz	1000MHz
LQW31HN8N8K03☐	8.8nH±10%	100MHz	750mA	0.029ohm±40%	50	436MHz	1000MHz
LQW31HN15NJ03☐	14.7nH±5%	100MHz	680mA	0.035ohm±40%	60	436MHz	1000MHz
LQW31HN15NK03☐	14.7nH±10%	100MHz	680mA	0.035ohm±40%	60	436MHz	1000MHz
LQW31HN17NJ03☐	17nH±5%	100MHz	650mA	0.037ohm±40%	60	436MHz	1000MHz
LQW31HN17NK03☐	17nH±10%	100MHz	650mA	0.037ohm±40%	60	436MHz	1000MHz
LQW31HN23NJ03☐	23nH±5%	100MHz	590mA	0.046ohm±40%	60	436MHz	1000MHz
LQW31HN23NK03☐	23nH±10%	100MHz	590mA	0.046ohm±40%	60	436MHz	1000MHz
LQW31HN27NJ03☐	27nH±5%	100MHz	560mA	0.051ohm±40%	60	436MHz	1000MHz
LQW31HN27NK03☐	27nH±10%	100MHz	560mA	0.051ohm±40%	60	436MHz	1000MHz
LQW31HN33NJ03☐	33nH±5%	100MHz	530mA	0.057ohm±40%	60	436MHz	1000MHz
LQW31HN33NK03☐	33nH±10%	100MHz	530mA	0.057ohm±40%	60	436MHz	1000MHz
LQW31HN39NJ03☐	39nH±5%	100MHz	490mA	0.067ohm±40%	60	436MHz	1000MHz
LQW31HN39NK03☐	39nH±10%	100MHz	490mA	0.067ohm±40%	60	436MHz	1000MHz
LQW31HN47NJ03☐	47nH±5%	100MHz	380mA	0.11ohm±40%	60	436MHz	1000MHz
LQW31HN47NK03☐	47nH±10%	100MHz	380mA	0.11ohm±40%	60	436MHz	1000MHz
LQW31HN56NJ03☐	56nH±5%	100MHz	330mA	0.14ohm±40%	60	436MHz	1000MHz
LQW31HN56NK03☐	56nH±10%	100MHz	330mA	0.14ohm±40%	60	436MHz	1000MHz
LQW31HN64NJ03☐	64nH±5%	100MHz	290mA	0.18ohm±40%	60	436MHz	1000MHz
LQW31HN64NK03☐	64nH±10%	100MHz	290mA	0.18ohm±40%	60	436MHz	1000MHz
LQW31HN84NJ03☐	84nH±5%	100MHz	240mA	0.28ohm±40%	60	436MHz	1000MHz
LQW31HN84NK03☐	84nH±10%	100MHz	240mA	0.28ohm±40%	60	436MHz	1000MHz
LQW31HNR10J03☐	100nH±5%	100MHz	230mA	0.3ohm±40%	60	436MHz	900MHz
LQW31HNR10K03☐	100nH±10%	100MHz	230mA	0.3ohm±40%	60	436MHz	900MHz

Operating Temperature Range: -40°C to +85°C

■ Q - Frequency Characteristics (Typ.)



Inductor for High Frequency Wire Wound Type Ferrite Core (Horizontal Wire Wound)

muRata

LQW21H Series (0805 Size)

LQW21H Series is wire-wound chip inductor which is based on Murata's original ferrite core and precise wound technology. The use of a high frequency ferrite core as winding bobbin enables small size, but high inductance (micro H order) and high Q at FM band.

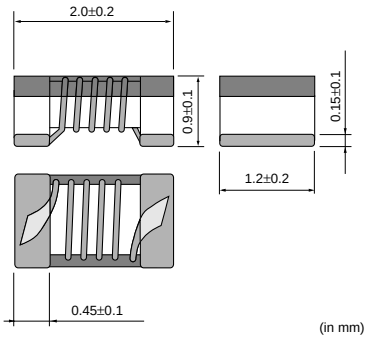
■ Features

1. High inductance (0.47 to 2.2 micro H) for FM band
2. High Q value
3. Smaller size and higher performance than 2.5x2.0mm air core inductor contributes to the design of smaller or thinner equipment.

■ Applications

1. TV tuner circuits of mobile phones
2. FM Transmitter circuits
3. Matching applications of FM band

■ Dimension



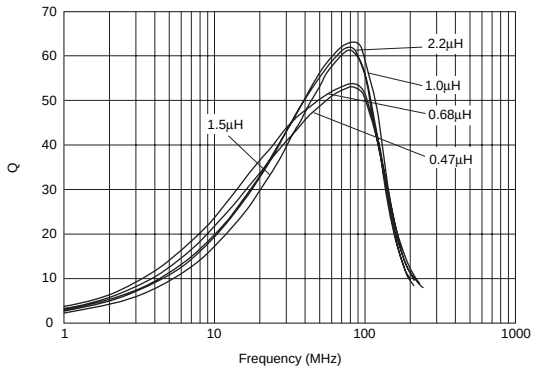
(in mm)

■ Rated Value (☐: packaging code)

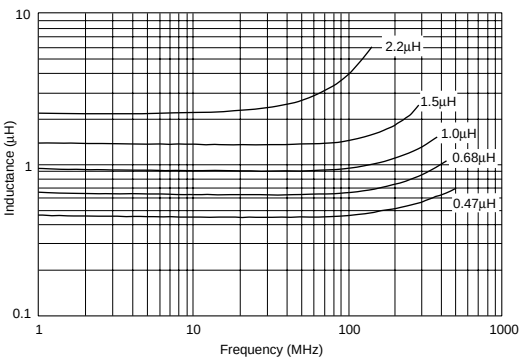
Part Number	Inductance	Test Frequency	Rated Current	Max. of DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQW21HNR47J00☐	0.47µH±5%	10MHz	160mA	1.30ohm	35	100MHz	620MHz
LQW21HNR56J00☐	0.56µH±5%	10MHz	150mA	1.43ohm	35	100MHz	580MHz
LQW21HNR68J00☐	0.68µH±5%	10MHz	130mA	2.21ohm	35	100MHz	520MHz
LQW21HNR82J00☐	0.82µH±5%	10MHz	125mA	2.34ohm	35	100MHz	480MHz
LQW21HN1R0J00☐	1.0µH±5%	10MHz	115mA	2.86ohm	35	100MHz	450MHz
LQW21HN1R2J00☐	1.2µH±5%	10MHz	100mA	3.12ohm	35	100MHz	400MHz
LQW21HN1R5J00☐	1.5µH±5%	10MHz	85mA	5.33ohm	35	100MHz	350MHz
LQW21HN1R8J00☐	1.8µH±5%	10MHz	80mA	5.85ohm	35	100MHz	320MHz
LQW21HN2R2J00☐	2.2µH±5%	10MHz	75mA	6.50ohm	35	100MHz	300MHz

Operating Temperature Range: -40°C to +85°C Only for reflow soldering.

■ Q - Frequency Characteristics (Typ.)



■ Inductance - Frequency Characteristics (Typ.)



muRata

Inductor for High Frequency Wire Wound Type Ferrite Core (Vertical Wire Wound)

muRata

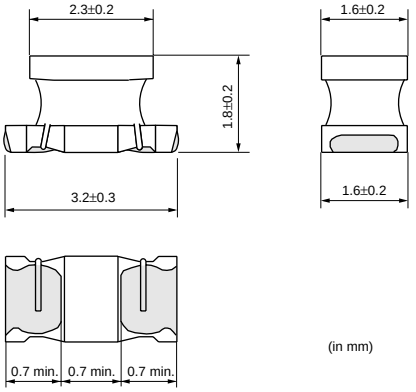
LQH31H Series (1206 Size)

LQH31H series is wire wound type chip inductor with ferrite core for high frequency.

■ Features

1. Inductance range from 54 to 880nH
2. High Q value and stable inductance in high frequency range from 30 to 150MHz
3. Applicable soldering methods are both flow soldering and reflow soldering.

■ Dimension



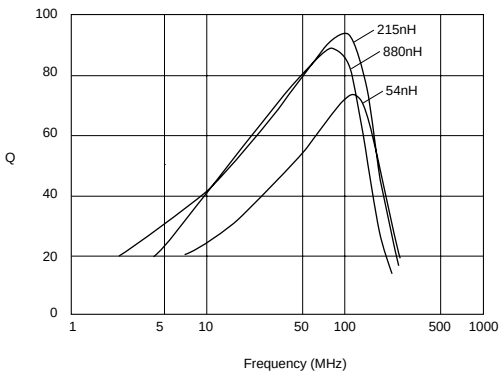
(in mm)

■ Rated Value (☐: packaging code)

Part Number	Inductance	Test Frequency	Rated Current	DC Resistance	Q (min.)	Test Frequency	Self Resonance Frequency (min.)
LQH31HN54NK03☐	54nH±10%	1MHz	920mA	0.035ohm±30%	50	100MHz	800MHz
LQH31HN95NK03☐	95nH±10%	1MHz	790mA	0.047ohm±30%	60	100MHz	650MHz
LQH31HNR14J03☐	145nH±5%	1MHz	700mA	0.061ohm±30%	60	100MHz	500MHz
LQH31HNR14K03☐	145nH±10%	1MHz	700mA	0.061ohm±30%	60	100MHz	500MHz
LQH31HNR21J03☐	215nH±5%	1MHz	520mA	0.11ohm±30%	60	100MHz	430MHz
LQH31HNR21K03☐	215nH±10%	1MHz	520mA	0.11ohm±30%	60	100MHz	430MHz
LQH31HNR29J03☐	290nH±5%	1MHz	420mA	0.17ohm±30%	60	100MHz	360MHz
LQH31HNR29K03☐	290nH±10%	1MHz	420mA	0.17ohm±30%	60	100MHz	360MHz
LQH31HNR39J03☐	390nH±5%	1MHz	330mA	0.26ohm±30%	60	100MHz	300MHz
LQH31HNR39K03☐	390nH±10%	1MHz	330mA	0.26ohm±30%	60	100MHz	300MHz
LQH31HNR50J03☐	500nH±5%	1MHz	260mA	0.44ohm±30%	60	100MHz	270MHz
LQH31HNR50K03☐	500nH±10%	1MHz	260mA	0.44ohm±30%	60	100MHz	270MHz
LQH31HNR61J03☐	610nH±5%	1MHz	250mA	0.48ohm±30%	60	100MHz	240MHz
LQH31HNR61K03☐	610nH±10%	1MHz	250mA	0.48ohm±30%	60	100MHz	240MHz
LQH31HNR75J03☐	750nH±5%	1MHz	190mA	0.79ohm±30%	60	100MHz	220MHz
LQH31HNR75K03☐	750nH±10%	1MHz	190mA	0.79ohm±30%	60	100MHz	220MHz
LQH31HNR88J03☐	880nH±5%	1MHz	180mA	0.86ohm±30%	60	100MHz	200MHz
LQH31HNR88K03☐	880nH±10%	1MHz	180mA	0.86ohm±30%	60	100MHz	200MHz

Operating Temperature Range: -40°C to +85°C

■ Q - Frequency Characteristics (Typ.)



⚠Caution/Notice

■ ⚠Caution (Rating)

Do not use products beyond the rated current as this may create excessive heat.

■ Notice (Storage and Operating Condition)

<Operating Environment>
Do not use products in chemical atmosphere such as chlorine gas, acid or sulfide gas.
<Storage Requirements>
1. Storage Period
LQG/LQM series should be used within 6 months; the other products should be used within 12 months. Check solderability if this period is exceeded.
2. Storage Conditions
(1) Store products in a warehouse in compliance with the following conditions:
Temperature: -10 to +40 degrees C.
Humidity: 15 to 85% (relative humidity)
Do not subject products to rapid changes in temperature and humidity.
Do not store them in chemical atmosphere such as one containing sulfurous acid gas or alkaline gas. This will prevent electrode oxidation which causes poor solderability and possible corrosion of inductors.
(2) Do not store products in bulk packaging to prevent collision among inductors which causes core chipping and wire breakage.
(3) Store products on pallets to protect from humidity, dust, etc.
(4) Avoid heat shock, vibration, direct sunlight, etc.

■ Notice (Handling)

This item is designed to have sufficient strength, but handle with care to avoid chipping or breaking its ceramic structure.
LQW_A series/ LQW_H series
• To prevent breaking the wire, avoid touching sharp material, such as tweezers, to the wire wound portion.
• To prevent breaking the core, avoid applying excessive mechanical shock to products mounted on the board.
• In some mounting machines, when picking up components, support pin pushes up the components from the bottom of base tape. In this case, please remove the support pin. The support pin may damage the components and break wire.
• In rare case, the laser recognition can not recognize this component. Please contact us when you use laser recognizion. (There is no problem with the permeation and reflection type.)
LQH_C/D/H/M/N/P series
• To prevent breaking the wire, avoid touching sharp material, such as tweezers, to the wire wound portion.
• To prevent breaking the core, avoid applying excessive mechanical shock to products mounted on the board.
• Temperature may rise up to max. 40 °C when applying the rated current to LQH3NP. Be careful of the temperature rating of the circuit board and components around the chip inductor.
LQG,LQP series (exept LQP02T_02/LQP03T_02)
• The pattern of the chip inductor is covered with protective film. Take care to avoid damaging the chip inductor when handling it with pick-up nozzles, sharp instruments, etc.
LQM series
• There is the possibility that magnetism may change the inductance value. Do not use a magnet or tweezers with magnetism when handling chip inductors. (The tip of the tweezers should be molded with resin or pottery.)
• When the excessive current over rated current is applied, it may cause the inductance value to change due to magnetism.
<Handling>
1. Avoid applying excessive stress to products to prevent damage.
2. Do not touch wire wound with sharp objects such as tweezers to prevent wire breakage.
3. Do not apply excessive force to products mounted on boards to prevent core breakage.

Continued on the following page.

⚠Caution/Notice

Continued from the preceding page.

<Transportation>

Do not apply excessive vibration or mechanical shock to products.

<Resin Coating>

When coating products with resin, the relatively high resin curing stress may change inductance values.

For exterior coating, select resin carefully so that electrical and mechanical performance of the product is not affected. Prior to use, please evaluate reliability with the product mounted in your application set.

(LQW,LQH series)

An open circuit issue may occur by mechanical stress caused by the resin, amount/cured shape of resin, or operating condition etc. Some resins containing impurities or chloride may possibly generate chlorine by hydrolysis under some operating condition may cause corrosion of wire of inductor, leading to open circuit.

(LQP02T_02,LQP03T_02)

When products are coated with resin, please contact us in advance.

<Allowable DC Current>

(LQH2MCN, LQH_P series)

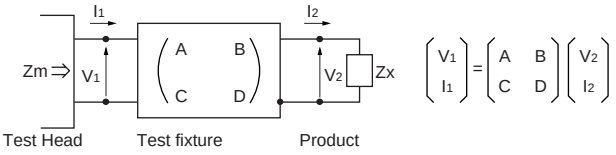
When Allowable DC Current is applied to the Products, self-generation of heat will rise to 40°C or less.

When Allowable DC Current is applied to the Products, Inductance will be within ±30% of nominal Inductance value.

■ Notice (Measuring Method)

Measuring Method of Inductance/Q

1. Residual elements and stray elements of test fixture can be described by F-parameter as shown in the following:



$$\begin{pmatrix} V_1 \\ I_1 \end{pmatrix} = \begin{pmatrix} A & B \\ C & D \end{pmatrix} \begin{pmatrix} V_2 \\ I_2 \end{pmatrix}$$

2. The impedance of chip inductor (chip coil) Zx and measured value Zm can be described by input/output current/voltage.

$$Zm = \frac{V_1}{I_1} \quad , \quad Zx = \frac{V_2}{I_2}$$

3. Thus, the relation between Zx and Zm is shown in the following:

$$Zx = \alpha \frac{Zm - \beta}{1 - Zm\Gamma}$$

where, $\alpha = D / A = 1$
$\beta = B / D = Zsm - (1 - Yom\ Zsm)\ Zss$
$\Gamma = C / A = Yom$

(Zsm: measured impedance of short chip
Zss: residual impedance of short chip*
Yom: measured admittance when opening the fixture)

*Residual impedance of short chip

Residual Impedance	Series
0nH	**LQG15HS**
0.110nH	**LQP02T**
0.430nH	**LQP03T_00/_04**
0.464nH	**LQW04A**
0.480nH	**LQP03T_02**
0.556nH	**LQG15HN, LQW15A, LQP15T/M**
0.771nH	**LQG18H, LQP18M, LQW18A, LQW21H**

4. Lx and Qx should be calculated with the following equation.

$$Lx = \frac{Im\ (Zx)}{2\pi f} \quad , \quad Qx = \frac{Im\ (Zx)}{Re\ (Zx)}$$

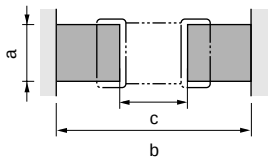
Lx: Inductance of chip inductor (chip coil)
Qx: Q of chip inductor (chip coil)
f: Measuring frequency

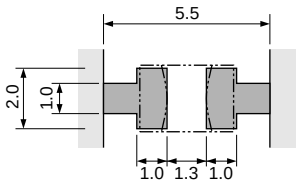
Soldering and Mounting

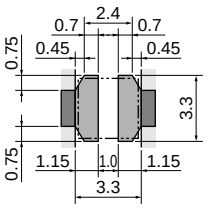
1. Standard Land Dimensions

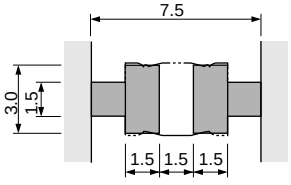
A high Q value is achieved when the PCB electrode land pattern is designed so that it does not project beyond the chip inductor (chip coil) electrode.

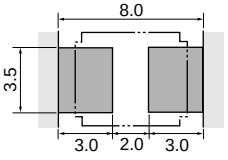
Land Pattern + Solder Resist
Land Pattern
Solder Resist
(in mm)

<table>
<tr><th>Series</th><th>Standard Land Dimensions</th></tr>
<tr><td>LQG15H
LQG18H
LQM18N/18F
LQM21N/21D/21F/21P
LQM2HP
LQM2MP
LQM31F
LQM31P
LQP02T
LQP03T
LQP15M/15T
LQP18M
LQH2MC
LQH32P
LQW04A
LQW15A
LQW18A
LQW21H
LQW2BH
LQW31H
LQH31M/31C/31H</td><td>


<table>
<tr><th colspan="2">Part Number</th><th>a</th><th>b</th><th>c</th></tr>
<tr><td colspan="2">LQG15H</td><td>0.5-0.6</td><td>1.4-1.5</td><td>0.4</td></tr>
<tr><td colspan="2">LQG18H</td><td>0.6-0.8</td><td>1.8-2.2</td><td>0.6-0.8</td></tr>
<tr><td rowspan="2">LQM18N /18F</td><td>Flow</td><td rowspan="2">0.7</td><td>2.2-2.6</td><td rowspan="2">0.7</td></tr>
<tr><td>Reflow</td><td>1.8-2.0</td></tr>
<tr><td colspan="2">LQM21N/21D/21F/21P</td><td>1.0</td><td>3.0-4.0</td><td>1.2</td></tr>
<tr><td colspan="2">LQM2HP</td><td>1.5</td><td>3.0</td><td>1.6</td></tr>
<tr><td colspan="2">LQM2MP</td><td>1.8</td><td>2.4</td><td>0.8</td></tr>
<tr><td colspan="2">LQM31F/31P</td><td>1.2</td><td>4.2-5.2</td><td>2.0</td></tr>
<tr><td colspan="2">LQP02T</td><td>0.2-0.23</td><td>0.4-0.56</td><td>0.16-0.2</td></tr>
<tr><td colspan="2">LQP03T</td><td>0.2-0.3</td><td>0.8-0.9</td><td>0.2-0.3</td></tr>
<tr><td colspan="2">LQP15M/15T</td><td>0.5-0.6</td><td>1.4-1.5</td><td>0.4</td></tr>
<tr><td colspan="2">LQP18M</td><td>0.7-0.9</td><td>1.8-2.2</td><td>0.6-0.8</td></tr>
<tr><td colspan="2">LQH2MC</td><td>1.0</td><td>2.6</td><td>0.8</td></tr>
<tr><td colspan="2">LQH32P</td><td>2.0</td><td>3.8</td><td>1.3</td></tr>
<tr><td colspan="2">LQW04A</td><td>0.40</td><td>1.0</td><td>0.40</td></tr>
<tr><td colspan="2">LQW15A</td><td>0.65</td><td>1.2</td><td>0.50</td></tr>
<tr><td colspan="2">LQW18A</td><td>0.7-1.0</td><td>1.8-2.0</td><td>0.6-0.8</td></tr>
<tr><td colspan="2">LQW21H</td><td>1.2</td><td>2.6</td><td>1.0</td></tr>
<tr><td colspan="2">LQW2BH</td><td>1.2</td><td>3.0</td><td>0.8</td></tr>
<tr><td colspan="2">LQH31M/31C/31H
LQW31H</td><td>1.5</td><td>4.5</td><td>1.0</td></tr>
</table>
</td></tr>
<tr><td>LQH32M
LQH32C</td><td>


</td></tr>
<tr><td>LQH3NP</td><td>


</td></tr>
<tr><td>LQH43M
LQH43N
LQH43C</td><td>


</td></tr>
<tr><td>LQH55D
LQH66S</td><td>


</td></tr>
</table>

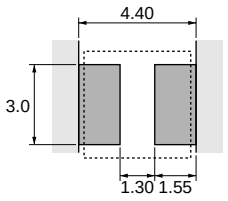
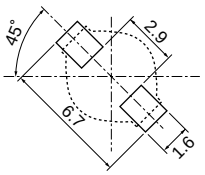
Attention should be paid to potential magnetic coupling effects when using the inductor (coil) as a resonator.

Continued on the following page.

Soldering and Mounting

Continued from the preceding page.

Land Pattern + Solder Resist
Land Pattern
Solder Resist
(in mm)

Series	Standard Land Dimensions
LQH44P	
LQH55P	

Attention should be paid to potential magnetic coupling effects when using the inductor (coil) as a resonator.

2. Standard Soldering Conditions

(1) Soldering method

Chip inductor (Chip coils) can be flow or reflow soldered. Please contact Murata regarding other soldering methods.

As for LQG, LQP, LQW04A/15A/18A/21H, LQH2MC/55D/66S/32P/3NP/44P/55P series, please use reflow soldering.

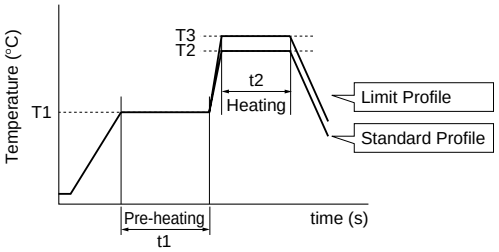
Solder: Use Sn-3.0Ag-0.5Cu solder.

Flux: Use rosin-based flux, but not strongly acidic flux (with chlorine content exceeding 0.2wt%).
Do not use water-soluble flux.
The flux used for LQW04/15/18/21 series should use the rosin-based flux that includes middle activator equivalent to 0.06wt% to 0.1wt% chlorine.

For additional mounting methods, please contact Murata.

(2) Soldering profile

●Flow Soldering profile
(Sn-3.0Ag-0.5Cu solder)



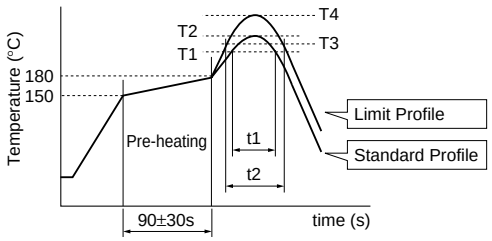
Series	Pre-heating		Standard Profile			Limit Profile		
			Heating		Cycle of flow	Heating		Cycle of flow
	Temp. (T1)	Time. (t1)	Temp. (T2)	Time. (t2)		Temp. (T3)	Time. (t2)	
LQM18N/18F LQM21N/21D/21F/21P/2HP/2MP LQM31F/31P LQW2BH/31H LQH31C/31H/31M	150°C	60s min.	250°C	4 to 6s	2 times max.	265±3°C	5s max.	2 times max.
LQH32C/32M LQH43C/43M(N)	150°C	60s min.	250°C	4 to 6s	2 times max.	265±3°C	5s max.	1 times

Continued on the following page.

Soldering and Mounting

Continued from the preceding page.

●Reflow Soldering profile
(Sn-3.0Ag-0.5Cu solder)



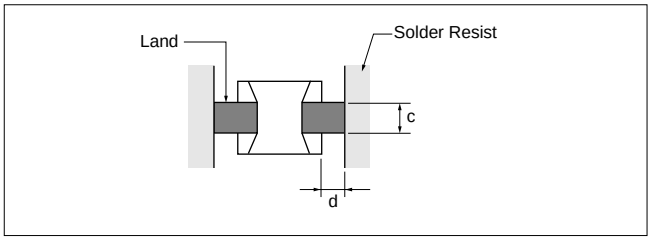
Series	Standard Profile				Limit Profile			
	Heating		Peak temperature (T2)	Cycle of reflow	Heating		Peak temperature (T4)	Cycle of reflow
	Temp. (T1)	Time. (t1)			Temp. (T3)	Time. (t2)		
LQG15H/18H LQW04A/15A/18A/21H LQP02T/03T/15M/15T/18M LQW2BH/31H LQM18N/18F LQM21N/21D/21F/21P/2HP/2MP LQM31F/31P, LQH2MC LQH31C/31H/31M LQH32P/3NP/44P/55P	220°C	30 to 60s	245±3°C	2 times max.	230°C	60s max.	260°C/10s	2 times max.
LQH32C/32M LQH43C/43M(N) LQH55D, LQH66S	220°C	30 to 60s	245±3°C	2 times max.	230°C	60s max.	260°C/10s	1 time

(3) Reworking with Soldering Iron *Except LQP02T Series
Preheating at 150°C for 1 minute is required. Do not directly touch the ceramic element with the tip of the soldering iron. The reworking soldering conditions are as follows:

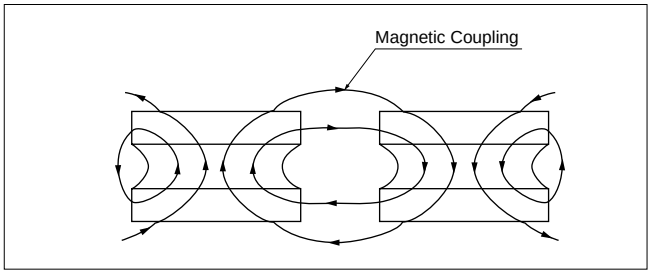
Soldering iron power output: 80W max.
Temperature of soldering iron tip: 350°C
Diameter of soldering iron end: 3.0mm max.
Soldering time: within 3 s

3. Mounting Instructions

(1) Land Pattern Dimensions
Large lands reduce Q of the mounted chip. Also, large protruding land areas (bordered by lines having dimensions 'c' and 'd' shown) cause floating and electrode leaching.



(2) Magnetic Coupling
Since some chip inductors (chip coils) are constructed like an open magnetic circuit, narrow spacing between inductors (coils) may cause magnetic coupling.
LQM, LQH66S and LQH32P/3NP series have a magnetically shielded structure. The structure makes their coupling coefficient smaller than that of conventional chip inductors (chip coils).



Continued on the following page.

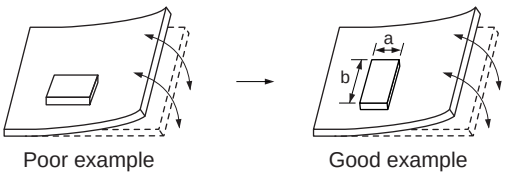
Soldering and Mounting

Continued from the preceding page.

(3) PCB Warping

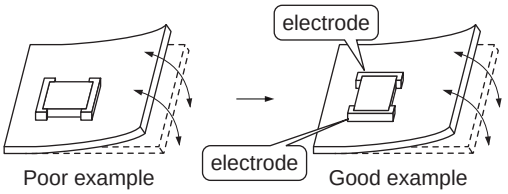
PCB should be designed so that products are not subjected to the mechanical stress caused by warping the board.

Products should be located in the sideways direction (Length: a<b) to the mechanical stress.



except LQH3NP/44P

The electrode part of the product should be located like the picture to the mechanical stress.



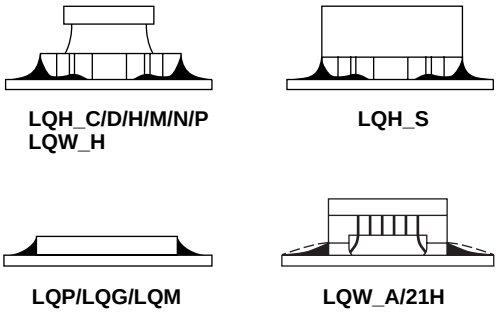
LQH3NP/44P

(4) Amount of Solder Paste

Excessive solder causes electrode corrosion, while insufficient solder causes low electrode bonding strength. Adjust the amount of solder paste as shown on the right so that solder is applied.

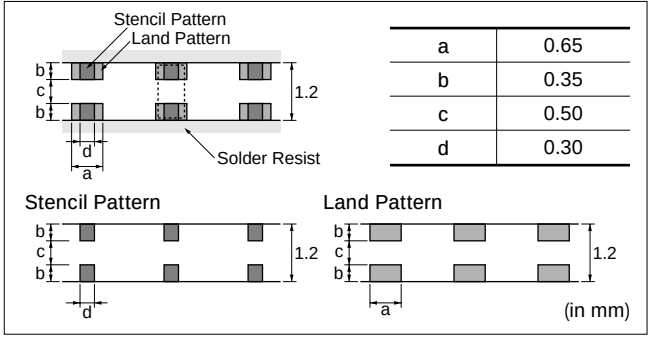
● Guideline of solder paste thickness

· LQP (Except LQP02T), LQG, LQM, LQW15A/18A/21H, LQH2MC, LQH44P/55P: 100 to 150μm
· LQP02T: 50 to 80μm
· LQW04A: 80 to 100μm
· LQW_H, LQHs except for ones written above: 200 to 300μm



LQW15A Series:

Too much solder may cause slant or rotation of chip at the time of solder melting. Please reduce the amount of solder by using smaller solder area than land pattern, as shown in figure at right.



a	0.65
b	0.35
c	0.50
d	0.30

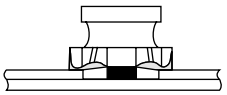
Continued on the following page.

Soldering and Mounting

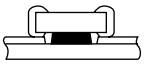
Continued from the preceding page.

(5) Amount of Adhesive

If too much adhesive is applied, then it may overflow into the land or termination areas and yield poor solderability. In contrast, if insufficient adhesive is applied, or if the adhesive is not sufficiently hardened, then the chip may become detached during flow soldering. Apply the adhesive in accordance with the conditions shown in chart.



LQH_C/H/M/N
LQW_H



LQM

Part Number	Typical Application Amount (in:mg)
	IR-100
LQM18N/18F	0.06-0.07
LQM21N/21D/21F/21P/2MP	0.20-0.25
LQM31F/31P/2HP	0.25-0.30
LQW2BH	0.15-0.20
LQH31M/31C/31H **LQW31H**	0.20-0.25
LQH32M/32C	0.27-0.35
LQH43M(N) **LQH43C**	0.60-0.80

4. Cleaning

The following conditions should be observed when cleaning chip inductors (chip coils):

(1) Cleaning Temperature: 60°C max. (40°C max. for alcohol cleaning agents)

(2) Ultrasonic

Output: 20W/l max.
Duration: 5 minutes max.
Frequency: 28 to 40kHz
Care should be taken not to cause resonance of the PCB and mounted products.

(3) Cleaning agent

The following cleaning agents have been tested on individual components. Evaluation in complete assembly should be done prior to production.

(a) Alcohol cleaning agents
Isopropyl alcohol (IPA)

(b) Aqueous cleaning agents
Pine Alpha ST-100S
LQH66S/LQH6PP/LQH88P series: Aqueous agents should not be used because they may cause quality deterioration or damage to appearance.

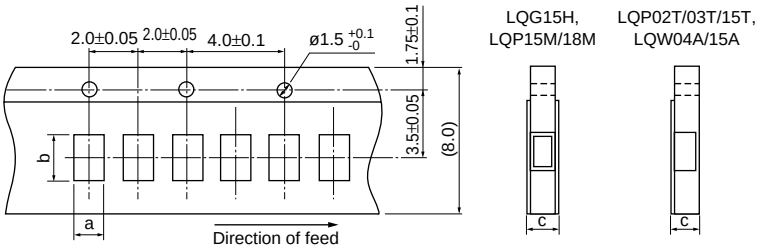
(4) Ensure that flux residue is completely removed.

Component should be thoroughly dried after aqueous agents have been removed with deionized water.

For additional cleaning methods, please contact Murata.

Packaging

■ Minimum Quantity and 8mm Width Taping Dimensions



Paper Tape

Part Number	Dimensions		Total Thickness of Tape	Packaging Code (Minimum Qty. [pcs.])		
	a	b	c	ø180mm reel	ø330mm reel	Bulk
LQG15H	0.62	1.12	0.8 max.	**D** [10000]	**J** [50000]	**B** [1000]
LQP02T	0.24	0.455	0.39 max.	**D** [20000]	-	**B** [500]
LQP03T_00/_04	0.38	0.68	0.55 max.	**D** [10000]	**J** [50000]	**B** [500]
LQP03T_02	0.35	0.65	0.55 max.	**D** [15000]	**J** [50000]	**B** [500]
LQP15T	0.62	1.12	0.8 max.	**D** [10000]	-	**B** [500]
LQP15M	0.70	1.20	0.8 max.	**D** [10000]	**J** [50000]	**B** [500]
LQP18M	1.19	2.0	0.8 max.	**D** [4000]	**J** [10000]	**B** [500]
LQW04A	0.50	0.905	0.75 max.	**D** [10000]	-	**B** [500]
LQW15A_00 ∗1	0.64/0.66/0.69	1.18	0.8 max.	**D** [10000]	-	**B** [500]
LQW15A_10 ∗2	0.66/0.69	1.18	0.8 max.	**D** [10000]	-	**B** [500]

∗1 0.69 (1.5-2.7nH, 3.9-4.7nH, 5.8-6.8nH, 8.2-9.5nH, 11nH, 12nH, 15nH)
0.66 (2.9nH, 5.1nH, 7.3nH, 7.5nH, 10nH, 13nH, 16-23nH, 100nH, 120nH)
0.64 (24-91nH)
∗2 0.69 (1.3nH)
0.66 (2.2-5.6nH)

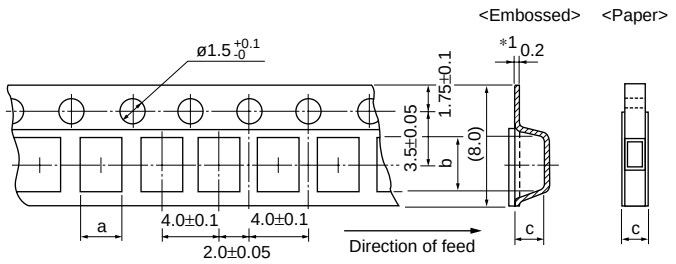
(in mm)

Continued on the following page.

Packaging

Continued from the preceding page.

■ Minimum Quantity and 8mm Width Taping Dimensions



*1: 0.3 LQW2BH
0.25 LQM2HP/31P_00, LQH2, LQW21H

Dimension of the cavity of embossed tape is measured at the bottom side.

Paper Tape

Part Number	Dimensions		Total Thickness of Tape	Packaging Code (Minimum Qty. [pcs.])		
	a	b	c	ø180mm reel	ø330mm reel	Bulk
LQM21N (0.1-2.2μH)	1.45	2.25	1.1 max.	**D** [4000]	**J** [10000]	**B** [1000]
LQM21D (1-10μH)	1.45	2.25	1.1 max.	**D** [4000]	**J** [10000]	**B** [1000]
LQM21F (1-2.2μH)	1.45	2.25	1.1 max.	**D** [4000]	**J** [10000]	**B** [1000]
LQM21P_C0	1.45	2.25	0.8 max.	**D** [4000]	-	-
LQM21P_G0	1.45	2.25	1.1 max.	**D** [4000]	-	-
LQM31P_C0	1.8	3.4	0.8 max.	**D** [4000]	-	**B** [1000]
LQG18H	1.05	1.85	1.1 max.	**D** [4000]	**J** [10000]	**B** [1000]
LQM18N/18F	1.05	1.85	1.1 max.	**D** [4000]	**J** [10000]	**B** [1000]
LQW18A_00	1.0	1.8	1.1 max.	**D** [4000]	**J** [10000]	**B** [500]
LQW18A_10	1.1	1.9	1.1 max.	**D** [4000]	**J** [10000]	**B** [500]

Embossed Tape

Part Number	Dimensions		Depth of Cavity	Packaging Code (Minimum Qty. [pcs.])		
	a	b	c	ø180mm reel	ø330mm reel	Bulk
LQM21N (2.7-4.7μH)	1.45	2.25	1.3	**L** [3000]	**K** [10000]	**B** [1000]
LQM21D (22-47μH)	1.45	2.25	1.3	**L** [3000]	**K** [10000]	**B** [1000]
LQM21F (4.7-47μH)	1.45	2.25	1.3	**L** [3000]	**K** [10000]	**B** [1000]
LQM2HP_J0	2.25	2.75	1.3	**L** [3000]	-	**B** [1000]
LQM2HP_G0	2.3	2.8	1.1	**L** [3000]	-	**B** [1000]
LQM2HP_E0	2.3	2.8	0.9	**L** [3000]	-	**B** [1000]
LQM2MP_G0	1.85	2.25	1.1	**L** [3000]	-	**B** [1000]
LQM31F	1.9	3.5	1.3	**L** [3000]	**K** [10000]	**B** [1000]
LQM31P_00	1.9	3.5	1.05	**L** [3000]	-	**B** [1000]
LQH31M/31C/31H, LQW31H	1.9	3.6	2.0	**L** [2000]	**K** [7500]	-
LQW21H	1.55	2.3	1.1	**L** [3000]	-	**B** [500]
LQW2BH	1.75	2.3	2.0	**L** [2000]	**K** [7500]	-
LQH32M, LQH32C_33/_23	2.9	3.6	2.1	**L** [2000]	**K** [7500]	-
LQH32C_53	2.9	3.6	1.7	**L** [2000]	**K** [7500]	-
LQH32P	2.9	3.6	1.7	**L** [2000]	**K** [7500]	-
LQH2MC_02	1.9	2.3	1.05	**L** [3000]	-	**B** [100]
LQH2MC_52	1.9	2.3	0.8	**L** [3000]	-	**B** [100]

(in mm)

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Packaging

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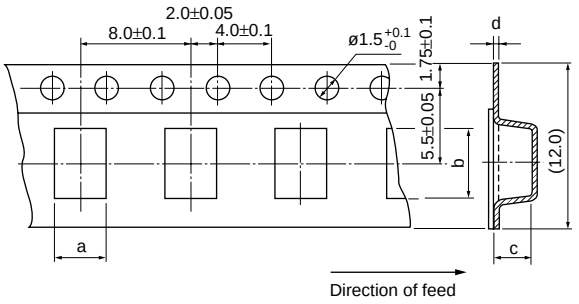
■ Minimum Quantity and 12mm Width Embossed Taping Dimensions



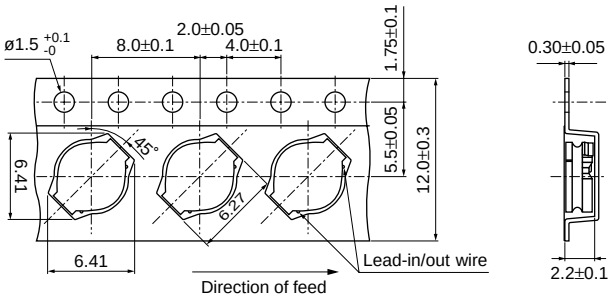
Dimension of the cavity of embossed tape is measured at the bottom side.

Embossed Tape

Part Number	Dimensions (*c: Depth of Cavity)				Packaging Code (Minimum Qty. [pcs.])		
	a	b	c	d	ø180mm reel	ø330mm reel	Bulk
LQH3NP_M0	3.3	3.3	1.6	0.25	**L** [1000]	**K** [4000]	-
LQH3NP_J0	3.3	3.3	1.3	0.25	**L** [1000]	**K** [5000]	-
LQH3NP_G0	3.3	3.3	1.1	0.25	**L** [1500]	**K** [6000]	-
LQH43M(N)	3.6	4.9	2.7	0.3	**L** [500]	**K** [2500]	-
LQH43C	3.6	4.9	2.7	0.3	**L** [500]	-	-
LQH44 P_J0	4.3	4.3	1.4	0.3	**L** [1000]	**K** [3500]	-
LQH44P_P0	4.3	4.3	1.9	0.3	**L** [1000]	**K** [3500]	-
LQH55D	5.4	6.1	5.0	0.4	**L** [350]	**K** [1500]	-
LQH6PP	6.3	6.3	4.7	0.4	**L** [250]	**K** [1500]	-
LQH66S	6.7	6.7	5.6	0.4	**L** [350]	**K** [1500]	-

(in mm)

■ Minimum Quantity and 12mm Width Embossed Taping Dimensions



Dimension of the cavity of embossed tape is measured at the bottom side.

Embossed Tape

Part Number	Packaging Code (Minimum Qty. [pcs.])		
	ø180mm reel	ø330mm reel	Bulk
LQH55P	**L** [500]	**K** [3000]	-

(in mm)

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Packaging

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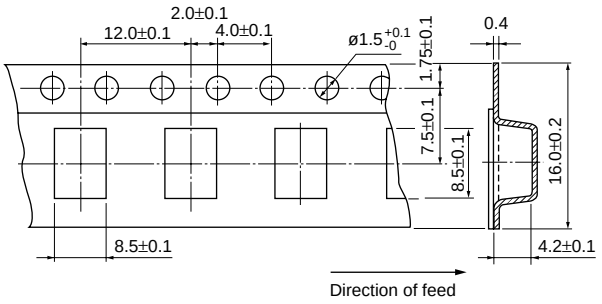
■ Minimum Quantity and 16mm Width Embossed Taping Dimensions



Dimension of the cavity of embossed tape is measured at the bottom side.

Embossed Tape

Part Number	Packaging Code (Minimum Qty. [pcs.])		
	ø180mm reel	ø330mm reel	Bulk
LQH88P	**L** [250]	**K** [1000]	-

(in mm)

Design Kits

●EKLMQ15SC (High Frequency Multilayer Type)

No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
1	**LQG15HS1N0S02**	10	1.0nH	±0.3nH	8	0.07	300
2	**LQG15HS1N1S02**	10	1.1nH	±0.3nH	8	0.09	300
3	**LQG15HS1N2S02**	10	1.2nH	±0.3nH	8	0.09	300
4	**LQG15HS1N3S02**	10	1.3nH	±0.3nH	8	0.09	300
5	**LQG15HS1N5S02**	10	1.5nH	±0.3nH	8	0.10	300
6	**LQG15HS1N6S02**	10	1.6nH	±0.3nH	8	0.10	300
7	**LQG15HS1N8S02**	10	1.8nH	±0.3nH	8	0.10	300
8	**LQG15HS2N0S02**	10	2.0nH	±0.3nH	8	0.10	300
9	**LQG15HS2N2S02**	10	2.2nH	±0.3nH	8	0.12	300
10	**LQG15HS2N4S02**	10	2.4nH	±0.3nH	8	0.15	300
11	**LQG15HS2N7S02**	10	2.7nH	±0.3nH	8	0.15	300
12	**LQG15HS3N0S02**	10	3.0nH	±0.3nH	8	0.17	300
13	**LQG15HS3N3S02**	10	3.3nH	±0.3nH	8	0.17	300
14	**LQG15HS3N6S02**	10	3.6nH	±0.3nH	8	0.18	300
15	**LQG15HS3N9S02**	10	3.9nH	±0.3nH	8	0.18	300
16	**LQG15HS4N3S02**	10	4.3nH	±0.3nH	8	0.18	300
17	**LQG15HS4N7S02**	10	4.7nH	±0.3nH	8	0.18	300
18	**LQG15HS5N1S02**	10	5.1nH	±0.3nH	8	0.20	300
19	**LQG15HS5N6S02**	10	5.6nH	±0.3nH	8	0.20	300
20	**LQG15HS6N2S02**	10	6.2nH	±0.3nH	8	0.22	300
21	**LQG15HS6N8J02**	10	6.8nH	±5%	8	0.24	300
22	**LQG15HS7N5J02**	10	7.5nH	±5%	8	0.24	300
23	**LQG15HS8N2J02**	10	8.2nH	±5%	8	0.24	300
24	**LQG15HS9N1J02**	10	9.1nH	±5%	8	0.26	300
25	**LQG15HS10NJ02**	10	10nH	±5%	8	0.26	300
26	**LQG15HS12NJ02**	10	12nH	±5%	8	0.28	300
27	**LQG15HS15NJ02**	10	15nH	±5%	8	0.32	300
28	**LQG15HS18NJ02**	10	18nH	±5%	8	0.36	300
29	**LQG15HS22NJ02**	10	22nH	±5%	8	0.42	300
30	**LQG15HS27NJ02**	10	27nH	±5%	8	0.46	300
31	**LQG15HS33NJ02**	10	33nH	±5%	8	0.58	200
32	**LQG15HS39NJ02**	10	39nH	±5%	8	0.65	200
33	**LQG15HS47NJ02**	10	47nH	±5%	8	0.72	200
34	**LQG15HS56NJ02**	10	56nH	±5%	8	0.82	200
35	**LQG15HS68NJ02**	10	68nH	±5%	8	0.92	180
36	**LQG15HS82NJ02**	10	82nH	±5%	8	1.20	150
37	**LQG15HSR10J02**	10	100nH	±5%	8	1.25	150
38	**LQG15HSR12J02**	10	120nH	±5%	8	1.30	150
39	**LQG15HSR15J02**	10	150nH	±5%	8	2.99	140
40	**LQG15HSR18J02**	10	180nH	±5%	8	3.38	130

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Design Kits

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No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
41	**LQG15HSR22J02**	10	220nH	±5%	8	3.77	120
42	**LQG15HSR27J02**	10	270nH	±5%	8	4.94	110

●EKLMQG18B (High Frequency Multilayer Type)

No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
1	**LQG18HN1N2S00**	10	1.2nH	±0.3nH	12	0.10	300
2	**LQG18HN1N5S00**	10	1.5nH	±0.3nH	12	0.10	300
3	**LQG18HN1N8S00**	10	1.8nH	±0.3nH	12	0.10	300
4	**LQG18HN2N2S00**	10	2.2nH	±0.3nH	12	0.10	300
5	**LQG18HN2N7S00**	10	2.7nH	±0.3nH	12	0.15	300
6	**LQG18HN3N3S00**	10	3.3nH	±0.3nH	12	0.15	300
7	**LQG18HN3N9S00**	10	3.9nH	±0.3nH	12	0.15	300
8	**LQG18HN4N7S00**	10	4.7nH	±0.3nH	12	0.20	300
9	**LQG18HN5N6S00**	10	5.6nH	±0.3nH	12	0.20	300
10	**LQG18HN6N8J00**	10	6.8nH	±5%	12	0.25	300
11	**LQG18HN8N2J00**	10	8.2nH	±5%	12	0.25	300
12	**LQG18HN10NJ00**	10	10nH	±5%	12	0.30	300
13	**LQG18HN12NJ00**	10	12nH	±5%	12	0.35	300
14	**LQG18HN15NJ00**	10	15nH	±5%	12	0.40	300
15	**LQG18HN18NJ00**	10	18nH	±5%	12	0.45	300
16	**LQG18HN22NJ00**	10	22nH	±5%	12	0.50	300
17	**LQG18HN27NJ00**	10	27nH	±5%	12	0.55	300
18	**LQG18HN33NJ00**	10	33nH	±5%	12	0.60	300
19	**LQG18HN39NJ00**	10	39nH	±5%	12	0.65	300
20	**LQG18HN47NJ00**	10	47nH	±5%	12	0.70	300
21	**LQG18HN56NJ00**	10	56nH	±5%	12	0.75	300
22	**LQG18HN68NJ00**	10	68nH	±5%	12	0.80	300
23	**LQG18HN82NJ00**	10	82nH	±5%	12	0.85	300
24	**LQG18HNR10J00**	10	100nH	±5%	12	0.90	300

●EKLMQP02C (High Frequency Film Type)

No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
1	**LQP02TN0N4S02**	10	0.4nH	±0.3nH	8	0.60	320
2	**LQP02TN0N5S02**	10	0.5nH	±0.3nH	8	0.60	320
3	**LQP02TN0N6S02**	10	0.6nH	±0.3nH	8	0.60	320
4	**LQP02TN0N7S02**	10	0.7nH	±0.3nH	8	0.60	320
5	**LQP02TN0N8S02**	10	0.8nH	±0.3nH	8	0.60	320
6	**LQP02TN0N9S02**	10	0.9nH	±0.3nH	8	0.60	320
7	**LQP02TN1N0S02**	10	1.0nH	±0.3nH	8	0.90	220
8	**LQP02TN1N1S02**	10	1.1nH	±0.3nH	8	0.90	220
9	**LQP02TN1N2S02**	10	1.2nH	±0.3nH	8	0.90	220
10	**LQP02TN1N3S02**	10	1.3nH	±0.3nH	8	0.90	220
11	**LQP02TN1N5S02**	10	1.5nH	±0.3nH	8	0.90	220
12	**LQP02TN1N6S02**	10	1.6nH	±0.3nH	8	0.90	220
13	**LQP02TN1N8S02**	10	1.8nH	±0.3nH	8	1.35	200
14	**LQP02TN2N0S02**	10	2.0nH	±0.3nH	8	1.35	200
15	**LQP02TN2N2S02**	10	2.2nH	±0.3nH	8	1.35	200
16	**LQP02TN2N4S02**	10	2.4nH	±0.3nH	8	1.35	200

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No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
17	**LQP02TN2N7S02**	10	2.7nH	±0.3nH	8	1.35	200
18	**LQP02TN3N0S02**	10	3.0nH	±0.3nH	8	1.35	200
19	**LQP02TN3N3S02**	10	3.3nH	±0.3nH	8	1.65	180
20	**LQP02TN3N6S02**	10	3.6nH	±0.3nH	8	1.65	180
21	**LQP02TN3N9S02**	10	3.9nH	±0.3nH	8	1.65	180
22	**LQP02TN4N3S02**	10	4.3nH	±0.3nH	8	1.65	180
23	**LQP02TN4N7S02**	10	4.7nH	±0.3nH	8	2.10	160
24	**LQP02TN5N1S02**	10	5.1nH	±0.3nH	8	2.10	160
25	**LQP02TN5N6S02**	10	5.6nH	±0.3nH	8	2.40	140
26	**LQP02TN6N2J02**	10	6.2nH	±5%	8	2.40	140
27	**LQP02TN6N8J02**	10	6.8nH	±5%	8	2.85	140
28	**LQP02TN7N5J02**	10	7.5nH	±5%	8	2.85	140
29	**LQP02TN8N2J02**	10	8.2nH	±5%	8	3.15	140
30	**LQP02TN9N1J02**	10	9.1nH	±5%	8	3.15	140
31	**LQP02TN10NJ02**	10	10nH	±5%	8	3.60	140
32	**LQP02TN12NJ02**	10	12nH	±5%	7	3.90	140
33	**LQP02TN15NJ02**	10	15nH	±5%	7	4.35	140
34	**LQP02TN18NJ02**	10	18nH	±5%	7	4.80	140

●EKLMQP03K (High Frequency Film Type)

No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
1	**LQP03TN0N6B00**	10	0.6nH	±0.1nH	13	0.08	840
2	**LQP03TN1N0B00**	10	1.0nH	±0.1nH	13	0.10	800
3	**LQP03TN1N1B00**	10	1.1nH	±0.1nH	13	0.13	560
4	**LQP03TN1N2B00**	10	1.2nH	±0.1nH	13	0.13	560
5	**LQP03TN1N3B00**	10	1.3nH	±0.1nH	13	0.16	560
6	**LQP03TN1N4B00**	10	1.4nH	±0.1nH	13	0.16	560
7	**LQP03TN1N5B00**	10	1.5nH	±0.1nH	13	0.16	560
8	**LQP03TN1N6B00**	10	1.6nH	±0.1nH	13	0.16	560
9	**LQP03TN1N7B00**	10	1.7nH	±0.1nH	13	0.16	560
10	**LQP03TN1N8B00**	10	1.8nH	±0.1nH	13	0.16	560
11	**LQP03TN1N9B00**	10	1.9nH	±0.1nH	13	0.18	440
12	**LQP03TN2N0B00**	10	2.0nH	±0.1nH	13	0.18	440
13	**LQP03TN2N1B00**	10	2.1nH	±0.1nH	13	0.18	440
14	**LQP03TN2N2B00**	10	2.2nH	±0.1nH	13	0.18	440
15	**LQP03TN2N3B00**	10	2.3nH	±0.1nH	13	0.21	440
16	**LQP03TN2N4B00**	10	2.4nH	±0.1nH	13	0.21	440
17	**LQP03TN2N5B00**	10	2.5nH	±0.1nH	13	0.21	440
18	**LQP03TN2N6B00**	10	2.6nH	±0.1nH	13	0.21	440
19	**LQP03TN2N7B00**	10	2.7nH	±0.1nH	13	0.21	440
20	**LQP03TN2N8B00**	10	2.8nH	±0.1nH	13	0.21	440
21	**LQP03TN2N9B00**	10	2.9nH	±0.1nH	13	0.21	440
22	**LQP03TN3N0B00**	10	3.0nH	±0.1nH	13	0.30	380
23	**LQP03TN3N1B00**	10	3.1nH	±0.1nH	13	0.30	380
24	**LQP03TN3N2B00**	10	3.2nH	±0.1nH	13	0.30	380
25	**LQP03TN3N3B00**	10	3.3nH	±0.1nH	13	0.30	380
26	**LQP03TN3N4B00**	10	3.4nH	±0.1nH	13	0.30	380
27	**LQP03TN3N5B00**	10	3.5nH	±0.1nH	13	0.30	380
28	**LQP03TN3N6B00**	10	3.6nH	±0.1nH	13	0.45	340
29	**LQP03TN3N7B00**	10	3.7nH	±0.1nH	13	0.45	340
30	**LQP03TN3N8B00**	10	3.8nH	±0.1nH	13	0.45	340

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Design Kits

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No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
31	**LQP03TN3N9B00**	10	3.9nH	±0.1nH	13	0.45	340
32	**LQP03TN4N3H00**	10	4.3nH	±3%	13	0.55	320
33	**LQP03TN4N7H00**	10	4.7nH	±3%	13	0.55	320
34	**LQP03TN5N1H00**	10	5.1nH	±3%	13	0.68	280
35	**LQP03TN5N6H00**	10	5.6nH	±3%	13	0.68	280
36	**LQP03TN6N2H00**	10	6.2nH	±3%	13	0.75	260
37	**LQP03TN6N8H00**	10	6.8nH	±3%	13	0.75	260
38	**LQP03TN7N5H00**	10	7.5nH	±3%	13	0.86	220
39	**LQP03TN8N2H00**	10	8.2nH	±3%	13	0.86	220
40	**LQP03TN9N1H00**	10	9.1nH	±3%	13	1.10	200
41	**LQP03TN10NH00**	10	10nH	±3%	13	1.10	200
42	**LQP03TN12NH00**	10	12nH	±3%	11	1.25	180
43	**LQP03TN15NH00**	10	15nH	±3%	11	1.40	180
44	**LQP03TN18NH00**	10	18nH	±3%	11	1.60	160
45	**LQP03TN22NH00**	10	22nH	±3%	11	2.55	140
46	**LQP03TN27NH00**	10	27nH	±3%	11	2.90	140
47	**LQP03TN33NJ00**	10	33nH	±5%	8	2.95	120
48	**LQP03TN39NJ00**	10	39nH	±5%	8	3.35	120
49	**LQP03TN47NJ00**	10	47nH	±5%	8	3.60	100
50	**LQP03TN56NJ00**	10	56nH	±5%	8	4.30	100

●EKLMQP15B (High Frequency Film Type)

No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
1	**LQP15MN1N0B02**	10	1.0nH	0.1nH	13	0.1	400
2	**LQP15MN1N1B02**	10	1.1nH	0.1nH	13	0.1	390
3	**LQP15MN1N2B02**	10	1.2nH	0.1nH	13	0.1	390
4	**LQP15MN1N3B02**	10	1.3nH	0.1nH	13	0.2	280
5	**LQP15MN1N5B02**	10	1.5nH	0.1nH	13	0.2	280
6	**LQP15MN1N6B02**	10	1.6nH	0.1nH	13	0.3	220
7	**LQP15MN1N8B02**	10	1.8nH	0.1nH	13	0.2	280
8	**LQP15MN2N0B02**	10	2.0nH	0.1nH	13	0.3	220
9	**LQP15MN2N2B02**	10	2.2nH	0.1nH	13	0.3	220
10	**LQP15MN2N4B02**	10	2.4nH	0.1nH	13	0.3	220
11	**LQP15MN2N7B02**	10	2.7nH	0.1nH	13	0.3	220
12	**LQP15MN3N0B02**	10	3.0nH	0.1nH	13	0.4	190
13	**LQP15MN3N3B02**	10	3.3nH	0.1nH	13	0.4	190
14	**LQP15MN3N6B02**	10	3.6nH	0.1nH	13	0.5	170
15	**LQP15MN3N9B02**	10	3.9nH	0.1nH	13	0.5	170
16	**LQP15MN4N3B02**	10	4.3nH	0.1nH	13	0.6	160
17	**LQP15MN4N7B02**	10	4.7nH	0.1nH	13	0.6	160
18	**LQP15MN5N1B02**	10	5.1nH	±0.1nH	13	0.7	140
19	**LQP15MN5N6B02**	10	5.6nH	±0.1nH	13	0.7	140
20	**LQP15MN6N2B02**	10	6.2nH	±0.1nH	13	0.9	130
21	**LQP15MN6N8B02**	10	6.8nH	±0.1nH	13	0.9	130
22	**LQP15MN7N5B02**	10	7.5nH	±0.1nH	13	1.1	110
23	**LQP15MN8N2B02**	10	8.2nH	±0.1nH	13	1.1	110
24	**LQP15MN9N1B02**	10	9.1nH	±0.1nH	13	1.3	100
25	**LQP15MN10NG02**	10	10nH	±2%	13	1.3	100
26	**LQP15MN12NG02**	10	12nH	±2%	13	1.6	90
27	**LQP15MN15NG02**	10	15nH	±2%	13	1.8	90
28	**LQP15MN18NG02**	10	18nH	±2%	13	2.0	80

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No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
29	**LQP15MN22NG02**	10	22nH	±2%	13	2.6	70
30	**LQP15MN27NG02**	10	27nH	±2%	13	3.1	70
31	**LQP15MN33NG02**	10	33nH	±2%	13	3.8	60

●EKLMQW04C (High Frequency Wire Wound Type)

No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
1	**LQW04AN1N1C00**	10	1.1nH	±0.2nH	15	0.03	990
2	**LQW04AN1N8C00**	10	1.8nH	±0.2nH	15	0.06	700
3	**LQW04AN2N7C00**	10	2.7nH	±0.2nH	15	0.07	570
4	**LQW04AN3N0C00**	10	3.0nH	±0.2nH	15	0.07	620
5	**LQW04AN3N6C00**	10	3.6nH	±0.2nH	15	0.10	530
6	**LQW04AN3N9C00**	10	3.9nH	±0.2nH	15	0.10	530
7	**LQW04AN4N3C00**	10	4.3nH	±0.2nH	15	0.10	530
8	**LQW04AN4N7C00**	10	4.7nH	±0.2nH	20	0.14	440
9	**LQW04AN5N1C00**	10	5.1nH	±0.2nH	20	0.12	470
10	**LQW04AN5N6C00**	10	5.6nH	±0.2nH	20	0.12	470
11	**LQW04AN6N2C00**	10	6.2nH	±0.2nH	20	0.19	390
12	**LQW04AN6N8C00**	10	6.8nH	±0.2nH	20	0.14	440
13	**LQW04AN7N5C00**	10	7.5nH	±0.2nH	20	0.14	440
14	**LQW04AN8N2C00**	10	8.2nH	±0.2nH	20	0.23	350
15	**LQW04AN9N1C00**	10	9.1nH	±0.2nH	20	0.16	400
16	**LQW04AN10NH00**	10	10nH	±3%	20	0.26	330
17	**LQW04AN11NH00**	10	11nH	±3%	15	0.28	310
18	**LQW04AN12NH00**	10	12nH	±3%	15	0.28	310
19	**LQW04AN13NH00**	10	13nH	±3%	15	0.34	280
20	**LQW04AN15NH00**	10	15nH	±3%	15	0.48	240
21	**LQW04AN16NH00**	10	16nH	±3%	15	0.38	270
22	**LQW04AN18NH00**	10	18nH	±3%	15	0.54	220
23	**LQW04AN19NH00**	10	19nH	±3%	15	0.73	160
24	**LQW04AN20NH00**	10	20nH	±3%	15	0.56	210
25	**LQW04AN22NH00**	10	22nH	±3%	15	0.63	200
26	**LQW04AN23NH00**	10	23nH	±3%	15	0.95	160
27	**LQW04AN24NH00**	10	24nH	±3%	15	0.95	160
28	**LQW04AN25NH00**	10	25nH	±3%	15	0.95	160
29	**LQW04AN27NH00**	10	27nH	±3%	15	0.95	160
30	**LQW04AN33NH00**	10	33nH	±3%	15	1.11	140

●EKLMQW15H (High Frequency Wire Wound Type)

No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
1	**LQW15AN1N3C10**	10	1.3nH	±0.2nH	20	0.017	1200
2	**LQW15AN1N5B00**	10	1.5nH	±0.1nH	10	0.03	1000
3	**LQW15AN2N2C10**	10	2.2nH	±0.2nH	25	0.027	1000
4	**LQW15AN2N4B00**	10	2.4nH	±0.1nH	20	0.05	850
5	**LQW15AN2N5B00**	10	2.5nH	±0.1nH	20	0.05	850
6	**LQW15AN2N7B00**	10	2.7nH	±0.1nH	20	0.05	850
7	**LQW15AN2N9B00**	10	2.9nH	±0.1nH	20	0.07	750
8	**LQW15AN3N3D10**	10	3.3nH	±0.5nH	30	0.040	900
9	**LQW15AN3N4C10**	10	3.4nH	±0.2nH	30	0.040	900

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No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
10	**LQW15AN3N6C10**	10	3.6nH	±0.2nH	30	0.040	900
11	**LQW15AN3N9B00**	10	3.9nH	±0.1nH	25	0.07	750
12	**LQW15AN4N1B00**	10	4.1nH	±0.1nH	25	0.07	750
13	**LQW15AN4N3B00**	10	4.3nH	±0.1nH	25	0.07	750
14	**LQW15AN4N7B00**	10	4.7nH	±0.1nH	25	0.07	750
15	**LQW15AN5N1B00**	10	5.1nH	±0.1nH	25	0.12	600
16	**LQW15AN5N6C10**	10	5.6nH	±0.2nH	30	0.051	800
17	**LQW15AN5N8B00**	10	5.8nH	±0.1nH	25	0.12	700
18	**LQW15AN6N2B00**	10	6.2nH	±0.1nH	25	0.09	700
19	**LQW15AN6N8G00**	10	6.8nH	±2%	25	0.09	700
20	**LQW15AN7N3G00**	10	7.3nH	±2%	25	0.13	570
21	**LQW15AN7N5G00**	10	7.5nH	±2%	25	0.13	570
22	**LQW15AN8N2G00**	10	8.2nH	±2%	25	0.14	540
23	**LQW15AN8N7G00**	10	8.7nH	±2%	25	0.14	540
24	**LQW15AN9N1G00**	10	9.1nH	±2%	25	0.14	540
25	**LQW15AN9N5G00**	10	9.5nH	±2%	25	0.14	540
26	**LQW15AN10NG00**	10	10nH	±2%	25	0.17	500
27	**LQW15AN11NG00**	10	11nH	±2%	30	0.14	500
28	**LQW15AN12NG00**	10	12nH	±2%	30	0.14	500
29	**LQW15AN13NG00**	10	13nH	±2%	25	0.21	430
30	**LQW15AN15NG00**	10	15nH	±2%	30	0.16	460
31	**LQW15AN16NG00**	10	16nH	±2%	25	0.24	370
32	**LQW15AN18NG00**	10	18nH	±2%	25	0.27	370
33	**LQW15AN19NG00**	10	19nH	±2%	25	0.27	370
34	**LQW15AN20NG00**	10	20nH	±2%	25	0.27	370
35	**LQW15AN22NG00**	10	22nH	±2%	25	0.30	310
36	**LQW15AN23NG00**	10	23nH	±2%	25	0.30	310
37	**LQW15AN24NG00**	10	24nH	±2%	25	0.52	280
38	**LQW15AN27NG00**	10	27nH	±2%	25	0.52	280
39	**LQW15AN30NG00**	10	30nH	±2%	25	0.58	270
40	**LQW15AN33NG00**	10	33nH	±2%	25	0.63	260
41	**LQW15AN36NG00**	10	36nH	±2%	25	0.63	260
42	**LQW15AN39NG00**	10	39nH	±2%	25	0.70	250
43	**LQW15AN40NG00**	10	40nH	±2%	25	0.70	250
44	**LQW15AN43NG00**	10	43nH	±2%	25	0.70	250
45	**LQW15AN47NG00**	10	47nH	±2%	25	1.08	210
46	**LQW15AN51NG00**	10	51nH	±2%	25	1.08	210
47	**LQW15AN56NG00**	10	56nH	±2%	25	1.17	200
48	**LQW15AN62NG00**	10	62nH	±2%	20	1.82	145
49	**LQW15AN68NG00**	10	68nH	±2%	20	1.96	140
50	**LQW15AN75NG00**	10	75nH	±2%	20	2.10	135
51	**LQW15AN82NG00**	10	82nH	±2%	20	2.24	130
52	**LQW15AN91NG00**	10	91nH	±2%	20	2.38	125
53	**LQW15ANR10J00**	10	100nH	±5%	20	2.52	120
54	**LQW15ANR12J00**	10	120nH	±5%	20	2.66	110

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●EKLMQ18GB (High Frequency Wire Wound Type Tight Tolerance)

No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
1	**LQW18AN3N6C00**	10	3.6nH	±0.2nH	25	0.059	850
2	**LQW18AN3N9C00**	10	3.9nH	±0.2nH	35	0.059	850
3	**LQW18AN4N3C00**	10	4.3nH	±0.2nH	35	0.059	850
4	**LQW18AN5N6C00**	10	5.6nH	±0.2nH	35	0.082	750
5	**LQW18AN6N2C00**	10	6.2nH	±0.2nH	35	0.082	750
6	**LQW18AN6N8C00**	10	6.8nH	±0.2nH	35	0.082	750
7	**LQW18AN10NG00**	10	10nH	±2%	35	0.11	650
8	**LQW18AN11NG00**	10	11nH	±2%	35	0.11	650
9	**LQW18AN12NG00**	10	12nH	±2%	35	0.13	600
10	**LQW18AN13NG00**	10	13nH	±2%	35	0.13	600
11	**LQW18AN15NG00**	10	15nH	±2%	40	0.13	600
12	**LQW18AN16NG00**	10	16nH	±2%	40	0.16	550
13	**LQW18AN18NG00**	10	18nH	±2%	40	0.16	550
14	**LQW18AN20NG00**	10	20nH	±2%	40	0.16	550
15	**LQW18AN22NG00**	10	22nH	±2%	40	0.17	500
16	**LQW18AN24NG00**	10	24nH	±2%	40	0.21	500
17	**LQW18AN27NG00**	10	27nH	±2%	40	0.21	440
18	**LQW18AN30NG00**	10	30nH	±2%	40	0.23	420
19	**LQW18AN33NG00**	10	33nH	±2%	40	0.23	420
20	**LQW18AN36NG00**	10	36nH	±2%	40	0.26	400
21	**LQW18AN39NG00**	10	39nH	±2%	40	0.26	400
22	**LQW18AN43NG00**	10	43nH	±2%	40	0.29	380
23	**LQW18AN47NG00**	10	47nH	±2%	38	0.29	380
24	**LQW18AN51NG00**	10	51nH	±2%	38	0.33	370
25	**LQW18AN56NG00**	10	56nH	±2%	38	0.35	360
26	**LQW18AN62NG00**	10	62nH	±2%	38	0.51	280
27	**LQW18AN68NG00**	10	68nH	±2%	38	0.38	340
28	**LQW18AN72NG00**	10	72nH	±2%	34	0.56	270
29	**LQW18AN75NG00**	10	75nH	±2%	34	0.56	270
30	**LQW18AN82NG00**	10	82nH	±2%	34	0.60	250
31	**LQW18AN91NG00**	10	91nH	±2%	34	0.64	230
32	**LQW18ANR10G00**	10	100nH	±2%	34	0.68	220
33	**LQW18ANR11G00**	10	110nH	±2%	32	1.2	200
34	**LQW18ANR12G00**	10	120nH	±2%	32	1.3	180
35	**LQW18ANR13G00**	10	130nH	±2%	32	1.4	170
36	**LQW18ANR15G00**	10	150nH	±2%	32	1.5	160
37	**LQW18ANR16G00**	10	160nH	±2%	32	2.1	150
38	**LQW18ANR18G00**	10	180nH	±2%	25	2.2	140
39	**LQW18ANR20G00**	10	200nH	±2%	25	2.4	120
40	**LQW18ANR22G00**	10	220nH	±2%	25	2.5	120
41	**LQW18ANR27G00**	10	270nH	±2%	30	3.4	110
42	**LQW18ANR33G00**	10	330nH	±2%	30	5.5	85
43	**LQW18ANR39G00**	10	390nH	±2%	30	6.2	80
44	**LQW18ANR47G00**	10	470nH	±2%	30	7.0	75
45	**LQW18AN3N9C10**	10	3.9nH	±0.2nH	38	0.032	1000
46	**LQW18AN6N8C10**	10	6.8nH	±0.2nH	38	0.045	900
47	**LQW18AN10NG10**	10	10nH	±2%	38	0.058	800
48	**LQW18AN12NG10**	10	12nH	±2%	38	0.071	750
49	**LQW18AN18NG10**	10	18nH	±2%	42	0.085	700
50	**LQW18AN22NG10**	10	22nH	±2%	42	0.099	640
51	**LQW18AN27NG10**	10	27nH	±2%	42	0.116	590

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Design Kits

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●EKLMQ18JC (High Frequency Wire Wound Type)

No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
1	**LQW18AN3N6D00**	10	3.6nH	±0.5nH	25	0.059	850
2	**LQW18AN4N3D00**	10	4.3nH	±0.5nH	35	0.059	850
3	**LQW18AN4N7D00**	10	4.7nH	±0.5nH	35	0.059	850
4	**LQW18AN6N2D00**	10	6.2nH	±0.5nH	35	0.082	750
5	**LQW18AN7N5D00**	10	7.5nH	±0.5nH	35	0.082	750
6	**LQW18AN8N7D00**	10	8.7nH	±0.5nH	35	0.11	650
7	**LQW18AN9N1D00**	10	9.1nH	±0.5nH	35	0.11	650
8	**LQW18AN9N5D00**	10	9.5nH	±0.5nH	35	0.11	650
9	**LQW18AN11NJ00**	10	11nH	±5%	35	0.11	650
10	**LQW18AN13NJ00**	10	13nH	±5%	35	0.13	600
11	**LQW18AN16NJ00**	10	16nH	±5%	40	0.16	550
12	**LQW18AN20NJ00**	10	20nH	±5%	40	0.16	550
13	**LQW18AN24NJ00**	10	24nH	±5%	40	0.21	500
14	**LQW18AN30NJ00**	10	30nH	±5%	40	0.23	420
15	**LQW18AN36NJ00**	10	36nH	±5%	40	0.26	400
16	**LQW18AN39NJ00**	10	39nH	±5%	40	0.26	400
17	**LQW18AN43NJ00**	10	43nH	±5%	40	0.29	380
18	**LQW18AN47NJ00**	10	47nH	±5%	38	0.29	380
19	**LQW18AN51NJ00**	10	51nH	±5%	38	0.33	370
20	**LQW18AN56NJ00**	10	56nH	±5%	38	0.35	360
21	**LQW18AN62NJ00**	10	62nH	±5%	38	0.51	280
22	**LQW18AN68NJ00**	10	68nH	±5%	38	0.38	340
23	**LQW18AN72NJ00**	10	72nH	±5%	34	0.56	270
24	**LQW18AN75NJ00**	10	75nH	±5%	34	0.56	270
25	**LQW18AN82NJ00**	10	82nH	±5%	34	0.60	250
26	**LQW18AN91NJ00**	10	91nH	±5%	34	0.64	230
27	**LQW18ANR10J00**	10	100nH	±5%	34	0.68	220
28	**LQW18ANR11J00**	10	110nH	±5%	32	1.2	200
29	**LQW18ANR12J00**	10	120nH	±5%	32	1.3	180
30	**LQW18ANR13J00**	10	130nH	±5%	32	1.4	170
31	**LQW18ANR15J00**	10	150nH	±5%	32	1.5	160
32	**LQW18ANR16J00**	10	160nH	±5%	32	2.1	150
33	**LQW18ANR18J00**	10	180nH	±5%	25	2.2	140
34	**LQW18ANR20J00**	10	200nH	±5%	25	2.4	120
35	**LQW18ANR22J00**	10	220nH	±5%	25	2.5	120
36	**LQW18ANR27J00**	10	270nH	±5%	30	3.4	110
37	**LQW18ANR33J00**	10	330nH	±5%	30	5.5	85
38	**LQW18ANR39J00**	10	390nH	±5%	30	6.2	80
39	**LQW18ANR47J00**	10	470nH	±5%	30	7.0	75
40	**LQW18AN2N2D10**	10	2.2nH	±0.5nH	25	0.018	1400
41	**LQW18AN3N9D10**	10	3.9nH	±0.5nH	38	0.032	1000
42	**LQW18AN5N6D10**	10	5.6nH	±0.5nH	38	0.045	900
43	**LQW18AN6N8D10**	10	6.8nH	±0.5nH	38	0.045	900
44	**LQW18AN8N2D10**	10	8.2nH	±0.5nH	38	0.058	800
45	**LQW18AN10NJ10**	10	10nH	±5%	38	0.058	800
46	**LQW18AN12NJ10**	10	12nH	±5%	38	0.071	750
47	**LQW18AN15NJ10**	10	15nH	±5%	42	0.085	700
48	**LQW18AN18NJ10**	10	18nH	±5%	42	0.085	700
49	**LQW18AN22NJ10**	10	22nH	±5%	42	0.099	640
50	**LQW18AN27NJ10**	10	27nH	±5%	42	0.116	590
51	**LQW18AN33NJ10**	10	33nH	±5%	42	0.132	550

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●EKLMQW21A (for High Frequency Wire Wound Ferrite Core Type)

No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
1	**LQW21HNR47J00**	10	0.47μH	±5%	35	1.30	160
2	**LQW21HNR56J00**	10	0.56μH	±5%	35	1.43	150
3	**LQW21HNR68J00**	10	0.68μH	±5%	35	2.21	130
4	**LQW21HNR82J00**	10	0.82μH	±5%	35	2.34	125
5	**LQW21HN1R0J00**	10	1.0μH	±5%	35	2.86	115
6	**LQW21HN1R2J00**	10	1.2μH	±5%	35	3.12	100
7	**LQW21HN1R5J00**	10	1.5μH	±5%	35	5.33	85
8	**LQW21HN1R8J00**	10	1.8μH	±5%	35	5.85	80
9	**LQW21HN2R2J00**	10	2.2μH	±5%	35	6.50	75

●EKLMQW2BB (for High Frequency Wire Wound Air Core Type)

No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
1	**LQW2BHN2N7D13**	10	2.7nH	±0.5nH	20	0.02	1900
2	**LQW2BHN3N1D13**	10	3.1nH	±0.5nH	20	0.02	1800
3	**LQW2BHN3N3D13**	10	3.3nH	±0.5nH	20	0.02	1700
4	**LQW2BHN5N6D13**	10	5.6nH	±0.5nH	35	0.02	1500
5	**LQW2BHN6N8D13**	10	6.8nH	±0.5nH	35	0.02	1400
6	**LQW2BHN8N6D13**	10	8.6nH	±0.5nH	35	0.03	1300
7	**LQW2BHN10NJ13**	10	10nH	±5%	35	0.03	1320
8	**LQW2BHN12NK13**	10	12nH	±10%	40	0.04	1100
9	**LQW2BHN15NK13**	10	15nH	±10%	40	0.04	1000
10	**LQW2BHN18NK13**	10	18.8nH	±10%	40	0.05	1000
11	**LQW2BHN21NK13**	10	21nH	±10%	40	0.05	950
12	**LQW2BHN27NK13**	10	27nH	±10%	40	0.06	900
13	**LQW2BHN33NJ03**	10	33nH	±5%	40	0.15	570
14	**LQW2BHN39NJ03**	10	39nH	±5%	40	0.09	730
15	**LQW2BHN47NJ03**	10	47nH	±5%	40	0.23	450
16	**LQW2BHN56NJ03**	10	56nH	±5%	40	0.26	430
17	**LQW2BHN68NJ03**	10	68nH	±5%	40	0.23	460
18	**LQW2BHN82NJ03**	10	82nH	±5%	40	0.42	320
19	**LQW2BHNR10J03**	10	100nH	±5%	40	0.38	350
20	**LQW2BHNR12J03**	10	120nH	±5%	40	0.40	320
21	**LQW2BHNR15J03**	10	150nH	±5%	30	0.47	390
22	**LQW2BHNR18J03**	10	180nH	±5%	35	0.71	250
23	**LQW2BHNR22J03**	10	220nH	±5%	35	0.70	240
24	**LQW2BHNR27K03**	10	270nH	±10%	15	2.00	190
25	**LQW2BHNR33K03**	10	330nH	±10%	15	2.20	180
26	**LQW2BHNR39K03**	10	390nH	±10%	15	2.50	170
27	**LQW2BHNR47K03**	10	470nH	±10%	15	2.80	160

●EKLMQM18B (for General Use Multilayer Type)

No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
1	**LQM18NN47NM00**	10	47nH	±20%	10	0.30	50
2	**LQM18NN68NM00**	10	68nH	±20%	10	0.30	50
3	**LQM18NN82NM00**	10	82nH	±20%	10	0.30	50
4	**LQM18NNR10K00**	10	100nH	±10%	15	0.50	50

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No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
5	**LQM18NNR12K00**	10	120nH	±10%	15	0.50	50
6	**LQM18NNR15K00**	10	150nH	±10%	15	0.60	50
7	**LQM18NNR18K00**	10	180nH	±10%	15	0.60	50
8	**LQM18NNR22K00**	10	220nH	±10%	15	0.80	50
9	**LQM18NNR27K00**	10	270nH	±10%	15	0.80	50
10	**LQM18NNR33K00**	10	330nH	±10%	15	0.85	35
11	**LQM18NNR39K00**	10	390nH	±10%	15	1.00	35
12	**LQM18NNR47K00**	10	470nH	±10%	15	1.35	35
13	**LQM18NNR56K00**	10	560nH	±10%	15	1.55	35
14	**LQM18NNR68K00**	10	680nH	±10%	15	1.70	35
15	**LQM18NNR82K00**	10	820nH	±10%	15	2.10	35
16	**LQM18NN1R0K00**	10	1000nH	±10%	35	0.60	25
17	**LQM18NN1R2K00**	10	1200nH	±10%	35	0.80	25
18	**LQM18NN1R5K00**	10	1500nH	±10%	35	0.80	25
19	**LQM18NN1R8K00**	10	1800nH	±10%	35	0.95	25
20	**LQM18NN2R2K00**	10	2200nH	±10%	35	1.15	15

●EKLMM21NB (for General Use Multilayer Type)

No.	Part Number	Quantity (pcs.)	Inductance		Q (min.)	DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance			
1	**LQM21NNR10K10**	10	0.1μH	±10%	20	0.26	250
2	**LQM21NNR12K10**	10	0.12μH	±10%	20	0.29	250
3	**LQM21NNR15K10**	10	0.15μH	±10%	20	0.32	250
4	**LQM21NNR18K10**	10	0.18μH	±10%	20	0.35	250
5	**LQM21NNR22K10**	10	0.22μH	±10%	20	0.38	250
6	**LQM21NNR27K10**	10	0.27μH	±10%	20	0.42	250
7	**LQM21NNR33K10**	10	0.33μH	±10%	20	0.48	250
8	**LQM21NNR39K10**	10	0.39μH	±10%	25	0.53	200
9	**LQM21NNR47K10**	10	0.47μH	±10%	25	0.57	200
10	**LQM21NNR56K10**	10	0.56μH	±10%	25	0.63	150
11	**LQM21NNR68K10**	10	0.68μH	±10%	25	0.72	150
12	**LQM21NNR82K10**	10	0.82μH	±10%	25	0.81	150
13	**LQM21NN1R0K10**	10	1.0μH	±10%	45	0.40	50
14	**LQM21NN1R2K10**	10	1.2μH	±10%	45	0.47	50
15	**LQM21NN1R5K10**	10	1.5μH	±10%	45	0.50	50
16	**LQM21NN1R8K10**	10	1.8μH	±10%	45	0.57	50
17	**LQM21NN2R2K10**	10	2.2μH	±10%	45	0.63	30
18	**LQM21NN2R7K10**	10	2.7μH	±10%	45	0.69	30
19	**LQM21NN3R3K10**	10	3.3μH	±10%	45	0.80	30
20	**LQM21NN3R9K10**	10	3.9μH	±10%	45	0.89	30
21	**LQM21NN4R7K10**	10	4.7μH	±10%	45	1.00	30

●EKLMH32MC (for General Use Wire Wound Type)

No.	Part Number	Quantity (pcs.)	Inductance		DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance		
1	**LQH32MN1R0M23**	10	1.0μH	±20%	0.50	445
2	**LQH32MN1R2M23**	10	1.2μH	±20%	0.60	425
3	**LQH32MN1R5K23**	10	1.5μH	±10%	0.60	400
4	**LQH32MN1R8K23**	10	1.8μH	±10%	0.70	390
5	**LQH32MN2R2K23**	10	2.2μH	±10%	0.80	370

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No.	Part Number	Quantity (pcs.)	Inductance		DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance		
6	**LQH32MN2R7K23**	10	2.7µH	±10%	0.90	320
7	**LQH32MN3R3K23**	10	3.3µH	±10%	1.00	300
8	**LQH32MN3R9K23**	10	3.9µH	±10%	1.10	290
9	**LQH32MN4R7K23**	10	4.7µH	±10%	1.20	270
10	**LQH32MN5R6K23**	10	5.6µH	±10%	1.30	250
11	**LQH32MN6R8K23**	10	6.8µH	±10%	1.50	240
12	**LQH32MN8R2K23**	10	8.2µH	±10%	1.60	225
13	**LQH32MN100K23**	10	10µH	±10%	1.8	190
14	**LQH32MN120K23**	10	12µH	±10%	2.0	180
15	**LQH32MN150K23**	10	15µH	±10%	2.2	170
16	**LQH32MN180K23**	10	18µH	±10%	2.5	165
17	**LQH32MN220K23**	10	22µH	±10%	2.8	150
18	**LQH32MN270K23**	10	27µH	±10%	3.1	125
19	**LQH32MN330K23**	10	33µH	±10%	3.5	115
20	**LQH32MN390K23**	10	39µH	±10%	3.9	110
21	**LQH32MN470K23**	10	47µH	±10%	4.3	100
22	**LQH32MN560K23**	10	56µH	±10%	4.9	85
23	**LQH32MN680K23**	10	68µH	±10%	5.5	80
24	**LQH32MN820K23**	10	82µH	±10%	6.2	70
25	**LQH32MN101K23**	10	100µH	±10%	7.0	80
26	**LQH32MN121K23**	10	120µH	±10%	8.0	75
27	**LQH32MN151K23**	10	150µH	±10%	9.3	70
28	**LQH32MN181K23**	10	180µH	±10%	10.2	65
29	**LQH32MN221K23**	10	220µH	±10%	11.8	65
30	**LQH32MN271K23**	10	270µH	±10%	12.5	65
31	**LQH32MN331K23**	10	330µH	±10%	13.0	65
32	**LQH32MN391K23**	10	390µH	±10%	22.0	50
33	**LQH32MN471K23**	10	470µH	±10%	25.0	45
34	**LQH32MN561K23**	10	560µH	±10%	28.0	40

●EKLMH43MB (for General Use Wire Wound Type)

No.	Part Number	Quantity (pcs.)	Inductance		DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance		
1	**LQH43MN1R0M03**	10	1.0µH	±20%	0.20	500
2	**LQH43MN1R2M03**	10	1.2µH	±20%	0.20	500
3	**LQH43MN1R5M03**	10	1.5µH	±20%	0.30	500
4	**LQH43MN1R8M03**	10	1.8µH	±20%	0.30	500
5	**LQH43MN2R2M03**	10	2.2µH	±20%	0.30	500
6	**LQH43MN2R7M03**	10	2.7µH	±20%	0.32	500
7	**LQH43MN3R3M03**	10	3.3µH	±20%	0.35	500
8	**LQH43MN3R9M03**	10	3.9µH	±20%	0.38	500
9	**LQH43MN4R7K03**	10	4.7µH	±10%	0.40	500
10	**LQH43MN5R6K03**	10	5.6µH	±10%	0.47	500
11	**LQH43MN6R8K03**	10	6.8µH	±10%	0.50	450
12	**LQH43MN8R2K03**	10	8.2µH	±10%	0.56	450
13	**LQH43MN100K03**	10	10µH	±10%	0.56	400
14	**LQH43MN120K03**	10	12µH	±10%	0.62	380
15	**LQH43MN150K03**	10	15µH	±10%	0.73	360
16	**LQH43MN180K03**	10	18µH	±10%	0.82	340
17	**LQH43MN220K03**	10	22µH	±10%	0.94	320
18	**LQH43MN270K03**	10	27µH	±10%	1.10	300
19	**LQH43MN330K03**	10	33µH	±10%	1.20	270

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No.	Part Number	Quantity (pcs.)	Inductance		DC Resistance (Ω) max.	Rated Current (mA)
			Nominal	Tolerance		
20	**LQH43MN390K03**	10	39μH	±10%	1.40	240
21	**LQH43MN470K03**	10	47μH	±10%	1.50	220
22	**LQH43MN560K03**	10	56μH	±10%	1.7	200
23	**LQH43MN680K03**	10	68μH	±10%	1.9	180
24	**LQH43MN820K03**	10	82μH	±10%	2.2	170
25	**LQH43MN101K03**	10	100μH	±10%	2.5	160
26	**LQH43MN121K03**	10	120μH	±10%	3.0	150
27	**LQH43MN151K03**	10	150μH	±10%	3.7	130
28	**LQH43MN181K03**	10	180μH	±10%	4.5	120
29	**LQH43MN221K03**	10	220μH	±10%	5.4	110
30	**LQH43MN271K03**	10	270μH	±10%	6.8	100
31	**LQH43MN331K03**	10	330μH	±10%	8.2	95
32	**LQH43MN391K03**	10	390μH	±10%	9.7	90
33	**LQH43MN471K03**	10	470μH	±10%	11.8	80
34	**LQH43MN561K03**	10	560μH	±10%	14.5	70
35	**LQH43MN681K03**	10	680μH	±10%	17.0	65
36	**LQH43MN821K03**	10	820μH	±10%	20.5	60
37	**LQH43MN102K03**	10	1000μH	±10%	25.0	50
38	**LQH43MN122K03**	10	1200μH	±10%	30.0	45
39	**LQH43MN152K03**	10	1500μH	±10%	37.0	40
40	**LQH43NN182K03**	10	1800μH	±10%	45.0	35
41	**LQH43NN222K03**	10	2200μH	±10%	50.0	30

●EKLMQ2PD (Power Inductor Multilayer Type)

No.	Part Number	Quantity (pcs.)	Inductance		DC Resistance (Ω)	Rated Current (mA)
			Nominal	Tolerance		
1	**LQM21PNR47MC0**	10	0.47μH	±20%	0.12±25%	1100
2	**LQM21PN1R0MC0**	10	1.0μH	±20%	0.19±25%	800
3	**LQM21PN1R5MC0**	10	1.5μH	±20%	0.26±25%	700
4	**LQM21PN2R2MC0**	10	2.2μH	±20%	0.34±25%	600
5	**LQM21PNR54MG0**	10	0.54μH	±20%	0.075±25%	1300
6	**LQM2MPNR47NG0**	10	0.47μH	±30%	0.06±25%	1600
7	**LQM2MPN1R0NG0**	10	1.0μH	±30%	0.085±25%	1400
8	**LQM2MPN1R5NG0**	10	1.5μH	±30%	0.11±25%	1200
9	**LQM2MPN2R2NG0**	10	2.2μH	±30%	0.11±25%	1200
10	**LQM2MPN3R3NG0**	10	3.3μH	±30%	0.12±25%	1200
11	**LQM2MPN4R7NG0**	10	4.7μH	±30%	0.14±25%	1100
12	**LQM2HPNR56ME0**	10	0.56μH	±20%	0.06±25%	1500
13	**LQM2HPNR47MG0**	10	0.47μH	±20%	0.04±25%	1800
14	**LQM2HPN1R0MG0**	10	1.0μH	±20%	0.055±25%	1600
15	**LQM2HPN1R5MG0**	10	1.5μH	±20%	0.07±25%	1500
16	**LQM2HPN2R2MG0**	10	2.2μH	±20%	0.08±25%	1300
17	**LQM2HPN3R3MG0**	10	3.3μH	±20%	0.10±25%	1200
18	**LQM2HPN4R7MG0**	10	4.7μH	±20%	0.11±25%	1100
19	**LQM2HPN1R0MJ0**	10	1.0μH	±20%	0.09±25%	1500
20	**LQM2HPN2R2MJ0**	10	2.2μH	±20%	0.12±25%	1000
21	**LQM2HPN3R3MJ0**	10	3.3μH	±20%	0.12±25%	1000
22	**LQM31PNR47MC0**	10	0.47μH	±20%	0.085±25%	1300
23	**LQM31PN1R0MC0**	10	1.0μH	±20%	0.14±25%	1100
24	**LQM31PN1R5MC0**	10	1.5μH	±20%	0.17±25%	1000
25	**LQM31PN2R2MC0**	10	2.2μH	±20%	0.25±25%	900
26	**LQM31PNR47M00**	10	0.47μH	±20%	0.07±25%	1400

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No.	Part Number	Quantity (pcs.)	Inductance		DC Resistance (Ω)	Rated Current (mA)
			Nominal	Tolerance		
27	**LQM31PN1R0M00**	10	1.0µH	±20%	0.12±25%	1200
28	**LQM31PN1R5M00**	10	1.5µH	±20%	0.14±25%	1000
29	**LQM31PN2R2M00**	10	2.2µH	±20%	0.19±25%	900
30	**LQM31PN3R3M00**	10	3.3µH	±20%	0.24±25%	800
31	**LQM31PN4R7M00**	10	4.7µH	±20%	0.30±25%	700

●EKLMH2MCF (Power Inductor Wire Wound Type)

No.	Part Number	Quantity (pcs.)	Inductance		DC Resistance (Ω)	Allowable DC Current (mA)	
			Nominal	Tolerance		Based on Temperature Rise	Based on Inductance Change
1	**LQH2MCN1R0M02**	10	1.0µH	±20%	0.30±30%	485	-
2	**LQH2MCN1R5M02**	10	1.5µH	±20%	0.40±30%	445	-
3	**LQH2MCN2R2M02**	10	2.2µH	±20%	0.48±30%	425	-
4	**LQH2MCN3R3M02**	10	3.3µH	±20%	0.60±30%	375	-
5	**LQH2MCN4R7M02**	10	4.7µH	±20%	0.8±30%	300	-
6	**LQH2MCN5R6M02**	10	5.6µH	±20%	0.9±30%	280	-
7	**LQH2MCN6R8M02**	10	6.8µH	±20%	1.0±30%	255	-
8	**LQH2MCN8R2M02**	10	8.2µH	±20%	1.1±30%	235	-
9	**LQH2MCN100K02**	10	10µH	±10%	1.2±30%	225	-
10	**LQH2MCN120K02**	10	12µH	±10%	1.4±30%	210	-
11	**LQH2MCN150K02**	10	15µH	±10%	1.6±30%	200	-
12	**LQH2MCN180K02**	10	18µH	±10%	1.8±30%	190	-
13	**LQH2MCN220K02**	10	22µH	±10%	2.1±30%	185	-
14	**LQH2MCN270K02**	10	27µH	±10%	2.5±30%	180	-
15	**LQH2MCN330K02**	10	33µH	±10%	2.8±30%	160	-
16	**LQH2MCN390K02**	10	39µH	±10%	4.4±30%	125	-
17	**LQH2MCN470K02**	10	47µH	±10%	5.1±30%	120	-
18	**LQH2MCN560K02**	10	56µH	±10%	5.7±30%	110	-
19	**LQH2MCN680K02**	10	68µH	±10%	6.6±30%	100	-
20	**LQH2MCN820K02**	10	82µH	±10%	7.5±30%	90	-
21	**LQH2MCN1R0M52**	10	1.0µH	±20%	0.25±30%	595	-
22	**LQH2MCN1R5M52**	10	1.5µH	±20%	0.33±30%	540	-
23	**LQH2MCN2R2M52**	10	2.2µH	±20%	0.42±30%	500	-
24	**LQH2MCN3R3M52**	10	3.3µH	±20%	0.74±30%	360	-
25	**LQH2MCN4R7M52**	10	4.7µH	±20%	0.91±30%	335	-
26	**LQH2MCN6R8M52**	10	6.8µH	±20%	1.23±30%	285	-
27	**LQH2MCN100M52**	10	10µH	±20%	2.27±30%	200	-
28	**LQH2MCN120M52**	10	12µH	±20%	2.4±30%	170	-
29	**LQH2MCN150M52**	10	15µH	±20%	3.5±30%	150	-
30	**LQH2MCN180M52**	10	18µH	±20%	4±30%	140	-
31	**LQH2MCN220M52**	10	22µH	±20%	5.5±30%	130	-

●EKLMQH3PC (Power Inductor Wire Wound Type)

No.	Part Number	Quantity (pcs.)	Inductance		DC Resistance (Ω)	Allowable DC Current (mA)	
			Nominal	Tolerance		Based on Temperature Rise	Based on Inductance Change
1	**LQH3NPN1R0NG0**	10	1.0µH	±30%	0.08±20%	1525	1650
2	**LQH3NPN1R5NG0**	10	1.5µH	±30%	0.10±20%	1470	1300
3	**LQH3NPN2R2NG0**	10	2.2µH	±30%	0.14±20%	1270	1250
4	**LQH3NPN3R3NG0**	10	3.3µH	±30%	0.18±20%	1130	850
5	**LQH3NPN4R7NG0**	10	4.7µH	±30%	0.26±20%	925	800
6	**LQH3NPN6R8NG0**	10	6.8µH	±30%	0.45±20%	710	650

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No.	Part Number	Quantity (pcs.)	Inductance		DC Resistance (Ω)	Allowable DC Current (mA)	
			Nominal	Tolerance		Based on Temperature Rise	Based on Inductance Change
7	**LQH3NPN100NG0**	10	10µH	±30%	0.57±20%	630	500
8	**LQH3NPN150NG0**	10	15µH	±30%	0.91±20%	475	370
9	**LQH3NPN220MG0**	10	22µH	±20%	1.1±20%	430	340
10	**LQH3NPN330MG0**	10	33µH	±20%	2.1±20%	345	250
11	**LQH3NPN470MG0**	10	47µH	±20%	3.0±20%	270	170
12	**LQH3NPN680MG0**	10	68µH	±20%	4.2±20%	235	150
13	**LQH3NPN101MG0**	10	100µH	±20%	8.0±20%	165	140
14	**LQH3NPN151MG0**	10	150µH	±20%	11±20%	145	110
15	**LQH3NPN221MG0**	10	220µH	±20%	14±20%	130	100
16	**LQH3NPN251MG0**	10	250µH	±20%	15±20%	130	80
17	**LQH3NPN1R0NJ0**	10	1.0µH	±30%	0.048±20%	1620	1650
18	**LQH3NPN1R5NJ0**	10	1.5µH	±30%	0.066±20%	1500	1200
19	**LQH3NPN2R2NJ0**	10	2.2µH	±30%	0.0828±20%	1460	1150
20	**LQH3NPN3R3NJ0**	10	3.3µH	±30%	0.126±20%	1270	950
21	**LQH3NPN4R7NJ0**	10	4.7µH	±30%	0.156±20%	1120	780
22	**LQH3NPN6R8NJ0**	10	6.8µH	±30%	0.252±20%	850	700
23	**LQH3NPN100NJ0**	10	10µH	±30%	0.36±20%	710	560
24	**LQH3NPN150NJ0**	10	15µH	±30%	0.528±20%	590	440
25	**LQH3NPN220MJ0**	10	22µH	±20%	0.72±20%	510	350
26	**LQH3NPN330MJ0**	10	33µH	±20%	1.08±20%	410	280
27	**LQH3NPN470MJ0**	10	47µH	±20%	1.56±20%	350	200
28	**LQH3NPN1R0MM0**	10	1.0µH	±20%	0.044±20%	2050	1400
29	**LQH3NPN2R2MM0**	10	2.2µH	±20%	0.073±20%	1600	1250
30	**LQH3NPN3R3MM0**	10	3.3µH	±20%	0.092±20%	1450	1000
31	**LQH3NPN4R7MM0**	10	4.7µH	±20%	0.13±20%	1250	880
32	**LQH3NPN6R8MM0**	10	6.8µH	±20%	0.20±20%	1000	820
33	**LQH3NPN100MM0**	10	10µH	±20%	0.26±20%	870	550
34	**LQH3NPN1R0NM0**	10	1.0µH	±30%	0.044±20%	2050	1400
35	**LQH3NPN2R2NM0**	10	2.2µH	±30%	0.073±20%	1600	1250
36	**LQH3NPN3R3NM0**	10	3.3µH	±30%	0.092±20%	1450	1000
37	**LQH3NPN4R7NM0**	10	4.7µH	±30%	0.13±20%	1250	880
38	**LQH3NPN6R8NM0**	10	6.8µH	±30%	0.20±20%	1000	820
39	**LQH3NPN100NM0**	10	10µH	±30%	0.26±20%	870	550
40	**LQH3NPN220MM0**	10	22µH	±20%	0.51±20%	650	410
41	**LQH3NPN330MM0**	10	33µH	±20%	0.85±20%	500	370
42	**LQH3NPN470MM0**	10	47µH	±20%	1.25±20%	410	310
43	**LQH3NPN101MM0**	10	100µH	±20%	3.50±20%	240	200
44	**LQH32PNR47NN0**	10	0.47µH	±30%	0.03±20%	2550	3400
45	**LQH32PN1R0NN0**	10	1.0µH	±30%	0.045±20%	2050	2300
46	**LQH32PN1R5NN0**	10	1.5µH	±30%	0.057±20%	1750	1750
47	**LQH32PN2R2NN0**	10	2.2µH	±30%	0.076±20%	1600	1550
48	**LQH32PN3R3NN0**	10	3.3µH	±30%	0.12±20%	1200	1250
49	**LQH32PN4R7NN0**	10	4.7µH	±30%	0.18±20%	1000	1000
50	**LQH32PN6R8NN0**	10	6.8µH	±30%	0.24±20%	850	850
51	**LQH32PN100MN0**	10	10µH	±20%	0.38±20%	700	750
52	**LQH32PN220MN0**	10	22µH	±20%	0.81±20%	450	500

Continued on the following page.

Design Kits

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●EKLMQH4PA (Power Inductor Wire Wound Type)

No.	Part Number	Quantity (pcs.)	Inductance		DC Resistance (Ω)	Allowable DC Current (mA)	
			Nominal	Tolerance		Based on Temperature Rise	Based on Inductance Change
1	**LQH44PN1R0NP0**	10	1.0μH	±30%	0.030±20%	2450	2950
2	**LQH44PN2R2MP0**	10	2.2μH	±20%	0.049±20%	1800	2500
3	**LQH44PN3R3MP0**	10	3.3μH	±20%	0.065±20%	1770	2100
4	**LQH44PN4R7MP0**	10	4.7μH	±20%	0.080±20%	1700	1700
5	**LQH44PN6R8MP0**	10	6.8μH	±20%	0.12±20%	1340	1400
6	**LQH44PN100MP0**	10	10μH	±20%	0.16±20%	1170	1150
7	**LQH44PN220MP0**	10	22μH	±20%	0.37±20%	790	800

●EKLMQH5PA (Power Inductor Wire Wound Type)

No.	Part Number	Quantity (pcs.)	Inductance		DC Resistance (Ω)	Allowable DC Current (mA)	
			Nominal	Tolerance		Based on Temperature Rise	Based on Inductance Change
1	**LQH55PN1R2NR0**	10	1.2μH	±30%	0.021±20%	2900	2600
2	**LQH55PN2R2NR0**	10	2.2μH	±30%	0.031±20%	2500	2100
3	**LQH55PN2R7NR0**	10	2.7μH	±30%	0.040±20%	2150	2070
4	**LQH55PN3R3NR0**	10	3.3μH	±30%	0.044±20%	2000	2000
5	**LQH55PN4R7NR0**	10	4.7μH	±30%	0.060±20%	1750	1400
6	**LQH55PN6R8NR0**	10	6.8μH	±30%	0.087±20%	1450	1200
7	**LQH55PN100MR0**	10	10μH	±20%	0.11±20%	1250	1000
8	**LQH55PN220MR0**	10	22μH	±30%	0.26±20%	850	670

●EKLMM18FB (Power Inductor Multilayer Type for Choke)

No.	Part Number	Quantity (pcs.)	Inductance		DC Resistance (Ω)	Rated Current (mA)
			Nominal	Tolerance		
1	**LQM18FN1R0M00**	10	1.0μH	±20%	0.20±30%	150
2	**LQM18FN2R2M00**	10	2.2μH	±20%	0.40±30%	120
3	**LQM18FN4R7M00**	10	4.7μH	±20%	0.60±30%	80
4	**LQM18FN100M00**	10	10μH	±20%	0.90±30%	50
5	**LQM21FN1R0N00**	10	1.0μH	±30%	0.20±30%	220
6	**LQM21FN2R2N00**	10	2.2μH	±30%	0.28±30%	150
7	**LQM21FN4R7M70**	10	4.7μH	±20%	0.35±30%	120
8	**LQM21FN4R7M80**	10	4.7μH	±20%	0.18±30%	120
9	**LQM21FN100M70**	10	10μH	±20%	0.60±30%	100
10	**LQM21FN100M80**	10	10μH	±20%	0.30±30%	100
11	**LQM21FN220N00**	10	22μH	±30%	0.35±30%	13
12	**LQM21FN470N00**	10	47μH	±30%	0.60±30%	7
13	**LQM31FN100M00**	10	10μH	±20%	0.50 max.	70

●EKLMH32CC (Power Inductor Wire Wound Type for Choke)

No.	Part Number	Quantity (pcs.)	Inductance		DC Resistance (Ω)	Rated Current (mA)
			Nominal	Tolerance		
1	**LQH32CNR15M33**	10	0.15μH	±20%	0.028±30%	1450
2	**LQH32CNR27M33**	10	0.27μH	±20%	0.034±30%	1250
3	**LQH32CNR47M33**	10	0.47μH	±20%	0.042±30%	1100
4	**LQH32CN1R0M33**	10	1.0μH	±20%	0.06±30%	1000
5	**LQH32CN2R2M33**	10	2.2μH	±20%	0.097±30%	790
6	**LQH32CN4R7M33**	10	4.7μH	±20%	0.15±30%	650

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Design Kits

Continued from the preceding page.

No.	Part Number	Quantity (pcs.)	Inductance		DC Resistance (Ω)	Rated Current (mA)
			Nominal	Tolerance		
7	**LQH32CN100K33**	10	10μH	±10%	0.3±30%	450
8	**LQH32CN1R0M23**	10	1.0μH	±20%	0.09±30%	800
9	**LQH32CN2R2M23**	10	2.2μH	±20%	0.13±30%	600
10	**LQH32CN4R7M23**	10	4.7μH	±20%	0.2±30%	450
11	**LQH32CN100K23**	10	10μH	±10%	0.44±30%	300
12	**LQH32CN220K23**	10	22μH	±10%	0.71±30%	250
13	**LQH32CN470K23**	10	47μH	±10%	1.3±30%	170
14	**LQH32CN101K23**	10	100μH	±10%	3.5±30%	100
15	**LQH32CN221K23**	10	220μH	±10%	8.4±30%	70
16	**LQH32CN331K23**	10	330μH	±10%	10±30%	60
17	**LQH32CN391K23**	10	390μH	±10%	17±30%	60
18	**LQH32CN471K23**	10	470μH	±10%	19±30%	60
19	**LQH32CN561K23**	10	560μH	±10%	22±30%	60
20	**LQH32CN1R0M53**	10	1.0μH	±20%	0.06±30%	1000
21	**LQH32CN2R2M53**	10	2.2μH	±20%	0.097±30%	790
22	**LQH32CN4R7M53**	10	4.7μH	±20%	0.15±30%	650
23	**LQH32CN100K53**	10	10μH	±10%	0.3±30%	450
24	**LQH32CN150K53**	10	15μH	±10%	0.58±30%	300
25	**LQH32CN220K53**	10	22μH	±10%	0.71±30%	250
26	**LQH32CN330K53**	10	33μH	±10%	1.1±30%	200
27	**LQH32CN470K53**	10	47μH	±10%	1.3±30%	170
28	**LQH32CN680K53**	10	68μH	±10%	2.2±30%	130
29	**LQH32CN101K53**	10	100μH	±10%	3.5±30%	100

●EKLMH43CC (Power Inductor Wire Wound Type for Choke)

No.	Part Number	Quantity (pcs.)	Inductance		DC Resistance (Ω)	Rated Current (mA)
			Nominal	Tolerance		
1	**LQH43CN1R0M03**	10	1.0μH	±20%	0.08 max	1080
2	**LQH43CN1R5M03**	10	1.5μH	±20%	0.09 max	1000
3	**LQH43CN2R2M03**	10	2.2μH	±20%	0.11 max	900
4	**LQH43CN3R3M03**	10	3.3μH	±20%	0.13 max	800
5	**LQH43CN4R7M03**	10	4.7μH	±20%	0.15 max	750
6	**LQH43CN6R8M03**	10	6.8μH	±20%	0.20 max	720
7	**LQH43CN100K03**	10	10μH	±10%	0.24 max	650
8	**LQH43CN150K03**	10	15μH	±10%	0.32 max	570
9	**LQH43CN220K03**	10	22μH	±10%	0.60 max	420
10	**LQH43CN330K03**	10	33μH	±10%	1.00 max	310
11	**LQH43CN470K03**	10	47μH	±10%	1.10 max	280
12	**LQH43CN680K03**	10	68μH	±10%	1.70 max	220
13	**LQH43CN101K03**	10	100μH	±10%	2.20 max	190
14	**LQH43CN151K03**	10	150μH	±10%	3.50 max	130
15	**LQH43CN221K03**	10	220μH	±10%	4.00 max	110
16	**LQH43CN331K03**	10	330μH	±10%	6.80 max	100
17	**LQH43CN471K03**	10	470μH	±10%	8.50 max	90

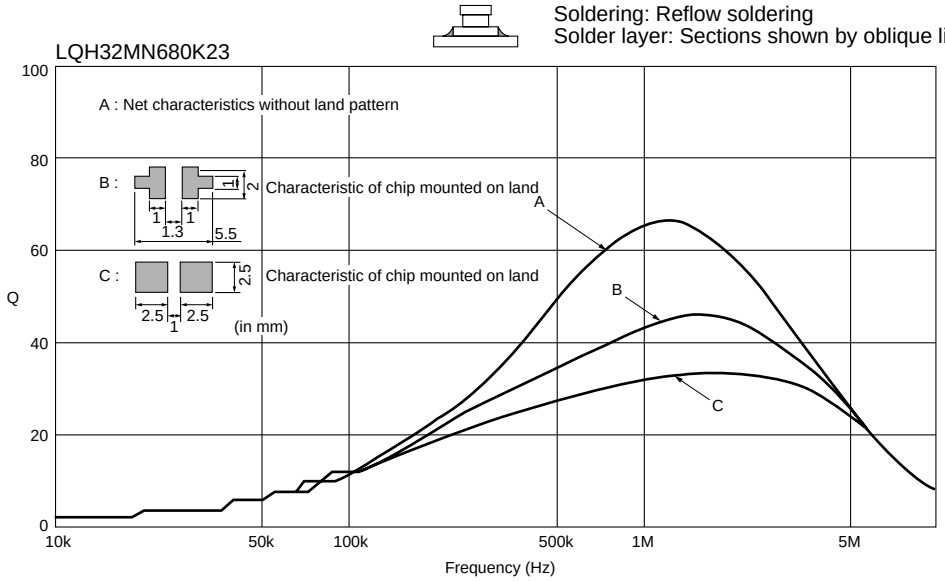
Part Number Quick Reference

Chip Inductor (Chip Coil)

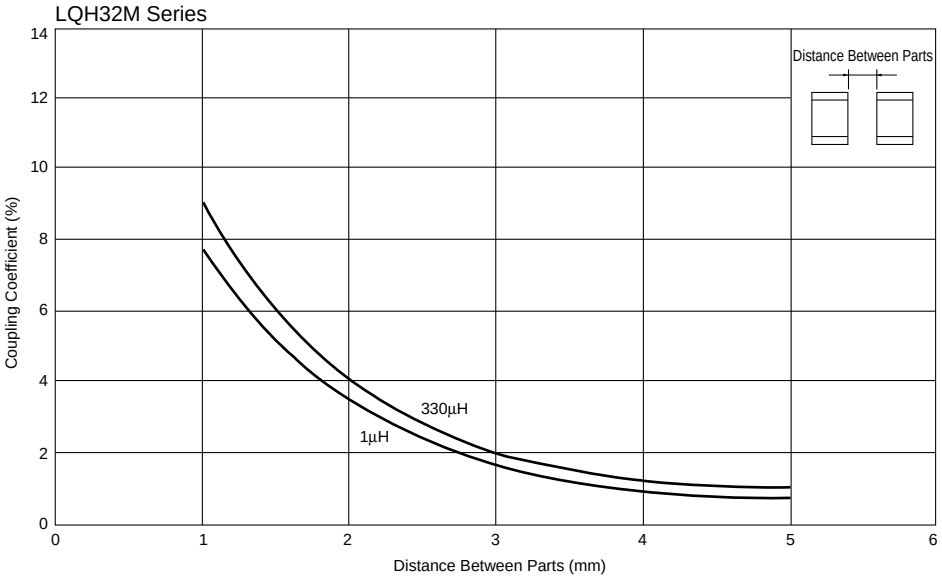
Technical Data

1. Land Area and Q-F Characteristics

PCB: Ag-Pb printed land formed on 0.6mm-thick alumina plate
Solder: H60A
Soldering: Reflow soldering
Solder layer: Sections shown by oblique lines in figure



2. Coupling coefficient versus Distance Between Parts

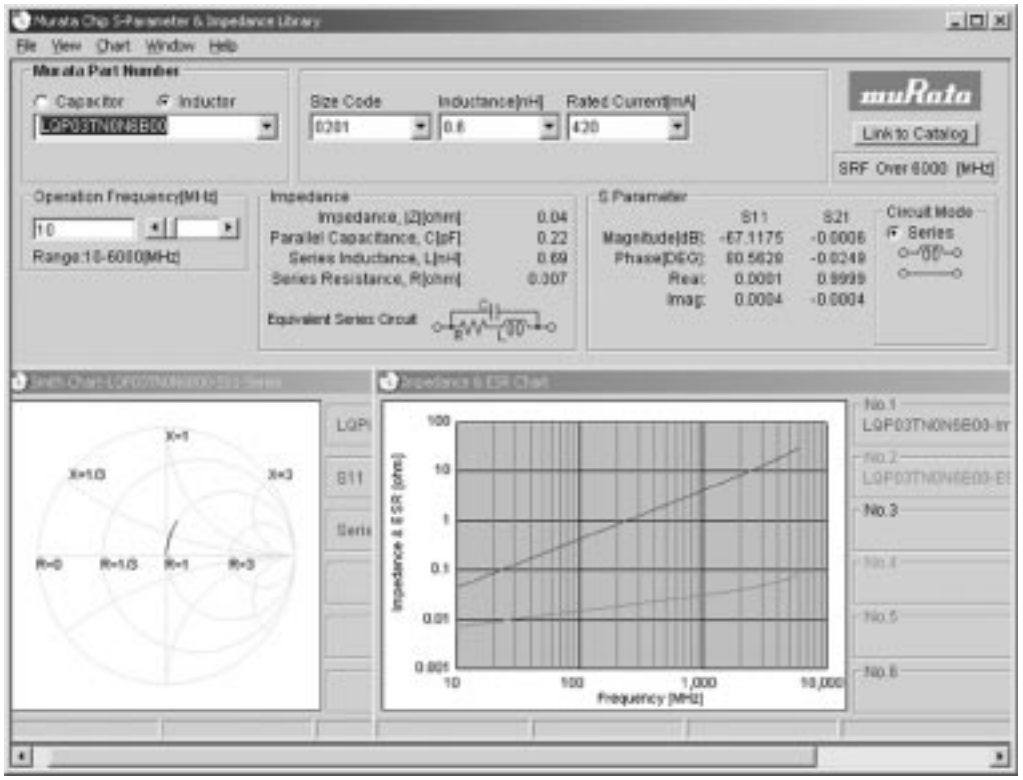


Murata Chip S-Parameter & Impedance Library

Download Service

The program enables you to calculate, view and print graphs of impedance and S parameter of chip capacitors or chip inductors.
S parameter data in Touchstone format can also be copied.

Main Window



- Easy operation due to using Windows interface.
- Fast calculation of data and graph for S parameter and impedance of chip capacitors or chip inductors.
- S parameter is saved in your personal computer and utilized for circuit simulation.

This simulator can be downloaded from Murata's website. **http://www.murata.com/products/design_support/mcsil/index.html**

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